8080 Microcomputer Systems User's Manual September 1975

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INTRODUCTION

Since their inception, digital computers have continuously become more efficient, expanding into new applications with each major technological improvement. The advent of minicomputers enabled the inclusion of digital computers as a permanent part of various process control systems. Unfortunately, the size and cost of minicomputers in "dedicated" applications has limited their use. Another approach has been the use of custom built systems made up of "random logic" (i.e., logic gates, flip-flops, counters, etc.). However, the huge expense and development time involved in the design and debugging of these systems has restricted their use to large volume applications where the development costs could be spread over a large number of machines.

Today, Intel offers the systems designer a new alternative . . . **the microcomputer.** Utilizing the technologies and experience gained in becoming the world's largest supplier of LSI memory components, Intel has made the power of the digital computer available at the integrated circuit level. Using the n-channel silicon gate MOS process, Intel engineers have implemented the fast (2 μs. cycle) and powerful (72 basic instructions) 8080 microprocessor on a single LSI chip. When this processor is combined with memory and I/O circuits, the computer is complete. Intel offers a variety of random-access memory (RAM), read-only memory (ROM) and shift register circuits, that combine with the 8080 processor to form the MCS-80™ microcomputer system, a system that can directly address and retrieve as many as 65,536 bytes stored in the memory devices.

The 8080 processor is packaged in a 40-pin dual in-line package (DIP) that allows for remarkably easy interfacing. The 8080 has a 16-bit address bus, a 8-bit bidirectional data bus and fully decoded, TTL-compatible control outputs. In addition to supporting up to 64K bytes of mixed RAM and ROM memory, the 8080 can address up to 256 input ports and 256 output ports; thus allowing for virtually unlimited system expansion. The 8080 instruction set includes conditional branching, decimal as well as binary arithmetic, logical, register-to-register, stack control and memory reference instructions. In fact, the 8080 instruction set is powerful enough to rival the performance of many of the much higher priced minicomputers, yet the 8080 is upward software compatible with Intel's earlier 8008 microprocessor (i.e., programs written for the 8008 can be assembled and executed on the 8080).

In addition to an extensive instruction set oriented to problem solving, the 8080 has another significant feature—SPEED. In contrast to random logic designs which tend to work in parallel, the microcomputer works by sequentially executing its program. As a result of this sequential execution, the number of tasks a microcomputer can undertake in a given period of time is directly proportional to the execution speed of the microcomputer. The speed of execution is the limiting factor of the realm of applications of the microcomputer. The 8080, with instruction times as short as 2 μsec., is an order of magnitude faster than earlier generations of microcomputers, and therefore has an expanded field of potential applications.

The architecture of the 8080 also shows a significant improvement over earlier microcomputer designs. The 8080 contains a 16-bit stack pointer that controls the addressing of an external stack located in memory. The pointer can be initialized via the proper instructions such that any portion of external memory can be used as a last in/first out stack; thus enabling almost unlimited subroutine nesting. The stack pointer allows the contents of the program counter, the accumulator, the condition flags or any of the data registers to be stored in or retrieved from the external stack. In addition, multi-level interrupt processing is possible using the 8080's stack control instructions. The status of the processor can be "pushed" onto the stack when an interrupt is accepted, then "popped" off the stack after the interrupt has been serviced. This ability to save the contents of the processor's registers is possible even if an interrupt service routine, itself, is interrupted.

	CONVENTIONAL SYSTEM	PROGRAMMED LOGIC
Product definition		Simplified because of ease of incorporating features
System and logic design	Done with logic diagrams	Can be programmed with design aids (compilers, assemblers, editors)
Debug	Done with conventional Lab Instrumentation	Software and hardware aids reduce time
PC card layout		Fewer cards to layout
Documentation		Less hardware to document
Cooling and packaging		Reduced system size and power consumption eases job
Power distribution		Less power to distribute
Engineering changes	Done with yellow wire	Change program

Table 0-1. The Advantages of Using Microprocessors

ADVANTAGES OF DESIGNING WITH MICROCOMPUTERS

Microcomputers simplify almost every phase of product development. The first step, as in any product development program, is to identify the various functions that the end system is expected to perform. Instead of realizing these functions with networks of gates and flip-flops, the functions are implemented by encoding suitable sequences of instructions (programs) in the memory elements. Data and certain types of programs are stored in RAM, while the basic program can be stored in ROM. The microprocessor performs all of the system's functions by fetching the instructions in memory, executing them and communicating the results via the microcomputer's I/O ports. An 8080 microprocessor, executing the programmed logic stored in a single 2048-byte ROM element, can perform the same logical functions that might have previously required up to 1000 logic gates.

The benefits of designing a microcomputer into your system go far beyond the advantages of merely simplifying product development. You will also appreciate the profit-making advantages of using a microcomputer in place of custom-designed random logic. The most apparent advantage is the significant savings in hardware costs. A microcomputer chip set replaces dozens of random logic elements, thus reducing the cost as well as the size of your system. In addition, production costs drop as the number of individual components to be handled decreases, and the number of complex printed circuit boards (which are difficult to layout, test and correct) is greatly reduced. Probably the most profitable advantage of a microcomputer is its flexibility for change. To modify your system, you merely re-program the memory elements; you don't have to redesign the entire system. You can imagine the savings in time and money when you want to upgrade your product. Reliability is another reason to choose the microcomputer over random logic. As the number of components decreases, the probability of a malfunctioning element likewise decreases. All of the logical control functions formerly performed by numerous hardware components can now be implemented in a few ROM circuits which are non-volatile; that is, the contents of ROM will never be lost, even in the event of a power failure. Table 0-1 summarizes many of the advantages of using microcomputers.

MICROCOMPUTER DESIGN AIDS

If you're used to logic design and the idea of designing with programmed logic seems like too radical a change, regardless of advantages, there's no need to worry because Intel has already done most of the groundwork for you. The INTELLEC® 8 Development Systems provide flexible, inexpensive and simplified methods for OEM product development. The INTELLEC® 8 provides RAM program storage making program loading and modification easier, a display and control console for system monitoring and debugging, a standard TTY interface, a PROM programming capability and a standard software package (System Monitor, Assembler and Test Editor). In addition to the standard software package available with the INTELLEC® 8, Intel offers a PL/M™ compiler, a cross-assembler and a simulator written in FORTRAN IV and designed to run on any large scale computer. These programs may be procured directly from Intel or from a number of nationwide computer time-sharing services. Intel's Microcomputer Systems Group is always available to provide assistance in every phase of your product development.

Intel also provides complete documentation on all their hardware and software products. In addition to this User's Manual, there are the:

- PL/M™ Language Reference Manual
- 8080 Assembly Language Programming Manual
- INTELLEC® 8/MOD 80 Operator's Manual
- INTELLEC® 8/MOD 80 Hardware Reference Manual
- 8080 User's Program Library

APPLICATIONS EXAMPLE

The 8080 can be used as the basis for a wide variety of calculation and control systems. The system configurations for particular applications will differ in the nature of the peripheral devices used and in the amount and the type of memory required. The applications and solutions described in this section are presented primarily to show how microcomputers can be used to solve design problems. The 8080 should not be considered limited either in scope or performance to those applications listed here.

Consider an 8080 microcomputer used within an automatic computing scale for a supermarket. The basic machine has two input devices: the weighing unit and a keyboard, used for function selection and to enter the price per unit of weight. The only output device is a display showing the total price, although a ticket printer might be added as an optional output device.

The control unit must accept weight information from the weighing unit, function and data inputs from the keyboard, and generate the display. The only arithmetic function to be performed is a simple multiplication of weight times rate.

The control unit could probably be realized with standard TTL logic. State diagrams for the various portions could be drawn and a multiplier unit designed. The whole design could then be tied together, and eventually reduced to a selection of packages and a printed circuit board layout. In effect, when designing with a logic family such as TTL, the designs are "customized" by the choice of packages and the wiring of the logic.

If, however, an 8080 microcomputer is used to realize the control unit (as shown in Figure 0-1), the only "custom" logic will be that of the interface circuits. These circuits are usually quite simple, providing electrical buffering for the input and output signals.

Instead of drawing state diagrams leading to logic, the system designer now prepares a flow chart, indicating which input signals must be read, what processing and computations are needed, and what output signals must be produced. A program is written from the flow chart. The program is then assembled into bit patterns which are loaded into the program memory. Thus, this system is customized primarily by the contents of program memory.

For this automatic scale, the program would probably reside in read-only memory (ROM), since the microcomputer would always execute the same program, the one which implements the scale functions. The processor would constantly monitor the keyboard and weighing unit, and update the display whenever necessary. The unit would require very little data memory; it would only be needed for rate storage, intermediate results, and for storing a copy of the display.

When the control portion of a product is implemented with a microcomputer chip set, functions can be changed and features added merely by altering the program in memory. With a TTL based system, however, alterations may require extensive rewiring, alteration of PC boards, etc.

The number of applications for microcomputers is limited only by the depth of the designer's imagination. We have listed a few potential applications in Table 0-2, along with the types of peripheral devices usually associated with each product.

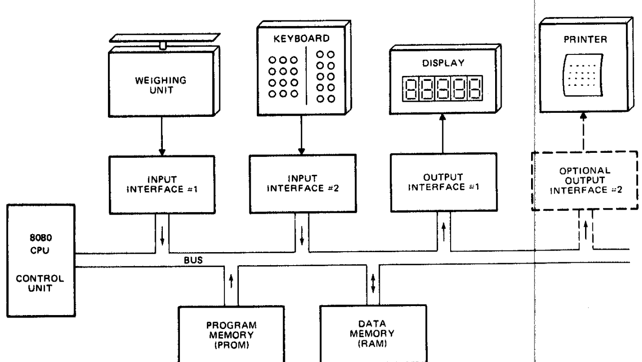


Figure 0-1. Microcomputer Application — Automatic Scale

with a clearly defined activity is called a **State**. And the interval between pulses of the timing oscillator is referred to as a **Clock Period**. As a general rule, one or more clock periods are necessary for the completion of a state, and there are several states in a cycle.

Instruction Fetch:

The first state(s) of any instruction cycle will be dedicated to fetching the next instruction. The CPU issues a read signal and the contents of the program counter are sent to memory, which responds by returning the next instruction word. The first byte of the instruction is placed in the instruction register. If the instruction consists of more than one byte, additional states are required to fetch each byte of the instruction. When the entire instruction is present in the CPU, the program counter is incremented (in preparation for the next instruction fetch) and the instruction is decoded. The operation specified in the instruction will be executed in the remaining states of the instruction cycle. The instruction may call for a memory read or write, an input or output and/or an internal CPU operation, such as a register-to-register transfer or an add-registers operation.

Memory Read:

An instruction **fetch** is merely a special memory read operation that brings the instruction to the CPU's instruction register. The instruction fetched may then call for data to be read from memory into the CPU. The CPU again issues a read signal and sends the proper memory address; memory responds by returning the requested word. The data received is placed in the accumulator or one of the other general purpose registers (not the instruction register).

Memory Write:

A memory write operation is similar to a read except for the direction of data flow. The CPU issues a write signal, sends the proper memory address, then sends the data word to be written into the addressed memory location.

Wait (memory synchronization):

As previously stated, the activities of the processor are timed by a master clock oscillator. The clock period determines the timing of all processing activity.

The speed of the processing cycle, however, is limited by the memory's **Access Time**. Once the processor has sent a read address to memory, it cannot proceed until the memory has had time to respond. Most memories are capable of responding much faster than the processing cycle requires. A few, however, cannot supply the addressed byte within the minimum time established by the processor's clock.

Therefore a processor should contain a synchronization provision, which permits the memory to request a **Wait state**. When the memory receives a read or write enable signal, it places a request signal on the processor's READY line, causing the CPU to idle temporarily. After the memory has had time to respond, it frees the processor's READY line, and the instruction cycle proceeds.

Input/Output:

Input and Output operations are similar to memory read and write operations with the exception that a peripheral I/O device is addressed instead of a memory location. The CPU issues the appropriate input or output control signal, sends the proper device address and either receives the data being input or sends the data to be output.

Data can be input/output in either parallel or serial form. All data within a digital computer is represented in binary coded form. A binary data word consists of a group of bits; each bit is either a one or a zero. **Parallel** I/O consists of transferring all bits in the word at the same time, one bit per line. **Serial** I/O consists of transferring one bit at a time on a single line. Naturally serial I/O is much slower, but it requires considerably less hardware than does parallel I/O.

Interrupts:

Interrupt provisions are included on many central processors, as a means of improving the processor's efficiency. Consider the case of a computer that is processing a large volume of data, portions of which are to be output to a printer. The CPU can output a byte of data within a single machine cycle but it may take the printer the equivalent of many machine cycles to actually print the character specified by the data byte. The CPU could then remain idle waiting until the printer can accept the next data byte. If an interrupt capability is implemented on the computer, the CPU can output a data byte then return to data processing. When the printer is ready to accept the next data byte, it can request an interrupt. When the CPU acknowledges the interrupt, it suspends main program execution and automatically branches to a routine that will output the next data byte. After the byte is output, the CPU continues with main program execution. Note that this is, in principle, quite similar to a subroutine call, except that the jump is initiated externally rather than by the program.

More complex interrupt structures are possible, in which several interrupting devices share the same processor but have different priority levels. Interruptive processing is an important feature that enables maximum utilization of a processor's capacity for high system throughput.

Hold:

Another important feature that improves the throughput of a processor is the **Hold**. The hold provision enables **Direct Memory Access** (DMA) operations.

In ordinary input and output operations, the processor itself supervises the entire data transfer. Information to be placed in memory is transferred from the input device to the processor, and then from the processor to the designated memory location. In similar fashion, information that goes

CHAPTER 1 THE FUNCTIONS OF A COMPUTER

This chapter introduces certain basic computer concepts. It provides background information and definitions which will be useful in later chapters of this manual. Those already familiar with computers may skip this material, at their option.

A TYPICAL COMPUTER SYSTEM

A typical digital computer consists of:

a) A central processor unit (CPU)
b) A memory
c) Input/output (I/O) ports

The memory serves as a place to store **Instructions**, the coded pieces of information that direct the activities of the CPU, and **Data**, the coded pieces of information that are processed by the CPU. A group of logically related instructions stored in memory is referred to as a **Program**. The CPU "reads" each instruction from memory in a logically determined sequence, and uses it to initiate processing actions. If the program sequence is coherent and logical, processing the program will produce intelligible and useful results.

The memory is also used to store the data to be manipulated, as well as the instructions that direct that manipulation. The program must be organized such that the CPU does not read a non-instruction word when it expects to see an instruction. The CPU can rapidly access any data stored in memory; but often the memory is not large enough to store the entire data bank required for a particular application. The problem can be resolved by providing the computer with one or more **Input Ports**. The CPU can address these ports and input the data contained there. The addition of input ports enables the computer to receive information from external equipment (such as a paper tape reader or floppy disk) at high rates of speed and in large volumes.

A computer also requires one or more **Output Ports** that permit the CPU to communicate the result of its processing to the outside world. The output may go to a display, for use by a human operator, to a peripheral device that produces "hard-copy," such as a line-printer, to a peripheral storage device, such as a floppy disk unit, or the output may constitute process control signals that direct the operations of another system, such as an automated assembly line. Like input ports, output ports are addressable. The input and output ports together permit the processor to communicate with the outside world.

The CPU unifies the system. It controls the functions performed by the other components. The CPU must be able to fetch instructions from memory, decode their binary contents and execute them. It must also be able to reference memory and I/O ports as necessary in the execution of instructions. In addition, the CPU should be able to recognize and respond to certain external control signals, such as INTERRUPT and WAIT requests. The functional units within a CPU that enable it to perform these functions are described below.

THE ARCHITECTURE OF A CPU

A typical central processor unit (CPU) consists of the following interconnected functional units:

- Registers
- Arithmetic/Logic Unit (ALU)
- Control Circuitry

Registers are temporary storage units within the CPU. Some registers, such as the program counter and instruction register, have dedicated uses. Other registers, such as the accumulator, are for more general purpose use.

Accumulator:

The accumulator usually stores one of the operands to be manipulated by the ALU. A typical instruction might direct the ALU to add the contents of some other register to the contents of the accumulator and store the result in the accumulator itself. In general, the accumulator is both a source (operand) and a destination (result) register.

Often a CPU will include a number of additional general purpose registers that can be used to store operands or intermediate data. The availability of general purpose

Code or **Operation Code**. An eight-bit word used as an instruction code can distinguish between 256 alternative actions, more than adequate for most processors.

The processor fetches an instruction in two distinct operations. First, the processor transmits the address in its Program Counter to the memory. Then the memory returns the addressed byte to the processor. The CPU stores this instruction byte in a register known as the **Instruction Register**, and uses it to direct activities during the remainder of the instruction execution.

The mechanism by which the processor translates an instruction code into specific processing actions requires more elaboration than we can here afford. The concept, however, should be intuitively clear to any logic designer. The eight bits stored in the instruction register can be decoded and used to selectively activate one of a number of output lines, in this case up to 256 lines. Each line represents a set of activities associated with execution of a particular instruction code. The enabled line can be combined with selected timing pulses, to develop electrical signals that can then be used to initiate specific actions. This translation of code into action is performed by the **Instruction Decoder** and by the associated control circuitry.

An eight-bit instruction code is often sufficient to specify a particular processing action. There are times, however, when execution of the instruction requires more information than eight bits can convey.

One example of this is when the instruction references a memory location. The basic instruction code identifies the operation to be performed, but cannot specify the object address as well. In a case like this, a two- or three-byte instruction must be used. Successive instruction bytes are stored in sequentially adjacent memory locations, and the processor performs two or three fetches in succession to obtain the full instruction. The first byte retrieved from memory is placed in the processor's instruction register, and subsequent bytes are placed in temporary storage; the processor then proceeds with the execution phase. Such an instruction is referred to as **Variable Length**.

Address Register(s):

A CPU may use a register or register-pair to hold the address of a memory location that is to be accessed for data. If the address register is **Programmable**, (i.e., if there are instructions that allow the programmer to alter the contents of the register) the program can "build" an address in the address register prior to executing a **Memory Reference** instruction (i.e., an instruction that reads data from memory, writes data to memory or operates on data stored in memory).

Arithmetic/Logic Unit (ALU):

All processors contain an arithmetic/logic unit, which is often referred to simply as the **ALU**. The ALU, as its name implies, is that portion of the CPU hardware which performs the arithmetic and logical operations on the binary data.

The ALU must contain an **Adder** which is capable of combining the contents of two registers in accordance with the logic of binary arithmetic. This provision permits the processor to perform arithmetic manipulations on the data it obtains from memory and from its other inputs.

Using only the basic adder a capable programmer can write routines which will subtract, multiply and divide, giving the machine complete arithmetic capabilities. In practice, however, most ALUs provide other built-in functions, including hardware subtraction, boolean logic operations, and shift capabilities.

The ALU contains **Flag Bits** which specify certain conditions that arise in the course of arithmetic and logical manipulations. Flags typically include **Carry, Zero, Sign,** and **Parity**. It is possible to program jumps which are conditionally dependent on the status of one or more flags. Thus, for example, the program may be designed to jump to a special routine if the carry bit is set following an addition instruction.

Control Circuitry:

The control circuitry is the primary functional unit within a CPU. Using clock inputs, the control circuitry maintains the proper sequence of events required for any processing task. After an instruction is fetched and decoded, the control circuitry issues the appropriate signals (to units both internal and external to the CPU) for initiating the proper processing action. Often the control circuitry will be capable of responding to external signals, such as an interrupt or wait request. An **Interrupt** request will cause the control circuitry to temporarily interrupt main program execution, jump to a special routine to service the interrupting device, then automatically return to the main program. A **Wait** request is often issued by a memory or I/O element that operates slower than the CPU. The control circuitry will idle the CPU until the memory or I/O port is ready with the data.

COMPUTER OPERATIONS

There are certain operations that are basic to almost any computer. A sound understanding of these basic operations is a necessary prerequisite to examining the specific operations of a particular computer.

Timing:

The activities of the central processor are cyclical. The processor fetches an instruction, performs the operations required, fetches the next instruction, and so on. This orderly sequence of events requires precise timing, and the CPU therefore requires a free running oscillator clock which furnishes the reference for all processor actions. The combined fetch and execution of a single instruction is referred to as an **Instruction Cycle**. The portion of a cycle identified be synchronized with the pulses of the driving clock. Thus, the duration of all states are integral multiples of the clock period.

To summarize then, each **clock period** marks a **state;** three to five states constitute a machine cycle; and one to five **machine cycles** comprise an **instruction cycle**. A full instruction cycle requires anywhere from four to eighteen states for its completion, depending on the kind of instruction involved.

Machine Cycle Identification:

With the exception of the DAD instruction, there is just one consideration that determines how many machine cycles are required in any given instruction cycle: the number of times that the processor must reference a memory address or an addressable peripheral device, in order to fetch and execute the instruction. Like many processors, the 8080 is so constructed that it can transmit only one address per machine cycle. Thus, if the fetch and execution of an instruction requires two memory references, then the instruction cycle associated with that instruction consists of two machine cycles. If five such references are called for, then the instruction cycle contains five machine cycles.

Every instruction cycle has at least one reference to memory, during which the instruction is fetched. An instruction cycle must always have a fetch, even if the execution of the instruction requires no further references to memory. The first machine cycle in every instruction cycle is therefore a FETCH. Beyond that, there are no fast rules. It depends on the kind of instruction that is fetched.

Consider some examples. The add-register (ADD r) instruction is an instruction that requires only a single machine cycle (FETCH) for its completion. In this one-byte instruction, the contents of one of the CPU's six general purpose registers is added to the existing contents of the accumulator. Since all the information necessary to execute the command is contained in the eight bits of the instruction code, only one memory reference is necessary. Three states are used to extract the instruction from memory, and one additional state is used to accomplish the desired addition. The entire instruction cycle thus requires only one machine cycle that consists of four states, or four periods of the external clock.

Suppose now, however, that we wish to add the contents of a specific memory location to the existing contents of the accumulator (ADD M). Although this is quite similar in principle to the example just cited, several additional steps will be used. An extra machine cycle will be used, in order to address the desired memory location.

The actual sequence is as follows. First the processor extracts from memory the one-byte instruction word addressed by its program counter. This takes three states. The eight-bit instruction word obtained during the FETCH machine cycle is deposited in the CPU's instruction register and used to direct activities during the remainder of the instruction cycle. Next, the processor sends out, as an address, the contents of its H and L registers. The eight-bit data word returned during this MEMORY READ machine cycle is placed in a temporary register inside the 8080 CPU. By now three more clock periods (states) have elapsed. In the seventh and final state, the contents of the temporary register are added to those of the accumulator. Two machine cycles, consisting of seven states in all, complete the "ADD M" instruction cycle.

At the opposite extreme is the save H and L registers (SHLD) instruction, which requires five machine cycles. During an "SHLD" instruction cycle, the contents of the processor's H and L registers are deposited in two sequentially adjacent memory locations; the destination is indicated by two address bytes which are stored in the two memory locations immediately following the operation code byte. The following sequence of events occurs:

(1) A FETCH machine cycle, consisting of four states. During the first three states of this machine cycle, the processor fetches the instruction indicated by its program counter. The program counter is then incremented. The fourth state is used for internal instruction decoding.

(2) A MEMORY READ machine cycle, consisting of three states. During this machine cycle, the byte indicated by the program counter is read from memory and placed in the processor's Z register. The program counter is incremented again.

(3) Another MEMORY READ machine cycle, consisting of three states, in which the byte indicated by the processor's program counter is read from memory and placed in the W register. The program counter is incremented, in anticipation of the next instruction fetch.

(4) A MEMORY WRITE machine cycle, of three states, in which the contents of the L register are transferred to the memory location pointed to by the present contents of the W and Z registers. The state following the transfer is used to increment the W,Z register pair so that it indicates the next memory location to receive data.

(5) A MEMORY WRITE machine cycle, of three states, in which the contents of the H register are transferred to the new memory location pointed to by the W,Z register pair.

In summary, the "SHLD" instruction cycle contains five machine cycles and takes 16 states to execute.

Most instructions fall somewhere between the extremes typified by the "ADD r" and the "SHLD" instructions. The input (INP) and the output (OUT) instructions, for example, require three machine cycles: a FETCH, to obtain the instruction; a MEMORY READ, to obtain the address of the object peripheral; and an INPUT or an OUTPUT machine cycle, to complete the transfer.

from memory to output devices goes by way of the processor.

Some peripheral devices, however, are capable of transferring information to and from memory much faster than the processor itself can accomplish the transfer. If any appreciable quantity of data must be transferred to or from such a device, then **system throughput** will be increased by having the device accomplish the transfer directly. The processor must temporarily suspend its operation during such a transfer, to prevent conflicts that would arise if processor and peripheral device attempted to access memory simultaneously. It is for this reason that a **hold** provision is included on some processors.

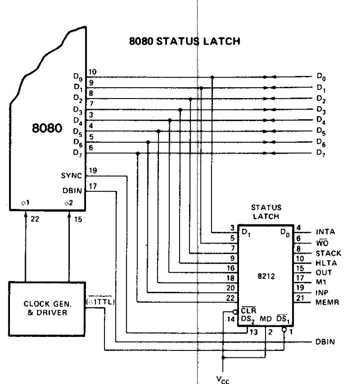
Instructions for the 8080 require from one to five machine cycles for complete execution. The 8080 sends out 8 bit of status information on the data bus at the beginning of each machine cycle (during SYNC time). The following table defines the status information.

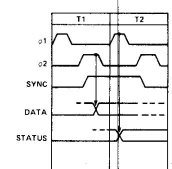
STATUS INFORMATION DEFINITION

Symbols	Data Bus Bit	Definition
INTA*	D_0	Acknowledge signal for INTERRUPT request. Signal should be used to gate a restart instruction onto the data bus when DBIN is active.
$\overline{WO}$	D_1	Indicates that the operation in the current machine cycle will be a WRITE memory or OUTPUT function ($\overline{WO}$ = 0). Otherwise, a READ memory or INPUT operation will be executed.
STACK	D_2	Indicates that the address bus holds the pushdown stack address from the Stack Pointer.
HLTA	D_3	Acknowledge signal for HALT instruction.
OUT	D_4	Indicates that the address bus contains the address of an output device and the data bus will contain the output data when $\overline{WR}$ is active.
M_1	D_5	Provides a signal to indicate that the CPU is in the fetch cycle for the first byte of an instruction.
INP*	D_6	Indicates that the address bus contains the address of an input device and the input data should be placed on the data bus when DBIN is active.
MEMR*	D_7	Designates that the data bus will be used for memory read data.

*These three status bits can be used to control the flow of data onto the 8080 data bus.

8080 STATUS LATCH





STATUS WORD CHART

TYPE OF MACHINE CYCLE

Ⓝ STATUS WORD

DATA BUS BIT	STATUS INFORMATION	① INSTRUCTION FETCH	② MEMORY READ	③ MEMORY WRITE	④ STACK READ	⑤ STACK WRITE	⑥ INPUT READ	⑦ OUTPUT WRITE	⑧ INTERRUPT ACKNOWLEDGE	⑨ HALT ACKNOWLEDGE	⑩ INTERRUPT ACKNOWLEDGE WHILE HALT
D_0	INTA	0	0	0	0	0	0	0	1	0	1
D_1	$\overline{WO}$	1	1	0	1	0	1	0	1	1	1
D_2	STACK	0	0	0	1	1	0	0	0	0	0
D_3	HLTA	0	0	0	0	0	0	0	0	1	1
D_4	OUT	0	0	0	0	0	0	1	0	0	0
D_5	M_1	1	0	0	0	0	0	0	1	0	1
D_6	INP	0	0	0	0	0	1	0	0	0	0
D_7	MEMR	1	1	0	1	0	0	0	0	1	0

Table 2-1. 8080 Status Bit Definitions

CHAPTER 2
THE 8080 CENTRAL PROCESSOR UNIT

The 8080 is a complete 8-bit parallel, central processor unit (CPU) for use in general purpose digital computer systems. It is fabricated on a single LSI chip (see Figure 3-1). using Intel's n-channel silicon gate MOS process. The 8080 transfers data and internal state information via an 8-bit, bidirectional 3-state Data Bus (D_0-D_7). Memory and peripheral device addresses are transmitted over a separate 16-bit 3-state Address Bus (A_0-A_{15}). Six timing and control outputs (SYNC, DBIN, WAIT, $\overline{WR}$, HLDA and INTE) emanate from the 8080, while four control inputs (READY, HOLD, INT and RESET), four power inputs (+12v, +5v, -5v, and GND) and two clock inputs (ϕ_1 and ϕ_2) are accepted by the 8080.

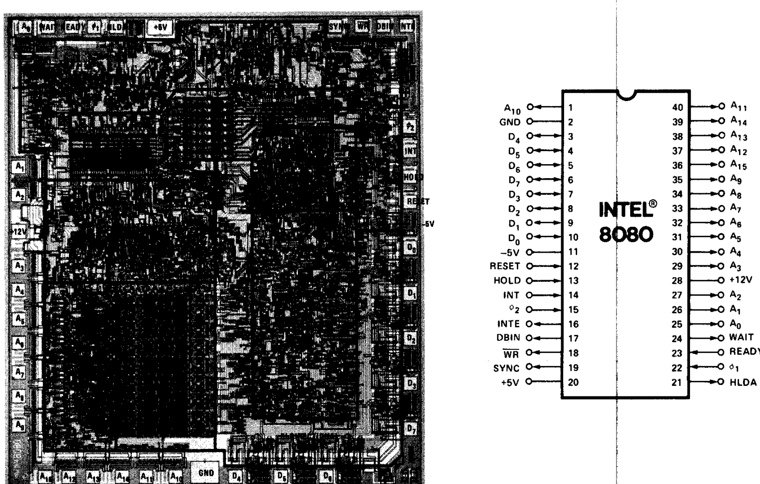


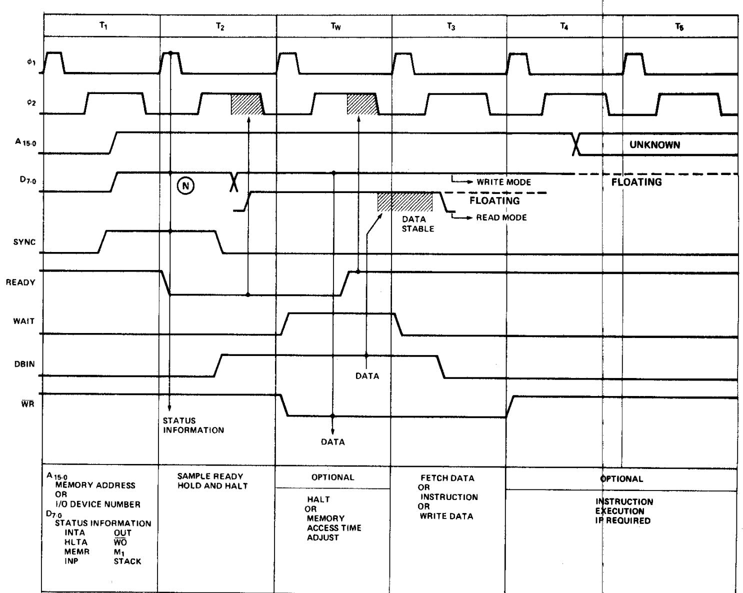
Figure 2-1. 8080 Photomicrograph With Pin Designations

The events that take place during the T_3 state are determined by the kind of machine cycle in progress. In a FETCH machine cycle, the processor interprets the data on its data bus as an instruction. During a MEMORY READ or a STACK READ, data on this bus is interpreted as a data word. The processor outputs data on this bus during a MEMORY WRITE machine cycle. During I/O operations, the processor may either transmit or receive data, depending on whether an OUTPUT or an INPUT operation is involved.

Figure 2-6 illustrates the timing that is characteristic of a data input operation. As shown, the low-to-high transition of ϕ_2 during T_2 clears status information from the processor's data lines, preparing these lines for the receipt of incoming data. The data presented to the processor must have stabilized prior to both the "ϕ_1–data set-up" interval (t_{DS1}), that precedes the falling edge of the ϕ_1 pulse defining state T_3, and the "ϕ_2–data set-up" interval (t_{DS2}), that precedes the rising edge of ϕ_2 in state T_3. This same data must remain stable during the "data hold" interval (t_{DH}) that occurs following the rising edge of the ϕ_2 pulse. Data placed on these lines by memory or by other external devices will be sampled during T_3.

During the input of data to the processor, the 8080 generates a DBIN signal which should be used externally to enable the transfer. Machine cycles in which DBIN is available include: FETCH, MEMORY READ, STACK READ, and INTERRUPT. DBIN is initiated by the rising edge of ϕ_2 during state T2 and terminated by the corresponding edge of ϕ_2 during T_3. Any T_W phases intervening between T_2 and T_3 will therefore extend DBIN by one or more clock periods.

Figure 2-7 shows the timing of a machine cycle in which the processor outputs data. Output data may be destined either for memory or for peripherals. The rising edge of ϕ_2 within state T_2 clears status information from the CPU's data lines, and loads in the data which is to be output to external devices. This substitution takes place within the



NOTE: (N) Refer to Status Word Chart on Page 2-6.

Figure 2-5. Basic 8080 Instruction Cycle

Arithmetic and Logic Unit (ALU):

The ALU contains the following registers:

- An 8-bit accumulator
- An 8-bit temporary accumulator (ACT)
- A 5-bit flag register: zero, carry, sign, parity and auxiliary carry
- An 8-bit temporary register (TMP)

Arithmetic, logical and rotate operations are performed in the ALU. The ALU is fed by the temporary register (TMP) and the temporary accumulator (ACT) and carry flip-flop. The result of the operation can be transferred to the internal bus or to the accumulator; the ALU also feeds the flag register.

The temporary register (TMP) receives information from the internal bus and can send all or portions of it to the ALU, the flag register and the internal bus.

The accumulator (ACC) can be loaded from the ALU and the internal bus and can transfer data to the temporary accumulator (ACT) and the internal bus. The contents of the accumulator (ACC) and the auxiliary carry flip-flop can be tested for decimal correction during the execution of the DAA instruction (see Chapter 4).

Instruction Register and Control:

During an instruction fetch, the first byte of an instruction (containing the OP code) is transferred from the internal bus to the 8-bit instruction register.

The contents of the instruction register are, in turn, available to the instruction decoder. The output of the decoder, combined with various timing signals, provides the control signals for the register array, ALU and data buffer blocks. In addition, the outputs from the instruction decoder and external control signals feed the timing and state control section which generates the state and cycle timing signals.

Data Bus Buffer:

This 8-bit bidirectional 3-state buffer is used to isolate the CPU's internal bus from the external data bus (D_0 through D_7). In the output mode, the internal bus content is loaded into an 8-bit latch that, in turn, drives the data bus output buffers. The output buffers are switched off during input or non-transfer operations.

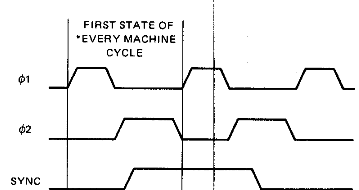
During the input mode, data from the external data bus is transferred to the internal bus. The internal bus is precharged at the beginning of each internal state, except for the transfer state (T_3—described later in this chapter).

THE PROCESSOR CYCLE

An **instruction cycle** is defined as the time required to fetch and execute an instruction. During the fetch, a selected instruction (one, two or three bytes) is extracted from memory and deposited in the CPU's instruction register. During the execution phase, the instruction is decoded and translated into specific processing activities.

Every instruction cycle consists of one, two, three, four or five machine cycles. A **machine cycle** is required each time the CPU accesses memory or an I/O port. The fetch portion of an instruction cycle requires one machine cycle for each byte to be fetched. The duration of the execution portion of the instruction cycle depends on the kind of instruction that has been fetched. Some instructions do not require any machine cycles other than those necessary to fetch the instruction; other instructions, however, require additional machine cycles to write or read data to/from memory or I/O devices. The DAD instruction is an exception in that it requires two additional machine cycles to complete an internal register-pair add (see Chapter 4).

Each machine cycle consists of three, four or five states. A state is the smallest unit of processing activity and is defined as the interval between two successive positive-going transitions of the ϕ_1 driven clock pulse. The 8080 is driven by a two-phase clock oscillator. All processing activities are referred to the period of this clock. The two non-overlapping clock pulses, labeled ϕ_1 and ϕ_2, are furnished by external circuitry. It is the ϕ_1 clock pulse which divides each machine cycle into states. Timing logic within the 8080 uses the clock inputs to produce a SYNC pulse, which identifies the beginning of every machine cycle. The SYNC pulse is triggered by the low-to-high transition of ϕ_2, as shown in Figure 2-3.



*SYNC DOES NOT OCCUR IN THE SECOND AND THIRD MACHINE CYCLES OF A DAD INSTRUCTION SINCE THESE MACHINE CYCLES ARE USED FOR AN INTERNAL REGISTER-PAIR ADD.

Figure 2-3. ϕ_1, ϕ_2 And SYNC Timing

There are three exceptions to the defined duration of a state. They are the WAIT state, the hold (HLDA) state and the halt (HLTA) state, described later in this chapter. Because the WAIT, the HLDA, and the HLTA states depend upon external events, they are by their nature of indeterminate length. Even these exceptional states, however, must

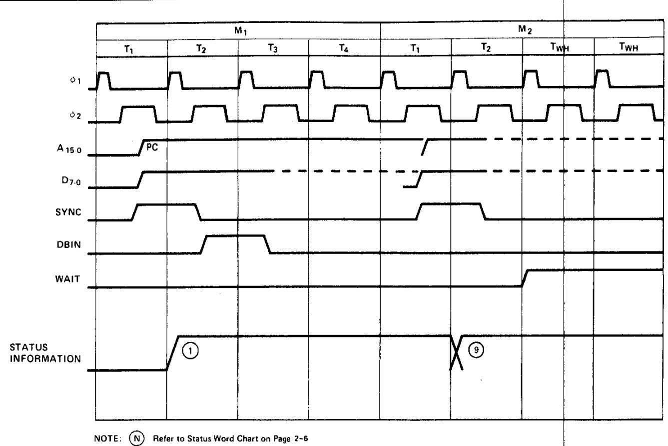


Figure 2-11. HALT Timing

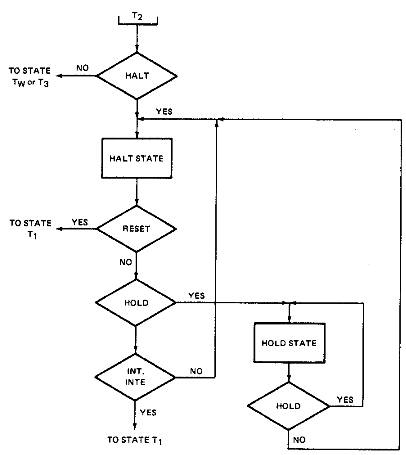


Figure 2-12. HALT Sequence Flow Chart.

While no one instruction cycle will consist of more then five machine cycles, the following ten different types of machine cycles may occur within an instruction cycle:

(1) FETCH (M1)

(2) MEMORY READ

(3) MEMORY WRITE

(4) STACK READ

(5) STACK WRITE

(6) INPUT

(7) OUTPUT

(8) INTERRUPT

(9) HALT

(10) HALT • INTERRUPT

The machine cycles that actually do occur in a particular instruction cycle depend upon the kind of instruction, with the overriding stipulation that the first machine cycle in any instruction cycle is always a FETCH.

The processor identifies the machine cycle in progress by transmitting an eight-bit status word during the first state of every machine cycle. Updated status information is presented on the 8080's data lines (D_0-D_7), during the SYNC interval. This data should be saved in latches, and used to develop control signals for external circuitry. Table 2-1 shows how the positive-true status information is distributed on the processor's data bus.

Status signals are provided principally for the control of external circuitry. Simplicity of interface, rather than machine cycle identification, dictates the logical definition of individual status bits. You will therefore observe that certain processor machine cycles are uniquely identified by a single status bit, but that others are not. The M_1 status bit (D_6), for example, unambiguously identifies a FETCH machine cycle. A STACK READ, on the other hand, is indicated by the coincidence of STACK and MEMR signals. Machine cycle identification data is also valuable in the test and de-bugging phases of system development. Table 2-1 lists the status bit outputs for each type of machine cycle.

State Transition Sequence:

Every machine cycle within an instruction cycle consists of three to five active states (referred to as T_1, T_2, T_3, T_4, T_5 or T_W). The actual number of states depends upon the instruction being executed, and on the particular machine cycle within the greater instruction cycle. The state transition diagram in Figure 2-4 shows how the 8080 proceeds from state to state in the course of a machine cycle. The diagram also shows how the READY, HOLD, and INTERRUPT lines are sampled during the machine cycle, and how the conditions on these lines may modify the basic transition sequence. In the present discussion, we are concerned only with the basic sequence and with the READY function. The HOLD and INTERRUPT functions will be discussed later.

The 8080 CPU does not directly indicate its internal state by transmitting a "state control" output during each state; instead, the 8080 supplies direct control output (INTE, HLDA, DBIN, $\overline{WR}$ and WAIT) for use by external circuitry.

Recall that the 8080 passes through at least three states in every machine cycle, with each state defined by successive low-to-high transitions of the ϕ_1 clock. Figure 2-5 shows the timing relationships in a typical FETCH machine cycle. Events that occur in each state are referenced to transitions of the ϕ_1 and ϕ_2 clock pulses.

The SYNC signal identifies the first state (T_1) in every machine cycle. As shown in Figure 2-5, the SYNC signal is related to the leading edge of the ϕ_2 clock. There is a delay (t_{DC}) between the low-to-high transition of ϕ_2 and the positive-going edge of the SYNC pulse. There also is a corresponding delay (also t_{DC}) between the next ϕ_2 pulse and the falling edge of the SYNC signal. Status information is displayed on D_0-D_7 during the same ϕ_2 to ϕ_2 interval. Switching of the status signals is likewise controlled by ϕ_2.

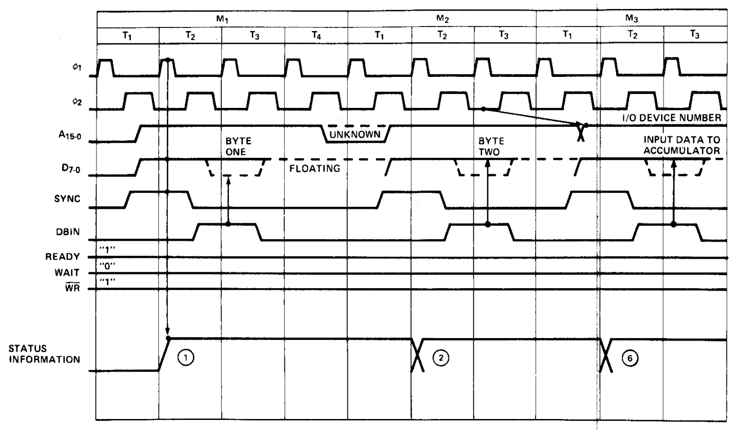
The rising edge of ϕ_2 during T_1 also loads the processor's address lines (A_0-A15). These lines become stable within a brief delay (t_{DA}) of the ϕ_2 clocking pulse, and they remain stable until the first ϕ_2 pulse after state T_3. This gives the processor ample time to read the data returned from memory.

Once the processor has sent an address to memory, there is an opportunity for the memory to request a WAIT. This it does by pulling the processor's READY line low, prior to the "Ready set-up" interval (t_{RS}) which occurs during the ϕ_2 pulse within state T_2 or T_W. As long as the READY line remains low, the processor will idle, giving the memory time to respond to the addressed data request. Refer to Figure 2-5.

The processor responds to a wait request by entering an alternative state (T_W) at the end of T_2, rather than proceeding directly to the T_3 state. Entry into the T_W state is indicated by a WAIT signal from the processor, acknowledging the memory's request. A low-to-high transition on the WAIT line is triggered by the rising edge of the ϕ_1 clock and occurs within a brief delay (t_{DC}) of the actual entry into the T_W state.

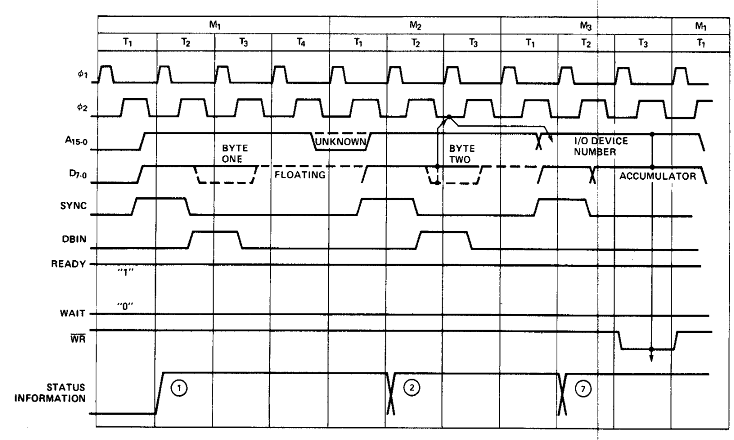
A wait period may be of indefinite duration. The processor remains in the waiting condition until its READY line again goes high. A READY indication **must** precede the falling edge of the ϕ_2 clock by a specified interval (t_{RS}), in order to guarantee an exit from the T_W state. The cycle may then proceed, beginning with the rising edge of the next ϕ_1 clock. A WAIT interval will therefore consist of an integral number of T_W states and will always be a multiple of the clock period.

MNEMONIC	OP CODE		M1[1]					M2		
	$D_7 D_6 D_5 D_4$	$D_3 D_2 D_1 D_0$	T1	T2[2]	T3	T4	T5	T1	T2[2]	T3
MOV r1, r2	0 1 D D	D S S S	PC OUT STATUS	PC = PC +1	INST→TMP/IR	(SSS)→TMP	(TMP)→DDD			
MOV r, M	0 1 D D	D 1 1 0				X[3]		HL OUT STATUS[6]	DATA →	DDD
MOV M, r	0 1 1 1	0 S S S				(SSS)→TMP		HL OUT STATUS[7]	(TMP) →	DATA BUS
SPHL	1 1 1 1	1 0 0 1				(HL) →	SP			
MVI r, data	0 0 D D	D 1 1 0				X		PC OUT STATUS[6]	B2 →	DDDD
MVI M, data	0 0 1 1	0 1 1 0				X			B2 →	TMP
LXI rp, data	0 0 R P	0 0 0 1				X			PC = PC + 1 B2 →	r1
LDA addr	0 0 1 1	1 0 1 0				X			PC = PC + 1 B2 →	Z
STA addr	0 0 1 1	0 0 1 0				X			PC = PC + 1 B2 →	Z
LHLD addr	0 0 1 0	1 0 1 0				X			PC = PC + 1 B2 →	Z
SHLD addr	0 0 1 0	0 0 1 0				X		PC OUT STATUS[6]	PC = PC + 1 B2 →	Z
LDAX rp[4]	0 0 R P	1 0 1 0				X		rp OUT STATUS[6]	DATA →	A
STAX rp[4]	0 0 R P	0 0 1 0				X		rp OUT STATUS[7]	(A) →	DATA BUS
XCHG	1 1 1 0	1 0 1 1				(HL)↔(DE)				
ADD r	1 0 0 0	0 S S S				(SSS)→TMP (A)→ACT		[9]	(ACT)+(TMP)→A	
ADD M	1 0 0 0	0 1 1 0				(A)→ACT		HL OUT STATUS[6]	DATA →	TMP
ADI data	1 1 0 0	0 1 1 0				(A)→ACT		PC OUT STATUS[6]	PC = PC + 1 B2 →	TMP
ADC r	1 0 0 0	1 S S S				(SSS)→TMP (A)→ACT		[9]	(ACT)+(TMP)+CY→A	
ADC M	1 0 0 0	1 1 1 0				(A)→ACT		HL OUT STATUS[6]	DATA →	TMP
ACI data	1 1 0 0	1 1 1 0				(A)→ACT		PC OUT STATUS[6]	PC = PC + 1 B2 →	TMP
SUB r	1 0 0 1	0 S S S				(SSS)→TMP (A)→ACT		[9]	(ACT)-(TMP)→A	
SUB M	1 0 0 1	0 1 1 0				(A)→ACT		HL OUT STATUS[6]	DATA →	TMP
SUI data	1 1 0 1	0 1 1 0				(A)→ACT		PC OUT STATUS[6]	PC = PC + 1 B2 →	TMP
SBB r	1 0 0 1	1 S S S				(SSS)→TMP (A)→ACT		[9]	(ACT)-(TMP)-CY→A	
SBB M	1 0 0 1	1 1 1 0				(A)→ACT		HL OUT STATUS[6]	DATA →	TMP
SBI data	1 1 0 1	1 1 1 0				(A)→ACT		PC OUT STATUS[6]	PC = PC + 1 B2 →	TMP
INR r	0 0 D D	D 1 0 0				(DDD)→TMP (TMP) + 1→ALU	ALU→DDD			
INR M	0 0 1 1	0 1 0 0				X		HL OUT STATUS[6]	DATA → (TMP)+1 →	TMP ALU
DCR r	0 0 D D	D 1 0 1				(DDD)→TMP (TMP)+1→ALU	ALU→DDD			
DCR M	0 0 1 1	0 1 0 1				X		HL OUT STATUS[6]	DATA → (TMP)-1 →	TMP ALU
INX rp	0 0 R P	0 0 1 1				(RP) + 1 →	RP			
DCX rp	0 0 R P	1 0 1 1				(RP) - 1 →	RP			
DAD rp[8]	0 0 R P	1 0 0 1				X		(ri)→ACT	(L)→TMP, (ACT)+(TMP)→ALU	ALU→L, CY
DAA	0 0 1 0	0 1 1 1				DAA→A, FLAGS[10]				
ANA r	1 0 1 0	0 S S S				(SSS)→TMP (A)→ACT		[9]	(ACT)+(TMP)→A	
ANA M	1 0 1 0	0 1 1 0	PC OUT STATUS	PC = PC + 1	INST→TMP/IR	(A)→ACT		HL OUT STATUS[6]	DATA →	TMP



NOTE: Ⓝ Refer to Status Word Chart on Page 2-6.

Figure 2-6. Input Instruction Cycle



NOTE: Ⓝ Refer to Status Word Chart on Page 2-6.

Figure 2-7. Output Instruction Cycle

MNEMONIC	OP CODE		M1[1]					M2		
	$D_7 D_6 D_5 D_4$	$D_3 D_2 D_1 D_0$	T1	T2[2]	T3	T4	T5	T1	T2[2]	T3
ANI data	1 1 1 0	0 1 1 0	PC OUT STATUS	PC = PC + 1	INST→TMP/IR	(A)→ACT		PC OUT STATUS[6]	PC = PC + 1 B2	→TMP
XRA r	1 0 1 0	1 S S S				(A)→ACT (SSS)→TMP		[9]	(ACT)+(TPM)→A	
XRA M	1 0 1 0	1 1 1 0				(A)→ACT		HL OUT STATUS[6]	DATA	→TMP
XRI data	1 1 1 0	1 1 1 0				(A)→ACT		PC OUT STATUS[6]	PC = PC + 1 B2	→TMP
ORA r	1 0 1 1	0 S S S				(A)→ACT (SSS)→TMP		[9]	(ACT)+(TMP)→A	
ORA M	1 0 1 1	0 1 1 0				(A)→ACT		HL OUT STATUS[6]	DATA	→TMP
ORI data	1 1 1 1	0 1 1 0				(A)→ACT		PC OUT STATUS[6]	PC = PC + 1 B2	→TMP
CMP r	1 0 1 1	1 S S S				(A)→ACT (SSS)→TMP		[9]	(ACT)-(TMP), FLAGS	
CMP M	1 0 1 1	1 1 1 0				(A)→ACT		HL OUT STATUS[6]	DATA	→TMP
CPI data	1 1 1 1	1 1 1 0				(A)→ACT		PC OUT STATUS[6]	PC = PC + 1 B2	→TMP
RLC	0 0 0 0	0 1 1 1				(A)→ALU ROTATE		[9]	ALU→A, CY	
RRC	0 0 0 0	1 1 1 1				(A)→ALU ROTATE		[9]	ALU→A, CY	
RAL	0 0 0 1	0 1 1 1				(A), CY→ALU ROTATE		[9]	ALU→A, CY	
RAR	0 0 0 1	1 1 1 1				(A), CY→ALU ROTATE		[9]	ALU→A, CY	
CMA	0 0 1 0	1 1 1 1				$(\bar{A})$→A				
CMC	0 0 1 1	1 1 1 1				$\overline{CY}$→CY				
STC	0 0 1 1	0 1 1 1				1→CY				
JMP addr	1 1 0 0	0 0 1 1				X		PC OUT STATUS[6]	PC = PC + 1 B2	→Z
J cond addr[17]	1 1 C C	C 0 1 0				JUDGE CONDITION		PC OUT STATUS[6]	PC = PC + 1 B2	→Z
CALL addr	1 1 0 0	1 1 0 1				SP = SP - 1		PC OUT STATUS[6]	PC = PC + 1 B2	→Z
C cond addr[17]	1 1 C C	C 1 0 0				JUDGE CONDITION IF TRUE, SP = SP - 1		PC OUT STATUS[6]	PC = PC + 1 B2	→Z
RET	1 1 0 0	1 0 0 1				X		SP OUT STATUS[15]	SP = SP + 1 DATA	→Z
R cond addr[17]	1 1 C C	C 0 0 0			INST→TMP/IR	JUDGE CONDITION[14]		SP OUT STATUS[15]	SP = SP + 1 DATA	→Z
RST n	1 1 N N	N 1 1 1			ϕ→W INST→TMP/IR	SP = SP - 1		SP OUT STATUS[16]	SP = SP - 1 (PCH)	→DATA BUS
PCHL	1 1 1 0	1 0 0 1			INST→TMP/IR	(HL) → PC				
PUSH rp	1 1 R P	0 1 0 1				SP = SP - 1		SP OUT STATUS[16]	SP = SP - 1 (rh)	→DATA BUS
PUSH PSW	1 1 1 1	0 1 0 1				SP = SP - 1		SP OUT STATUS[16]	SP = SP - 1 (A)	→DATA BUS
POP rp	1 1 R P	0 0 0 1				X		SP OUT STATUS[15]	SP = SP + 1 DATA	→r1
POP PSW	1 1 1 1	0 0 0 1				X		SP OUT STATUS[15]	SP = SP + 1 DATA	→FLAGS
XTHL	1 1 1 0	0 0 1 1				X		SP OUT STATUS[15]	SP = SP + 1 DATA	→Z
IN port	1 1 0 1	1 0 1 1				X		PC OUT STATUS[6]	PC = PC + 1 B2	→Z, W
OUT port	1 1 0 1	0 0 1 1				X		PC OUT STATUS[6]	PC = PC + 1 B2	→Z, W
EI	1 1 1 1	1 0 1 1				SET INTE F/F				
DI	1 1 1 1	0 0 1 1				RESET INTE F/F				
HLT	0 1 1 1	0 1 1 0				X		PC OUT STATUS	HALT MODE[20]	
NOP	0 0 0 0	0 0 0 0	PC OUT STATUS	PC = PC + 1	INST→TMP/IR	X				

INTERRUPT SEQUENCES

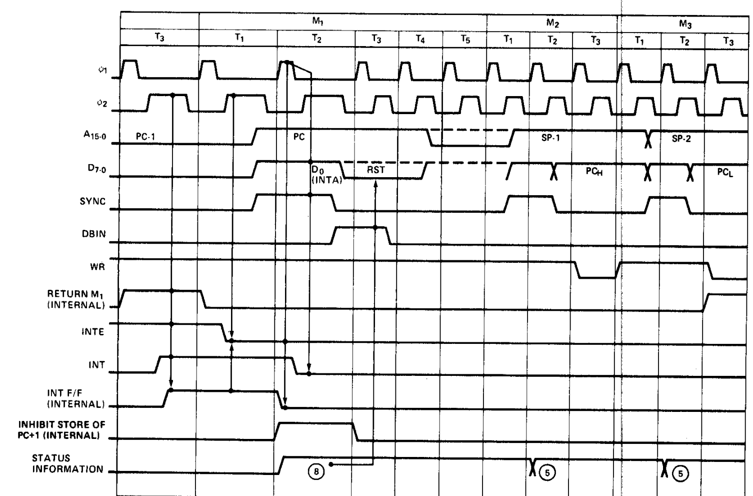
The 8080 has the built-in capacity to handle external interrupt requests. A peripheral device can initiate an interrupt simply by driving the processor's interrupt (INT) line high.

The interrupt (INT) input is asynchronous, and a request may therefore originate at any time during any instruction cycle. Internal logic re-clocks the external request, so that a proper correspondence with the driving clock is established. As Figure 2-8 shows, an interrupt request (INT) arriving during the time that the interrupt enable line (INTE) is high, acts in coincidence with the ϕ_2 clock to set the internal interrupt latch. This event takes place during the last state of the instruction cycle in which the request occurs, thus ensuring that any instruction in progress is completed before the interrupt can be processed.

The INTERRUPT machine cycle which follows the arrival of an enabled interrupt request resembles an ordinary FETCH machine cycle in most respects. The M_1 status bit is transmitted as usual during the SYNC interval. It is accompanied, however, by an INTA status bit (D_0) which acknowledges the external request. The contents of the program counter are latched onto the CPU's address lines during T_1, but the counter itself is not incremented during the INTERRUPT machine cycle, as it otherwise would be. In this way, the pre-interrupt status of the program counter is preserved, so that data in the counter may be restored by the interrupted program after the interrupt request has been processed.

The interrupt cycle is otherwise indistinguishable from an ordinary FETCH machine cycle. The processor itself takes no further special action. It is the responsibility of the peripheral logic to see that an eight-bit interrupt instruction is "jammed" onto the processor's data bus during state T_3. In a typical system, this means that the data-in bus from memory must be temporarily disconnected from the processor's main data bus, so that the interrupting device can command the main bus without interference.

The 8080's instruction set provides a special one-byte call which facilitates the processing of interrupts (the ordinary program Call takes three bytes). This is the RESTART instruction (RST). A variable three-bit field embedded in the eight-bit field of the RST enables the interrupting device to direct a Call to one of eight fixed memory locations. The decimal addresses of these dedicated locations are: 0, 8, 16, 24, 32, 40, 48, and 56. Any of these addresses may be used to store the first instruction(s) of a routine designed to service the requirements of an interrupting device. Since the (RST) is a call, completion of the instruction also stores the old program counter contents on the STACK.



NOTE: Ⓝ Refer to Status Word Chart on Page 2-6.

Figure 2-8. Interrupt Timing

NOTES:

1. The first memory cycle (M1) is always an instruction fetch; the first (or only) byte, containing the op code, is fetched during this cycle.

2. If the READY input from memory is not high during T2 of each memory cycle, the processor will enter a wait state (TW) until READY is sampled as high.

3. States T4 and T5 are present, as required, for operations which are completely internal to the CPU. The contents of the internal bus during T4 and T5 are available at the data bus; this is designed for testing purposes only. An "X" denotes that the state is present, but is only used for such internal operations as instruction decoding.

4. Only register pairs rp = B (registers B and C) or rp = D (registers D and E) may be specified.

5. These states are skipped.

6. Memory read sub-cycles; an instruction or data word will be read.

7. Memory write sub-cycle.

8. The READY signal is not required during the second and third sub-cycles (M2 and M3). The HOLD signal is accepted during M2 and M3. The SYNC signal is not generated during M2 and M3. During the execution of DAD, M2 and M3 are required for an internal register-pair add; memory is not referenced.

9. The results of these arithmetic, logical or rotate instructions are not moved into the accumulator (A) until state T2 of the next instruction cycle. That is, A is loaded while the next instruction is being fetched; this overlapping of operations allows for faster processing.

10. If the value of the least significant 4-bits of the accumulator is greater than 9 <u>or</u> if the auxiliary carry bit is set, 6 is added to the accumulator. If the value of the most significant 4-bits of the accumulator is now greater than 9, <u>or</u> if the carry bit is set, 6 is added to the most significant 4-bits of the accumulator.

11. This represents the first sub-cycle (the instruction fetch) of the next instruction cycle.

12. If the condition was met, the contents of the register pair WZ are output on the address lines (A_{0-15}) instead of the contents of the program counter (PC).

13. If the condition was not met, sub-cycles M4 and M5 are skipped; the processor instead proceeds immediately to the instruction fetch (M1) of the next instruction cycle.

14. If the condition was not met, sub-cycles M2 and M3 are skipped; the processor instead proceeds immediately to the instruction fetch (M1) of the next instruction cycle.

15. Stack read sub-cycle.

16. Stack write sub-cycle.

17. CONDITION

CONDITION	CCC
NZ – not zero (Z = 0)	000
Z – zero (Z = 1)	001
NC – no carry (CY = 0)	010
C – carry (CY = 1)	011
PO – parity odd (P = 0)	100
PE – parity even (P = 1)	101
P – plus (S = 0)	110
M – minus (S = 1)	111

18. I/O sub-cycle: the I/O port's 8-bit select code is duplicated on address lines 0-7 (A_{0-7}) and 8-15 (A_{8-15}).

19. Output sub-cycle.

20. The processor will remain idle in the halt state until an interrupt, a reset or a hold is accepted. When a hold request is accepted, the CPU enters the hold mode; after the hold mode is terminated, the processor returns to the halt state. After a reset is accepted, the processor begins execution at memory location zero. After an interrupt is accepted, the processor executes the instruction forced onto the data bus (usually a restart instruction).

SSS or DDD	Value
A	111
B	000
C	001
D	010
E	011
H	100
L	101

rp	Value
B	00
D	01
H	10
SP	11

HOLD SEQUENCES

The 8080A CPU contains provisions for Direct Memory Access (DMA) operations. By applying a HOLD to the appropriate control pin on the processor, an external device can cause the CPU to suspend its normal operations and relinquish control of the address and data busses. The processor responds to a request of this kind by floating its address to other devices sharing the busses. At the same time, the processor acknowledges the HOLD by placing a high on its HLDA outpin pin. During an acknowledged HOLD, the address and data busses are under control of the peripheral which originated the request, enabling it to conduct memory transfers without processor intervention.

Like the interrupt, the HOLD input is synchronized internally. A HOLD signal must be stable prior to the "Hold set-up" interval (t_{HS}), that precedes the rising edge of ϕ_2.

Figures 2-9 and 2-10 illustrate the timing involved in HOLD operations. Note the delay between the asynchronous HOLD REQUEST and the re-clocked HOLD. As shown in the diagram, a coincidence of the READY, the HOLD, and the ϕ_2 clocks sets the internal hold latch. Setting the latch enables the subsequent rising edge of the ϕ_1 clock pulse to trigger the HLDA output.

Acknowledgement of the HOLD REQUEST precedes slightly the actual floating of the processor's address and data lines. The processor acknowledges a HOLD at the beginning of T_3, if a read or an input machine cycle is in progress (see Figure 2-9). Otherwise, acknowledgement is deferred until the beginning of the state following T_3 (see Figure 2-10). In both cases, however, the HLDA goes high within a specified delay (t_{DC}) of the rising edge of the selected ϕ_1 clock pulse. Address and data lines are floated within a brief delay after the rising edge of the next ϕ_2 clock pulse. This relationship is also shown in the diagrams.

To all outward appearances, the processor has suspended its operations once the address and data busses are floated. Internally, however, certain functions may continue. If a HOLD REQUEST is acknowledged at T_3, and if the processor is in the middle of a machine cycle which requires four or more states to complete, the CPU proceeds through T_4 and T_5 before coming to a rest. Not until the end of the machine cycle is reached will processing activities cease. Internal processing is thus permitted to overlap the external DMA transfer, improving both the efficiency and the speed of the entire system.

The processor exits the holding state through a sequence similar to that by which it entered. A HOLD REQUEST is terminated asynchronously when the external device has completed its data transfer. The HLDA output returns to a low level following the leading edge of the next $\phi 1$ clock pulse. Normal processing resumes with the machine cycle following the last cycle that was executed.

HALT SEQUENCES

When a halt instruction (HLT) is executed, the CPU enters the halt state (T_{WH}) after state T_2 of the next machine cycle, as shown in Figure 2-11. There are only three ways in which the 8080 can exit the halt state:

- A high on the RESET line will always reset the 8080 to state T_1; RESET also clears the program counter.
- A HOLD input will cause the 8080 to enter the hold state, as previously described. When the HOLD line goes low, the 8080 re-enters the halt state on the rising edge of the next ϕ_1 clock pulse.
- An interrupt (i.e., INT goes high while INTE is enabled) will cause the 8080 to exit the Halt state and enter state T_1 on the rising edge of the next ϕ_1 clock pulse. NOTE: The interrupt enable (INTE) flag **must** be set when the halt state is entered; otherwise, the 8080 will only be able to exit via a RESET signal.

Figure 2-12 illustrates halt sequencing in flow chart form.

START-UP OF THE 8080 CPU

When power is applied initially to the 8080, the processor begins operating immediately. The contents of its program counter, stack pointer, and the other working registers are naturally subject to random factors and cannot be specified. For this reason, it will be necessary to begin the power-up sequence with RESET.

An external RESET signal of three clock period duration (minimum) restores the processor's internal program counter to zero. Program execution thus begins with memory location zero, following a RESET. Systems which require the processor to wait for an explicit start-up signal will store a halt instruction (EI, HLT) in the first two locations. A manual or an automatic INTERRUPT will be used for starting. In other systems, the processor may begin executing its stored program immediately. Note, however, that the RESET has no effect on status flags, or on any of the processor's working registers (accumulator, registers, or stack pointer). The contents of these registers remain indeterminate, until initialized explicitly by the program.

The following pages will cover the detailed design of the CPU Module with the 8080. The three Busses (Data, Address and Control) will be developed and the interconnection to Memory and I/O will be shown.

Design philosophies and system architectures presented in this manual are consistent with product development programs underway at INTEL for the MCS™-80. Thus, the designer who uses this manual as a guide for his total system engineering is assured that all new developments in components and software for MCS-80 from INTEL will be compatible with his design approach.

CPU Module Design

The CPU Module contains three major areas:

1. The 8080 Central Processing Unit
2. A Clock Generator and High Level Driver
3. A bi-directional Data Bus Driver and System Control Logic

The following will discuss the design of the three major areas contained in the CPU Module. This design is presented as an alternative to the Intel® 8224 Clock Generator and Intel 8228 System Controller. By studying the alternative approach, the designer can more clearly see the considerations involved in the specification and engineering of the 8224 and 8228. Standard TTL components and Intel general purpose peripheral devices are used to implement the design and to achieve operational characteristics that are as close as possible to those of the 8224 and 8228. Many auxiliary timing functions and features of the 8224 and 8228 are too complex to practically implement in standard components, so only the basic functions of the 8224 and 8228 are generated. Since significant benefits in system timing and component count reduction can be realized by using the 8224 and 8228, this is the preferred method of implementation.

1. **8080 CPU**

   The operation of the 8080 CPU was covered in previous chapters of this manual, so little reference will be made to it in the design of the Module.

2. **Clock Generator and High Level Driver**

   The 8080 is a dynamic device, meaning that its internal storage elements and logic circuitry require a timing reference (Clock), supplied by external circuitry, to refresh and provide timing control signals.

   The 8080 requires two (2) such Clocks. Their waveforms must be non-overlapping, and comply with the timing and levels specified in the 8080 A.C. and D.C. Characteristics, page 5-15.

   Clock Generator Design

   The Clock Generator consists of a crystal controlled,

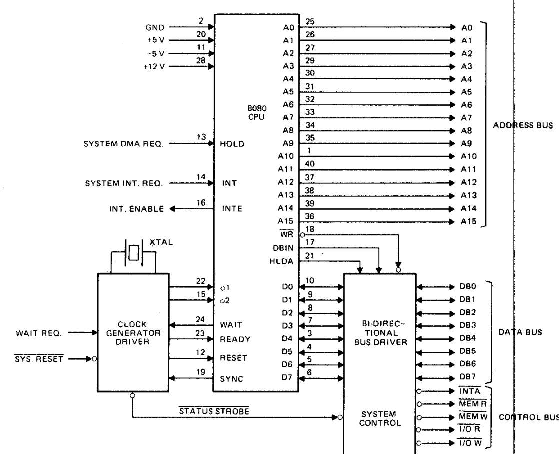
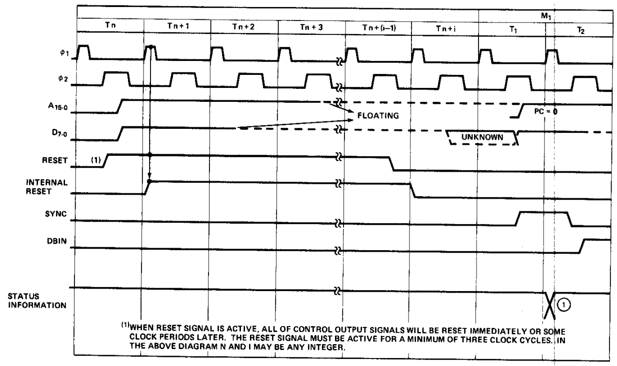
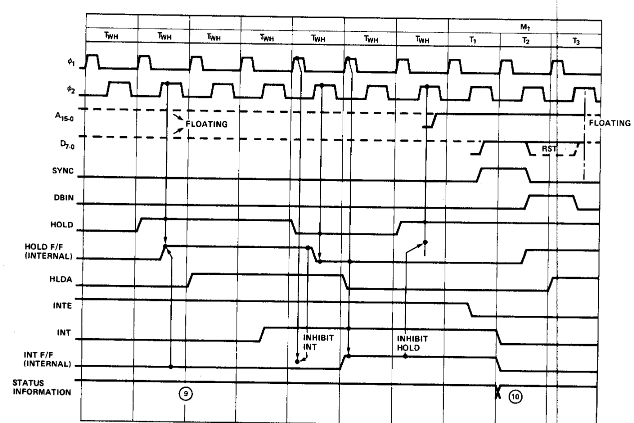


Figure 3-2. 8080 CPU Interface



NOTE: (N) Refer to Status Word Chart on Page 2-6.

Figure 2-13. Reset.



NOTE: (N) Refer to Status Word Chart on Page 2-6.

Figure 2-14. Relation between HOLD and INT in the HALT State.

Auxiliary Timing Signals and Functions

The Clock Generator can also be used to provide other signals that the designer can use to simplify large system timing or the interface to dynamic memories.

Functions such as power-on reset, synchronization of external requests (HOLD, READY, etc.) and single step, could easily be added to the Clock Generator to further enhance its capabilities.

For instance, the 20 MHZ signal from the oscillator can be buffered so that it could provide the basis for communication baud rate generation.

The Clock Generator diagram also shows how to generate an advanced timing signal (ϕ1A) that is handy to use in clocking "D" type flipflops to synchronize external requests. It can also be used to generate a strobe ($\overline{STSTB}$) that is the latching signal for the status information which is available on the Data Bus at the beginning of each machine cycle. A simple gating of the SYNC signal from the 8080 and the advanced (ϕ1A) will do the job. See Figure 3-3.

3. Bi-Directional Bus Driver and System Control Logic

The system Memory and I/O devices communicate with the CPU over the bi-directional Data Bus. The system Control Bus is used to gate data on and off the Data Bus within the proper timing sequences as dictated by the operation of the 8080 CPU. The data lines of the 8080 CPU, Memory and I/O devices are 3-state in nature, that is, their output drivers have the ability to be forced into a high-impedance mode and are, effectively, removed from the circuit. This 3-state bus technique allows the designer to construct a system around a single, eight (8) bit parallel, bi-directional Data Bus and simply gate the information on or off this bus by selecting or deselecting (3-stating) Memory and I/O devices with signals from the Control Bus.

Bi-Directional Data Bus Driver Design

The 8080 Data Bus (D7-D0) has two (2) major areas of concern for the designer:

1. Input Voltage level (V_{IH}) 3.3 volts minimum.
2. Output Drive Capability (I_{OL}) 1.7 mA maximum.

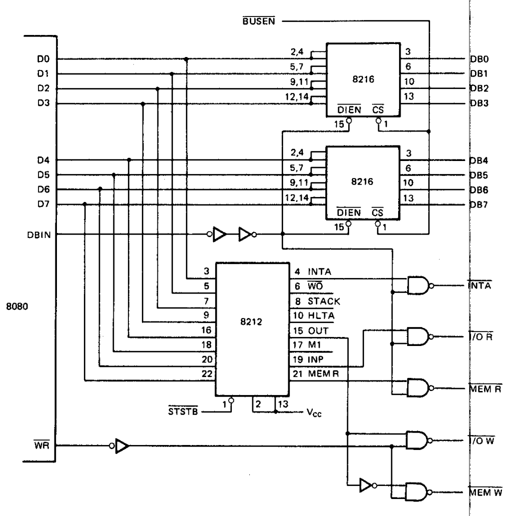


Figure 3-5. 8080 System Control

M3			M4			M5				
T1	T2[2]	T3	T1	T2[2]	T3	T1	T2[2]	T3	T4	T5
HL OUT STATUS[7]	(TMP) →	DATA BUS								
PC OUT STATUS[6]	PC = PC + 1 B3 →	rh								
↑	PC = PC + 1 B3 →	W	WZ OUT STATUS[6]	DATA →	A					
↕	PC = PC + 1 B3 →	W	WZ OUT STATUS[7]	(A) →	DATA BUS					
↓	PC = PC + 1 B3 →	W	WZ OUT STATUS[6]	DATA → WZ = WZ + 1	L	WZ OUT STATUS[6]	DATA →	H		
PC OUT STATUS[6]	PC = PC + 1 B3 →	W	WZ OUT STATUS[7]	(L) → WZ = WZ + 1	DATA BUS	WZ OUT STATUS[7]	(H) →	DATA BUS		
[9]	(ACT)+(TMP)→A									
[9]	(ACT)+(TMP)→A									
[9]	(ACT)+(TMP)+CY→A									
[9]	(ACT)+(TMP)+CY→A									
[9]	(ACT)-(TMP)→A									
[9]	(ACT)-(TMP)→A									
[9]	(ACT)-(TMP)-CY→A									
[9]	(ACT)-(TMP)-CY→A									
HL OUT STATUS[7]	ALU →	DATA BUS								
HL OUT STATUS[7]	ALU →	DATA BUS								
(rh)→ACT	(H)→TMP (ACT)+(TMP)+CY→ALU	ALU→H, CY								
[9]	(ACT)+(TMP)→A									

I/O INTERFACE

General Theory

As in any computer based system, the 8080 CPU must be able to communicate with devices or structures that exist outside its normal memory array. Devices like keyboards, paper tape, floppy disks, printers, displays and other control structures are used to input information into the 8080 CPU and display or store the results of the computational activity.

Probably the most important and strongest feature of the 8080 Microcomputer System is the flexibility and power of its I/O structure and the components that support it. There are many ways to structure the I/O array so that it will "fit" the total system environment to maximize efficiency and minimize component count.

The basic operation of the I/O structure can best be viewed as an array of single byte memory locations that can be Read from or Written into. The 8080 CPU has special instructions devoted to managing such transfers (IN, OUT). These instructions generally isolate memory and I/O arrays so that memory address space is not effected by the I/O structure and the general concept is that of a simple transfer to or from the Accumulator with an addressed "PORT". Another method of I/O architecture is to treat the I/O structure as part of the Memory array. This is generally referred to as "Memory Mapped I/O" and provides the designer with a powerful new "instruction set" devoted to I/O manipulation.

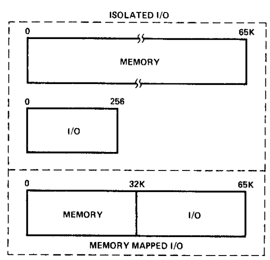


Figure 3-8. Memory/I/O Mapping.

Isolated I/O

In Figure 3-9 the system control signals, previously detailed in this chapter, are shown. This type of I/O architecture separates the memory address space from the I/O address space and uses a conceptually simple transfer to or from Accumulator technique. Such an architecture is easy to understand because I/O communicates only with the Accumulator using the IN or OUT instructions. Also because of the isolation of memory and I/O, the full address space (65K) is uneffected by I/O addressing.

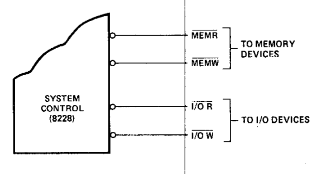


Figure 3-9. Isolated I/O.

Memory Mapped I/O

By assigning an area of memory address space as I/O a powerful architecture can be developed that can manipulate I/O using the same instructions that are used to manipulate memory locations. Thus, a "new" instruction set is created that is devoted to I/O handling.

As shown in Figure 3-10, new control signals are generated by gating the $\overline{MEMR}$ and $\overline{MEMW}$ signals with A_{15}, the most significant address bit. The new I/O control signals connect in exactly the same manner as Isolated I/O, thus the system bus characteristics are unchanged.

By assigning A_{15} as the I/O "flag", a simple method of I/O discipline is maintained:

If A_{15} is a "zero" then Memory is active.
If A_{15} is a "one" then I/O is active.

Other address bits can also be used for this function. A_{15} was chosen because it is the most significant address bit so it is easier to control with software and because it still allows memory addressing of 32K.

I/O devices are still considered addressed "ports" but instead of the Accumulator as the only transfer medium any of the internal registers can be used. All instructions that could be used to operate on memory locations can be used in I/O.

Examples:

MOVr, M	(Input Port to any Register)
MOV M, r	(Output any Register to Port)
MVI M	(Output immediate data to Port)
LDA	(Input to ACC)
STA	(Output from ACC to Port)
LHLD	(16 Bit Input)
SHLD	(16 Bit Output)
ADD M	(Add Port to ACC)
ANA M	("AND" Port with ACC)

It is easy to see that from the list of possible "new" instructions that this type of I/O architecture could have a drastic effect on increased system throughput. It is conceptually more difficult to understand than Isolated I/O and it does limit memory address space, but Memory Mapped I/O can mean a significant increase in overall speed and at the same time reducing required program memory area.

M3			M4			M5						
T1	T2[2]	T3	T1	T2[2]	T3	T1	T2[2]	T3	T4	T5		
[9]	(ACT)+(TMP)→A											
[9]	(ACT)+(TMP)→A											
[9]	(ACT)+(TMP)→A											
[9]	(ACT)+(TMP)→A											
[9]	(ACT)+(TMP)→A											
[9]	(ACT)-(TMP); FLAGS											
[9]	(ACT)-(TMP); FLAGS											
PC OUT STATUS[6]	PC = PC + 1 B3 →	W									WZ OUT STATUS[11]	(WZ) + 1 → PC
PC OUT STATUS[6]	PC = PC + 1 B3 →	W									WZ OUT STATUS[11,12]	(WZ) + 1 → PC
PC OUT STATUS[6]	PC = PC + 1 B3 →	W	SP OUT STATUS[16]	(PCH) → SP = SP - 1	DATA BUS	SP OUT STATUS[16]	(PCL) →	DATA BUS			WZ OUT STATUS[11]	(WZ) + 1 → PC
PC OUT STATUS[6]	PC = PC + 1 B3 →	W[13]	SP OUT STATUS[16]	(PCH) → SP = SP - 1	DATA BUS	SP OUT STATUS[16]	(PCL) →	DATA BUS			WZ OUT STATUS[11,12]	(WZ) + 1 → PC
SP OUT STATUS[15]	SP = SP + 1 DATA →	W									WZ OUT STATUS[11]	(WZ) + 1 → PC
SP OUT STATUS[15]	SP = SP + 1 DATA →	W									WZ OUT STATUS[11,12]	(WZ) + 1 → PC
SP OUT STATUS[16]	(TMP = 00NNN000) → (PCL) →	Z DATA BUS									WZ OUT STATUS[11]	(WZ) + 1 → PC
SP OUT STATUS[16]	(rl) →	DATA BUS										
SP OUT STATUS[16]	FLAGS →	DATA BUS										
SP OUT STATUS[15]	SP = SP + 1 DATA →	rh										
SP OUT STATUS[15]	SP = SP + 1 DATA →	A										
SP OUT STATUS[15]	DATA →	W	SP OUT STATUS[16]	(H) →	DATA BUS	SP OUT STATUS[16]	(L) →	DATA BUS	(WZ) →	HL		
WZ OUT STATUS[18]	DATA →	A										
WZ OUT STATUS[18]	(A) →	DATA BUS										

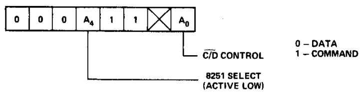


Figure 3-13. 8251 Format.

The two (2) 8255s provide twenty four bits each of programmable I/O data and control so that keyboards, sensors, paper tape, etc., can be interfaced to the system.

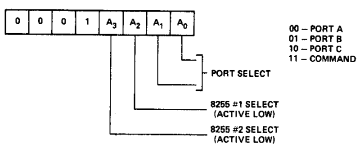


Figure 3-14. 8255 Format.

The three 8212s can be used to drive long lines or LED indicators due to their high drive capability. (15mA)

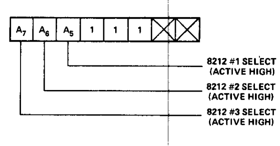


Figure 3-15. 8212 Format.

Addressing the structure is described in the formats illustrated in Figures 3-13, 3-14, 3-15. Linear Select is used so that no decoders are required thus, each device has an exclusive "enable bit".

The example shows how a powerful yet flexible I/O structure can be created using a minimum component count with devices that are all members of the 8080 Microcomputer System.

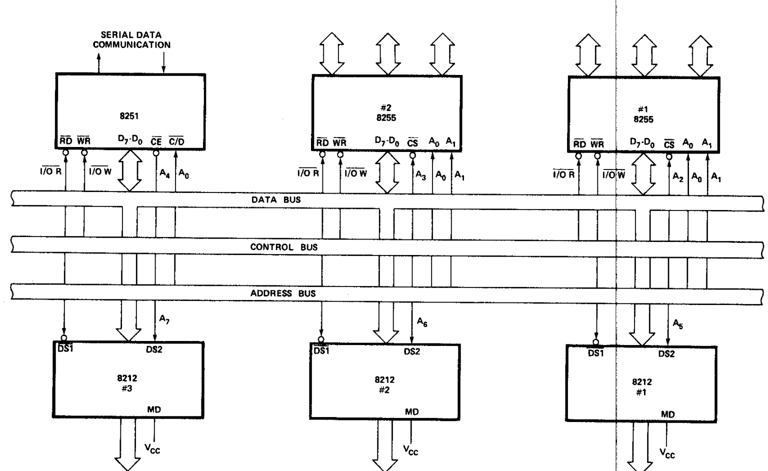


Figure 3-16. Typical I/O Interface.

CHAPTER 3 INTERFACING THE 8080

This chapter will illustrate, in detail, how to interface the 8080 CPU with Memory and I/O. It will also show the benefits and tradeoffs encountered when using a variety of system architectures to achieve higher throughput, decreased component count or minimization of memory size.

8080 Microcomputer system design lends itself to a simple, modular approach. Such an approach will yield the designer a reliable, high performance system that contains a minimum component count and is easy to manufacture and maintain.

The overall system can be thought of as a simple block diagram. The three (3) blocks in the diagram represent the functions common to **any** computer system.

CPU Module* Contains the Central Processing Unit, system timing and interface circuitry to Memory and I/O devices.

Memory Contains Read Only Memory (ROM) and Read/Write Memory (RAM) for program and data storage.

I/O Contains circuitry that allows the computer system to communicate with devices or structures existing outside of the CPU or Memory array.

for example: Keyboards, Floppy Disks, Paper Tape, etc.

There are three busses that interconnect these blocks:

Data Bus† A bi-directional path on which data can flow between the CPU and Memory or I/O.

Address Bus A uni-directional group of lines that identify a particular Memory location or I/O device.

*"Module" refers to a functional block, it does not reference a printed circuit board manufactured by INTEL.

†"Bus" refers to a set of signals grouped together because of the similarity of their functions.

Control Bus A uni-directional set of signals that indicate the type of activity in current process.

Type of activities:
1. Memory Read
2. Memory Write
3. I/O Read
4. I/O Write
5. Interrupt Acknowledge

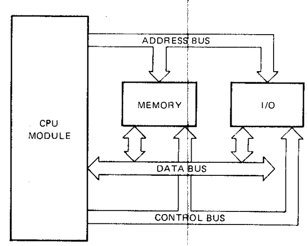


Figure 3-1. Typical Computer System Block Diagram

Basic System Operation

1. The CPU Module issues an activity command on the Control Bus.
2. The CPU Module issues a binary code on the Address Bus to identify which particular Memory location or I/O device will be involved in the current process activity.
3. The CPU Module receives or transmits data with the selected Memory location or I/O device.
4. The CPU Module returns to (1) and issues the next activity command.

It is easy to see at this point that the CPU module is the central element in any computer system.

The 8080 can directly address up to 65,536 bytes of memory, which may consist of both read-only memory (ROM) elements and random-access memory (RAM) elements (read/write memory).

Data in the 8080 is stored in the form of 8-bit binary integers:

DATA WORD

D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0
MSB							LSB

When a register or data word contains a binary number, it is necessary to establish the order in which the bits of the number are written. In the Intel 8080, BIT 0 is referred to as the **Least Significant Bit (LSB)**, and BIT 7 (of an 8 bit number) is referred to as the **Most Significant Bit (MSB)**.

The 8080 program instructions may be one, two or three bytes in length. Multiple byte instructions must be stored in successive memory locations; the address of the first byte is always used as the address of the instructions. The exact instruction format will depend on the particular operation to be executed.

Single Byte Instructions

	D_7 … D_0	Op Code	

Two-Byte Instructions

Byte One	D_7 … D_0	Op Code	
Byte Two	D_7 … D_0	Data or Address	

Three-Byte Instructions

Byte One	D_7 … D_0	Op Code	
Byte Two	D_7 … D_0	Data or Address	
Byte Three	D_7 … D_0		

Addressing Modes:

Often the data that is to be operated on is stored in memory. When multi-byte numeric data is used, the data, like instructions, is stored in successive memory locations, with the least significant byte first, followed by increasingly significant bytes. The 8080 has four different modes for addressing data stored in memory or in registers:

- Direct – Bytes 2 and 3 of the instruction contain the exact memory address of the data item (the low-order bits of the address are in byte 2, the high-order bits in byte 3).
- Register – The instruction specifies the register or register-pair in which the data is located.
- Register Indirect – The instruction specifies a register-pair which contains the memory address where the data is located (the high-order bits of the address are in the first register of the pair, the low-order bits in the second).
- Immediate – The instruction contains the data itself. This is either an 8-bit quantity or a 16-bit quantity (least significant byte first, most significant byte second).

Unless directed by an interrupt or branch instruction, the execution of instructions proceeds through consecutively increasing memory locations. A branch instruction can specify the address of the next instruction to be executed in one of two ways:

- Direct – The branch instruction contains the address of the next instruction to be executed. (Except for the 'RST' instruction, byte 2 contains the low-order address and byte 3 the high-order address.)
- Register indirect – The branch instruction indicates a register-pair which contains the address of the next instruction to be executed. (The high-order bits of the address are in the first register of the pair, the low-order bits in the second.)

The RST instruction is a special one-byte call instruction (usually used during interrupt sequences). RST includes a three-bit field; program control is transferred to the instruction whose address is eight times the contents of this three-bit field.

Condition Flags:

There are five condition flags associated with the execution of instructions on the 8080. They are Zero, Sign, Parity, Carry, and Auxiliary Carry, and are each represented by a 1-bit register in the CPU. A flag is "set" by forcing the bit to 1; "reset" by forcing the bit to 0.

Unless indicated otherwise, when an instruction affects a flag, it affects it in the following manner:

Zero: If the result of an instruction has the value 0, this flag is set; otherwise it is reset.

Sign: If the most significant bit of the result of the operation has the value 1, this flag is set; otherwise it is reset.

Parity: If the modulo 2 sum of the bits of the result of the operation is 0, (i.e., if the result has even parity), this flag is set; otherwise it is reset (i.e., if the result has odd parity).

Carry: If the instruction resulted in a carry (from addition), or a borrow (from subtraction or a comparison) out of the high-order bit, this flag is set; otherwise it is reset.

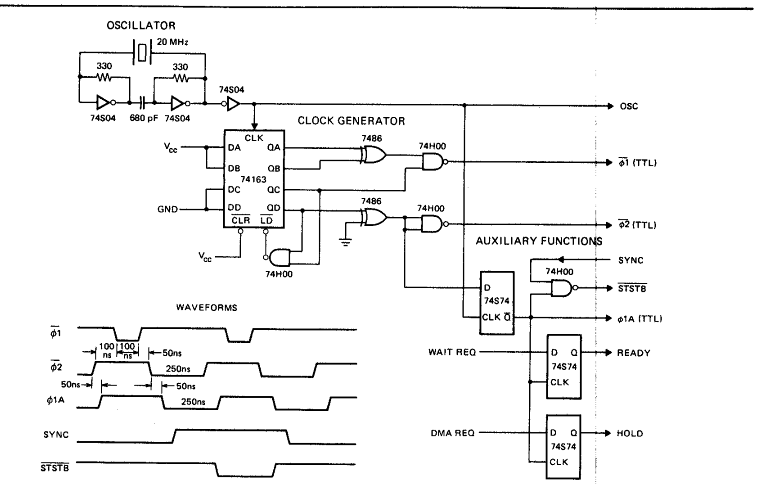


Figure 3-3. 8080 Clock Generator

20 MHZ oscillator, a four bit counter, and gating circuits.

The oscillator provides a 20 MHZ signal to the input of a four (4) bit, presettable, synchronous, binary counter. By presetting the counter as shown in figure 3-3 and clocking it with the 20 MHZ signal, a simple decoding of the counters outputs using standard TTL gates, provides proper timing for the two (2) 8080 clock inputs.

Note that the timing must actually be measured at the output of the High Level Driver to take into account the added delays and waveform distortions within such a device.

High Level Driver Design

The voltage level of the clocks for the 8080 is not TTL compatible like the other signals that input to the 8080. The voltage swing is from .6 volts (V_{ILC}) to 11 volts (V_{IHC}) with risetimes and falltimes under 50 ns. The Capacitive Drive is 20 pf (max.). Thus, a High Level Driver is required to interface the outputs of the Clock Generator (TTL) to the 8080.

The two (2) outputs of the Clock Generator are capacitivity coupled to a dual- High Level clock driver. The driver must be capable of complying with the 8080 clock input specifications, page 5-15. A driver of this type usually has little problem supplying the positive transition when biased from the 8080 V_{DD} supply (12V) but to achieve the low voltage specification (V_{ILC}) .8 volts Max. the driver is biased to the 8080 V_{BB} supply (-5V). This allows the driver to swing from GND to V_{DD} with the aid of a simple resistor divider.

A low resistance series network is added between the driver and the 8080 to eliminate any overshoot of the pulsed waveforms. Now a circuit is apparent that can easily comply with the 8080 specifications. In fact rise and falltimes of this design are typically less than 10 ns.

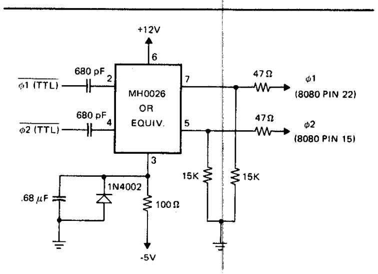


Figure 3-4. High Level Driver

6. The last four lines contain incidental information about the execution of the instruction. The number of machine cycles and states required to execute the instruction are listed first. If the instruction has two possible execution times, as in a Conditional Jump, both times will be listed, separated by a slash. Next, any significant data addressing modes (see Page 4-2) are listed. The last line lists any of the five Flags that are affected by the execution of the instruction.

Data Transfer Group:

This group of instructions transfers data to and from registers and memory. **Condition flags are not affected** by any instruction in this group.

MOV r1, r2 (Move Register)

(r1) ← (r2)

The content of register r2 is moved to register r1.

0	1	D	D	D	S	S	S

Cycles: 1
States: 5
Addressing: register
Flags: none

MOV r, M (Move from memory)

(r) ← ((H) (L))

The content of the memory location, whose address is in registers H and L, is moved to register r.

0	1	D	D	D	1	1	0

Cycles: 2
States: 7
Addressing: reg. indirect
Flags: none

MOV M, r (Move to memory)

((H) (L)) ← (r)

The content of register r is moved to the memory location whose address is in registers H and L.

0	1	1	1	0	S	S	S

Cycles: 2
States: 7
Addressing: reg. indirect
Flags: none

MVI r, data (Move Immediate)

(r) ← (byte 2)

The content of byte 2 of the instruction is moved to register r.

0	0	D	D	D	1	1	0
data							

Cycles: 2
States: 7
Addressing: immediate
Flags: none

MVI M, data (Move to memory immediate)

((H) (L)) ← (byte 2)

The content of byte 2 of the instruction is moved to the memory location whose address is in registers H and L.

0	0	1	1	0	1	1	0
data							

Cycles: 3
States: 10
Addressing: immed./reg. indirect
Flags: none

LXI rp, data 16 (Load register pair immediate)

(rh) ← (byte 3),
(rl) ← (byte 2)

Byte 3 of the instruction is moved into the high-order register (rh) of the register pair rp. Byte 2 of the instruction is moved into the low-order register (rl) of the register pair rp.

0	0	R	P	0	0	0	1
low-order data							
high-order data							

Cycles: 3
States: 10
Addressing: immediate
Flags: none

The input level specification implies that any semiconductor memory or I/O device connected to the 8080 Data Bus must be able to provide a minimum of 3.3 volts in its high state. Most semiconductor memories and standard TTL I/O devices have an output capability of between 2.0 and 2.8 volts, obviously a direct connection onto the 8080 Data Bus would require pullup resistors, whose value should not affect the bus speed or stress the drive capability of the memory or I/O components.

The 8080A output drive capability (I_{OL}) 1.9mA max. is sufficient for small systems where Memory size and I/O requirements are minimal and the entire system is contained on a single printed circuit board. Most systems however, take advantage of the high-performance computing power of the 8080 CPU and thus a more typical system would require some form of buffering on the 8080 Data Bus to support a larger array of Memory and I/O devices which are likely to be on separate boards.

A device specifically designed to do this buffering function is the INTEL® 8216, a (4) four bit bi-directional bus driver whose input voltage level is compatible with standard TTL devices and semiconductor memory components, and has output drive capability of 50 mA. At the 8080 side, the 8216 has a "high" output of 3.65 volts that not only meets the 8080 input spec but provides the designer with a worse case 350 mV noise margin.

A pair of 8216's are connected directly to the 8080 Data Bus (D7-D0) as shown in figure 3-5. Note that the DBIN signal from the 8080 is connected to the direction control input ($\overline{DIEN}$) so the correct flow of data on the bus is maintained. The chip select ($\overline{CS}$) of the 8216 is connected to BUS ENABLE ($\overline{BUSEN}$) to allow for DMA activities by deselecting the Data Bus Buffer and forcing the outputs of the 8216's into their high impedance (3-state) mode. This allows other devices to gain access to the data bus (DMA).

System Control Logic Design

The Control Bus maintains discipline of the bi-directional Data Bus, that is, it determines what type of device will have access to the bus (Memory or I/O) and generates signals to assure that these devices transfer Data with the 8080 CPU within the proper timing "windows" as dictated by the CPU operational characteristics.

As described previously, the 8080 issues Status information at the beginning of each Machine Cycle on its Data Bus to indicate what operation will take place during that cycle. A simple (8) bit latch, like an INTEL® 8212, connected directly to the 8080 Data Bus (D7-D0) as shown in figure 3-5 will store the Status information. The signal that loads the data into the Status Latch comes from the Clock Generator, it is Status Strobe ($\overline{STSTB}$) and occurs at the start of each Machine Cycle.

Note that the Status Latch is connected onto the 8080 Data Bus (D7-D0) before the Bus Buffer. This is to maintain the integrity of the Data Bus and simplify Control Bus timing in DMA dependent environments.

As shown in the diagram, a simple gating of the outputs of the Status Latch with the DBIN and $\overline{WR}$ signals from the 8080 generate the (4) four Control signals that make up the basic Control Bus.

These four signals: 1. Memory Read ($\overline{MEM\ R}$)

2. Memory Write ($\overline{MEM\ W}$)

3. I/O Read ($\overline{I/O\ R}$)

4. I/O Write ($\overline{I/O\ W}$)

connect directly to the MCS™-80 component "family" of ROMs, RAMs and I/O devices.

A fifth signal, Interrupt Acknowledge ($\overline{INTA}$) is added to the Control Bus by gating data off the Status Latch with the DBIN signal from the 8080 CPU. This signal is used to enable the Interrupt Instruction Port which holds the RST instruction onto the Data Bus.

Other signals that are part of the Control Bus such as $\overline{WO}$, Stack and M1 are present to aid in the testing of the System and also to simplify interfacing the CPU to dynamic memories or very large systems that require several levels of bus buffering.

Address Buffer Design

The Address Bus (A15-A0) of the 8080, like the Data Bus, is sufficient to support a small system that has a moderate size Memory and I/O structure, confined to a single card. To expand the size of the system that the Address Bus can support a simple buffer can be added, as shown in figure 3-6. The INTEL® 8212 or 8216 is an excellent device for this function. They provide low input loading (.25 mA), high output drive and insert a minimal delay in the System Timing.

Note that BUS ENABLE ($\overline{BUSEN}$) is connected to the buffers so that they are forced into their high-impedance (3-state) mode during DMA activities so that other devices can gain access to the Address Bus.

Arithmetic Group:

This group of instructions performs arithmetic operations on data in registers and memory.

Unless indicated otherwise, all instructions in this group affect the Zero, Sign, Parity, Carry, and Auxiliary Carry flags according to the standard rules.

All subtraction operations are performed via two's complement arithmetic and set the carry flag to one to indicate a borrow and clear it to indicate no borrow.

ADD r (Add Register)

(A) ← (A) + (r)

The content of register r is added to the content of the accumulator. The result is placed in the accumulator.

1	0	0	0	0	S	S	S

Cycles: 1
States: 4
Addressing: register
Flags: Z,S,P,CY,AC

ADD M (Add memory)

(A) ← (A) + ((H) (L))

The content of the memory location whose address is contained in the H and L registers is added to the content of the accumulator. The result is placed in the accumulator.

1	0	0	0	0	1	1	0

Cycles: 2
States: 7
Addressing: reg. indirect
Flags: Z,S,P,CY,AC

ADI data (Add immediate)

(A) ← (A) + (byte 2)

The content of the second byte of the instruction is added to the content of the accumulator. The result is placed in the accumulator.

1	1	0	0	0	1	1	0
data							

Cycles: 2
States: 7
Addressing: immediate
Flags: Z,S,P,CY,AC

ADC r (Add Register with carry)

(A) ← (A) + (r) + (CY)

The content of register r and the content of the carry bit are added to the content of the accumulator. The result is placed in the accumulator.

1	0	0	0	1	S	S	S

Cycles: 1
States: 4
Addressing: register
Flags: Z,S,P,CY,AC

ADC M (Add memory with carry)

(A) ← (A) + ((H) (L)) + (CY)

The content of the memory location whose address is contained in the H and L registers and the content of the CY flag are added to the accumulator. The result is placed in the accumulator.

1	0	0	0	1	1	1	0

Cycles: 2
States: 7
Addressing: reg. indirect
Flags: Z,S,P,CY,AC

ACI data (Add immediate with carry)

(A) ← (A) + (byte 2) + (CY)

The content of the second byte of the instruction and the content of the CY flag are added to the contents of the accumulator. The result is placed in the accumulator.

1	1	0	0	1	1	1	0
data							

Cycles: 2
States: 7
Addressing: immediate
Flags: Z,S,P,CY,AC

SUB r (Subtract Register)

(A) ← (A) – (r)

The content of register r is subtracted from the content of the accumulator. The result is placed in the accumulator.

1	0	0	1	0	S	S	S

Cycles: 1
States: 4
Addressing: register
Flags: Z,S,P,CY,AC

RAM memory must be provided, such as: Floppy Disk, Paper Tape, etc.

The CPU treats RAM in exactly the same manner as ROM for addressing data to be read. Writing data is very similar; the RAM is issued an address during the first portion of the Memory Write cycle (T1 & T2) in T3 when the data that is to be written is output by the CPU and is stable on the bus an $\overline{\text{MEMW}}$ command is generated. The $\overline{\text{MEMW}}$ signal is connected to the R/W input of the RAM and strobes the data into the addressed location.

In Figure 3-7 a typical Memory system is illustrated to show how standard semiconductor components interface to the 8080 bus. The memory array shown has 8K bytes (8 bits/byte) of ROM storage, using four Intel®8216As and 512 bytes of RAM storage, using Intel 8111 static RAMs. The basic interface to the bus structure detailed here is common to almost any size memory. The only addition that might have to be made for larger systems is more buffers (8216/8212) and decoders (8205) for generating "chip selects."

The memories chosen for this example have an access time of 850 nS (max) to illustrate that slower, economical devices can be easily interfaced to the 8080 with little effect on performance. When the 8080 is operated from a clock generator with a tCY of 500 nS the required memory access time is Approx. 450-550 nS. See detailed timing specification Pg. 5-16. Using memory devices of this speed such as Intel®8308, 8102A, 8107A, etc. the READY input to the 8080 CPU can remain "high" because no "wait" states are required. Note that the bus interface to memory shown in Figure 3-7 remains the same. However, if slower memories are to be used, such as the devices illustrated (8316A, 8111) that have access times slower than the minimum requirement a simple logic control of the READY input to the 8080 CPU will insert an extra "wait state" that is equal to one or more clock periods as an access time "adjustment" delay to compensate. The effect of the extra "wait" state is naturally a slower execution time for the instruction. A single "wait" changes the basic instruction cycle to 2.5 microSeconds.

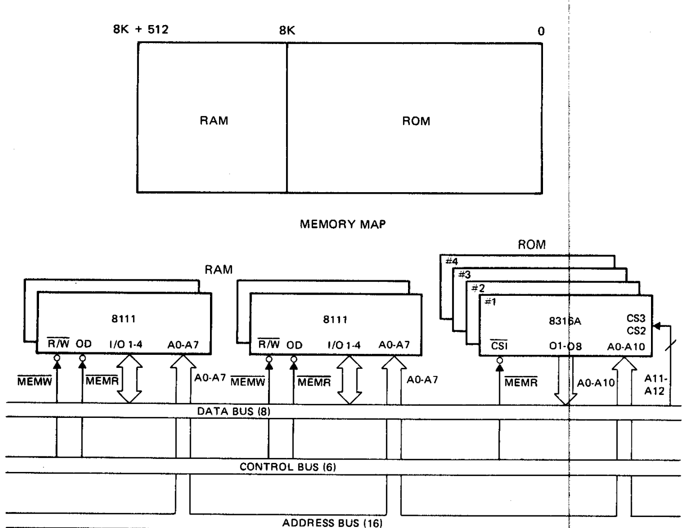


Figure 3-7. Typical Memory Interface

DCR M (Decrement memory)

((H) (L)) ← ((H) (L)) – 1

The content of the memory location whose address is contained in the H and L registers is decremented by one. Note: All condition flags **except CY** are affected.

0	0	1	1	0	1	0	1

Cycles: 3
States: 10
Addressing: reg. indirect
Flags: Z,S,P,AC

INX rp (Increment register pair)

(rh) (rl) ← (rh) (rl) + 1

The content of the register pair rp is incremented by one. Note: **No condition flags are affected.**

0	0	R	P	0	0	1	1

Cycles: 1
States: 5
Addressing: register
Flags: none

DCX rp (Decrement register pair)

(rh) (rl) ← (rh) (rl) – 1

The content of the register pair rp is decremented by one. Note: **No condition flags are affected.**

0	0	R	P	1	0	1	1

Cycles: 1
States: 5
Addressing: register
Flags: none

DAD rp (Add register pair to H and L)

(H) (L) ← (H) (L) + (rh) (rl)

The content of the register pair rp is added to the content of the register pair H and L. The result is placed in the register pair H and L. Note: **Only the CY flag is affected.** It is set if there is a carry out of the double precision add; otherwise it is reset.

0	0	R	P	1	0	0	1

Cycles: 3
States: 10
Addressing: register
Flags: CY

DAA (Decimal Adjust Accumulator)

The eight-bit number in the accumulator is adjusted to form two four-bit Binary-Coded-Decimal digits by the following process:

1. If the value of the least significant 4 bits of the accumulator is greater than 9 **or** if the AC flag is set, 6 is added to the accumulator.
2. If the value of the most significant 4 bits of the accumulator is now greater than 9, **or** if the CY flag is set, 6 is added to the most significant 4 bits of the accumulator.

NOTE: All flags are affected.

0	0	1	0	0	1	1	1

Cycles: 1
States: 4
Flags: Z,S,P,CY,AC

Logical Group:

This group of instructions performs logical (Boolean) operations on data in registers and memory and on condition flags.

Unless indicated otherwise, all instructions in this group affect the Zero, Sign, Parity, Auxiliary Carry, and Carry flags according to the standard rules.

ANA r (AND Register)

(A) ← (A) ∧ (r)

The content of register r is logically anded with the content of the accumulator. The result is placed in the accumulator. **The CY flag is cleared.**

1	0	1	0	0	S	S	S

Cycles: 1
States: 4
Addressing: register
Flags: Z,S,P,CY,AC

ANA M (AND memory)

(A) ← (A) ∧ ((H) (L))

The contents of the memory location whose address is contained in the H and L registers is logically anded with the content of the accumulator. The result is placed in the accumulator. **The CY flag is cleared.**

1	0	1	0	0	1	1	0

Cycles: 2
States: 7
Addressing: reg. indirect
Flags: Z,S,P,CY,AC

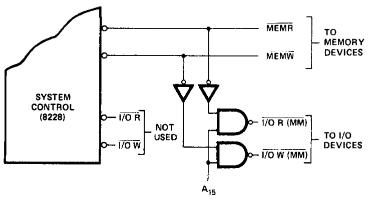


Figure 3-10. Memory Mapped I/O.

I/O Addressing

With both systems of I/O structure the addressing of each device can be configured to optimize efficiency and reduce component count. One method, the most common, is to decode the address bus into exclusive "chip selects" that enable the addressed I/O device, similar to generating chip-selects in memory arrays.

Another method is called "linear select". In this method, instead of decoding the Address Bus, a singular bit from the bus is assigned as the exclusive enable for a specific I/O device. This method, of course, limits the number of I/O devices that can be addressed but eliminates the need for extra decoders, an important consideration in small system design.

A simple example illustrates the power of such a flexible I/O structure. The first example illustrates the format of the second byte of the IN or OUT instruction using the Isolated I/O technique. The devices used are Intel®8255 Programmable Peripheral Interface units and are linear selected. Each device has three ports and from the format it can be seen that six devices can be addressed without additional decoders.

EXAMPLE #1

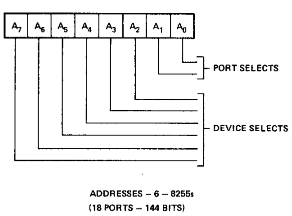


Figure 3-11. Isolated I/O – (Linear Select) (8255)

The second example uses Memory Mapped I/O and linear select to show how thirteen devices (8255) can be addressed without the use of extra decoders. The format shown could be the second and third bytes of the LDA or STA instructions or any other instructions used to manipulate I/O using the Memory Mapped technique.

It is easy to see that such a flexible I/O structure, that can be "tailored" to the overall system environment, provides the designer with a powerful tool to optimize efficiency and minimize component count.

EXAMPLE #2

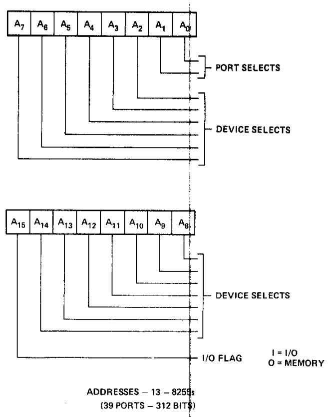


Figure 3-12. Memory Mapped I/O – (Linear Select (8255)

I/O Interface Example

In Figure 3-16 a typical I/O system is shown that uses a variety of devices (8212, 8251 and 8255). It could be used to interface the peripherals around an intelligent CRT terminals; keyboards, display, and communication interface. Another application could be in a process controller to interface sensors, relays, and motor controls. The limitation of the application area for such a circuit is solely that of the designers imagination.

The I/O structure shown interfaces to the 8080 CPU using the bus architecture developed previously in this chapter. Either Isolated or Memory Mapped techniques can be used, depending on the system I/O environment.

The 8251 provides a serial data communication interface so that the system can transmit and receive data over communication links such as telephone lines.

CMP M (Compare memory)

(A) – ((H) (L))

The content of the memory location whose address is contained in the H and L registers is subtracted from the accumulator. The accumulator remains unchanged. The condition flags are set as a result of the subtraction. The Z flag is set to 1 if (A) = ((H) (L)). The CY flag is set to 1 if (A) < ((H) (L)).

1	0	1	1	1	1	1	0

Cycles: 2
States: 7
Addressing: reg. indirect
Flags: Z,S,P,CY,AC

CPI data (Compare immediate)

(A) – (byte 2)

The content of the second byte of the instruction is subtracted from the accumulator. The condition flags are set by the result of the subtraction. The Z flag is set to 1 if (A) = (byte 2). The CY flag is set to 1 if (A) < (byte 2).

1	1	1	1	1	1	1	0
data							

Cycles: 2
States: 7
Addressing: immediate
Flags: Z,S,P,CY,AC

RLC (Rotate left)

$(A_{n+1}) \leftarrow (A_n)$; $(A_0) \leftarrow (A_7)$

$(CY) \leftarrow (A_7)$

The content of the accumulator is rotated left one position. The low order bit and the CY flag are both set to the value shifted out of the high order bit position. **Only the CY flag is affected.**

0	0	0	0	0	1	1	1

Cycles: 1
States: 4
Flags: CY

RRC (Rotate right)

$(A_n) \leftarrow (A_{n-1})$; $(A_7) \leftarrow (A_0)$

$(CY) \leftarrow (A_0)$

The content of the accumulator is rotated right one position. The high order bit and the CY flag are both set to the value shifted out of the low order bit position. **Only the CY flag is affected.**

0	0	0	0	1	1	1	1

Cycles: 1
States: 4
Flags: CY

RAL (Rotate left through carry)

$(A_{n+1}) \leftarrow (A_n)$; $(CY) \leftarrow (A_7)$

$(A_0) \leftarrow (CY)$

The content of the accumulator is rotated left one position through the CY flag. The low order bit is set equal to the CY flag and the CY flag is set to the value shifted out of the high order bit. **Only the CY flag is affected.**

0	0	0	1	0	1	1	1

Cycles: 1
States: 4
Flags: CY

RAR (Rotate right through carry)

$(A_n) \leftarrow (A_{n+1})$; $(CY) \leftarrow (A_0)$

$(A_7) \leftarrow (CY)$

The content of the accumulator is rotated right one position through the CY flag. The high order bit is set to the CY flag and the CY flag is set to the value shifted out of the low order bit. **Only the CY flag is affected.**

0	0	0	1	1	1	1	1

Cycles: 1
States: 4
Flags: CY

CMA (Complement accumulator)

$(A) \leftarrow (\overline{A})$

The contents of the accumulator are complemented (zero bits become 1, one bits become 0). **No flags are affected.**

0	0	1	0	1	1	1	1

Cycles: 1
States: 4
Flags: none

CHAPTER 4 INSTRUCTION SET

A computer, no matter how sophisticated, can only do what it is "told" to do. One "tells" the computer what to do via a series of coded instructions referred to as a **Program**. The realm of the programmer is referred to as **Software**, in contrast to the **Hardware** that comprises the actual computer equipment. A computer's software refers to all of the programs that have been written for that computer.

When a computer is designed, the engineers provide the Central Processing Unit (CPU) with the ability to perform a particular set of operations. The CPU is designed such that a specific operation is performed when the CPU control logic decodes a particular instruction. Consequently, the operations that can be performed by a CPU define the computer's **Instruction Set**.

Each computer instruction allows the programmer to initiate the performance of a specific operation. All computers implement certain arithmetic operations in their instruction set, such as an instruction to add the contents of two registers. Often logical operations (e.g., OR the contents of two registers) and register operate instructions (e.g., increment a register) are included in the instruction set. A computer's instruction set will also have instructions that move data between registers, between a register and memory, and between a register and an I/O device. Most instruction sets also provide **Conditional Instructions.** A conditional instruction specifies an operation to be performed only if certain conditions have been met; for example, jump to a particular instruction if the result of the last operation was zero. Conditional instructions provide a program with a decision-making capability.

By logically organizing a sequence of instructions into a coherent program, the programmer can "tell" the computer to perform a very specific and useful function.

The computer, however, can only execute programs whose instructions are in a binary coded form (i.e., a series of 1's and 0's), that is called **Machine Code.** Because it would be extremely cumbersome to program in machine code, programming languages have been developed. There are programs available which convert the programming language instructions into machine code that can be interpreted by the processor.

One type of programming language is **Assembly Language**. A unique assembly language mnemonic is assigned to each of the computer's instructions. The programmer can write a program (called the **Source Program**) using these mnemonics and certain operands; the source program is then converted into machine instructions (called the **Object Code**). Each assembly language instruction is converted into one machine code instruction (1 or more bytes) by an **Assembler** program. Assembly languages are usually machine dependent (i.e., they are usually able to run on only one type of computer).

THE 8080 INSTRUCTION SET

The 8080 instruction set includes five different types of instructions:

- **Data Transfer Group**—move data between registers or between memory and registers
- **Arithmetic Group** — add, subtract, increment or decrement data in registers or in memory
- **Logical Group** — AND, OR, EXCLUSIVE-OR, compare, rotate or complement data in registers or in memory
- **Branch Group** — conditional and unconditional jump instructions, subroutine call instructions and return instructions
- **Stack, I/O and Machine Control Group** — includes I/O instructions, as well as instructions for maintaining the stack and internal control flags.

Instruction and Data Formats:

Memory for the 8080 is organized into 8-bit quantities, called Bytes. Each byte has a unique 16-bit binary address corresponding to its sequential position in memory.

XTHL (Exchange stack top with H and L)

(L) ↔ ((SP))
(H) ↔ ((SP) + 1)
The content of the L register is exchanged with the content of the memory location whose address is specified by the content of register SP. The content of the H register is exchanged with the content of the memory location whose address is one more than the content of register SP.

1	1	1	0	0	0	1	1

Cycles: 5
States: 18
Addressing: reg. indirect
Flags: none

SPHL (Move HL to SP)

(SP) ← (H) (L)
The contents of registers H and L (16 bits) are moved to register SP.

1	1	1	1	1	0	0	1

Cycles: 1
States: 5
Addressing: register
Flags: none

IN port (Input)

(A) ← (data)
The data placed on the eight bit bi-directional data bus by the specified port is moved to register A.

1	1	0	1	1	0	1	1
port							

Cycles: 3
States: 10
Addressing: direct
Flags: none

OUT port (Output)

(data) ← (A)
The content of register A is placed on the eight bit bi-directional data bus for transmission to the specified port.

1	1	0	1	0	0	1	1
port							

Cycles: 3
States: 10
Addressing: direct
Flags: none

EI (Enable interrupts)

The interrupt system is enabled **following the execution of the next instruction.**

1	1	1	1	1	0	1	1

Cycles: 1
States: 4
Flags: none

DI (Disable interrupts)

The interrupt system is disabled **immediately following the execution of the DI instruction.**

1	1	1	1	0	0	1	1

Cycles: 1
States: 4
Flags: none

HLT (Halt)

The processor is stopped. The registers and flags are unaffected.

0	1	1	1	0	1	1	0

Cycles: 1
States: 7
Flags: none

NOP (No op)

No operation is performed. The registers and flags are unaffected.

0	0	0	0	0	0	0	0

Cycles: 1
States: 4
Flags: none

Auxiliary Carry: If the instruction caused a carry out of bit 3 and into bit 4 of the resulting value, the auxiliary carry is set; otherwise it is reset. This flag is affected by single precision additions, subtractions, increments, decrements, comparisons, and logical operations, but is principally used with additions and increments preceding a DAA (Decimal Adjust Accumulator) instruction.

Symbols and Abbreviations:

The following symbols and abbreviations are used in the subsequent description of the 8080 instructions:

SYMBOLS	MEANING
accumulator	Register A
addr	16-bit address quantity
data	8-bit data quantity
data 16	16-bit data quantity
byte 2	The second byte of the instruction
byte 3	The third byte of the instruction
port	8-bit address of an I/O device
r,r1,r2	One of the registers A,B,C,D,E,H,L
DDD,SSS	The bit pattern designating one of the registers A,B,C,D,E,H,L (DDD=destination, SSS=source):

DDD or SSS	REGISTER NAME
111	A
000	B
001	C
010	D
011	E
100	H
101	L

rp — One of the register pairs:

B represents the B,C pair with B as the high-order register and C as the low-order register;

D represents the D,E pair with D as the high-order register and E as the low-order register;

H represents the H,L pair with H as the high-order register and L as the low-order register;

SP represents the 16-bit stack pointer register.

RP — The bit pattern designating one of the register pairs B,D,H,SP:

RP	REGISTER PAIR
00	B-C
01	D-E
10	H-L
11	SP

rh	The first (high-order) register of a designated register pair.
rl	The second (low-order) register of a designated register pair.
PC	16-bit program counter register (PCH and PCL are used to refer to the high-order and low-order 8 bits respectively).
SP	16-bit stack pointer register (SPH and SPL are used to refer to the high-order and low-order 8 bits respectively).
r_m	Bit m of the register r (bits are number 7 through 0 from left to right).
Z,S,P,CY,AC	The condition flags: Zero, Sign, Parity, Carry, and Auxiliary Carry, respectively.
( )	The contents of the memory location or registers enclosed in the parentheses.
$\leftarrow$	"Is transferred to"
$\wedge$	Logical AND
$\forall$	Exclusive OR
$\vee$	Inclusive OR
+	Addition
–	Two's complement subtraction
*	Multiplication
$\leftrightarrow$	"Is exchanged with"
—	The one's complement (e.g., $(\overline{A})$)
n	The restart number 0 through 7
NNN	The binary representation 000 through 111 for restart number 0 through 7 respectively.

Description Format:

The following pages provide a detailed description of the instruction set of the 8080. Each instruction is described in the following manner:

1. The MAC 80 assembler format, consisting of the instruction mnemonic and operand fields, is printed in **BOLDFACE** on the left side of the first line.
2. The name of the instruction is enclosed in parenthesis on the right side of the first line.
3. The next line(s) contain a symbolic description of the operation of the instruction.
4. This is followed by a narative description of the operation of the instruction.
5. The following line(s) contain the binary fields and patterns that comprise the machine instruction.

CHAPTER 5
MCS-80™ COMPONENT FAMILY

LDA addr (Load Accumulator direct)

(A) ← ((byte 3)(byte 2))

The content of the memory location, whose address is specified in byte 2 and byte 3 of the instruction, is moved to register A.

0	0	1	1	1	0	1	0
low-order addr							
high-order addr							

Cycles: 4
States: 13
Addressing: direct
Flags: none

STA addr (Store Accumulator direct)

((byte 3)(byte 2)) ← (A)

The content of the accumulator is moved to the memory location whose address is specified in byte 2 and byte 3 of the instruction.

0	0	1	1	0	0	1	0
low-order addr							
high-order addr							

Cycles: 4
States: 13
Addressing: direct
Flags: none

LHLD addr (Load H and L direct)

(L) ← ((byte 3)(byte 2))
(H) ← ((byte 3)(byte 2) + 1)

The content of the memory location, whose address is specified in byte 2 and byte 3 of the instruction, is moved to register L. The content of the memory location at the succeeding address is moved to register H.

0	0	1	0	1	0	1	0
low-order addr							
high-order addr							

Cycles: 5
States: 16
Addressing: direct
Flags: none

SHLD addr (Store H and L direct)

((byte 3)(byte 2)) ← (L)
((byte 3)(byte 2) + 1) ← (H)

The content of register L is moved to the memory location whose address is specified in byte 2 and byte 3. The content of register H is moved to the succeeding memory location.

0	0	1	0	0	0	1	0
low-order addr							
high-order addr							

Cycles: 5
States: 16
Addressing: direct
Flags: none

LDAX rp (Load accumulator indirect)

(A) ← ((rp))

The content of the memory location, whose address is in the register pair rp, is moved to register A. Note: only register pairs rp=B (registers B and C) or rp=D (registers D and E) may be specified.

0	0	R	P	1	0	1	0

Cycles: 2
States: 7
Addressing: reg. indirect
Flags: none

STAX rp (Store accumulator indirect)

((rp)) ← (A)

The content of register A is moved to the memory location whose address is in the register pair rp. Note: only register pairs rp=B (registers B and C) or rp=D (registers D and E) may be specified.

0	0	R	P	0	0	1	0

Cycles: 2
States: 7
Addressing: reg. indirect
Flags: none

XCHG (Exchange H and L with D and E)

(H) ↔ (D)
(L) ↔ (E)

The contents of registers H and L are exchanged with the contents of registers D and E.

1	1	1	0	1	0	1	1

Cycles: 1
States: 4
Addressing: register
Flags: none

SUB M (Subtract memory)

(A) ← (A) – ((H) (L))

The content of the memory location whose address is contained in the H and L registers is subtracted from the content of the accumulator. The result is placed in the accumulator.

1	0	0	1	0	1	1	0

Cycles: 2
States: 7
Addressing: reg. indirect
Flags: Z,S,P,CY,AC

SUI data (Subtract immediate)

(A) ← (A) – (byte 2)

The content of the second byte of the instruction is subtracted from the content of the accumulator. The result is placed in the accumulator.

1	1	0	1	0	1	1	0
data							

Cycles: 2
States: 7
Addressing: immediate
Flags: Z,S,P,CY,AC

SBB r (Subtract Register with borrow)

(A) ← (A) – (r) – (CY)

The content of register r and the content of the CY flag are both subtracted from the accumulator. The result is placed in the accumulator.

1	0	0	1	1	S	S	S

Cycles: 1
States: 4
Addressing: register
Flags: Z,S,P,CY,AC

SBB M (Subtract memory with borrow)

(A) ← (A) – ((H) (L)) – (CY)

The content of the memory location whose address is contained in the H and L registers and the content of the CY flag are both subtracted from the accumulator. The result is placed in the accumulator.

1	0	0	1	1	1	1	0

Cycles: 2
States: 7
Addressing: reg. indirect
Flags: Z,S,P,CY,AC

SBI data (Subtract immediate with borrow)

(A) ← (A) – (byte 2) – (CY)

The contents of the second byte of the instruction and the contents of the CY flag are both subtracted from the accumulator. The result is placed in the accumulator.

1	1	0	1	1	1	1	0
data							

Cycles: 2
States: 7
Addressing: immediate
Flags: Z,S,P,CY,AC

INR r (Increment Register)

(r) ← (r) + 1

The content of register r is incremented by one. Note: All condition flags **except CY** are affected.

0	0	D	D	D	1	0	0

Cycles: 1
States: 5
Addressing: register
Flags: Z,S,P,AC

INR M (Increment memory)

((H) (L)) ← ((H) (L)) + 1

The content of the memory location whose address is contained in the H and L registers is incremented by one. Note: All condition flags **except CY** are affected.

0	0	1	1	0	1	0	0

Cycles: 3
States: 10
Addressing: reg. indirect
Flags: Z,S,P,AC

DCR r (Decrement Register)

(r) ← (r) – 1

The content of register r is decremented by one. Note: All condition flags **except CY** are affected.

0	0	D	D	D	1	0	1

Cycles: 1
States: 5
Addressing: register
Flags: Z,S,P,AC

D.C. Characteristics

T_A = 0°C to 70°C; V_{CC} = +5.0V ±5%; V_{DD} = +12V ±5%.

Symbol	Parameter	Limits Min.	Typ.	Max.	Units	Test Conditions
I_F	Input Current Loading			-.25	mA	V_F = .45V
I_R	Input Leakage Current			10	μA	V_R = 5.25V
V_C	Input Forward Clamp Voltage			1.0	V	I_C = -5mA
V_{IL}	Input "Low" Voltage			.8	V	V_{CC} = 5.0V
V_{IH}	Input "High" Voltage	2.6 2.0			V	Reset Input All Other Inputs
V_{IH}-V_{IL}	REDIN Input Hysteresis	.25			mV	V_{CC} = 5.0V
V_{OL}	Output "Low" Voltage			.45 .45	V V	(ϕ_1,ϕ_2), Ready, Reset, $\overline{STSTB}$ I_{OL} =2.5mA All Other Outputs I_{OL} = 15mA
V_{OH}	Output "High" Voltage ϕ_1 , ϕ_2 READY, RESET All Other Outputs	 9.4 3.6 2.4			 V V V	 I_{OH} = -100μA I_{OH} = -100μA I_{OH} = -1mA
I_{SC}[1]	Output Short Circuit Current (All Low Voltage Outputs Only)	-10		-60	mA	V_O = 0V V_{CC} = 5.0V
I_{CC}	Power Supply Current			115	mA	
I_{DD}	Power Supply Current			12	mA	

Note: 1. Caution, ϕ_1 and ϕ_2 output drivers do not have short circuit protection

CRYSTAL REQUIREMENTS

Tolerance: .005% at 0°C -70°C
Resonance: Series (Fundamental)*
Load Capacitance: 20-35pF
Equivalent Resistance: 75-20 ohms
Power Dissipation (Min): 4mW

*With tank circuit use 3rd overtone mode.

CMC (Complement carry)

(CY) ← $(\overline{CY})$

The CY flag is complemented. **No other flags are affected.**

0	0	1	1	1	1	1	1

Cycles: 1
States: 4
Flags: CY

STC (Set carry)

(CY) ← 1

The CY flag is set to 1. **No other flags are affected.**

0	0	1	1	0	1	1	1

Cycles: 1
States: 4
Flags: CY

Branch Group:

This group of instructions alter normal sequential program flow.

Condition flags are not affected by any instruction in this group.

The two types of branch instructions are unconditional and conditional. Unconditional transfers simply perform the specified operation on register PC (the program counter). Conditional transfers examine the status of one of the four processor flags to determine if the specified branch is to be executed. The conditions that may be specified are as follows:

CONDITION		CCC
NZ	– not zero (Z = 0)	000
Z	– zero (Z = 1)	001
NC	– no carry (CY = 0)	010
C	– carry (CY = 1)	011
PO	– parity odd (P = 0)	100
PE	– parity even (P = 1)	101
P	– plus (S = 0)	110
M	– minus (S = 1)	111

JMP addr (Jump)

(PC) ← (byte 3) (byte 2)

Control is transferred to the instruction whose address is specified in byte 3 and byte 2 of the current instruction.

1	1	0	0	0	0	1	1
low-order addr							
high-order addr							

Cycles: 3
States: 10
Addressing: immediate
Flags: none

Jcondition addr (Conditional jump)

If (CCC),

(PC) ← (byte 3) (byte 2)

If the specified condition is true, control is transferred to the instruction whose address is specified in byte 3 and byte 2 of the current instruction; otherwise, control continues sequentially.

1	1	C	C	C	0	1	0
low-order addr							
high-order addr							

Cycles: 3
States: 10
Addressing: immediate
Flags: none

CALL addr (Call)

((SP) – 1) ← (PCH)

((SP) – 2) ← (PCL)

(SP) ← (SP) – 2

(PC) ← (byte 3) (byte 2)

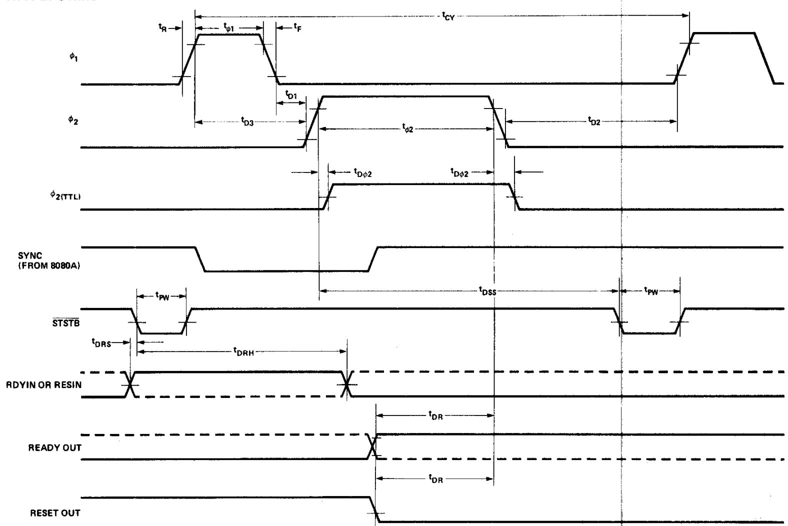
The high-order eight bits of the next instruction address are moved to the memory location whose address is one less than the content of register SP. The low-order eight bits of the next instruction address are moved to the memory location whose address is two less than the content of register SP. The content of register SP is decremented by 2. Control is transferred to the instruction whose address is specified in byte 3 and byte 2 of the current instruction.

1	1	0	0	1	1	0	1
low-order addr							
high-order addr							

Cycles: 5
States: 17
Addressing: immediate/reg. indirect
Flags: none

SCHOTTKY BIPOLAR 8224

WAVEFORMS



VOLTAGE MEASUREMENT POINTS: ϕ_1, ϕ_2 Logic "0" = 1.0V, Logic "1" = 8.0V. All other signals measured at 1.5V.

EXAMPLE:

A.C. Characteristics (For t_{CY} = 488.28 ns)

T_A = 0°C to 70°C; V_{DD} = +5V ±5%; V_{DD} = +12V ±5%.

Symbol	Parameter	Limits Min.	Typ.	Max.	Units	Test Conditions
$t_{\phi 1}$	ϕ_1 Pulse Width	89			ns	t_{CY}=488.28ns
$t_{\phi 2}$	ϕ_2 Pulse Width	236			ns	
t_{D1}	Delay ϕ_1 to ϕ_2	0			ns	
t_{D2}	Delay ϕ_2 to ϕ_1	95			ns	ϕ_1 & ϕ_2 Loaded to C_L = 20 to 50pF
t_{D3}	Delay ϕ_1 to ϕ_2 Leading Edges	109		129	ns	
t_r	Output Rise Time			20	ns	
t_f	Output Fall Time			20	ns	
t_{DSS}	ϕ_2 to $\overline{STSTB}$ Delay	296		326	ns	
$t_{D\phi 2}$	ϕ_2 to ϕ_2 (TTL) Delay	-5		+15	ns	
t_{PW}	Status Strobe Pulse Width	40			ns	Ready & Reset Loaded to 2mA/10pF
t_{DRS}	RDYIN Setup Time to $\overline{STSTB}$	-167			ns	All measurements referenced to 1.5V unless specified otherwise.
t_{DRH}	RDYIN Hold Time after $\overline{STSTB}$	217			ns	
t_{DR}	READY or RESET to ϕ_2 Delay	192			ns	
f_{MAX}	Oscillator Frequency			18.432	MHz	

Stack, I/O, and Machine Control Group:

This group of instructions performs I/O, manipulates the Stack, and alters internal control flags.

Unless otherwise specified, **condition flags are not affected by any instructions in this group.**

FLAG WORD

D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0
S	Z	0	AC	0	P	1	CY

PUSH rp (Push)

((SP) − 1) ← (rh)
((SP) − 2) ← (rl)
(SP) ← (SP) − 2

The content of the high-order register of register pair rp is moved to the memory location whose address is one less than the content of register SP. The content of the low-order register of register pair rp is moved to the memory location whose address is two less than the content of register SP. The content of register SP is decremented by 2. **Note: Register pair rp = SP may not be specified.**

1	1	R	P	0	1	0	1

Cycles: 3
States: 11
Addressing: reg. indirect
Flags: none

PUSH PSW (Push processor status word)

((SP) − 1) ← (A)
$((SP)-2)_0$ ← (CY), $((SP)-2)_1$ ← 1
$((SP)-2)_2$ ← (P), $((SP)-2)_3$ ← 0
$((SP)-2)_4$ ← (AC), $((SP)-2)_5$ ← 0
$((SP)-2)_6$ ← (Z), $((SP)-2)_7$ ← (S)
(SP) ← (SP) − 2

The content of register A is moved to the memory location whose address is one less than register SP. The contents of the condition flags are assembled into a processor status word and the word is moved to the memory location whose address is two less than the content of register SP. The content of register SP is decremented by two.

1	1	1	1	0	1	0	1

Cycles: 3
States: 11
Addressing: reg. indirect
Flags: none

POP rp (Pop)

(rl) ← ((SP))
(rh) ← ((SP) + 1)
(SP) ← (SP) + 2

The content of the memory location, whose address is specified by the content of register SP, is moved to the low-order register of register pair rp. The content of the memory location, whose address is one more than the content of register SP, is moved to the high-order register of register pair rp. The content of register SP is incremented by 2. **Note: Register pair rp = SP may not be specified.**

1	1	R	P	0	0	0	1

Cycles: 3
States: 10
Addressing: reg. indirect
Flags: none

POP PSW (Pop processor status word)

(CY) ← $((SP))_0$
(P) ← $((SP))_2$
(AC) ← $((SP))_4$
(Z) ← $((SP))_6$
(S) ← $((SP))_7$
(A) ← ((SP) + 1)
(SP) ← (SP) + 2

The content of the memory location whose address is specified by the content of register SP is used to restore the condition flags. The content of the memory location whose address is one more than the content of register SP is moved to register A. The content of register SP is incremented by 2.

1	1	1	1	0	0	0	1

Cycles: 3
States: 10
Addressing: reg. indirect
Flags: Z,S,P,CY,AC

FUNCTIONAL DESCRIPTION

General

The 8228 is a single chip System Controller and Data Bus driver for the 8080 Microcomputer System. It generates all control signals required to directly interface MCS-80™ family RAM, ROM, and I/O components.

Schottky Bipolar technology is used to maintain low delay times and provide high output drive capability to support small to medium systems.

Bi-Directional Bus Driver

An eight bit, bi-directional bus driver is provided to buffer the 8080 data bus from Memory and I/O devices. The 8080A data bus has an input requirement of 3.3 volts (min) and can drive (sink) a maximum current of 1.9mA. The 8228 data bus driver assures that these input requirements will be not only met but exceeded for enhanced noise immunity. Also, on the system side of the driver adequate drive current is available (10mA Typ.) so that a large number of Memory and I/O devices can be directly connected to the bus.

The Bi-Directional Bus Driver is controlled by signals from the Gating Array so that proper bus flow is maintained and its outputs can be forced into their high impedance state (3-state) for DMA activities.

Status Latch

At the beginning of each machine cycle the 8080 CPU issues "status" information on its data bus that indicates the type of activity that will occur during the cycle. The 8228 stores this information in the Status Latch when the STSTB input goes "low". The output of the Status Latch is connected to the Gating Array and is part of the Control Signal generation.

Gating Array

The Gating Array generates control signals (MEM R, MEM W, I/O R, I/O W and INTA) by gating the outputs of the Status Latch with signals from the 8080 CPU (DBIN, WR, and HLDA).

The "read" control signals (MEM R, I/O R and INTA) are derived from the logical combination of the appropriate Status Bit (or bits) and the DBIN input from the 8080 CPU.

The "write" control signals (MEM W, I/O W) are derived from the logical combination of the appropriate Status Bit (or bits) and the WR input from the 8080 CPU.

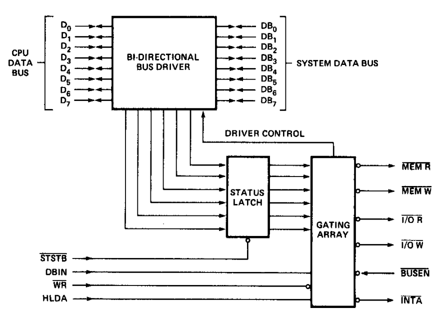
All Control Signals are "active low" and directly interface to MCS-80 family RAM, ROM and I/O components.

The INTA control signal is normally used to gate the "interrupt instruction port" onto the bus. It also provides a special feature in the 8228. If only one basic vector is needed in the interrupt structure, such as in small systems, the 8228 can automatically insert a RST 7 instruction onto the bus at the proper time. To use this option, simply connect the INTA output of the 8228 (pin 23) to the +12 volt supply through a series resistor (1K ohms). The voltage is sensed internally by the 8228 and logic is "set-up" so that when the DBIN input is active a RST 7 instruction is gated on to the bus when an interrupt is acknowledged. This feature provides a single interrupt vector with no additional components, such as an interrupt instruction port.

When using CALL as an Interrupt instruction the 8228 will generate an INTA pulse for each of the three bytes.

The BUSEN (Bus Enable) input to the Gating Array is an asynchronous input that forces the data bus output buffers and control signal buffers into their high-impedance state if it is a "one". If BUSEN is a "zero" normal operation of the data buffer and control signals take place.

8228 BLOCK DIAGRAM



INSTRUCTION SET

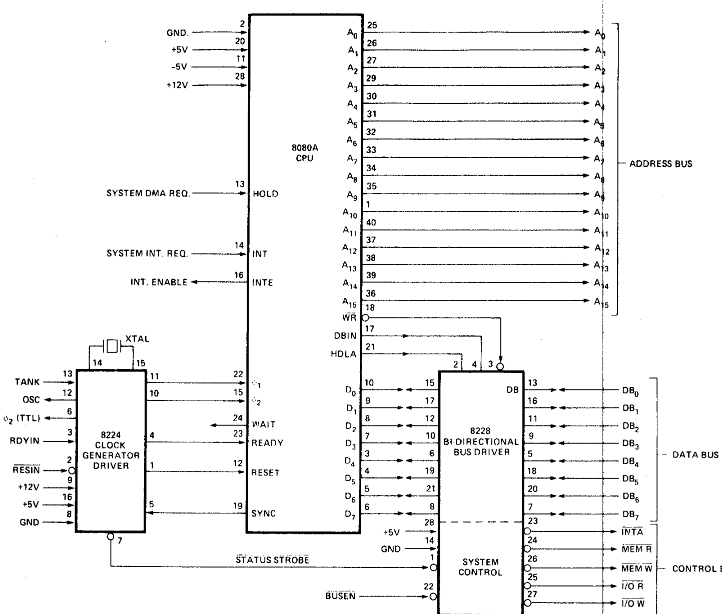
Summary of Processor Instructions

Mnemonic	Description	D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0	Clock[2] Cycles
$MOV_{r1,r2}$	Move register to register	0	1	D	D	D	S	S	S	5
MOV M, r	Move register to memory	0	1	1	1	0	S	S	S	7
MOV r, M	Move memory to register	0	1	D	D	D	1	1	0	7
HLT	Halt	0	1	1	1	0	1	1	0	7
MVI r	Move immediate register	0	0	D	D	D	1	1	0	7
MVI M	Move immediate memory	0	0	1	1	0	1	1	0	10
INR r	Increment register	0	0	D	D	D	1	0	0	5
DCR r	Decrement register	0	0	D	D	D	1	0	1	5
INR M	Increment memory	0	0	1	1	0	1	0	0	10
DCR M	Decrement memory	0	0	1	1	0	1	0	1	10
ADD r	Add register to A	1	0	0	0	0	S	S	S	4
ADC r	Add register to A with carry	1	0	0	0	1	S	S	S	4
SUB r	Subtract register from A	1	0	0	1	0	S	S	S	4
SBB r	Subtract register from A with borrow	1	0	0	1	1	S	S	S	4
ANA r	And register with A	1	0	1	0	0	S	S	S	4
XRA r	Exclusive Or register with A	1	0	1	0	1	S	S	S	4
ORA r	Or register with A	1	0	1	1	0	S	S	S	4
CMP r	Compare register with A	1	0	1	1	1	S	S	S	4
ADD M	Add memory to A	1	0	0	0	0	1	1	0	7
ADC M	Add memory to A with carry	1	0	0	0	1	1	1	0	7
SUB M	Subtract memory from A	1	0	0	1	0	1	1	0	7
SBB M	Subtract memory from A with borrow	1	0	0	1	1	1	1	0	7
ANA M	And memory with A	1	0	1	0	0	1	1	0	7
XRA M	Exclusive Or memory with A	1	0	1	0	1	1	1	0	7
ORA M	Or memory with A	1	0	1	1	0	1	1	0	7
CMP M	Compare memory with A	1	0	1	1	1	1	1	0	7
ADI	Add immediate to A	1	1	0	0	0	1	1	0	7
ACI	Add immediate to A with carry	1	1	0	0	1	1	1	0	7
SUI	Subtract immediate from A	1	1	0	1	0	1	1	0	7
SBI	Subtract immediate from A with borrow	1	1	0	1	1	1	1	0	7
ANI	And immediate with A	1	1	1	0	0	1	1	0	7
XRI	Exclusive Or immediate with A	1	1	1	0	1	1	1	0	7
ORI	Or immediate with A	1	1	1	1	0	1	1	0	7
CPI	Compare immediate with A	1	1	1	1	1	1	1	0	7
RLC	Rotate A left	0	0	0	0	0	1	1	1	4
RRC	Rotate A right	0	0	0	0	1	1	1	1	4
RAL	Rotate A left through carry	0	0	0	1	0	1	1	1	4
RAR	Rotate A right through carry	0	0	0	1	1	1	1	1	4
JMP	Jump unconditional	1	1	0	0	0	0	1	1	10
JC	Jump on carry	1	1	0	1	1	0	1	0	10
JNC	Jump on no carry	1	1	0	1	0	0	1	0	10
JZ	Jump on zero	1	1	0	0	1	0	1	0	10
JNZ	Jump on no zero	1	1	0	0	0	0	1	0	10
JP	Jump on positive	1	1	1	1	0	0	1	0	10
JM	Jump on minus	1	1	1	1	1	0	1	0	10
JPE	Jump on parity even	1	1	1	0	1	0	1	0	10
JPO	Jump on parity odd	1	1	1	0	0	0	1	0	10
CALL	Call unconditional	1	1	0	0	1	1	0	1	17
CC	Call on carry	1	1	0	1	1	1	0	0	11/17
CNC	Call on no carry	1	1	0	1	0	1	0	0	11/17
CZ	Call on zero	1	1	0	0	1	1	0	0	11/17
CNZ	Call on no zero	1	1	0	0	0	1	0	0	11/17
CP	Call on positive	1	1	1	1	0	1	0	0	11/17
CM	Call on minus	1	1	1	1	1	1	0	0	11/17
CPE	Call on parity even	1	1	1	0	1	1	0	0	11/17
CPO	Call on parity odd	1	1	1	0	0	1	0	0	11/17
RET	Return	1	1	0	0	1	0	0	1	10
RC	Return on carry	1	1	0	1	1	0	0	0	5/11
RNC	Return on no carry	1	1	0	1	0	0	0	0	5/11

Mnemonic	Description	D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0	Clock[2] Cycles
RZ	Return on zero	1	1	0	0	1	0	0	0	5/11
RNZ	Return on no zero	1	1	0	0	0	0	0	0	5/11
RP	Return on positive	1	1	1	1	0	0	0	0	5/11
RM	Return on minus	1	1	1	1	1	0	0	0	5/11
RPE	Return on parity even	1	1	1	0	1	0	0	0	5/11
RPO	Return on parity odd	1	1	1	0	0	0	0	0	5/11
RST	Restart	1	1	A	A	A	1	1	1	11
IN	Input	1	1	0	1	1	0	1	1	10
OUT	Output	1	1	0	1	0	0	1	1	10
LXI B	Load immediate register Pair B & C	0	0	0	0	0	0	0	1	10
LXI D	Load immediate register Pair D & E	0	0	0	1	0	0	0	1	10
LXI H	Load immediate register Pair H & L	0	0	1	0	0	0	0	1	10
LXI SP	Load immediate stack pointer	0	0	1	1	0	0	0	1	10
PUSH B	Push register Pair B & C on stack	1	1	0	0	0	1	0	1	11
PUSH D	Push register Pair D & E on stack	1	1	0	1	0	1	0	1	11
PUSH H	Push register Pair H & L on stack	1	1	1	0	0	1	0	1	11
PUSH PSW	Push A and Flags on stack	1	1	1	1	0	1	0	1	11
POP B	Pop register pair B & C off stack	1	1	0	0	0	0	0	1	10
POP D	Pop register pair D & E off stack	1	1	0	1	0	0	0	1	10
POP H	Pop register pair H & L off stack	1	1	1	0	0	0	0	1	10
POP PSW	Pop A and Flags off stack	1	1	1	1	0	0	0	1	10
STA	Store A direct	0	0	1	1	0	0	1	0	13
LDA	Load A direct	0	0	1	1	1	0	1	0	13
XCHG	Exchange D & E, H & L Registers	1	1	1	0	1	0	1	1	4
XTHL	Exchange top of stack, H & L	1	1	1	0	0	0	1	1	18
SPHL	H & L to stack pointer	1	1	1	1	1	0	0	1	5
PCHL	H & L to program counter	1	1	1	0	1	0	0	1	5
DAD B	Add B & C to H & L	0	0	0	0	1	0	0	1	10
DAD D	Add D & E to H & L	0	0	0	1	1	0	0	1	10
DAD H	Add H & L to H & L	0	0	1	0	1	0	0	1	10
DAD SP	Add stack pointer to H & L	0	0	1	1	1	0	0	1	10
STAX B	Store A indirect	0	0	0	0	0	0	1	0	7
STAX D	Store A indirect	0	0	0	1	0	0	1	0	7
LDAX B	Load A indirect	0	0	0	0	1	0	1	0	7
LDAX D	Load A indirect	0	0	0	1	1	0	1	0	7
INX B	Increment B & C registers	0	0	0	0	0	0	1	1	5
INX D	Increment D & E registers	0	0	0	1	0	0	1	1	5
INX H	Increment H & L registers	0	0	1	0	0	0	1	1	5
INX SP	Increment stack pointer	0	0	1	1	0	0	1	1	5
DCX B	Decrement B & C	0	0	0	0	1	0	1	1	5
DCX D	Decrement D & E	0	0	0	1	1	0	1	1	5
DCX H	Decrement H & L	0	0	1	0	1	0	1	1	5
DCX SP	Decrement stack pointer	0	0	1	1	1	0	1	1	5
CMA	Complement A	0	0	1	0	1	1	1	1	4
STC	Set carry	0	0	1	1	0	1	1	1	4
CMC	Complement carry	0	0	1	1	1	1	1	1	4
DAA	Decimal adjust A	0	0	1	0	0	1	1	1	4
SHLD	Store H & L direct	0	0	1	0	0	0	1	0	16
LHLD	Load H & L direct	0	0	1	0	1	0	1	0	16
EI	Enable Interrupts	1	1	1	1	1	0	1	1	4
DI	Disable interrupt	1	1	1	1	0	0	1	1	4
NOP	No-operation	0	0	0	0	0	0	0	0	4

Instruction Code[1]

NOTES: 1. DDD or SSS – 000 B – 001 C – 010 D – 011 E – 100 H – 101 L – 110 Memory – 111 A.
2. Two possible cycle times, (5/11) indicate instruction cycles dependent on condition flags.

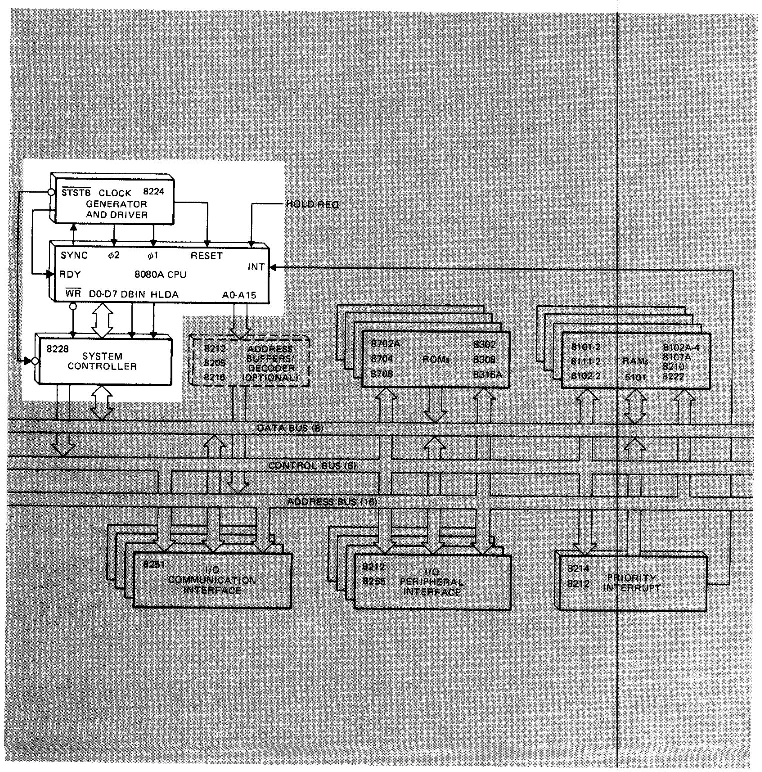


8080A CPU Standard Interface

intel® Microcomputer Systems

CPU Group

8224 8080A-1
8228 8080A-2
8080A M8080-A



8080A FUNCTIONAL PIN DEFINITION

The following describes the function of all of the 8080A I/O pins. Several of the descriptions refer to internal timing periods.

A_{15}-A_0 (output three-state)
ADDRESS BUS; the address bus provides the address to memory (up to 64K 8-bit words) or denotes the I/O device number for up to 256 input and 256 output devices. A_0 is the least significant address bit.

D_7-D_0 (input/output three-state)
DATA BUS; the data bus provides bi-directional communication between the CPU, memory, and I/O devices for instructions and data transfers. Also, during the first clock cycle of each machine cycle, the 8080A outputs a status word on the data bus that describes the current machine cycle. D_0 is the least significant bit.

SYNC (output)
SYNCHRONIZING SIGNAL; the SYNC pin provides a signal to indicate the beginning of each machine cycle.

DBIN (output)
DATA BUS IN; the DBIN signal indicates to external circuits that the data bus is in the input mode. This signal should be used to enable the gating of data onto the 8080A data bus from memory or I/O.

READY (input)
READY; the READY signal indicates to the 8080A that valid memory or input data is available on the 8080A data bus. This signal is used to synchronize the CPU with slower memory or I/O devices. If after sending an address out the 8080A does not receive a READY input, the 8080A will enter a WAIT state for as long as the READY line is low. READY can also be used to single step the CPU.

WAIT (output)
WAIT; the WAIT signal acknowledges that the CPU is in a WAIT state.

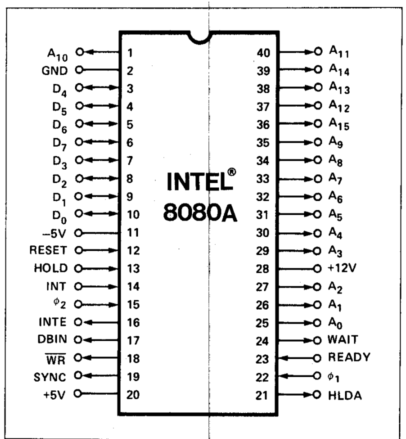
$\overline{WR}$ (output)
WRITE; the $\overline{WR}$ signal is used for memory WRITE or I/O output control. The data on the data bus is stable while the $\overline{WR}$ signal is active low ($\overline{WR}$ = 0).

HOLD (input)
HOLD; the HOLD signal requests the CPU to enter the HOLD state. The HOLD state allows an external device to gain control of the 8080A address and data bus as soon as the 8080A has completed its use of these buses for the current machine cycle. It is recognized under the following conditions:
- the CPU is in the HALT state.
- the CPU is in the T2 or TW state and the READY signal is active.

As a result of entering the HOLD state the CPU ADDRESS BUS (A_{15}-A_0) and DATA BUS (D_7-D_0) will be in their high impedance state. The CPU acknowledges its state with the HOLD ACKNOWLEDGE (HLDA) pin.

HLDA (output)
HOLD ACKNOWLEDGE; the HLDA signal appears in response to the HOLD signal and indicates that the data and address bus will go to the high impedance state. The HLDA signal begins at:
- T3 for READ memory or input.
- The Clock Period following T3 for WRITE memory or OUTPUT operation.

In either case, the HLDA signal appears after the rising edge of ϕ_1 and high impedance occurs after the rising edge of ϕ_2.



Pin Configuration

INTE (output)
INTERRUPT ENABLE; indicates the content of the internal interrupt enable flip/flop. This flip/flop may be set or reset by the Enable and Disable Interrupt instructions and inhibits interrupts from being accepted by the CPU when it is reset. It is automatically reset (disabling further interrupts) at time T1 of the instruction fetch cycle (M1) when an interrupt is accepted and is also reset by the RESET signal.

INT (input)
INTERRUPT REQUEST; the CPU recognizes an interrupt request on this line at the end of the current instruction or while halted. If the CPU is in the HOLD state or if the Interrupt Enable flip/flop is reset it will not honor the request.

RESET (input)[1]
RESET; while the RESET signal is activated, the content of the program counter is cleared. After RESET, the program will start at location 0 in memory. The INTE and HLDA flip/flops are also reset. Note that the flags, accumulator, stack pointer, and registers are not cleared.

V_{SS}	Ground Reference.
V_{DD}	+12 ± 5% Volts.
V_{CC}	+5 ± 5% Volts.
V_{BB}	-5 ±5% Volts (substrate bias).
ϕ_1, ϕ_2	2 externally supplied clock phases. (non TTL compatible)

Schottky Bipolar 8224

CLOCK GENERATOR AND DRIVER FOR 8080A CPU

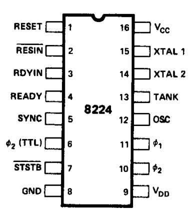
- **Single Chip Clock Generator/Driver for 8080A CPU**
- **Power-Up Reset for CPU**
- **Ready Synchronizing Flip-Flop**
- **Advanced Status Strobe**
- **Oscillator Output for External System Timing**
- **Crystal Controlled for Stable System Operation**
- **Reduces System Package Count**

The 8224 is a single chip clock generator/driver for the 8080A CPU. It is controlled by a crystal, selected by the designer, to meet a variety of system speed requirements.

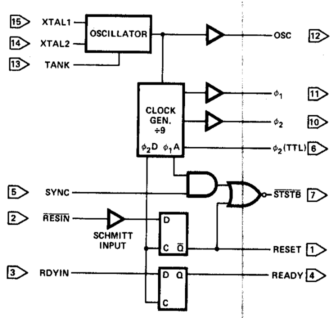
Also included are circuits to provide power-up reset, advance status strobe and synchronization of ready.

The 8224 provides the designer with a significant reduction of packages used to generate clocks and timing for 8080A.

PIN CONFIGURATION



BLOCK DIAGRAM



PIN NAMES

$\overline{\text{RESIN}}$	RESET INPUT
RESET	RESET OUTPUT
RDYIN	READY INPUT
READY	READY OUTPUT
SYNC	SYNC INPUT
$\overline{\text{STSTB}}$	STATUS STB (ACTIVE LOW)
ϕ_1	8080
ϕ_2	CLOCKS

XTAL 1	CONNECTIONS
XTAL 2	FOR CRYSTAL
TANK	USED WITH OVERTONE XTAL
OSC	OSCILLATOR OUTPUT
ϕ_2 (TTL)	ϕ_2 CLK (TTL LEVEL)
V_{CC}	+5V
V_{DD}	+12V
GND	0V

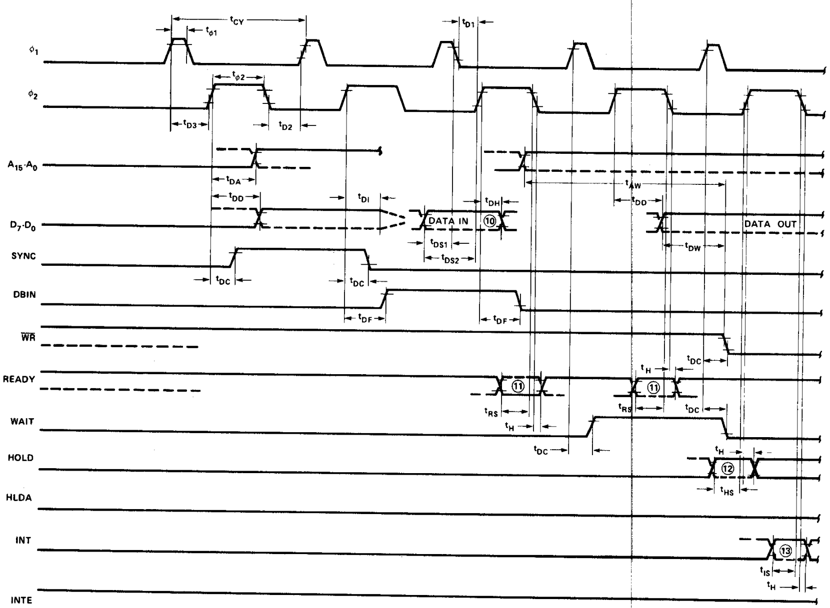
A.C. CHARACTERISTICS

T_A = 0°C to 70°C, V_{DD} = +12V ± 5%, V_{CC} = +5V ± 5%, V_{BB} = -5V ± 5%, V_{SS} = 0V, Unless Otherwise Noted

Symbol	Parameter	Min.	Max.	Unit	Test Condition
t_{CY} [3]	Clock Period	0.48	2.0	μsec	
t_r, t_f	Clock Rise and Fall Time	0	50	nsec	
$t_{\phi 1}$	ϕ_1 Pulse Width	60		nsec	
$t_{\phi 2}$	ϕ_2 Pulse Width	220		nsec	
t_{D1}	Delay ϕ_1 to ϕ_2	0		nsec	
t_{D2}	Delay ϕ_2 to ϕ_1	70		nsec	
t_{D3}	Delay ϕ_1 to ϕ_2 Leading Edges	80		nsec	
t_{DA} [2]	Address Output Delay From ϕ_2		200	nsec	C_L = 100pf
t_{DD} [2]	Data Output Delay From ϕ_2		220	nsec	
t_{DC} [2]	Signal Output Delay From ϕ_1, or ϕ_2 (SYNC, $\overline{WR}$, WAIT, HLDA)		120	nsec	C_L = 50pf
t_{DF} [2]	DBIN Delay From ϕ_2	25	140	nsec	
t_{DI} [1]	Delay for Input Bus to Enter Input Mode		t_{DF}	nsec	
t_{DS1}	Data Setup Time During ϕ_1 and DBIN	30		nsec	

TIMING WAVEFORMS [14]

(Note: Timing measurements are made at the following reference voltages: CLOCK "1" = 8.0V "0" = 1.0V; INPUTS "1" = 3.3V, "0" = 0.8V; OUTPUTS "1" = 2.0V, "0" = 0.8V.)



STSTB (Status Strobe)

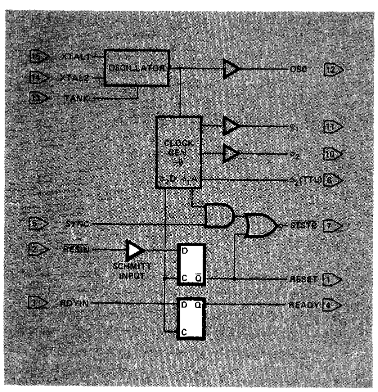
At the beginning of each machine cycle the 8080A CPU issues status information on its data bus. This information tells what type of action will take place during that machine cycle. By bringing in the SYNC signal from the CPU, and gating it with an internal timing signal (ϕ1A), an active low strobe can be derived that occurs at the start of each machine cycle at the earliest possible moment that status data is stable on the bus. The STSTB signal connects directly to the 8228 System Controller.

The power-on Reset also generates STSTB, but of course, for a longer period of time. This feature allows the 8228 to be automatically reset without additional pins devoted for this function.

Power-On Reset and Ready Flip-Flops

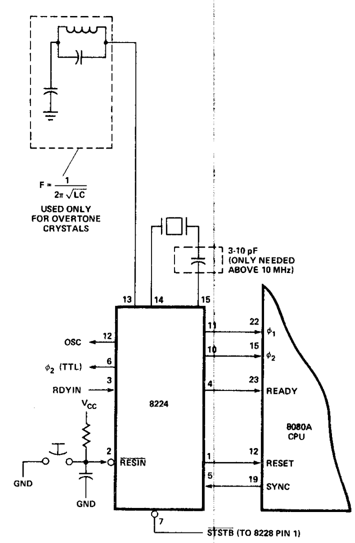
A common function in 8080A Microcomputer systems is the generation of an automatic system reset and start-up upon initial power-on. The 8224 has a built in feature to accomplish this feature.

An external RC network is connected to the RESIN input. The slow transition of the power supply rise is sensed by an internal Schmitt Trigger. This circuit converts the slow transition into a clean, fast edge when its input level reaches a predetermined value. The output of the Schmitt Trigger is connected to a "D" type flip-flop that is clocked with ϕ2D (an internal timing signal). The flip-flop is synchronously reset and an active high level that complies with the 8080A input spec is generated. For manual switch type system Reset circuits, an active low switch closing can be connected to the RESIN input in addition to the power-on RC network.



The READY input to the 8080A CPU has certain timing specifications such as "set-up and hold" thus, an external synchronizing flip-flop is required. The 8224 has this feature built-in. The RDYIN input presents the asynchronous "wait request" to the "D" type flip-flop. By clocking the flip-flop with ϕ2D, a synchronized READY signal at the correct input level, can be connected directly to the 8080A.

The reason for requiring an external flip-flop to synchronize the "wait request" rather than internally in the 8080 CPU is that due to the relatively long delays of MOS logic such an implementation would "rob" the designer of about 200ns during the time his logic is determining if a "wait" is necessary. An external bipolar circuit built into the clock generator eliminates most of this delay and has no effect on component count.



INSTRUCTION SET

The accumulator group instructions include arithmetic and logical operators with direct, indirect, and immediate addressing modes.

Move, load, and store instruction groups provide the ability to move either 8 or 16 bits of data between memory, the six working registers and the accumulator using direct, indirect, and immediate addressing modes.

The ability to branch to different portions of the program is provided with jump, jump conditional, and computed jumps. Also the ability to call to and return from subroutines is provided both conditionally and unconditionally. The RESTART (or single byte call instruction) is useful for interrupt vector operation.

Double precision operators such as stack manipulation and double add instructions extend both the arithmetic and interrupt handling capability of the 8080A. The ability to increment and decrement memory, the six general registers and the accumulator is provided as well as extended increment and decrement instructions to operate on the register pairs and stack pointer. Further capability is provided by the ability to rotate the accumulator left or right through or around the carry bit.

Input and output may be accomplished using memory addresses as I/O ports or the directly addressed I/O provided for in the 8080A instruction set.

The following special instruction group completes the 8080A instruction set: the NOP instruction, HALT to stop processor execution and the DAA instructions provide decimal arithmetic capability. STC allows the carry flag to be directly set, and the CMC instruction allows it to be complemented. CMA complements the contents of the accumulator and XCHG exchanges the contents of two 16-bit register pairs directly.

Data and Instruction Formats

Data in the 8080A is stored in the form of 8-bit binary integers. All data transfers to the system data bus will be in the same format.

D_7 D_6 D_5 D_4 D_3 D_2 D_1 D_0

DATA WORD

The program instructions may be one, two, or three bytes in length. Multiple byte instructions must be stored in successive words in program memory. The instruction formats then depend on the particular operation executed.

Format		TYPICAL INSTRUCTIONS
One Byte Instructions		
D_7 D_6 D_5 D_4 D_3 D_2 D_1 D_0	OP CODE	Register to register, memory reference, arithmetic or logical, rotate, return, push, pop, enable or disable Interrupt instructions
Two Byte Instructions		
D_7 D_6 D_5 D_4 D_3 D_2 D_1 D_0	OP CODE	
D_7 D_6 D_5 D_4 D_3 D_2 D_1 D_0	OPERAND	Immediate mode or I/O instructions
Three Byte Instructions		
D_7 D_6 D_5 D_4 D_3 D_2 D_1 D_0	OP CODE	Jump, call or direct load and store instructions
D_7 D_6 D_5 D_4 D_3 D_2 D_1 D_0	LOW ADDRESS OR OPERAND 1	
D_7 D_6 D_5 D_4 D_3 D_2 D_1 D_0	HIGH ADDRESS OR OPERAND 2	

For the 8080A a logic "1" is defined as a high level and a logic "0" is defined as a low level.

Schottky Bipolar 8228

SYSTEM CONTROLLER AND BUS DRIVER FOR 8080A CPU

- **Single Chip System Control for MCS™-80 Systems**
- **Built-in Bi-Directional Bus Driver for Data Bus Isolation**
- **Allows the use of Multiple Byte Instructions (e.g. CALL) for Interrupt Acknowledge**
- **User Selected Single Level Interrupt Vector (RST 7)**
- **28 Pin Dual In-Line Package**
- **Reduces System Package Count**

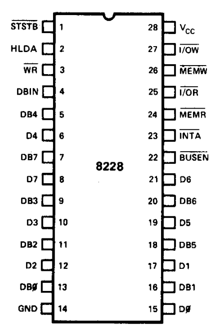
The 8228 is a single chip system controller and bus driver for MCS-80. It generates all signals required to directly interface MCS-80 family RAM, ROM, and I/O components.

A bi-directional bus driver is included to provide high system TTL fan-out. It also provides isolation of the 8080 data bus from memory and I/O. This allows for the optimization of control signals, enabling the systems deisgner to use slower memory and I/O. The isolation of the bus driver also provides for enhanced system noise immunity.

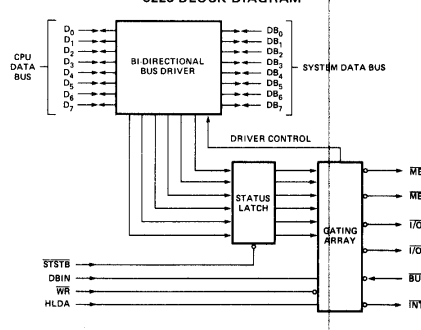
A user selected single level interrupt vector (RST 7) is provided to simplify real time, interrupt driven, small system requirements. The 8228 also generates the correct control signals to allow the use of multiple byte instructions (e.g., CALL) in response to an INTERRUPT ACKNOWLEDGE by the 8080A. This feature permits large, interrupt driven systems to have an unlimited number of interrupt levels.

The 8228 is designed to support a wide variety of system bus structures and also reduce system package count for cost effective, reliable, design of the MCS-80 systems.

PIN CONFIGURATION



8228 BLOCK DIAGRAM



PIN NAMES

D7-D0	DATA BUS (8080 SIDE)	INTA	INTERRUPT ACKNOWLEDGE
DB7-DB0	DATA BUS (SYSTEM SIDE)	HLDA	HLDA (FROM 8080)
I/OR	I/O READ	WR	WR (FROM 8080)
I/OW	I/O WRITE	BUSEN	BUS ENABLE INPUT
MEMR	MEMORY READ	STSTB	STATUS STROBE (FROM 8224)
MEMW	MEMORY WRITE	V_{CC}	+5V
DBIN	DBIN (FROM 8080)	GND	0 VOLTS

intel® Silicon Gate MOS 8080A-1

SINGLE CHIP 8-BIT N-CHANNEL MICROPROCESSOR

The 8080A is functionally and electrically compatible with the Intel® 8080.

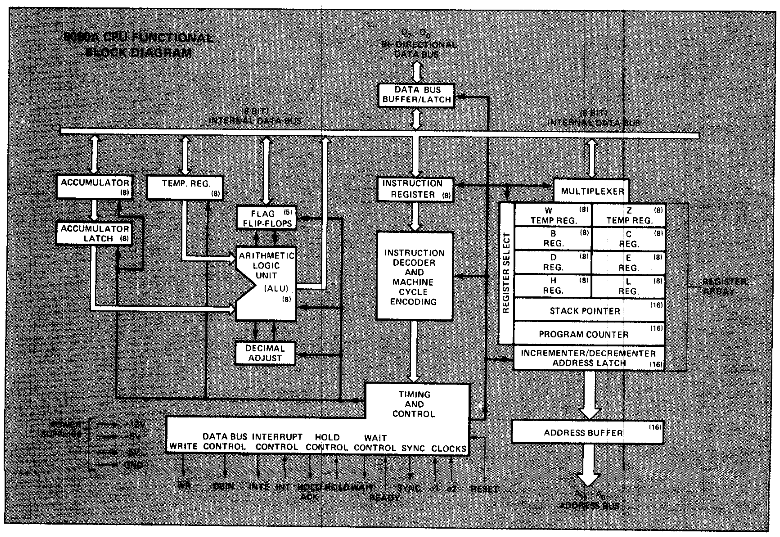
- **TTL Drive Capability**
- **1.3 μs Instruction Cycle**
- **Powerful Problem Solving Instruction Set**
- **Six General Purpose Registers and an Accumulator**
- **Sixteen Bit Program Counter for Directly Addressing up to 64K Bytes of Memory**
- **Sixteen Bit Stack Pointer and Stack Manipulation Instructions for Rapid Switching of the Program Environment**
- **Decimal,Binary and Double Precision Arithmetic**
- **Ability to Provide Priority Vectored Interrupts**
- **512 Directly Addressed I/O Ports**

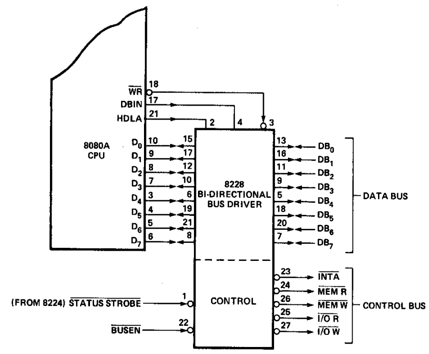
The Intel® 8080A is a complete 8-bit parallel central processing unit (CPU). It is fabricated on a single LSI chip using Intel's n-channel silicon gate MOS process. This offers the user a high performance solution to control and processing applications.

The 8080A contains six 8-bit general purpose working registers and an accumulator. The six general purpose registers may be addressed individually or in pairs providing both single and double precision operators. Arithmetic and logical instructions set or reset four testable flags. A fifth flag provides decimal arithmetic operation.

The 8080A has an external stack feature wherein any portion of memory may be used as a last in/first out stack to store/retrieve the contents of the accumulator, flags, program counter and all of the six general purpose registers. The sixteen bit stack pointer controls the addressing of this external stack. This stack gives the 8080A the ability to easily handle multiple level priority interrupts by rapidly storing and restoring processor status. It also provides almost unlimited subroutine nesting.

This microprocessor has been designed to simplify systems design. Separate 16-line address and 8-line bi-directional data busses are used to facilitate easy interface to memory and I/O. Signals to control the interface to memory and I/O are provided directly by the 8080A. Ultimate control of the address and data busses resides with the HOLD signal. It provides the ability to suspend processor operation and force the address and data busses into a high impedance state. This permits OR-tying these busses with other controlling devices for (DMA) direct memory access or multi-processor operation.





STATUS WORD CHART

TYPE OF MACHINE CYCLE

DATA BUS BIT	STATUS INFORMATION	① INSTRUCTION FETCH	② MEMORY READ	③ MEMORY WRITE	④ STACK READ	⑤ STACK WRITE	⑥ INPUT READ	⑦ OUTPUT WRITE	⑧ INTERRUPT ACKNOWLEDGE	⑨ HALT ACKNOWLEDGE	⑩ INTERRUPT ACKNOWLEDGE WHILE HALT
D_0	INTA	0	0	0	0	0	0	0	1	0	1
D_1	$\overline{WO}$	1	1	0	1	0	1	0	1	1	1
D_2	STACK	0	0	0	1	1	0	0	0	0	0
D_3	HLTA	0	0	0	0	0	0	0	0	1	1
D_4	OUT	0	0	0	0	0	0	1	0	0	0
D_5	M_1	1	0	0	0	0	0	0	1	0	1
D_6	INP	0	0	0	0	0	1	0	0	0	0
D_7	MEMR	1	1	0	1	0	0	0	0	1	0
CONTROL SIGNALS		$\overline{MEM\ R}$	$\overline{MEM\ R}$	$\overline{MEM\ W}$	$\overline{MEM\ R}$	$\overline{MEM\ W}$	$\overline{I/O\ R}$	$\overline{I/O\ W}$	$\overline{INTA}$	(NONE)	$\overline{INTA}$

Ⓝ STATUS WORD

SILICON GATE MOS 8080A-1

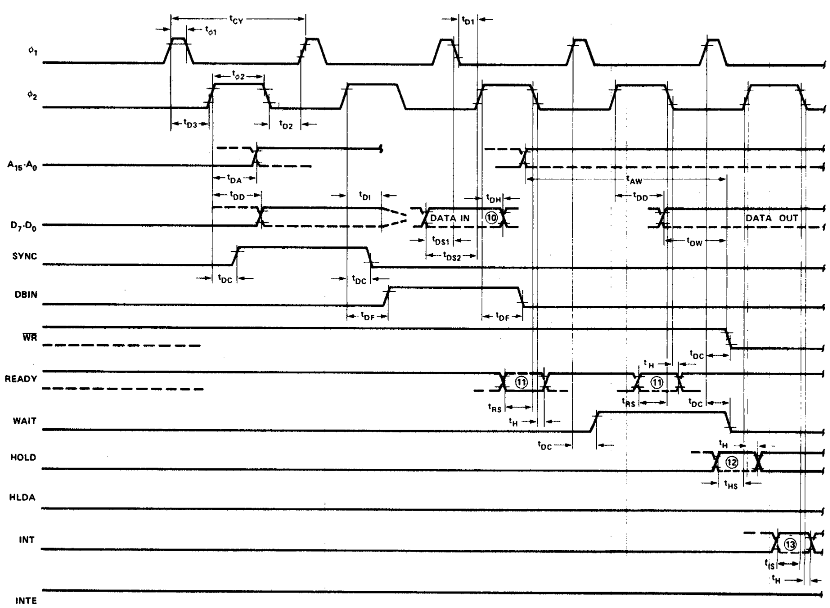
A.C. CHARACTERISTICS *CAUTION: When operating the 8080A-1 at or near full speed, care must be taken to assure precise timing compatibility between 8080A-1, 8224 and 8228.*

T_A = 0°C to 70°C, V_{DD} = +12V ± 5%, V_{CC} = +5V ± 5%, V_{BB} = -5V ± 5%, V_{SS} = 0V, Unless Otherwise Noted

Symbol	Parameter	Min.	Max.	Unit	Test Condition
t_{CY} [3]	Clock Period	.32	2.0	μsec	
t_r, t_f	Clock Rise and Fall Time	0	25	nsec	
$t_{\phi 1}$	ϕ_1 Pulse Width	50		nsec	
$t_{\phi 2}$	ϕ_2 Pulse Width	145		nsec	
t_{D1}	Delay ϕ_1 to ϕ_2	0		nsec	
t_{D2}	Delay ϕ_2 to ϕ_1	60		nsec	
t_{D3}	Delay ϕ_1 to ϕ_2 Leading Edges	60		nsec	
t_{DA} [2]	Address Output Delay From ϕ_2		150	nsec	C_L = 50pf
t_{DD} [2]	Data Output Delay From ϕ_2		180	nsec	
t_{DC} [2]	Signal Output Delay From ϕ_1, or ϕ_2 (SYNC, $\overline{WR}$, WAIT, HLDA)		110	nsec	C_L = 50pf
t_{DF} [2]	DBIN Delay From ϕ_2	25	130	nsec	
t_{DI} [1]	Delay for Input Bus to Enter Input Mode		t_{DF}	nsec	
t_{DS1}	Data Setup Time During ϕ_1 and DBIN	10		nsec	

TIMING WAVEFORMS [14]

(Note: Timing measurements are made at the following reference voltages: CLOCK "1" = 8.0V "0" = 1.0V; INPUTS "1" = 3.3V, "0" = 0.8V; OUTPUTS "1" = 2.0V, "0" = 0.8V.)



SCHOTTKY BIPOLAR 8228

D.C. Characteristics $T_A = 0°C$ to $70°C$; $V_{CC} = 5V \pm 5\%$.

Symbol	Parameter	Limits Min.	Typ.[1]	Max.	Unit	Test Conditions
V_C	Input Clamp Voltage, All Inputs		.75	-1.0	V	V_{CC}=4.75V; I_C=-5mA
I_F	Input Load Current, $\overline{STSTB}$			500	μA	V_{CC} = 5.25V
	D_2 & D_6			750	μA	V_F = 0.45V
	D_0, D_1, D_4, D_5, & D_7			250	μA	
	All Other Inputs			250	μA	
I_R	Input Leakage Current $\overline{STSTB}$			100	μA	V_{CC}=5.25V
	DB_0-DB_7			20	μA	V_R = 5.25V
	All Other Inputs			100	μA	
V_{TH}	Input Threshold Voltage, All Inputs	0.8		2.0	V	V_{CC} = 5V
I_{CC}	Power Supply Current		140	190	mA	V_{CC}=5.25V
V_{OL}	Output Low Voltage, D_0-D_7			.45	V	V_{CC}=4.75V; I_{OL}=2mA
	All Other Outputs			.45	V	I_{OL} = 10mA
V_{OH}	Output High Voltage, D_0-D_7	3.6	3.8		V	V_{CC}=4.75V; I_{OH}=-10μA
	All Other Outputs	2.4			V	I_{OH} = -1mA
I_{OS}	Short Circuit Current, All Outputs	15		90	mA	V_{CC}=5V
$I_{O(off)}$	Off State Output Current, All Control Outputs			100	μA	V_{CC}=5.25V; V_O=5.25
				-100	μA	V_O=.45V
I_{INT}	INTA Current			5	mA	(See Figure below)

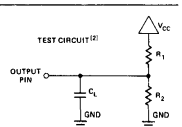
Note 1: Typical values are for T_A = 25°C and nominal supply voltages.

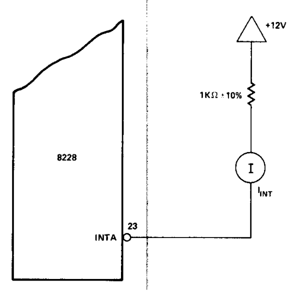
Capacitance This parameter is periodically sampled and not 100% tested.

Symbol	Parameter	Limits Min.	Typ.[1]	Max.	Unit
C_{IN}	Input Capacitance		8	12	pF
C_{OUT}	Output Capacitance Control Signals		7	15	pF
I/O	I/O Capacitance (D or DB)		8	15	pF

TEST CONDITIONS: V_{BIAS} = 2.5V, V_{CC}=5.0V, T_A = 25°C, f = 1MHz.

Note 2: For D_0-D_7: R_1 = 4KΩ, R_2 = ∞Ω, C_L = 25pF. For all other outputs: R_1 = 500Ω, R_2 = 1KΩ, C_L = 100pF.





INTA Test Circuit (for RST 7)

Silicon Gate MOS 8080A-2

SINGLE CHIP 8-BIT N-CHANNEL MICROPROCESSOR

The 8080A is functionally and electrically compatible with the Intel® 8080.

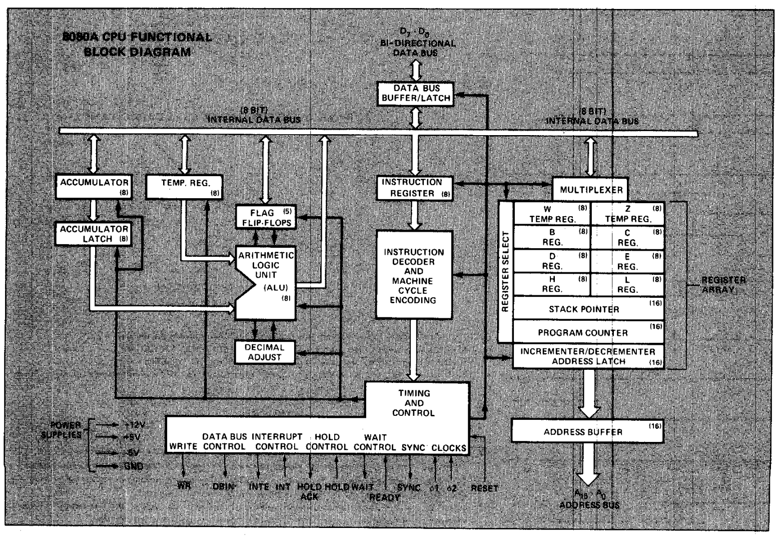
- **TTL Drive Capability**
- **1.5 μs Instruction Cycle**
- **Powerful Problem Solving Instruction Set**
- **Six General Purpose Registers and an Accumulator**
- **Sixteen Bit Program Counter for Directly Addressing up to 64K Bytes of Memory**
- **Sixteen Bit Stack Pointer and Stack Manipulation Instructions for Rapid Switching of the Program Environment**
- **Decimal,Binary and Double Precision Arithmetic**
- **Ability to Provide Priority Vectored Interrupts**
- **512 Directly Addressed I/O Ports**

The Intel® 8080A is a complete 8-bit parallel central processing unit (CPU). It is fabricated on a single LSI chip using Intel's n-channel silicon gate MOS process. This offers the user a high performance solution to control and processing applications.

The 8080A contains six 8-bit general purpose working registers and an accumulator. The six general purpose registers may be addressed individually or in pairs providing both single and double precision operators. Arithmetic and logical instructions set or reset four testable flags. A fifth flag provides decimal arithmetic operation.

The 8080A has an external stack feature wherein any portion of memory may be used as a last in/first out stack to store/retrieve the contents of the accumulator, flags, program counter and all of the six general purpose registers. The sixteen bit stack pointer controls the addressing of this external stack. This stack gives the 8080A the ability to easily handle multiple level priority interrupts by rapidly storing and restoring processor status. It also provides almost unlimited subroutine nesting.

This microprocessor has been designed to simplify systems design. Separate 16-line address and 8-line bi-directional data busses are used to facilitate easy interface to memory and I/O. Signals to control the interface to memory and I/O are provided directly by the 8080A. Ultimate control of the address and data busses resides with the HOLD signal. It provides the ability to suspend processor operation and force the address and data busses into a high impedance state. This permits OR-tying these busses with other controlling devices for (DMA) direct memory access or multi-processor operation.



intel®

Silicon Gate MOS 8080A

SINGLE CHIP 8-BIT N-CHANNEL MICROPROCESSOR

The 8080A is functionally and electrically compatible with the Intel® 8080.

- **TTL Drive Capability**
- **2 μs Instruction Cycle**
- **Powerful Problem Solving Instruction Set**
- **Six General Purpose Registers and an Accumulator**
- **Sixteen Bit Program Counter for Directly Addressing up to 64K Bytes of Memory**
- **Sixteen Bit Stack Pointer and Stack Manipulation Instructions for Rapid Switching of the Program Environment**
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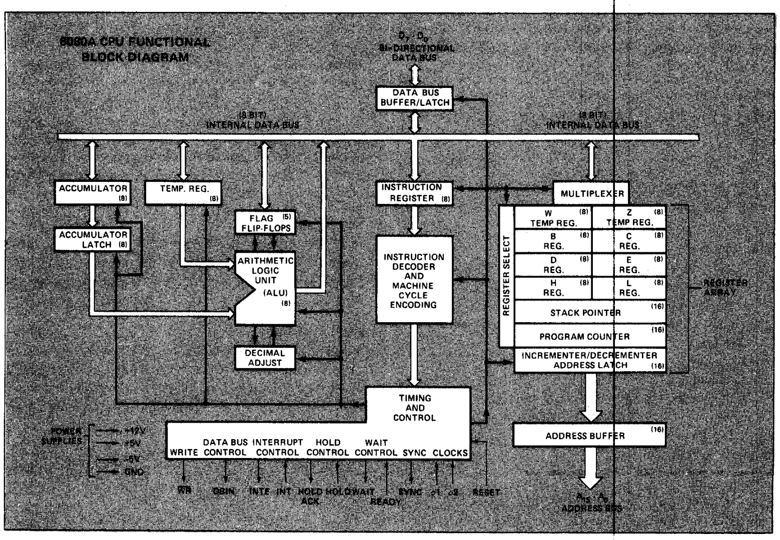


SILICON GATE MOS 8080A-2

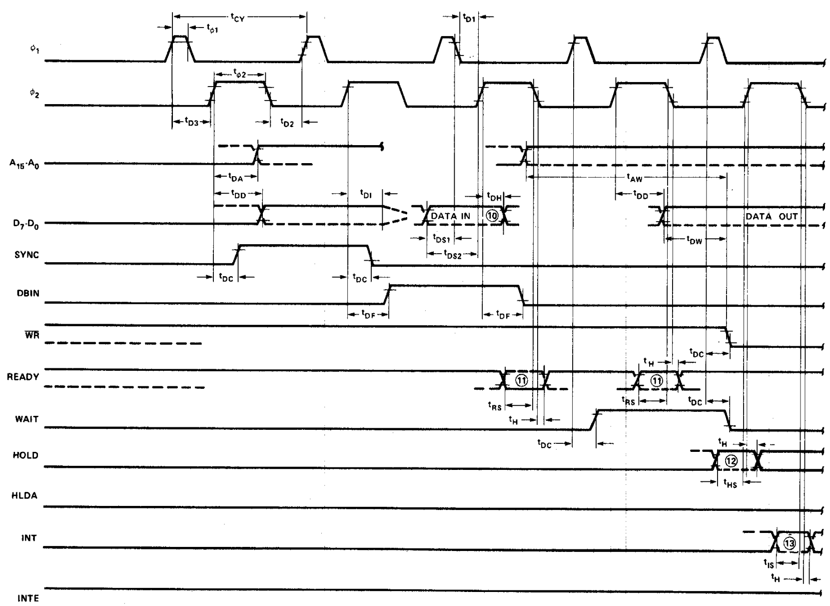
A.C. CHARACTERISTICS

T_A = 0°C to 70°C, V_{DD} = +12V ± 5%, V_{CC} = +5V ± 5%, V_{BB} = -5V ± 5%, V_{SS} = 0V, Unless Otherwise Noted

Symbol	Parameter	Min.	Max.	Unit	Test Condition
t_{CY} [3]	Clock Period	.38	2.0	μsec	
t_r, t_f	Clock Rise and Fall Time	0	50	nsec	
$t_{\phi 1}$	ϕ_1 Pulse Width	60		nsec	
$t_{\phi 2}$	ϕ_2 Pulse Width	175		nsec	
t_{D1}	Delay ϕ_1 to ϕ_2	0		nsec	
t_{D2}	Delay ϕ_2 to ϕ_1	70		nsec	
t_{D3}	Delay ϕ_1 to ϕ_2 Leading Edges	70		nsec	
t_{DA} [2]	Address Output Delay From ϕ_2		175	nsec	C_L = 100pf
t_{DD} [2]	Data Output Delay From ϕ_2		200	nsec	C_L = 100pf
t_{DC} [2]	Signal Output Delay From ϕ_1, or ϕ_2 (SYNC, $\overline{WR}$, WAIT, HLDA)		120	nsec	C_L = 50pf
t_{DF} [2]	DBIN Delay From ϕ_2	25	140	nsec	C_L = 50pf
t_{DI} [1]	Delay for Input Bus to Enter Input Mode		t_{DF}	nsec	
t_{DS1}	Data Setup Time During ϕ_1 and DBIN	20		nsec	

TIMING WAVEFORMS [14]

(Note: Timing measurements are made at the following reference voltages: CLOCK "1" = 8.0V "0" = 1.0V; INPUTS "1" = 3.3V, "0" = 0.8V; OUTPUTS "1" = 2.0V, "0" = 0.8V.)



ABSOLUTE MAXIMUM RATINGS*

Temperature Under Bias . . . . 0°C to +70° C
Storage Temperature . . . . -65°C to +150°C
All Input or Output Voltages
With Respect to V_{BB} . . . . -0.3V to +20V
V_{CC}, V_{DD} and V_{SS} With Respect to V_{BB} -0.3V to +20V
Power Dissipation 1.5W

**COMMENT: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.*

D.C. CHARACTERISTICS

T_A = 0°C to 70°C, V_{DD} = +12V ± 5%, V_{CC} = +5V ± 5%, V_{BB} = -5V ± 5%, V_{SS} = 0V, Unless Otherwise Noted.

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Condition
V_{ILC}	Clock Input Low Voltage	$V_{SS}-1$		$V_{SS}+0.8$	V	
V_{IHC}	Clock Input High Voltage	9.0		$V_{DD}+1$	V	
V_{IL}	Input Low Voltage	$V_{SS}-1$		$V_{SS}+0.8$	V	
V_{IH}	Input High Voltage	3.3		$V_{CC}+1$	V	
V_{OL}	Output Low Voltage			0.45	V	I_{OL} = 1.9mA on all outputs,
V_{OH}	Output High Voltage	3.7			V	I_{OH} = -150μA.
$I_{DD\,(AV)}$	Avg. Power Supply Current (V_{DD})		40	70	mA	Operation
$I_{CC\,(AV)}$	Avg. Power Supply Current (V_{CC})		60	80	mA	T_{CY} = .48 μsec
$I_{BB\,(AV)}$	Avg. Power Supply Current (V_{BB})		.01	1	mA	
I_{IL}	Input Leakage			±10	μA	$V_{SS} \leq V_{IN} \leq V_{CC}$
I_{CL}	Clock Leakage			±10	μA	$V_{SS} \leq V_{CLOCK} \leq V_{DD}$
I_{DL} [2]	Data Bus Leakage in Input Mode			-100 -2.0	μA mA	$V_{SS} \leq V_{IN} \leq V_{SS}+0.8V$ $V_{SS}+0.8V \leq V_{IN} \leq V_{CC}$
I_{FL}	Address and Data Bus Leakage During HOLD			+10 -100	μA	$V_{ADDR/DATA} = V_{CC}$ $V_{ADDR/DATA} = V_{SS} + 0.45V$

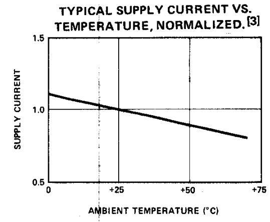
CAPACITANCE

T_A = 25°C $V_{CC} = V_{DD} = V_{SS}$ = 0V, V_{BB} = -5V

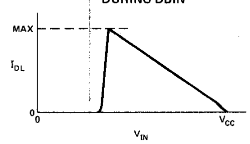
Symbol	Parameter	Typ.	Max.	Unit	Test Condition
C_ϕ	Clock Capacitance	17	25	pf	f_c = 1 MHz
C_{IN}	Input Capacitance	6	10	pf	Unmeasured Pins
C_{OUT}	Output Capacitance	10	20	pf	Returned to V_{SS}

NOTES:
1. The RESET signal must be active for a minimum of 3 clock cycles.
2. When DBIN is high and $V_{IN} > V_{IH}$ an internal active pull up will be switched onto the Data Bus.
3. ΔI supply / ΔT_A = -0.45%/°C.

TYPICAL SUPPLY CURRENT VS. TEMPERATURE, NORMALIZED.[3]



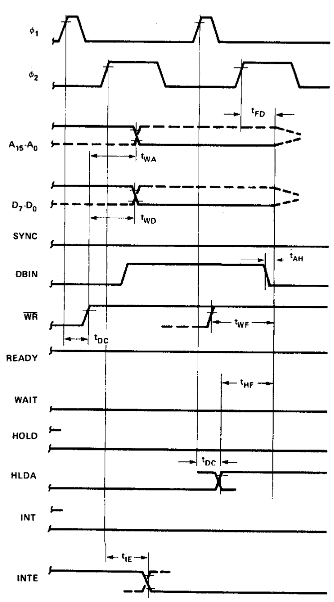
DATA BUS CHARACTERISTIC DURING DBIN



A.C. CHARACTERISTICS (Continued)

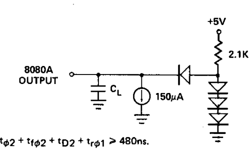
T_A = 0°C to 70°C, V_{DD} = +12V ± 5%, V_{CC} = +5V ± 5%, V_{BB} = -5V ± 5%, V_{SS} = 0V, Unless Otherwise Noted

Symbol	Parameter	Min.	Max.	Unit	Test Condition
t_{DS2}	Data Setup Time to ϕ_2 During DBIN	150		nsec	
t_{DH} [1]	Data Hold Time From ϕ_2 During DBIN	[1]		nsec	
t_{IE} [2]	INTE Output Delay From ϕ_2		200	nsec	C_L = 50pf
t_{RS}	READY Setup Time During ϕ_2	120		nsec	
t_{HS}	HOLD Setup Time to ϕ_2	140		nsec	
t_{IS}	INT Setup Time During ϕ_2 (During ϕ_1 in Halt Mode)	120		nsec	
t_H	Hold Time From ϕ_2 (READY, INT, HOLD)	0		nsec	
t_{FD}	Delay to Float During Hold (Address and Data Bus)		120	nsec	
t_{AW} [2]	Address Stable Prior to $\overline{WR}$	[5]		nsec	
t_{DW} [2]	Output Data Stable Prior to $\overline{WR}$	[6]		nsec	
t_{WD} [2]	Output Data Stable From $\overline{WR}$	[7]		nsec	
t_{WA} [2]	Address Stable From $\overline{WR}$	[7]		nsec	C_L = 100pf: Address, Data C_L = 50pf: $\overline{WR}$, HLDA, DBIN
t_{HF} [2]	HLDA to Float Delay	[8]		nsec	
t_{WF} [2]	$\overline{WR}$ to Float Delay	[9]		nsec	
t_{AH} [2]	Address Hold Time After DBIN During HLDA	-20		nsec	



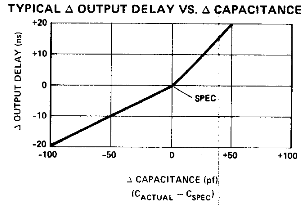
NOTES:

1. Data input should be enabled with DBIN status. No bus conflict can then occur and data hold time is assured. t_{DH} = 50 ns or t_{DF}, whichever is less.
2. Load Circuit.



3. $t_{CY} = t_{D3} + t_{r\phi2} + t_{\phi2} + t_{f\phi2} + t_{D2} + t_{r\phi1} \geq 480ns$.

TYPICAL Δ OUTPUT DELAY VS. Δ CAPACITANCE



4. The following are relevant when interfacing the 8080A to devices having V_{IH} = 3.3V:
   a) Maximum output rise time from .8V to 3.3V = 100ns @ C_L = SPEC.
   b) Output delay when measured to 3.0V = SPEC +60ns @ C_L = SPEC.
   c) If $C_L \neq$ SPEC, add .6ns/pF if $C_L > C_{SPEC}$, subtract .3ns/pF (from modified delay) if $C_L < C_{SPEC}$.
5. $t_{AW} = 2\,t_{CY} - t_{D3} - t_{r\phi2} - 140nsec$.
6. $t_{DW} = t_{CY} - t_{D3} - t_{r\phi2} - 170nsec$.
7. If not HLDA, $t_{WD} = t_{WA} = t_{D3} + t_{r\phi2} + 10ns$. If HLDA, $t_{WD} = t_{WA} = t_{WF}$.
8. $t_{HF} = t_{D3} + t_{r\phi2} - 50ns$.
9. $t_{WF} = t_{D3} + t_{r\phi2} - 10ns$
10. Data in must be stable for this period during DBIN $\cdot T_3$. Both t_{DS1} and t_{DS2} must be satisfied.
11. Ready signal must be stable for this period during T_2 or T_W. (Must be externally synchronized.)
12. Hold signal must be stable for this period during T_2 or T_W when entering hold mode, and during T_3, T_4, T_5 and T_{WH} when in hold mode. (External synchronization is not required.)
13. Interrupt signal must be stable during this period of the last clock cycle of any instruction in order to be recognized on the following instruction. (External synchronization is not required.)
14. This timing diagram shows timing relationships only; it does not represent any specific machine cycle.

INSTRUCTION SET

The accumulator group instructions include arithmetic and logical operators with direct, indirect, and immediate addressing modes.

Move, load, and store instruction groups provide the ability to move either 8 or 16 bits of data between memory, the six working registers and the accumulator using direct, indirect, and immediate addressing modes.

The ability to branch to different portions of the program is provided with jump, jump conditional, and computed jumps. Also the ability to call to and return from subroutines is provided both conditionally and unconditionally. The RESTART (or single byte call instruction) is useful for interrupt vector operation.

Double precision operators such as stack manipulation and double add instructions extend both the arithmetic and interrupt handling capability of the M8080A. The ability to increment and decrement memory, the six general registers and the accumulator is provided as well as extended increment and decrement instructions to operate on the register pairs and stack pointer. Further capability is provided by the ability to rotate the accumulator left or right through or around the carry bit.

Input and output may be accomplished using memory addresses as I/O ports or the directly addressed I/O provided for in the M8080A instruction set.

The following special instruction group completes the M8080A instruction set: the NOP instruction, HALT to stop processor execution and the DAA instructions provide decimal arithmetic capability. STC allows the carry flag to be directly set, and the CMC instruction allows it to be complemented. CMA complements the contents of the accumulator and XCHG exchanges the contents of two 16-bit register pairs directly.

Data and Instruction Formats

Data in the M8080A is stored in the form of 8-bit binary integers. All data transfers to the system data bus will be in the same format.

D_7 D_6 D_5 D_4 D_3 D_2 D_1 D_0

DATA WORD

The program instructions may be one, two, or three bytes in length. Multiple byte instructions must be stored in successive words in program memory. The instruction formats then depend on the particular operation executed.

		TYPICAL INSTRUCTIONS
One Byte Instructions		
D_7 D_6 D_5 D_4 D_3 D_2 D_1 D_0	OP CODE	Register to register, memory reference, arithmetic or logical, rotate, return, push, pop, enable or disable Interrupt instructions
Two Byte Instructions		
D_7 D_6 D_5 D_4 D_3 D_2 D_1 D_0	OP CODE	
D_7 D_6 D_5 D_4 D_3 D_2 D_1 D_0	OPERAND	Immediate mode or I/O instructions
Three Byte Instructions		
D_7 D_6 D_5 D_4 D_3 D_2 D_1 D_0	OP CODE	Jump, call or direct load and store instructions
D_7 D_6 D_5 D_4 D_3 D_2 D_1 D_0	LOW ADDRESS OR OPERAND 1	
D_7 D_6 D_5 D_4 D_3 D_2 D_1 D_0	HIGH ADDRESS OR OPERAND 2	

For the M8080A a logic "1" is defined as a high level and a logic "0" is defined as a low level.

INSTRUCTION SET

Summary of Processor Instructions

		Instruction Code[1]								Clock[2]
Mnemonic	Description	D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0	Cycles
$MOV_{r1, r2}$	Move register to register	0	1	D	D	D	S	S	S	5
MOV M, r	Move register to memory	0	1	1	1	0	S	S	S	7
MOV r, M	Move memory to register	0	1	D	D	D	1	1	0	7
HLT	Halt	0	1	1	1	0	1	1	0	7
MVI r	Move immediate register	0	0	D	D	D	1	1	0	7
MVI M	Move immediate memory	0	0	1	1	0	1	1	0	10
INR r	Increment register	0	0	D	D	D	1	0	0	5
DCR r	Decrement register	0	0	D	D	D	1	0	1	5
INR M	Increment memory	0	0	1	1	0	1	0	0	10
DCR M	Decrement memory	0	0	1	1	0	1	0	1	10
ADD r	Add register to A	1	0	0	0	0	S	S	S	4
ADC r	Add register to A with carry	1	0	0	0	1	S	S	S	4
SUB r	Subtract register from A	1	0	0	1	0	S	S	S	4
SBB r	Subtract register from A with borrow	1	0	0	1	1	S	S	S	4
ANA r	And register with A	1	0	1	0	0	S	S	S	4
XRA r	Exclusive Or register with A	1	0	1	0	1	S	S	S	4
ORA r	Or register with A	1	0	1	1	0	S	S	S	4
CMP r	Compare register with A	1	0	1	1	1	S	S	S	4
ADD M	Add memory to A	1	0	0	0	0	1	1	0	7
ADC M	Add memory to A with carry	1	0	0	0	1	1	1	0	7
SUB M	Subtract memory from A	1	0	0	1	0	1	1	0	7
SBB M	Subtract memory from A with borrow	1	0	0	1	1	1	1	0	7
ANA M	And memory with A	1	0	1	0	0	1	1	0	7
XRA M	Exclusive Or memory with A	1	0	1	0	1	1	1	0	7
ORA M	Or memory with A	1	0	1	1	0	1	1	0	7
CMP M	Compare memory with A	1	0	1	1	1	1	1	0	7
ADI	Add immediate to A	1	1	0	0	0	1	1	0	7
ACI	Add immediate to A with carry	1	1	0	0	1	1	1	0	7
SUI	Subtract immediate from A	1	1	0	1	0	1	1	0	7
SBI	Subtract immediate from A with borrow	1	1	0	1	1	1	1	0	7
ANI	And immediate with A	1	1	1	0	0	1	1	0	7
XRI	Exclusive Or immediate with A	1	1	1	0	1	1	1	0	7
ORI	Or immediate with A	1	1	1	1	0	1	1	0	7
CPI	Compare immediate with A	1	1	1	1	1	1	1	0	7
RLC	Rotate A left	0	0	0	0	0	1	1	1	4
RRC	Rotate A right	0	0	0	0	1	1	1	1	4
RAL	Rotate A left through carry	0	0	0	1	0	1	1	1	4
RAR	Rotate A right through carry	0	0	0	1	1	1	1	1	4
JMP	Jump unconditional	1	1	0	0	0	0	1	1	10
JC	Jump on carry	1	1	0	1	1	0	1	0	10
JNC	Jump on no carry	1	1	0	1	0	0	1	0	10
JZ	Jump on zero	1	1	0	0	1	0	1	0	10
JNZ	Jump on no zero	1	1	0	0	0	0	1	0	10
JP	Jump on positive	1	1	1	1	0	0	1	0	10
JM	Jump on minus	1	1	1	1	1	0	1	0	10
JPE	Jump on parity even	1	1	1	0	1	0	1	0	10
JPO	Jump on parity odd	1	1	1	0	0	0	1	0	10
CALL	Call unconditional	1	1	0	0	1	1	0	1	17
CC	Call on carry	1	1	0	1	1	1	0	0	11/17
CNC	Call on no carry	1	1	0	1	0	1	0	0	11/17
CZ	Call on zero	1	1	0	0	1	1	0	0	11/17
CNZ	Call on no zero	1	1	0	0	0	1	0	0	11/17
CP	Call on positive	1	1	1	1	0	1	0	0	11/17
CM	Call on minus	1	1	1	1	1	1	0	0	11/17
CPE	Call on parity even	1	1	1	0	1	1	0	0	11/17
CPO	Call on parity odd	1	1	1	0	0	1	0	0	11/17
RET	Return	1	1	0	0	1	0	0	1	10
RC	Return on carry	1	1	0	1	1	0	0	0	5/11
RNC	Return on no carry	1	1	0	1	0	0	0	0	5/11
RZ	Return on zero	1	1	0	0	1	0	0	0	5/11
RNZ	Return on no zero	1	1	0	0	0	0	0	0	5/11
RP	Return on positive	1	1	1	1	0	0	0	0	5/11
RM	Return on minus	1	1	1	1	1	0	0	0	5/11
RPE	Return on parity even	1	1	1	0	1	0	0	0	5/11
RPO	Return on parity odd	1	1	1	0	0	0	0	0	5/11
RST	Restart	1	1	A	A	A	1	1	1	11
IN	Input	1	1	0	1	1	0	1	1	10
OUT	Output	1	1	0	1	0	0	1	1	10
LXI B	Load immediate register Pair B & C	0	0	0	0	0	0	0	1	10
LXI D	Load immediate register Pair D & E	0	0	0	1	0	0	0	1	10
LXI H	Load immediate register Pair H & L	0	0	1	0	0	0	0	1	10
LXI SP	Load immediate stack pointer	0	0	1	1	0	0	0	1	10
PUSH B	Push register Pair B & C on stack	1	1	0	0	0	1	0	1	11
PUSH D	Push register Pair D & E on stack	1	1	0	1	0	1	0	1	11
PUSH H	Push register Pair H & L on stack	1	1	1	0	0	1	0	1	11
PUSH PSW	Push A and Flags on stack	1	1	1	1	0	1	0	1	11
POP B	Pop register pair B & C off stack	1	1	0	0	0	0	0	1	10
POP D	Pop register pair D & E off stack	1	1	0	1	0	0	0	1	10
POP H	Pop register pair H & L off stack	1	1	1	0	0	0	0	1	10
POP PSW	Pop A and Flags off stack	1	1	1	1	0	0	0	1	10
STA	Store A direct	0	0	1	1	0	0	1	0	13
LDA	Load A direct	0	0	1	1	1	0	1	0	13
XCHG	Exchange D & E, H & L Registers	1	1	1	0	1	0	1	1	4
XTHL	Exchange top of stack, H & L	1	1	1	0	0	0	1	1	18
SPHL	H & L to stack pointer	1	1	1	1	1	0	0	1	5
PCHL	H & L to program counter	1	1	1	0	1	0	0	1	5
DAD B	Add B & C to H & L	0	0	0	0	1	0	0	1	10
DAD D	Add D & E to H & L	0	0	0	1	1	0	0	1	10
DAD H	Add H & L to H & L	0	0	1	0	1	0	0	1	10
DAD SP	Add stack pointer to H & L	0	0	1	1	1	0	0	1	10
STAX B	Store A indirect	0	0	0	0	0	0	1	0	7
STAX D	Store A indirect	0	0	0	1	0	0	1	0	7
LDAX B	Load A indirect	0	0	0	0	1	0	1	0	7
LDAX D	Load A indirect	0	0	0	1	1	0	1	0	7
INX B	Increment B & C registers	0	0	0	0	0	0	1	1	5
INX D	Increment D & E registers	0	0	0	1	0	0	1	1	5
INX H	Increment H & L registers	0	0	1	0	0	0	1	1	5
INX SP	Increment stack pointer	0	0	1	1	0	0	1	1	5
DCX B	Decrement B & C	0	0	0	0	1	0	1	1	5
DCX D	Decrement D & E	0	0	0	1	1	0	1	1	5
DCX H	Decrement H & L	0	0	1	0	1	0	1	1	5
DCX SP	Decrement stack pointer	0	0	1	1	1	0	1	1	5
CMA	Complement A	0	0	1	0	1	1	1	1	4
STC	Set carry	0	0	1	1	0	1	1	1	4
CMC	Complement carry	0	0	1	1	1	1	1	1	4
DAA	Decimal adjust A	0	0	1	0	0	1	1	1	4
SHLD	Store H & L direct	0	0	1	0	0	0	1	0	16
LHLD	Load H & L direct	0	0	1	0	1	0	1	0	16
EI	Enable Interrupts	1	1	1	1	1	0	1	1	4
DI	Disable interrupt	1	1	1	1	0	0	1	1	4
NOP	No-operation	0	0	0	0	0	0	0	0	4

NOTES: 1. DDD or SSS – 000 B – 001 C – 010 D – 011 E – 100 H – 101 L – 110 Memory – 111 A.

2. Two possible cycle times, (5/11) indicate instruction cycles dependent on condition flags.

M8080A FUNCTIONAL PIN DEFINITION

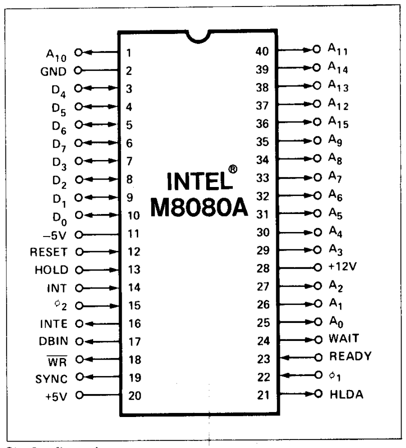
The following describes the function of all of the M8080A I/O pins. Several of the descriptions refer to internal timing periods.

A_{15}-A_0 (output three-state)
ADDRESS BUS; the address bus provides the address to memory (up to 64K 8-bit words) or denotes the I/O device number for up to 256 input and 256 output devices. A_0 is the least significant address bit.

D_7-D_0 (input/output three-state)
DATA BUS; the data bus provides bi-directional communication between the CPU, memory, and I/O devices for instructions and data transfers. Also, during the first clock cycle of each machine cycle, the M8080A outputs a status word on the data bus that describes the current machine cycle. D_0 is the least significant bit.

SYNC (output)
SYNCHRONIZING SIGNAL; the SYNC pin provides a signal to indicate the beginning of each machine cycle.

DBIN (output)
DATA BUS IN; the DBIN signal indicates to external circuits that the data bus is in the input mode. This signal should be used to enable the gating of data onto the M8080A data bus from memory or I/O.



Pin Configuration

READY (input)
READY; the READY signal indicates to the M8080A that valid memory or input data is available on the M8080A data bus. This signal is used to synchronize the CPU with slower memory or I/O devices. If after sending an address out the M8080A does not receive a READY input, the M8080A will enter a WAIT state for as long as the READY line is low. READY can also be used to single step the CPU.

WAIT (output)
WAIT; the WAIT signal acknowledges that the CPU is in a WAIT state.

$\overline{WR}$ (output)
WRITE; the $\overline{WR}$ signal is used for memory WRITE or I/O output control. The data on the data bus is stable while the $\overline{WR}$ signal is active low ($\overline{WR}$ = 0).

HOLD (input)
HOLD; the HOLD signal requests the CPU to enter the HOLD state. The HOLD state allows an external device to gain control of the M8080A address and data bus as soon as the M8080A has completed its use of these buses for the current machine cycle. It is recognized under the following conditions:

- the CPU is in the HALT state.
- the CPU is in the T2 or TW state and the READY signal is active.

As a result of entering the HOLD state the CPU ADDRESS BUS (A_{15}-A_0) and DATA BUS (D_7-D_0) will be in their high impedance state. The CPU acknowledges its state with the HOLD ACKNOWLEDGE (HLDA) pin.

HLDA (output)
HOLD ACKNOWLEDGE; the HLDA signal appears in response to the HOLD signal and indicates that the data and address bus will go to the high impedance state. The HLDA signal begins at:

- T3 for READ memory or input.
- The Clock Period following T3 for WRITE memory or OUTPUT operation.

In either case, the HLDA signal appears after the rising edge of ϕ_1 and high impedance occurs after the rising edge of ϕ_2.

INTE (output)
INTERRUPT ENABLE; indicates the content of the internal interrupt enable flip/flop. This flip/flop may be set or reset by the Enable and Disable Interrupt instructions and inhibits interrupts from being accepted by the CPU when it is reset. It is automatically reset (disabling further interrupts) at time T1 of the instruction fetch cycle (M1) when an interrupt is accepted and is also reset by the RESET signal.

INT (input)
INTERRUPT REQUEST; the CPU recognizes an interrupt request on this line at the end of the current instruction or while halted. If the CPU is in the HOLD state or if the Interrupt Enable flip/flop is reset it will not honor the request.

RESET (input) [1]
RESET; while the RESET signal is activated, the content of the program counter is cleared. After RESET, the program will start at location 0 in memory. The INTE and HLDA flip/flops are also reset. Note that the flags, accumulator, stack pointer, and registers are not cleared.

V_{SS}	Ground Reference
V_{DD}	+12 Volts ±10%.
V_{CC}	+5 Volts ±10%.
V_{BB}	-5 Volts ±10%.
ϕ_1, ϕ_2	2 externally supplied clock phases. (non TTL compatible)

SILICON GATE MOS 8080A-1

ABSOLUTE MAXIMUM RATINGS*

Temperature Under Bias . . . . 0°C to +70° C
Storage Temperature . . . . -65°C to +150°C
All Input or Output Voltages
With Respect to V_{BB} . . . . -0.3V to +20V
V_{CC}, V_{DD} and V_{SS} With Respect to V_{BB} -0.3V to +20V
Power Dissipation 1.5W

**COMMENT: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.*

D.C. CHARACTERISTICS

T_A = 0°C to 70°C, V_{DD} = +12V ± 5%, V_{CC} = +5V ± 5%, V_{BB} = -5V ± 5%, V_{SS} = 0V, Unless Otherwise Noted.

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Condition
V_{ILC}	Clock Input Low Voltage	$V_{SS}-1$		$V_{SS}+0.8$	V	
V_{IHC}	Clock Input High Voltage	9.0		$V_{DD}+1$	V	
V_{IL}	Input Low Voltage	$V_{SS}-1$		$V_{SS}+0.8$	V	
V_{IH}	Input High Voltage	3.3		$V_{CC}+1$	V	
V_{OL}	Output Low Voltage			0.45	V	I_{OL} = 1.9mA on all outputs,
V_{OH}	Output High Voltage	3.7			V	I_{OH} = 150µA.
$I_{DD\,(AV)}$	Avg. Power Supply Current (V_{DD})		40	70	mA	Operation
$I_{CC\,(AV)}$	Avg. Power Supply Current (V_{CC})		60	80	mA	T_{CY} = .32µsec
$I_{BB\,(AV)}$	Avg. Power Supply Current (V_{BB})		.01	1	mA	
I_{IL}	Input Leakage			±10	µA	$V_{SS} \leq V_{IN} \leq V_{CC}$
I_{CL}	Clock Leakage			±10	µA	$V_{SS} \leq V_{CLOCK} \leq V_{DD}$
I_{DL} [2]	Data Bus Leakage in Input Mode			-100 -2.0	µA mA	$V_{SS} \leq V_{IN} \leq V_{SS}+0.8V$ $V_{SS}+0.8V \leq V_{IN} \leq V_{CC}$
I_{FL}	Address and Data Bus Leakage During HOLD			+10 -100	µA	$V_{ADDR/DATA} = V_{CC}$ $V_{ADDR/DATA} = V_{SS} + 0.45V$

CAPACITANCE

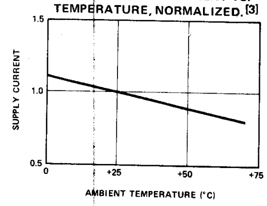
T_A = 25°C $V_{CC} = V_{DD} = V_{SS}$ = 0V, V_{BB} = -5V

Symbol	Parameter	Typ.	Max.	Unit	Test Condition
C_ϕ	Clock Capacitance	17	25	pf	f_c = 1 MHz
C_{IN}	Input Capacitance	6	10	pf	Unmeasured Pins
C_{OUT}	Output Capacitance	10	20	pf	Returned to V_{SS}

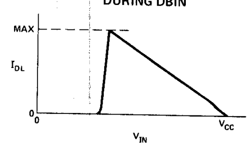
NOTES:

1. The RESET signal must be active for a minimum of 3 clock cycles.
2. When DBIN is high and $V_{IN} > V_{IH}$ an internal active pull up will be switched onto the Data Bus.
3. ΔI supply / ΔT_A = -0.45%/°C.

TYPICAL SUPPLY CURRENT VS. TEMPERATURE, NORMALIZED.[3]



DATA BUS CHARACTERISTIC DURING DBIN

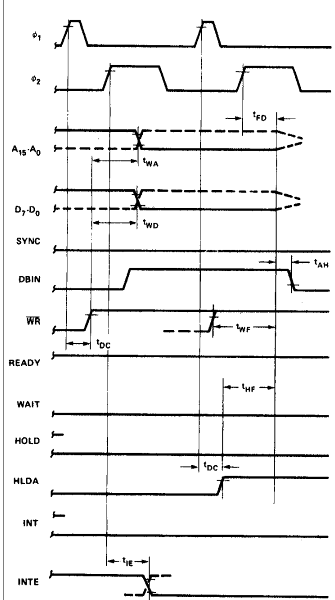


SILICON GATE MOS 8080A-1

A.C. CHARACTERISTICS (Continued)

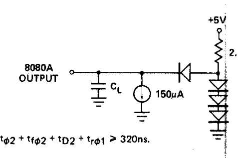
T_A = 0°C to 70°C, V_{DD} = +12V ± 5%, V_{CC} = +5V ± 5%, V_{BB} = -5V ± 5%, V_{SS} = 0V, Unless Otherwise Noted

Symbol	Parameter	Min.	Max.	Unit	Test Condition
t_{DS2}	Data Setup Time to ϕ_2 During DBIN	120		nsec	C_L = 50pf
t_{DH} [1]	Data Hold Time From ϕ_2 During DBIN	[1]		nsec	
t_{IE} [2]	INTE Output Delay From ϕ_2		200	nsec	
t_{RS}	READY Setup Time During ϕ_2	90		nsec	
t_{HS}	HOLD Setup Time to ϕ_2	120		nsec	
t_{IS}	INT Setup Time During ϕ_2 (During ϕ_1 in Halt Mode)	100		nsec	
t_H	Hold Time From ϕ_2 (READY, INT, HOLD)	0		nsec	
t_{FD}	Delay to Float During Hold (Address and Data Bus)		120	nsec	
t_{AW} [2]	Address Stable Prior to $\overline{WR}$	[5]		nsec	C_L = 50pf: Address, Data; C_L=50pf: $\overline{WR}$, HLDA, DBIN
t_{DW} [2]	Output Data Stable Prior to $\overline{WR}$	[6]		nsec	
t_{WD} [2]	Output Data Stable From $\overline{WR}$	[7]		nsec	
t_{WA} [2]	Address Stable From $\overline{WR}$	[7]		nsec	
t_{HF} [2]	HLDA to Float Delay	[8]		nsec	
t_{WF} [2]	$\overline{WR}$ to Float Delay	[9]		nsec	
t_{AH} [2]	Address Hold Time After DBIN During HLDA	-20		nsec	



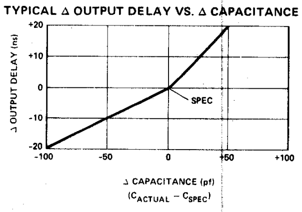
NOTES:

1. Data input should be enabled with DBIN status. No bus conflict can then occur and data hold time is assured. t_{DH} = 50 ns or t_{DF}, whichever is less.
2. Load Circuit.



3. $t_{CY} = t_{D3} + t_{r\phi2} + t_{\phi2} + t_{f\phi2} + t_{D2} + t_{r\phi1} \geq 320ns$.

TYPICAL Δ OUTPUT DELAY VS. Δ CAPACITANCE



4. The following are relevant when interfacing the 8080A to devices having V_{IH} = 3.3V:
   a) Maximum output rise time from .8V to 3.3V = 100ns @ C_L = SPEC.
   b) Output delay when measured to 3.0V = SPEC +60ns @ C_L = SPEC.
   c) If $C_L \neq$ SPEC, add .6ns/pF if $C_L > C_{SPEC}$, subtract .3ns/pF (from modified delay) if $C_L < C_{SPEC}$.
5. $t_{AW} = 2\,t_{CY} - t_{D3} - t_{r\phi2}$ -110nsec.
6. $t_{DW} = t_{CY} - t_{D3} - t_{r\phi2}$ -150nsec.
7. If not HLDA, $t_{WD} = t_{WA} = t_{D3} + t_{r\phi2}$ +10ns. If HLDA, $t_{WD} = t_{WA} = t_{WF}$.
8. $t_{HF} = t_{D3} + t_{r\phi2}$ -50ns.
9. $t_{WF} = t_{D3} + t_{r\phi2}$ -10ns
10. Data in must be stable for this period during DBIN $\cdot T_3$. Both t_{DS1} and t_{DS2} must be satisfied.
11. Ready signal must be stable for this period during T_2 or T_W. (Must be externally synchronized.)
12. Hold signal must be stable for this period during T_2 or T_W when entering hold mode, and during T_3, T_4, T_5 and T_{WH} when in hold mode. (External synchronization is not required.)
13. Interrupt signal must be stable during this period of the last clock cycle of any instruction in order to be recognized on the following instruction. (External synchronization is not required.)
14. This timing diagram shows timing relationships only; it does not represent any specific machine cycle.

SILICON GATE MOS 8080A-2

ABSOLUTE MAXIMUM RATINGS*

Temperature Under Bias . . . . 0°C to +70° C
Storage Temperature . . . . -65°C to +150°C
All Input or Output Voltages
With Respect to V_{BB} . . . . -0.3V to +20V
V_{CC}, V_{DD} and V_{SS} With Respect to V_{BB} -0.3V to +20V
Power Dissipation 1.5W

**COMMENT: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.*

D.C. CHARACTERISTICS

T_A = 0°C to 70°C, V_{DD} = +12V ± 5%, V_{CC} = +5V ± 5%, V_{BB} = -5V ± 5%, V_{SS} = 0V, Unless Otherwise Noted.

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Condition
V_{ILC}	Clock Input Low Voltage	$V_{SS}-1$		V_{SS}+0.8	V	
V_{IHC}	Clock Input High Voltage	9.0		V_{DD}+1	V	
V_{IL}	Input Low Voltage	$V_{SS}-1$		V_{SS}+0.8	V	
V_{IH}	Input High Voltage	3.3		V_{CC}+1	V	
V_{OL}	Output Low Voltage			0.45	V	I_{OL} = 1.9mA on all outputs,
V_{OH}	Output High Voltage	3.7			V	I_{OH} = 150μA.
$I_{DD\ (AV)}$	Avg. Power Supply Current (V_{DD})		40	70	mA	Operation
$I_{CC\ (AV)}$	Avg. Power Supply Current (V_{CC})		60	80	mA	T_{CY} = .38μsec
$I_{BB\ (AV)}$	Avg. Power Supply Current (V_{BB})		.01	1	mA	
I_{IL}	Input Leakage			±10	μA	$V_{SS} \leq V_{IN} \leq V_{CC}$
I_{CL}	Clock Leakage			±10	μA	$V_{SS} \leq V_{CLOCK} \leq V_{DD}$
I_{DL} [2]	Data Bus Leakage in Input Mode			-100 -2.0	μA mA	$V_{SS} \leq V_{IN} \leq V_{SS}+0.8V$ $V_{SS}+0.8V \leq V_{IN} \leq V_{CC}$
I_{FL}	Address and Data Bus Leakage During HOLD			+10 -100	μA	$V_{ADDR/DATA} = V_{CC}$ $V_{ADDR/DATA} = V_{SS} + 0.45V$

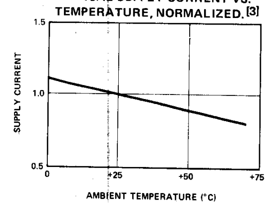
CAPACITANCE

T_A = 25°C $V_{CC} = V_{DD} = V_{SS}$ = 0V, V_{BB} = -5V

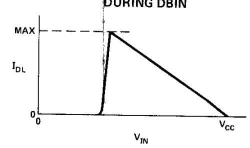
Symbol	Parameter	Typ.	Max.	Unit	Test Condition
C_ϕ	Clock Capacitance	17	25	pf	f_c = 1 MHz
C_{IN}	Input Capacitance	6	10	pf	Unmeasured Pins
C_{OUT}	Output Capacitance	10	20	pf	Returned to V_{SS}

NOTES:
1. The RESET signal must be active for a minimum of 3 clock cycles.
2. When DBIN is high and $V_{IN} > V_{IH}$ an internal active pull up will be switched onto the Data Bus.
3. ΔI supply / ΔT_A = -0.45%/°C.

TYPICAL SUPPLY CURRENT VS. TEMPERATURE, NORMALIZED.[3]



DATA BUS CHARACTERISTIC DURING DBIN



PIN CONNECTIONS

The external lead connections to the 8702A differ, depending on whether the device is being programmed[1] or used in read mode. (See following table.)

PIN / MODE	12 (V_{CC})	13 (Program)	14 ($\overline{CS}$)	15 (V_{BB})	16 (V_{GG})	22 (V_{CC})	23 (V_{CC})
Read	V_{CC}	V_{CC}	GND	V_{CC}	V_{GG}	V_{CC}	V_{CC}
Programming	GND	Program Pulse	GND	V_{BB}	Pulsed V_{GG} (V_{IL4P})	GND	GND

ABSOLUTE MAXIMUM RATINGS*

Ambient Temperature Under Bias . . . . 0°C to +70°C
Storage Temperature . . . . −65°C to +125°C
Soldering Temperature of Leads (10 sec) . . . . +300°C
Power Dissipation . . . . 2 Watts
Read Operation: Input Voltages and Supply
Voltages with respect to V_{CC} . . . .+0.5V to −20V
Program Operation: Input Voltages and Supply
Voltages with respect to V_{CC} . . . . −48V

*COMMENT

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or at any other condition above those indicated in the operational sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

READ OPERATION

D.C. AND OPERATING CHARACTERISTICS

T_A = 0°C to 70°C, V_{CC} = +5V±5%, V_{DD} = −9V±5%, $V_{GG}^{(2)}$ = −9V±5%, unless otherwise noted.

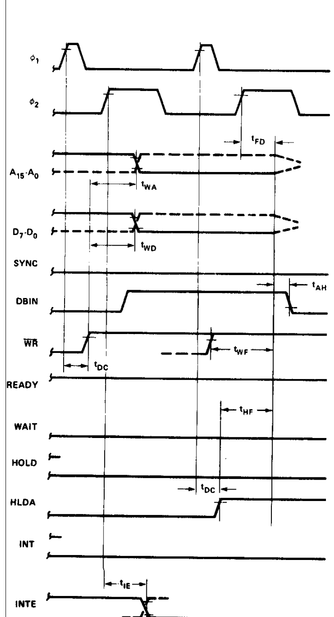
SYMBOL	TEST	MIN.	TYP.[3]	MAX.	UNIT	CONDITIONS	
I_{LI}	Address and Chip Select Input Load Current			10	μA	V_{IN} = 0.0V	
I_{LO}	Output Leakage Current			10	μA	V_{OUT} = 0.0V, $\overline{CS}$ = V_{CC} −2	
I_{DD0}	Power Supply Current		5	10	mA	V_{GG}=V_{CC}, $\overline{CS}$=V_{CC}−2, I_{OL} = 0.0mA, T_A = 25°C	
I_{DD1}	Power Supply Current		35	50	mA	$\overline{CS}$=V_{CC} −2, I_{OL} =0.0mA, T_A = 25°C	Continuous Operation
I_{DD2}	Power Supply Current		32	46	mA	$\overline{CS}$=0.0, I_{OL} =0.0mA, T_A = 25°C	Continuous Operation
I_{DD3}	Power Supply Current		38.5	60	mA	$\overline{CS}$=V_{CC} −2, I_{OL} =0.0mA, T_A = 0°C	Continuous Operation
I_{CF1}	Output Clamp Current		8	14	mA	V_{OUT} = −1.0V, T_A = 0°C	Continuous Operation
I_{CF2}	Output Clamp Current			13	mA	V_{OUT} = −1.0V, T_A = 25°C	Continuous Operation
I_{GG}	Gate Supply Current			10	μA		
V_{IL1}	Input Low Voltage for TTL Interface	−1.0		0.65	V		
V_{IL2}	Input Low Voltage for MOS Interface	V_{DD}		V_{CC} −6	V		
V_{IH}	Address and Chip Select Input High Voltage	V_{CC}−2		V_{CC} +0.3	V		
I_{OL}	Output Sink Current	1.6	4		mA	V_{OUT} = 0.45V	
V_{OL}	Output Low Voltage		−.7	0.45	V	I_{OL} = 1.6mA	
V_{OH}	Output High Voltage	3.5			V	I_{OH} = −200 μA	

Note 1: In the programming mode, the data inputs 1–8 are pins 4–11 respectively. $\overline{CS}$ = GND.
Note 2: V_{GG} may be clocked to reduce power dissipation. In this mode average I_{DD} increases in proportion to V_{GG} duty cycle. (See p. 5)
Note 3: Typical values are at nominal voltages and T_A = 25°C.

A.C. CHARACTERISTICS (Continued)

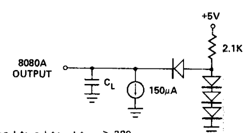
$T_A = 0°C$ to $70°C$, $V_{DD} = +12V \pm 5\%$, $V_{CC} = +5V \pm 5\%$, $V_{BB} = -5V \pm 5\%$, $V_{SS} = 0V$, Unless Otherwise Noted

Symbol	Parameter	Min.	Max.	Unit	Test Condition
t_{DS2}	Data Setup Time to ϕ_2 During DBIN	130		nsec	
t_{DH} [1]	Data Hold Time From ϕ_2 During DBIN	[1]		nsec	
t_{IE} [2]	INTE Output Delay From ϕ_2		200	nsec	C_L = 50pf
t_{RS}	READY Setup Time During ϕ_2	90		nsec	
t_{HS}	HOLD Setup Time to ϕ_2	120		nsec	
t_{IS}	INT Setup Time During ϕ_2 (During ϕ_1 in Halt Mode)	100		nsec	
t_H	Hold Time From ϕ_2 (READY, INT, HOLD)	0		nsec	
t_{FD}	Delay to Float During Hold (Address and Data Bus)		120	nsec	
t_{AW} [2]	Address Stable Prior to $\overline{WR}$	[5]		nsec	C_L=100pf: Address, Data C_L=50pf: $\overline{WR}$, HLDA, DBIN
t_{DW} [2]	Output Data Stable Prior to $\overline{WR}$	[6]		nsec	
t_{WD} [2]	Output Data Stable From $\overline{WR}$	[7]		nsec	
t_{WA} [2]	Address Stable From $\overline{WR}$	[7]		nsec	
t_{HF} [2]	HLDA to Float Delay	[8]		nsec	
t_{WF} [2]	$\overline{WR}$ to Float Delay	[9]		nsec	
t_{AH} [2]	Address Hold Time After DBIN During HLDA	-20		nsec	



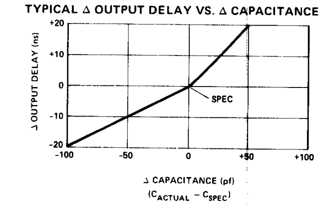
NOTES:

1. Data input should be enabled with DBIN status. No bus conflict can then occur and data hold time is assured. t_{DH} = 50 ns or t_{DF}, whichever is less.
2. Load Circuit.



3. $t_{CY} = t_{D3} + t_{r\phi2} + t_{\phi2} + t_{f\phi2} + t_{D2} + t_{r\phi1} \geq 380ns$.

TYPICAL Δ OUTPUT DELAY VS. Δ CAPACITANCE



4. The following are relevant when interfacing the 8080A to devices having V_{IH} = 3.3V:
   a) Maximum output rise time from .8V to 3.3V = 100ns @ C_L = SPEC.
   b) Output delay when measured to 3.0V = SPEC +60ns @ C_L = SPEC.
   c) If $C_L \neq$ SPEC, add .6ns/pF if $C_L > C_{SPEC}$, subtract .3ns/pF (from modified delay) if $C_L < C_{SPEC}$.
5. $t_{AW} = 2\,t_{CY} - t_{D3} - t_{r\phi2} - 130nsec$.
6. $t_{DW} = t_{CY} - t_{D3} - t_{r\phi2} - 170nsec$.
7. If not HLDA, $t_{WD} = t_{WA} = t_{D3} + t_{r\phi2} + 10ns$. If HLDA, $t_{WD} = t_{WA} = t_{WF}$.
8. $t_{HF} = t_{D3} + t_{r\phi2} - 50ns$.
9. $t_{WF} = t_{D3} + t_{r\phi2} - 10ns$
10. Data in must be stable for this period during DBIN $\cdot T_3$. Both t_{DS1} and t_{DS2} must be satisfied.
11. Ready signal must be stable for this period during T_2 or T_W. (Must be externally synchronized.)
12. Hold signal must be stable for this period during T_2 or T_W when entering hold mode, and during T_3, T_4, T_5 and T_{WH} when in hold mode. (External synchronization is not required.)
13. Interrupt signal must be stable during this period of the last clock cycle of any instruction in order to be recognized on the following instruction. (External synchronization is not required.)
14. This timing diagram shows timing relationships only; it does not represent any specific machine cycle.

Silicon Gate MOS M8080A

SINGLE CHIP 8-BIT N-CHANNEL MICROPROCESSOR

The M8080A is functionally compatible with the Intel® 8080.

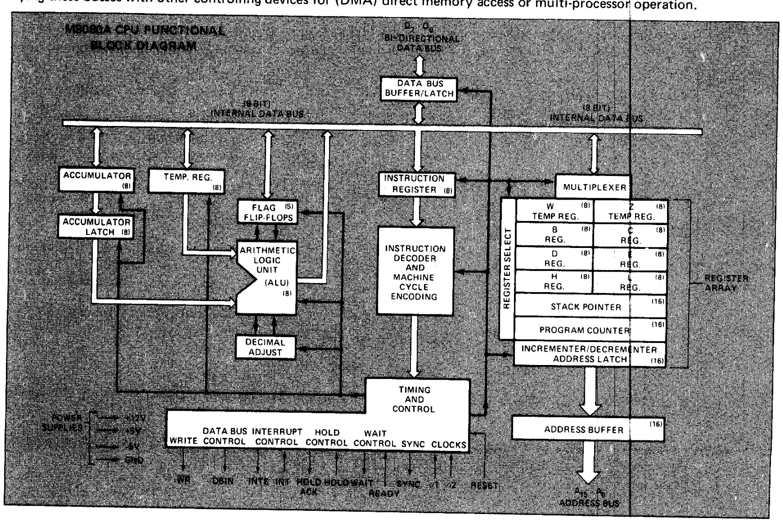
- **Full Military Temperature Range −55°C to +125°C**
- **±10% Power Supply Tolerance**
- **2 μs Instruction Cycle**
- **Powerful Problem Solving Instruction Set**
- **Six General Purpose Registers and an Accumulator**
- **Sixteen Bit Program Counter for Directly Addressing up to 64K Bytes of Memory**
- **Sixteen Bit Stack Pointer and Stack Manipulation Instructions for Rapid Switching of the Program Environment**
- **Decimal,Binary and Double Precision Arithmetic**
- **Ability to Provide Priority Vectored Interrupts**
- **512 Directly Addressed I/O Ports**
- **TTL Drive Capability**

The Intel® M8080A is a complete 8-bit parallel central processing unit (CPU). It is fabricated on a single LSI chip using Intel's n-channel silicon gate MOS process. This offers the user a high performance solution to control and processing applications.

The M8080A contains six 8-bit general purpose working registers and an accumulator. The six general purpose registers may be addressed individually or in pairs providing both single and double precision operators. Arithmetic and logical instructions set or reset four testable flags. A fifth flag provides decimal arithmetic operation.

The M8080A has an external stack feature wherein any portion of memory may be used as a last in/first out stack to store/retrieve the contents of the accumulator, flags, program counter and all of the six general purpose registers. The sixteen bit stack pointer controls the addressing of this external stack. This stack gives the M8080A the ability to easily handle multiple level priority interrupts by rapidly storing and restoring processor status. It also provides almost unlimited subroutine nesting.

This microprocessor has been designed to simplify systems design. Separate 16-line address and 8-line bi-directional data busses are used to facilitate easy interface to memory and I/O. Signals to control the interface to memory and I/O are provided directly by the M8080A. Ultimate control of the address and data busses resides with the HOLD signal. It provides the ability to suspend processor operation and force the address and data busses into a high impedance state. This permits OR-tying these busses with other controlling devices for (DMA) direct memory access or multi-processor operation.



Absolute Maximum Ratings*

Temperature Under Bias . . . . -25°C to +85°C
Storage Temperature . . . . -65°C to +125°C
All Input or Output Voltages with Respect to V_{BB}
(except Program) . . . . +15V to -0.3V
Program Input to V_{BB} . . . . +35V to -0.3V
Supply Voltages V_{CC} and V_{SS} with Respect to V_{BB} . . . . +15V to -0.3V
V_{DD} with Respect to V_{BB} . . . . +20V to -0.3V
Power Dissipation 1.5W

*COMMENT

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

READ OPERATION

D.C. and Operating Characteristics

T_A = 0°C to 70°C, V_{CC} = +5V ±5%, V_{DD} = +12V ±5%, V_{BB} = -5V ±5%, V_{SS} = 0V, Unless Otherwise Noted.

Symbol	Parameter	Min.	Typ.[1]	Max.	Unit	Conditions
I_{LI}	Address and Chip Select Input Load Current			10	μA	V_{IN} = 5.25V
I_{LO}	Output Leakage Current			10	μA	V_{OUT} = 5.25V, $\overline{CS}$/WE = 5V
I_{DD}	V_{DD} Supply Current		50	65	mA	Worst Case Supply Currents:
I_{CC}	V_{CC} Supply Current		6	10	mA	All Inputs High
I_{BB}	V_{BB} Supply Current		30	45	mA	$\overline{CS}$/WE = 5V; T_A = 0°C
V_{IL}	Input Low Voltage	V_{SS}		0.65	V	
V_{IH}	Input High Voltage	3.0		V_{CC}+1	V	
V_{OL}	Output Low Voltage			0.45	V	I_{OL} = 1.6mA
V_{OH1}	Output High Voltage	3.7			V	I_{OH} = -100μA
V_{OH2}	Output High Voltage	2.4			V	I_{OH} = -1mA
P_D	Power Dissipation			800	mW	T_A = 70°C

NOTES: 1. Typical values are for T_A = 25°C and nominal supply voltages.
2. The program input (Pin 18) may be tied to V_{SS} or V_{CC} during the read mode.

INSTRUCTION SET

Summary of Processor Instructions

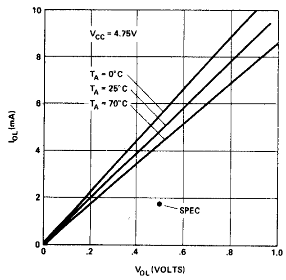
Mnemonic	Description	D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0	Clock[2] Cycles
		Instruction Code[1]								
$MOV_{r1, r2}$	Move register to register	0	1	D	D	D	S	S	S	5
MOV M, r	Move register to memory	0	1	1	1	0	S	S	S	7
MOV r, M	Move memory to register	0	1	D	D	D	1	1	0	7
HLT	Halt	0	1	1	1	0	1	1	0	7
MVI r	Move immediate register	0	0	D	D	D	1	1	0	7
MVI M	Move immediate memory	0	0	1	1	0	1	1	0	10
INR r	Increment register	0	0	D	D	D	1	0	0	5
DCR r	Decrement register	0	0	D	D	D	1	0	1	5
INR M	Increment memory	0	0	1	1	0	1	0	0	10
DCR M	Decrement memory	0	0	1	1	0	1	0	1	10
ADD r	Add register to A	1	0	0	0	0	S	S	S	4
ADC r	Add register to A with carry	1	0	0	0	1	S	S	S	4
SUB r	Subtract register from A	1	0	0	1	0	S	S	S	4
SBB r	Subtract register from A with borrow	1	0	0	1	1	S	S	S	4
ANA r	And register with A	1	0	1	0	0	S	S	S	4
XRA r	Exclusive Or register with A	1	0	1	0	1	S	S	S	4
ORA r	Or register with A	1	0	1	1	0	S	S	S	4
CMP r	Compare register with A	1	0	1	1	1	S	S	S	4
ADD M	Add memory to A	1	0	0	0	0	1	1	0	7
ADC M	Add memory to A with carry	1	0	0	0	1	1	1	0	7
SUB M	Subtract memory from A	1	0	0	1	0	1	1	0	7
SBB M	Subtract memory from A with borrow	1	0	0	1	1	1	1	0	7
ANA M	And memory with A	1	0	1	0	0	1	1	0	7
XRA M	Exclusive Or memory with A	1	0	1	0	1	1	1	0	7
ORA M	Or memory with A	1	0	1	1	0	1	1	0	7
CMP M	Compare memory with A	1	0	1	1	1	1	1	0	7
ADI	Add immediate to A	1	1	0	0	0	1	1	0	7
ACI	Add immediate to A with carry	1	1	0	0	1	1	1	0	7
SUI	Subtract immediate from A	1	1	0	1	0	1	1	0	7
SBI	Subtract immediate from A with borrow	1	1	0	1	1	1	1	0	7
ANI	And immediate with A	1	1	1	0	0	1	1	0	7
XRI	Exclusive Or immediate with A	1	1	1	0	1	1	1	0	7
ORI	Or immediate with A	1	1	1	1	0	1	1	0	7
CPI	Compare immediate with A	1	1	1	1	1	1	1	0	7
RLC	Rotate A left	0	0	0	0	0	1	1	1	4
RRC	Rotate A right	0	0	0	0	1	1	1	1	4
RAL	Rotate A left through carry	0	0	0	1	0	1	1	1	4
RAR	Rotate A right through carry	0	0	0	1	1	1	1	1	4
JMP	Jump unconditional	1	1	0	0	0	0	1	1	10
JC	Jump on carry	1	1	0	1	1	0	1	0	10
JNC	Jump on no carry	1	1	0	1	0	0	1	0	10
JZ	Jump on zero	1	1	0	0	1	0	1	0	10
JNZ	Jump on no zero	1	1	0	0	0	0	1	0	10
JP	Jump on positive	1	1	1	1	0	0	1	0	10
JM	Jump on minus	1	1	1	1	1	0	1	0	10
JPE	Jump on parity even	1	1	1	0	1	0	1	0	10
JPO	Jump on parity odd	1	1	1	0	0	0	1	0	10
CALL	Call unconditional	1	1	0	0	1	1	0	1	17
CC	Call on carry	1	1	0	1	1	1	0	0	11/17
CNC	Call on no carry	1	1	0	1	0	1	0	0	11/17
CZ	Call on zero	1	1	0	0	1	1	0	0	11/17
CNZ	Call on no zero	1	1	0	0	0	1	0	0	11/17
CP	Call on positive	1	1	1	1	0	1	0	0	11/17
CM	Call on minus	1	1	1	1	1	1	0	0	11/17
CPE	Call on parity even	1	1	1	0	1	1	0	0	11/17
CPO	Call on parity odd	1	1	1	0	0	1	0	0	11/17
RET	Return	1	1	0	0	1	0	0	1	10
RC	Return on carry	1	1	0	1	1	0	0	0	5/11
RNC	Return on no carry	1	1	0	1	0	0	0	0	5/11

Mnemonic	Description	D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0	Clock[2] Cycles
		Instruction Code[1]								
RZ	Return on zero	1	1	0	0	1	0	0	0	5/11
RNZ	Return on no zero	1	1	0	0	0	0	0	0	5/11
RP	Return on positive	1	1	1	1	0	0	0	0	5/11
RM	Return on minus	1	1	1	1	1	0	0	0	5/11
RPE	Return on parity even	1	1	1	0	1	0	0	0	5/11
RPO	Return on parity odd	1	1	1	0	0	0	0	0	5/11
RST	Restart	1	1	A	A	A	1	1	1	11
IN	Input	1	1	0	1	1	0	1	1	10
OUT	Output	1	1	0	1	0	0	1	1	10
LXI B	Load immediate register Pair B & C	0	0	0	0	0	0	0	1	10
LXI D	Load immediate register Pair D & E	0	0	0	1	0	0	0	1	10
LXI H	Load immediate register Pair H & L	0	0	1	0	0	0	0	1	10
LXI SP	Load immediate stack pointer	0	0	1	1	0	0	0	1	10
PUSH B	Push register Pair B & C on stack	1	1	0	0	0	1	0	1	11
PUSH D	Push register Pair D & E on stack	1	1	0	1	0	1	0	1	11
PUSH H	Push register Pair H & L on stack	1	1	1	0	0	1	0	1	11
PUSH PSW	Push A and Flags on stack	1	1	1	1	0	1	0	1	11
POP B	Pop register pair B & C off stack	1	1	0	0	0	0	0	1	10
POP D	Pop register pair D & E off stack	1	1	0	1	0	0	0	1	10
POP H	Pop register pair H & L off stack	1	1	1	0	0	0	0	1	10
POP PSW	Pop A and Flags off stack	1	1	1	1	0	0	0	1	10
STA	Store A direct	0	0	1	1	0	0	1	0	13
LDA	Load A direct	0	0	1	1	1	0	1	0	13
XCHG	Exchange D & E, H & L Registers	1	1	1	0	1	0	1	1	4
XTHL	Exchange top of stack, H & L	1	1	1	0	0	0	1	1	18
SPHL	H & L to stack pointer	1	1	1	1	1	0	0	1	5
PCHL	H & L to program counter	1	1	1	0	1	0	0	1	5
DAD B	Add B & C to H & L	0	0	0	0	1	0	0	1	10
DAD D	Add D & E to H & L	0	0	0	1	1	0	0	1	10
DAD H	Add H & L to H & L	0	0	1	0	1	0	0	1	10
DAD SP	Add stack pointer to H & L	0	0	1	1	1	0	0	1	10
STAX B	Store A indirect	0	0	0	0	0	0	1	0	7
STAX D	Store A indirect	0	0	0	1	0	0	1	0	7
LDAX B	Load A indirect	0	0	0	0	1	0	1	0	7
LDAX D	Load A indirect	0	0	0	1	1	0	1	0	7
INX B	Increment B & C registers	0	0	0	0	0	0	1	1	5
INX D	Increment D & E registers	0	0	0	1	0	0	1	1	5
INX H	Increment H & L registers	0	0	1	0	0	0	1	1	5
INX SP	Increment stack pointer	0	0	1	1	0	0	1	1	5
DCX B	Decrement B & C	0	0	0	0	1	0	1	1	5
DCX D	Decrement D & E	0	0	0	1	1	0	1	1	5
DCX H	Decrement H & L	0	0	1	0	1	0	1	1	5
DCX SP	Decrement stack pointer	0	0	1	1	1	0	1	1	5
CMA	Complement A	0	0	1	0	1	1	1	1	4
STC	Set carry	0	0	1	1	0	1	1	1	4
CMC	Complement carry	0	0	1	1	1	1	1	1	4
DAA	Decimal adjust A	0	0	1	0	0	1	1	1	4
SHLD	Store H & L direct	0	0	1	0	0	0	1	0	16
LHLD	Load H & L direct	0	0	1	0	1	0	1	0	16
EI	Enable Interrupts	1	1	1	1	1	0	1	1	4
DI	Disable interrupt	1	1	1	1	0	0	1	1	4
NOP	No-operation	0	0	0	0	0	0	0	0	4

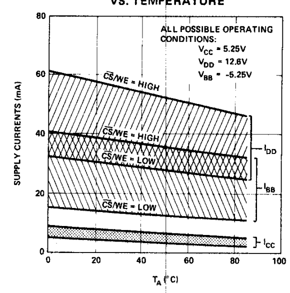
NOTES: 1. DDD or SSS – 000 B – 001 C – 010 D – 011 E – 100 H – 101 L – 110 Memory – 111 A.
2. Two possible cycle times, (5/11) indicate instruction cycles dependent on condition flags.

Typical Characteristics (Nominal supply voltages unless otherwise noted):

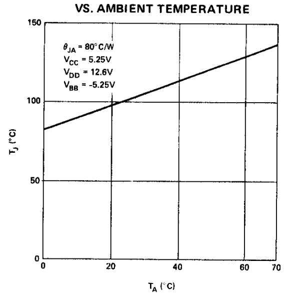
OUTPUT SINK CURRENT
VS. OUTPUT VOLTAGE



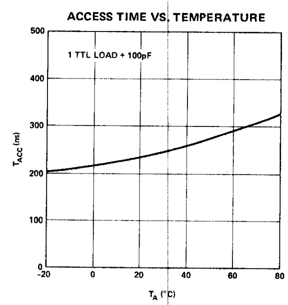
RANGE OF SUPPLY CURRENTS
VS. TEMPERATURE



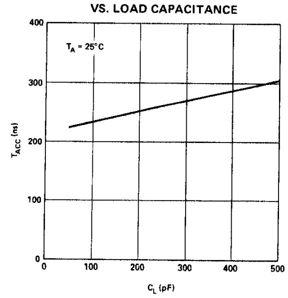
MAXIMUM JUNCTION TEMPERATURE
VS. AMBIENT TEMPERATURE



ACCESS TIME VS. TEMPERATURE



ACCESS TIME
VS. LOAD CAPACITANCE



SILICON GATE MOS M8080A

ABSOLUTE MAXIMUM RATINGS*

Temperature Under Bias . . . . -55°C to +125°C
Storage Temperature . . . . -65°C to +150°C
All Input or Output Voltages
With Respect to V_{BB} . . . . -0.3V to +20V
V_{CC}, V_{DD} and V_{SS} With Respect to V_{BB} -0.3V to +20V
Power Dissipation 1.7W

COMMENT: *Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.*

D.C. CHARACTERISTICS

T_A = -55°C to +125°C, V_{DD} = +12V ±10%, V_{CC} = +5V ±10%, V_{BB} = -5V ±10%, V_{SS} = 0V, Unless Otherwise Noted.

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Condition
V_{ILC}	Clock Input Low Voltage	$V_{SS}-1$		$V_{SS}+0.8$	V	
V_{IHC}	Clock Input High Voltage	8.5		$V_{DD}+1$	V	
V_{IL}	Input Low Voltage	$V_{SS}-1$		$V_{SS}+0.8$	V	
V_{IH}	Input High Voltage	3.0		$V_{CC}+1$	V	
V_{OL}	Output Low Voltage			0.45	V	I_{OL} = 1.9mA on all outputs,
V_{OH}	Output High Voltage	3.7			V	I_{OH} = 150μA.
$I_{DD\,(AV)}$	Avg. Power Supply Current (V_{DD})		50	80	mA	Operation
$I_{CC\,(AV)}$	Avg. Power Supply Current (V_{CC})		60	100	mA	T_{CY} = .48 μsec
$I_{BB\,(AV)}$	Avg. Power Supply Current (V_{BB})		.01	1	mA	
I_{IL}	Input Leakage			±10	μA	$V_{SS} \leq V_{IN} \leq V_{CC}$
I_{CL}	Clock Leakage			±10	μA	$V_{SS} \leq V_{CLOCK} \leq V_{DD}$
I_{DL} [2]	Data Bus Leakage in Input Mode			-100 -2.0	μA mA	$V_{SS} \leq V_{IN} \leq V_{SS}+0.8V$ $V_{SS}+0.8V \leq V_{IN} \leq V_{CC}$
I_{FL}	Address and Data Bus Leakage During HOLD			+10 -100	μA	$V_{ADDR/DATA} = V_{CC}$ $V_{ADDR/DATA} = V_{SS} + 0.45V$

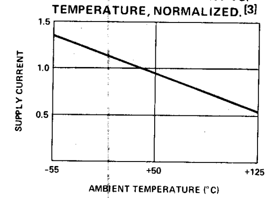
CAPACITANCE

T_A = 25°C $V_{CC} = V_{DD} = V_{SS}$ = 0V, V_{BB} = -5V

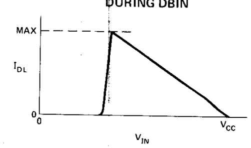
Symbol	Parameter	Typ.	Max.	Unit	Test Condition
C_ϕ	Clock Capacitance	17	25	pf	f_c = 1 MHz
C_{IN}	Input Capacitance	6	10	pf	Unmeasured Pins
C_{OUT}	Output Capacitance	10	20	pf	Returned to V_{SS}

NOTES:
1. The RESET signal must be active for a minimum of 3 clock cycles.
2. When DBIN is high and $V_{IN} > V_{IH}$ an internal active pull up will be switched onto the Data Bus.
3. ΔI supply / ΔT_A = -0.45%/°C.

TYPICAL SUPPLY CURRENT VS. TEMPERATURE, NORMALIZED.[3]



DATA BUS CHARACTERISTIC DURING DBIN



Absolute Maximum Ratings*

Ambient Temperature Under Bias .... 0°C to +70°C
Storage Temperature .... −65°C to +125°C
Soldering Temperature of Leads (10 sec) .... +300°C
Power Dissipation .... 2 Watts
Input Voltages and Supply
Voltages with respect to V_{CC} ....+0.5V to −20V

*COMMENT

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or at any other condition above those indicated in the operational sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

READ OPERATION

D.C. and Operating Characteristics

T_A = 0°C to 70°C, V_{CC} = +5V±5%, V_{DD} = −9V±5%, $V_{GG}^{(1)}$ = −9V±5%, unless otherwise noted.

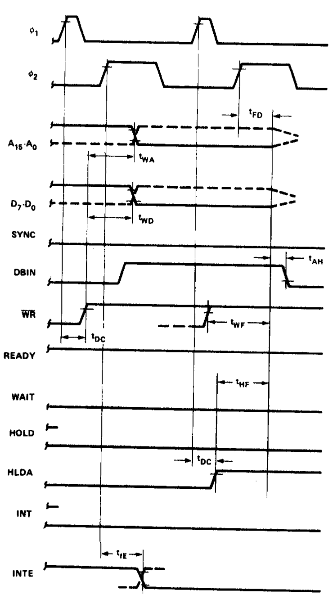
SYMBOL	TEST	MIN.	TYP.(2)	MAX.	UNIT	CONDITIONS	
I_{LI}	Address and Chip Select Input Load Current			1	μA	V_{IN} = 0.0V	
I_{LO}	Output Leakage Current			1	μA	V_{OUT} = 0.0V, $\overline{CS}$ = V_{CC} −2	
I_{DDO}	Power Supply Current		5	10	mA	V_{GG}=V_{CC}, $\overline{CS}$=V_{CC}−2 I_{OL} = 0.0mA, T_A = 25°C	
I_{DD1}	Power Supply Current		35	50	mA	$\overline{CS}$=V_{CC} −2 I_{OL} =0.0mA, T_A = 25°C	Continuous Operation
I_{DD2}	Power Supply Current		32	46	mA	$\overline{CS}$=0.0 I_{OL} =0.0mA, T_A = 25°C	Continuous Operation
I_{DD3}	Power Supply Current		38.5	60	mA	$\overline{CS}$=V_{CC} −2 I_{OL} =0.0mA, T_A = 0°C	Continuous Operation
I_{CF1}	Output Clamp Current		8	14	mA	V_{OUT} = −1.0V, T_A = 0°C	Continuous Operation
I_{CF2}	Output Clamp Current			13	mA	V_{OUT} = −1.0V, T_A = 25°C	Continuous Operation
I_{GG}	Gate Supply Current			1	μA		
V_{IL1}	Input Low Voltage for TTL Interface	−1.0		0.65	V		
V_{IL2}	Input Low Voltage for MOS Interface	V_{DD}		V_{CC} −6	V		
V_{IH}	Address and Chip Select Input High Voltage	V_{CC}−2		V_{CC}+0.3	V		
I_{OL}	Output Sink Current	1.6	4		mA	V_{OUT} = 0.45V	
I_{OH}	Output Source Current	−2.0			mA	V_{OUT} = 0.0V	
V_{OL}	Output Low Voltage		−.7	0.45	V	I_{OL} = 1.6mA	
V_{OH}	Output High Voltage	3.5	4.5		V	I_{OH} = −100 μA	

Note 1. V_{GG} may be clocked to reduce power dissipation. In this mode average I_{DD} increases in proportion to V_{GG} duty cycle.
Note 2. Typical values are at nominal voltages and T_A = 25°C.

A.C. CHARACTERISTICS (Continued)

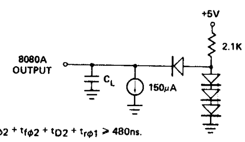
T_A = -55°C to +125°C, V_{DD} = +12V ±10%, V_{CC} = +5V ±10%, V_{BB} = -5V ±10%, V_{SS} = 0V, Unless Otherwise Noted.

Symbol	Parameter	Min.	Max.	Unit	Test Condition
t_{DS2}	Data Setup Time to ϕ_2 During DBIN	130		nsec	
t_{DH} [1]	Data Hold Time From ϕ_2 During DBIN	50		nsec	
t_{IE} [2]	INTE Output Delay From ϕ_2		200	nsec	C_L = 50pf
t_{RS}	READY Setup Time During ϕ_2	120		nsec	
t_{HS}	HOLD Setup Time to ϕ_2	140		nsec	
t_{IS}	INT Setup Time During ϕ_2 (During ϕ_1 in Halt Mode)	120		nsec	
t_H	Hold Time From ϕ_2 (READY, INT, HOLD)	0		nsec	
t_{FD}	Delay to Float During Hold (Address and Data Bus)		130	nsec	
t_{AW} [2]	Address Stable Prior to $\overline{WR}$	[5]		nsec	
t_{DW} [2]	Output Data Stable Prior to $\overline{WR}$	[6]		nsec	
t_{WD} [2]	Output Data Stable From $\overline{WR}$	[7]		nsec	
t_{WA} [2]	Address Stable From $\overline{WR}$	[7]		nsec	C_L =50pf
t_{HF} [2]	HLDA to Float Delay	[8]		nsec	
t_{WF} [2]	$\overline{WR}$ to Float Delay	[9]		nsec	
t_{AH} [2]	Address Hold Time After DBIN During HLDA	-20		nsec	



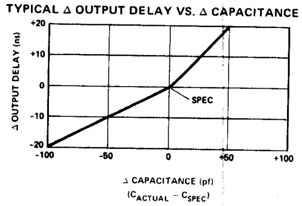
NOTES:

1. Data input should be enabled with DBIN status. No bus conflict can then occur and data hold time is assured. t_{DH} = 50 ns or t_{DF}, whichever is less.
2. Load Circuit.



3. $t_{CY} = t_{D3} + t_{r\phi2} + t_{\phi2} + t_{f\phi2} + t_{D2} + t_{r\phi1} \geq 480ns$.

TYPICAL Δ OUTPUT DELAY VS. Δ CAPACITANCE



4. The following are relevant when interfacing the M8080A to devices having V_{IH} = 3.3V:
   a) Maximum output rise time from .8V to 3.3V = 100ns @ C_L = SPEC.
   b) Output delay when measured to 3.0V = SPEC +60ns @ C_L = SPEC.
   c) If $C_L \neq$ SPEC, add .6ns/pF if $C_L > C_{SPEC}$, subtract .3ns/pF (from modified delay) if $C_L < C_{SPEC}$.
5. $t_{AW} = 2\ t_{CY} - t_{D3} - t_{r\phi2}$ -140nsec.
6. $t_{DW} = t_{CY} - t_{D3} - t_{r\phi2}$ -170nsec.
7. If not HLDA, $t_{WD} = t_{WA} = t_{D3} + t_{r\phi2}$ +10ns. If HLDA, $t_{WD} = t_{WA} = t_{WF}$.
8. $t_{HF} = t_{D3} + t_{r\phi2}$ -50ns.
9. $t_{WF} = t_{D3} + t_{r\phi2}$ -10ns
10. Data in must be stable for this period during DBIN $\cdot T_3$. Both t_{DS1} and t_{DS2} must be satisfied.
11. Ready signal must be stable for this period during T_2 or T_W. (Must be externally synchronized.)
12. Hold signal must be stable for this period during T_2 or T_W when entering hold mode, and during T_3, T_4, T_5 and T_{WH} when in hold mode. (External synchronization is not required.)
13. Interrupt signal must be stable during this period of the last clock cycle of any instruction in order to be recognized on the following instruction. (External synchronization is not required.)
14. This timing diagram shows timing relationships only; it does not represent any specific machine cycle.

Absolute Maximum Ratings*

Ambient Temperature Under Bias . . . . . . -25°C to +85°C
Storage Temperature . . . . -65°C to +150°C
Voltage On Any Pin With Respect
To V_{BB} . . . . -0.3V to 20V
Power Dissipation . . . . 1.0 Watt

*COMMENT

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

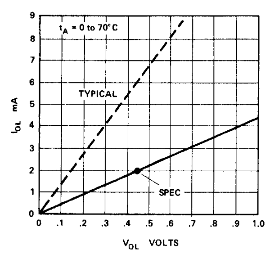
D.C. and Operating Characteristics

T_A = 0°C to +70°C, V_{CC} = 5V ±5%; V_{DD} = 12V ±5%, V_{BB} = -5V ±5%, V_{SS} = 0V Unless Otherwise Specified.

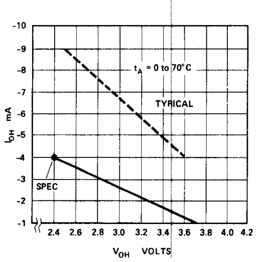
Symbol	Parameter	Limits Min.	Typ.[1]	Max.	Unit	Test Conditions
I_{LI}	Input Load Current (All Input Pins Except $\overline{CS}_1$)			10	µA	V_{IN} = 0 to 5.25V
I_{LCL}	Input Load Current on $\overline{CS}_1$			1.6	mA	V_{IN} = 0.45V
I_{LPC}	Input Peak Load Current on $\overline{CS}_1$			4	mA	V_{IN} = 0.8V to 3.3V
I_{LKC}	Input Leakage Current on $\overline{CS}_1$			10	µA	V_{IN} = 3.3V to 5.25V
I_{LO}	Output Leakage Current			10	µA	Chip Deselected
V_{IL}	Input "Low" Voltage	V_{SS}-1		0.8V	V	
V_{IH}	Input "High" Voltage	3.3		V_{CC}+1.0	V	
V_{OL}	Output "Low" Voltage			0.45	V	I_{OL} = 2mA
V_{OH1}	Output "High" Voltage	2.4			V	I_{OH} = -4mA
V_{OH2}	Output "High" Voltage	3.7			V	I_{OH} = -1mA
I_{CC}	Power Supply Current V_{CC}		.8	2	mA	
I_{DD}	Power Supply Current V_{DD}		32	60	mA	
I_{BB}	Power Supply Current V_{BB}		10µA	1	mA	
P_D	Power Dissipation			775	mW	

NOTE 1: Typical values for T_A = 25°C and nominal supply voltage

D.C. OUTPUT CHARACTERISTICS



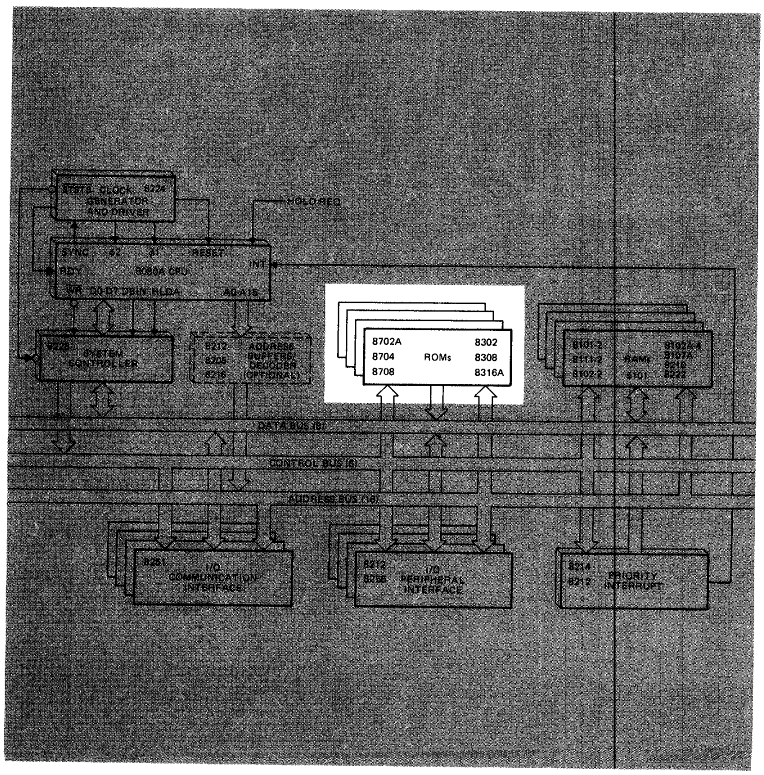
D.C. OUTPUT CHARACTERISTICS



intel® Microcomputer Systems

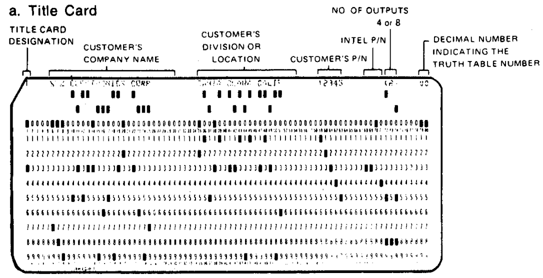
ROMs

8702A	8302
8704	8308
8708	8316A



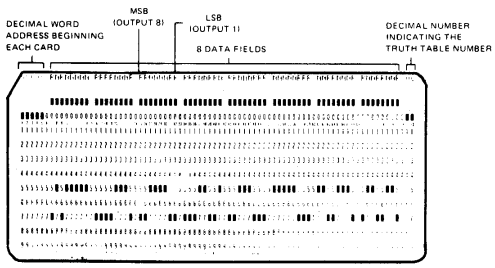
MCS™ CUSTOM ROM ORDER FORM 8308

a. Title Card



Column	Data
1	Punch a T
2–5	Blank
6–30	Customer Company Name
31–34	Blank
35–54	Customer's Company Division or location
55–57	Blank
58–66	Customer Part Number
67	Blank
68–75	Punch the Intel 4-digit basic part number and in ( ) the number of output bits, e.g., 8308(8).
76–78	Blank
79–80	Punch a 2-digit decimal number to identify the truth table number (mask programmed chip select number).

b. For a 1024 word X 8-bit organization only, cards 2 and the following cards should be punched as shown.



Column	Data
1–5	Punch the 5-digit decimal equivalent of the binary coded location which begins each card. The address is right justified, i.e., 00000, 00008, 00016, etc.
6	Blank
7–14	Data Field
15	Blank
16–23	Data Field
33	Blank
34–41	Data Field
42	Blank
43–50	Data Field
51	Blank
52–59	Data Field
60	Blank
61–68	Data Field
69	Blank
70–77	Data Field
78	Blank
79–80	Punch same 2-digit decimal number as in title card.

2. Paper Tape Format

1" wide paper tape using 7- or 8-bit ASCII code, such as a model 33 ASR teletype produces, or the 11/16" wide paper tape using a 5-bit Baudot code, such as a Telex produces.

The format requirements are as follows:

a. All word fields are to be punched in consecutive order, starting with word field 0 (all addresses low). There must be exactly 1024 word fields for the 1024 X 8 ROM organization.

b. Each word field must begin with the start character B and end with the stop character F. There must be exactly 8 data characters between the B and F.

NO OTHER CHARACTERS, SUCH AS RUBOUTS, ARE ALLOWED ANYWHERE IN A WORD FIELD. If in preparing a tape an error is made, the entire word field, including the B and F, must be rubbed out. Within the word field, a P results in a high level output and an N results in a low level output.

c. Preceding the first word field and following the last word field, there must be a leader/trailer length of *at least 25 characters. This should consist of rubout or null punches (letter key for Telex tapes).*

d. Between word fields, comments not containing B's or F's may be inserted. Carriage return and line feed characters should be inserted as a "comment")

just before each word field (or at least between every four word fields). When these carriage returns, etc., are inserted, the tape may be easily listed on the teletype for purposes of error checking. The customer may also find it helpful to insert the word number (as a comment) at least every four word fields.

e. Included in the tape before the leader should be the customer's complete Telex or TWX number and, if more than one pattern is being transmitted, the ROM pattern number.

f. MSB and LSB are the most and least significant bit of the device outputs. Refer to the data sheet for the pin numbers.

Leader: Rubout Key for TWX and Letter Key for Telex (at least 25 frames).

Start Character → B; Stop Character → F; Data Field; MSB; LSB

B P P P N N N N F B N N N N N N P P F ... B N P N P P P N N F

Word Field 0 — Word Field 1 — Word Field 1023

Trailer: Rubout Key for TWX and Letter Key for Telex (at least 25 frames)

Silicon Gate MOS 8702A

2048 BIT ERASABLE AND ELECTRICALLY REPROGRAMMABLE READ ONLY MEMORY

- **Access Time — 1.3 μsec Max.**
- **Fast Programming — 2 Minutes for All 2048 Bits**
- **Fully Decoded, 256 x 8 Organization**
- **Static MOS — No Clocks Required**
- **Inputs and Outputs TTL Compatible**
- **Three-State Output — OR-Tie Capability**
- **Simple Memory Expansion Chip Select Input Lead**

The 8702A is a 256 word by 8 bit electrically programmable ROM ideally suited for microcomputer system development where fast turn-around and pattern experimentation are important. The 8702A undergoes complete programming and functional testing on each bit position prior to shipment, thus insuring 100% programmability.

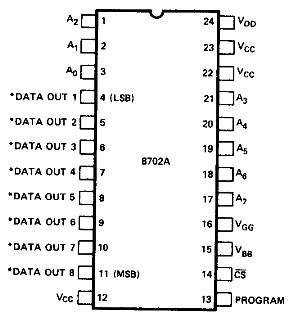
The 8702A is packaged in a 24 pin dual-in line package with a transparent quartz lid. The transparent quartz lid allows the user to expose the chip to ultraviolet light to erase the bit pattern. A new pattern can then be written into the device. This procedure can be repeated as many times as required.

The circuitry of the 8702A is entirely static; no clocks are required.

A pin-for-pin metal mask programmed ROM, the Intel 8302, is ideal for large volume production runs of systems initially using the 8702A.

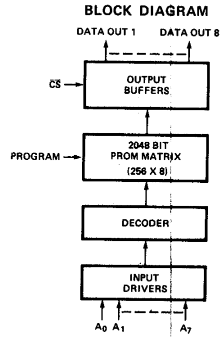
The 8702A is fabricated with silicon gate technology. This low threshold technology allows the design and production of higher performance MOS circuits and provides a higher functional density on a monolithic chip than conventional MOS technologies.

PIN CONFIGURATION



*THIS PIN IS THE DATA INPUT LEAD DURING PROGRAMMING.

BLOCK DIAGRAM



PIN NAMES

A_0-A_7	ADDRESS INPUTS
$\overline{CS}$	CHIP SELECT INPUT
DO_1- DO_2	DATA OUTPUTS

SILICON GATE MOS ROM 8316A

ABSOLUTE MAXIMUM RATINGS*

Ambient Temperature Under Bias . . . . 0°C to 70°C
Storage Temperature . . . . -65°C to +150°C
Voltage On Any Pin With Respect
To Ground . . . . -0.5V to +7V
Power Dissipation . . . . 1.0 Watt

*COMMENT: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

D.C. AND OPERATING CHARACTERISTICS

T_A = 0°C to +70°C, V_{CC} = 5V ±5% unless otherwise specified

SYMBOL	PARAMETER	LIMITS			UNIT	TEST CONDITIONS
		MIN.	TYP.(1)	MAX.		
I_{LI}	Input Load Current (All Input Pins)			10	μA	V_{IN} = 0 to 5.25V
I_{LOH}	Output Leakage Current			10	μA	CS = 2.2V, V_{OUT} = 4.0V
I_{LOL}	Output Leakage Current			-20	μA	CS = 2.2V, V_{OUT} = 0.45V
I_{CC}	Power Supply Current		40	98	mA	All inputs 5.25V Data Out Open
V_{IL}	Input "Low" Voltage	-0.5		0.8	V	
V_{IH}	Input "High" Voltage	2.0		V_{CC}+1.0V	V	
V_{OL}	Output "Low" Voltage			0.45	V	I_{OL} = 2.0 mA
V_{OH}	Output "High" Voltage	2.2			V	I_{OH} = -100 μA

(1) Typical values for T_A = 25°C and nominal supply voltage.

A.C. CHARACTERISTICS

T_A = 0°C to +70°C, V_{CC} = +5V ±5% unless otherwise specified

SYMBOL	PARAMETER	LIMITS			UNIT
		MIN.	TYP.(1)	MAX.	
t_A	Address to Output Delay Time		400	850	nS
t_{CO}	Chip Select to Output Enable Delay Time			300	nS
t_{DF}	Chip Deselect to Output Data Float Delay Time	0		300	nS

CONDITIONS OF TEST FOR A.C. CHARACTERISTICS

Output Load . . . 1 TTL Gate, and C_{LOAD} = 100 pF
Input Pulse Levels . . . . 0.8 to 2.0V
Input Pulse Rise and Fall Times . (10% to 90%) 20 nS
Timing Measurement Reference Level
Input 1.5V
Output . . . . 0.45V to 2.2V

CAPACITANCE(2) T_A = 25°C, f = 1 MHz

SYMBOL	TEST	LIMITS	
		TYP.	MAX.
C_{IN}	All Pins Except Pin Under Test Tied to AC Ground	4 pF	10 pF
C_{OUT}	All Pins Except Pin Under Test Tied to AC Ground	8 pF	15 pF

(2) This parameter is periodically sampled and is not 100% tested.

A.C. CHARACTERISTICS

$T_A = 0°C$ to $+70°C$, $V_{CC} = +5V \pm 5\%$, $V_{DD} = -9V \pm 5\%$, $V_{GG} = -9V \pm 5\%$ unless otherwise noted

SYMBOL	TEST	MINIMUM	TYPICAL	MAXIMUM	UNIT
Freq.	Repetition Rate			1	MHz
t_{OH}	Previous read data valid			100	ns
t_{ACC}	Address to output delay			1.3	μs
t_{DVGG}	Clocked V_{GG} set up	1.0			μs
t_{CS}	Chip select delay			400	ns
t_{CO}	Output delay from $\overline{CS}$			900	ns
t_{OD}	Output deselect			400	ns
t_{OHC}	Data out hold in clocked V_{GG} mode (Note 1)			5	μs

Note 1. The output will remain valid for t_{OHC} as long as clocked V_{GG} is at V_{CC}. An address change may occur as soon as the output is sensed (clocked V_{GG} may still be at V_{CC}). Data becomes invalid for the old address when clocked V_{GG} is returned to V_{GG}.

CAPACITANCE* $T_A = 25°C$

SYMBOL	TEST	MINIMUM	TYPICAL	MAXIMUM	UNIT	CONDITIONS
C_{IN}	Input Capacitance		8	15	pF	$V_{IN} = V_{CC}$, $\overline{CS} = V_{CC}$, $V_{OUT} = V_{CC}$, $V_{GG} = V_{CC}$; All unused pins are at A.C. ground
C_{OUT}	Output Capacitance		10	15	pF	
C_{VGG}	V_{GG} Capacitance (Clocked V_{GG} Mode)			30	pF	

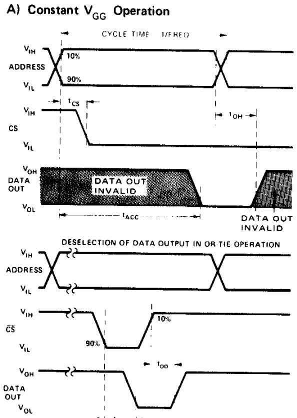
*This parameter is periodically sampled and is not 100% tested.

SWITCHING CHARACTERISTICS

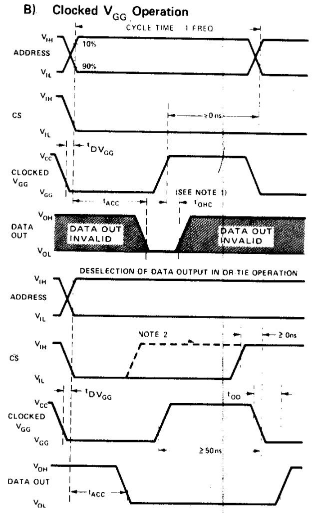
Conditions of Test:

Input pulse amplitudes: 0 to 4V; t_R, $t_F \leq 50$ ns
Output load is 1 TTL gate; measurements made at output of TTL gate ($t_{PD} \leq 15$ ns)

A) Constant V_{GG} Operation



B) Clocked V_{GG} Operation

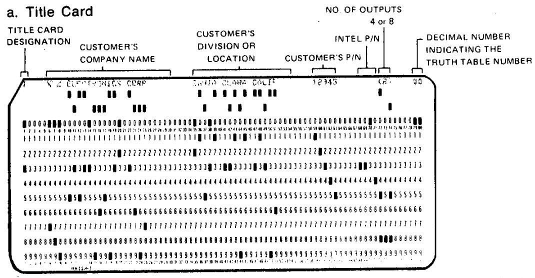


NOTE 1: The output will remain valid for t_{OHC} as long as clocked V_{GG} is at V_{CC}. An address change may occur as soon as the output is sensed (clocked V_{GG} may still be at V_{CC}). Data becomes invalid for the old address when clocked V_{GG} is returned to V_{GG}.

NOTE 2: If $\overline{CS}$ makes a transition from V_{IL} to V_{IH} while clocked V_{GG} is at V_{GG}, then deselection of output occurs at t_{OD} as shown in static operation with constant V_{GG}.

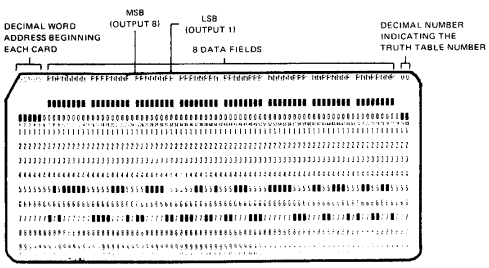
MCS™ CUSTOM ROM ORDER FORM

a. Title Card



Column	Data
1	Punch a T
2–5	Blank
6–30	Customer Company Name
31–34	Blank
35–54	Customer's Company Division or location
55–57	Blank
58–66	Customer Part Number
67	Blank
68–75	Punch the Intel 4-digit basic part number and in ( ) the number of output bits, e.g., 8316A(8).
76–78	Blank
79–80	Punch a 2-digit decimal number to identify the truth table number (mask programmed chip select number).

b. For a 2048 word X 8-bit organization only, cards 2 and the following cards should be punched as shown.



Column	Data
1–5	Punch the 5-digit decimal equivalent of the binary coded location which begins each card. The address is right justified, i.e., 00000, 00008, 00016, etc.
6	Blank
7–14	Data Field
15	Blank
16–23	Data Field
33	Blank
34–41	Data Field
42	Blank
43–50	Data Field
51	Blank
52–59	Data Field
60	Blank
61–68	Data Field
69	Blank
70–77	Data Field
78	Blank
79–80	Punch same 2-digit decimal number as in title card.

2. Paper Tape Format

1" wide paper tape using 7- or 8-bit ASCII code, such as a model 33 ASR teletype produces, or the 11/16" wide paper tape using a 5-bit Baudot code, such as a Telex produces.

The format requirements are as follows:

a. All word fields are to be punched in consecutive order, starting with word field 0 (all addresses low). There must be exactly 2048 word fields for the 2048 X 8 ROM organization.

b. Each word field must begin with the start character B and end with the stop character F. There must be exactly 8 data characters between the B and F.

NO OTHER CHARACTERS, SUCH AS RUBOUTS, ARE ALLOWED ANYWHERE IN A WORD FIELD. If in preparing a tape an error is made, the entire word field, including the B and F, must be rubbed out. Within the word field, a P results in a high level output and an N results in a low level output.

c. Preceding the first word field and following the last word field, there must be a leader/trailer length of *at least 25 characters. This should consist of rubout or null punches (letter key for Telex tapes).*

d. Between word fields, comments not containing B's or F's may be inserted. Carriage return and line feed characters should be inserted as a "comment") just before each word field (or at least between every four word fields). When these carriage returns, etc., are inserted, the tape may be easily listed on the teletype for purposes of error checking. The customer may also find it helpful to insert the word number (as a comment) at least every four word fields.

e. Included in the tape before the leader should be the customer's complete Telex or TWX number and, if more than one pattern is being transmitted, the ROM pattern number.

f. MSB and LSB are the most and least significant bit of the device outputs. Refer to the data sheet for the pin numbers.

Leader: Rubout Key for TWX and Letter Key for Telex (at least 25 frames).

Start Character — Stop Character — Data Field — MSB — LSB

BPPPNNNNNF (Word Field 0) BNNNNNNPPF (Word Field 1) ... BNPNPPPNNF (Word Field 2048)

Trailer: Rubout Key for TWX and Letter Key for Telex (at least 25 frames).

PROGRAMMING OPERATION

D.C. AND OPERATING CHARACTERISTICS FOR PROGRAMMING OPERATION

$T_A = 25°C$, $V_{CC} = 0V$, $V_{BB} = +12V \pm 10\%$, $\overline{CS} = 0V$ unless otherwise noted

SYMBOL	TEST	MIN.	TYP.	MAX.	UNIT	CONDITIONS
I_{LI1P}	Address and Data Input Load Current			10	mA	$V_{IN} = -48V$
I_{LI2P}	Program and V_{GG} Load Current			10	mA	$V_{IN} = -48V$
I_{BB}	V_{BB} Supply Load Current		.05		mA	
I_{DDP}[1]	Peak I_{DD} Supply Load Current		200		mA	$V_{DD} = V_{prog} = -48V$, $V_{GG} = -35V$
V_{IHP}	Input High Voltage			0.3	V	
V_{IL1P}	Pulsed Data Input Low Voltage	−46		−48	V	
V_{IL2P}	Address Input Low Voltage	−40		−48	V	
V_{IL3P}	Pulsed Input Low V_{DD} and Program Voltage	−46		−48	V	
V_{IL4P}	Pulsed Input Low V_{GG} Voltage	−35		−40	V	

Note 1: I_{DDP} flows only during V_{DD}, V_{GG} on time. I_{DDP} should not be allowed to exceed 300mA for greater than 100μsec. Average power supply current I_{DDP} is typically 40mA at 20% duty cycle.

A.C. CHARACTERISTICS FOR PROGRAMMING OPERATION

$T_{AMBIENT} = 25°C$, $V_{CC} = 0V$, $V_{BB} = +12V \pm 10\%$, $\overline{CS} = 0V$ unless otherwise noted

SYMBOL	TEST	MIN.	TYP.	MAX.	UNIT	CONDITIONS
	Duty Cycle (V_{DD}, V_{GG})			20	%	
$t_{\phi PW}$	Program Pulse Width			3	ms	$V_{GG} = -35V$, $V_{DD} = V_{prog} = -48V$
t_{DW}	Data Set Up Time	25			μs	
t_{DH}	Data Hold Time	10			μs	
t_{VW}	V_{DD}, V_{GG} Set Up	100			μs	
t_{VD}	V_{DD}, V_{GG} Hold	10		100	μs	
t_{ACW}[2]	Address Complement Set Up	25			μs	
t_{ACH}[2]	Address Complement Hold	25			μs	
t_{ATW}	Address True Set Up	10			μs	
t_{ATH}	Address True Hold	10			μs	

Note 2. All 8 address bits must be in the complement state when pulsed V_{DD} and V_{GG} move to their negative levels. The addresses (0 through 255) must be programmed as shown in the timing diagram for a minimum of 32 times.

PROGRAMMING INSTRUCTIONS FOR THE 8702A

I. Operation of the 8702A in Program Mode

Initially, all 2048 bits of the ROM are in the "0" state (output low). Information is introduced by selectively programming "1"s (output high) in the proper bit locations.

Word address selection is done by the same decoding circuitry used in the READ mode (see table on page 6 for logic levels). All 8 address bits must be in the binary complement state when pulsed V_{DD} and V_{GG} move to their negative levels. The addresses must be held in their binary complement state for a minimum of 25 μsec after V_{DD} and V_{GG} have moved to their negative levels. The addresses must then make the transition to their true state a minimum of 10 μsec before the program pulse is applied. The addresses should be programmed in the sequence 0 through 255 for a minimum of 32 times. The eight output terminals are used as data inputs to determine the information pattern in the eight bits of each word. A low data input level (−48V) will program a "1" and a high data input level (ground) will leave a "0" (see table on page 6). All eight bits of one word are programmed simultaneously by setting the desired bit information patterns on the data input terminals.

During the programming, V_{GG}, V_{DD} and the Program Pulse are pulsed signals.

II. Programming of the 8702A Using Intel® Microcomputers

Intel provides low cost program development systems which may be used to program its electrically programmable ROMs. Note that the programming specifications that apply to the 8702A are identical to those for Intel's 1702A.

A. Intellec®

The Intellec series of program development systems, the Intellec 8/Mod 8 and Intellec 8/Mod 80, are used as program development tools for the 8008 and 8080 microprocessors respectively. As such, they are equipped with a PROM programmer card and may be used to program Intel's electrically programmable and ultraviolet erasable ROMs.

An ASR-33 teletype terminal is used as the input device. Through use of the Intellec software system monitor, programs to be loaded into PROM may be typed in directly or loaded through the paper tape reader. The system monitor allows the program to be reviewed or altered at will prior to actually programming the PROM. For more complete information on these program development systems, refer to the Intel Microcomputer Catalog or the Intellec Specifications.

B. Users of the SIM8 microcomputer programming systems may also program the 8702A using the MP7-03 programmer card and the appropriate control ROMs:
SIM8 system—Control ROMs A0860, A0861 and A0863.

III. 8702A Erasing Procedure

The 8702A may be erased by exposure to high intensity short-wave ultraviolet light at a wavelength of 2537A. The recommended integrated dose (i.e., UV intensity x exposure time) is 6W-sec/cm². Examples of ultraviolet sources which can erase the 8702A in 10 to 20 minutes are the Model UVS-54 and Model S-52 short-wave ultraviolet lamps manufactured by Ultra-Violet Products, Inc. (5114 Walnut Grove Avenue, San Gabriel, California). The lamps should be used without short-wave filters, and the 8702A to be erased should be placed about one inch away from the lamp tubes.

Absolute Maximum Ratings*

Ambient Temperature Under Bias . . . . . . 0°C to 70°C

Storage Temperature . . . . -65°C to +150°C

Voltage On Any Pin
With Respect to Ground . . . . -0.5V to +7V

Power Dissipation . . . . 1 Watt

**COMMENT:*

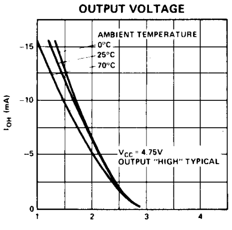
Stresses above those listed under "Absolute Maximum Rating" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or at any other condition above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

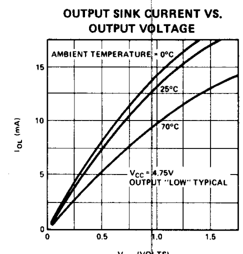
D.C. and Operating Characteristics

T_A = 0°C to 70°C, V_{CC} = 5V ±5% unless otherwise specified.

Symbol	Parameter	Min.	Typ.[1]	Max.	Unit	Test Conditions
I_{LI}	Input Current			10	μA	V_{IN} = 0 to 5.25V
I_{LOH}	I/O Leakage Current[2]			15	μA	$\overline{CE}$ = 2.2V, V_{OUT} = 4.0V
I_{LOL}	I/O Leakage Current[2]			-50	μA	$\overline{CE}$ = 2.2V, V_{OUT} = 0.45V
I_{CC1}	Power Supply Current		30	60	mA	V_{IN} = 5.25V, I_O = 0mA T_A = 25°C
I_{CC2}	Power Supply Current			70	mA	V_{IN} = 5.25V, I_O = 0mA T_A = 0°C
V_{IL}	Input "Low" Voltage	-0.5		+0.65	V	
V_{IH}	Input "High" Voltage	2.2		V_{CC}	V	
V_{OL}	Output "Low" Voltage			+0.45	V	I_{OL} = 2.0mA
V_{OH}	Output "High" Voltage	2.2			V	I_{OH} = -150 μA

NOTE: 1. Typical values are for T_A = 25°C and nominal supply voltage.
2. Input and Output tied together.





intel Silicon Gate MOS 8708/8704

8192/4096 BIT ERASABLE AND ELECTRICALLY REPROGRAMMABLE READ ONLY MEMORY

- **8708 1024x8 Organization**
- **8704 512x8 Organization**

- **Fast Programming — Typ. 100 sec. For All 8K Bits**
- **Low Power During Programming**
- **Access Time—450 ns**
- **Standard Power Supplies— +12V, ±5V**
- **Static—No Clocks Required**
- **Inputs and Outputs TTL Compatible During Both Read and Program Modes**
- **Three-State Output—OR-Tie Capability**

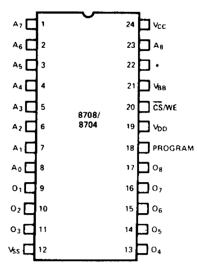
The Intel® 8708/8704 are high speed 8192/4096 bit erasable and electrically reprogrammable ROM's (EPROM) ideally suited where fast turn around and pattern experimentation are important requirements.

The 8708/8704 are packaged in a 24 pin dual-in-line package with transparent lid. The transparent lid allows the user to expose the chip to ultraviolet light to erase the bit pattern. A new pattern can then be written into the devices.

A pin for pin mask programmed ROM, the Intel® 8308, is available for large volume production runs of systems initially using the 8708.

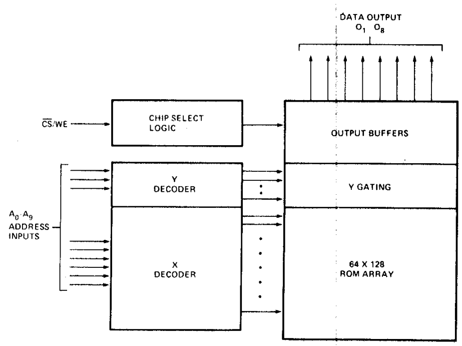
The 8708/8704 is fabricated with the time proven N-channel silicon gate technology.

PIN CONFIGURATIONS



*8704 = V_{SS}
8708 = A_9

BLOCK DIAGRAM



PIN NAMES

A_0-A_9	ADDRESS INPUTS
O_1-O_8	DATA OUTPUTS
$\overline{CS}$/WE	CHIP SELECT/WRITE ENABLE INPUT

A.C. Characteristics

$T_A = 0°C$ to $70°C$, $V_{CC} = +5V \pm 5\%$, $V_{DD} = +12V \pm 5\%$, $V_{BB} = -5V \pm 5\%$, $V_{SS} = 0V$, Unless Otherwise Noted.

Symbol	Parameter	Min.	Typ.	Max.	Unit
t_{ACC}	Address to Output Delay		280	450	ns
$t_{\overline{CO}}$	Chip Select to Output Delay			120	ns
t_{DF}	Chip De-Select to Output Float	0		120	ns
t_{OH}	Address to Output Hold	0			ns

Capacitance[1] $T_A = 25°C$, f = 1MHz

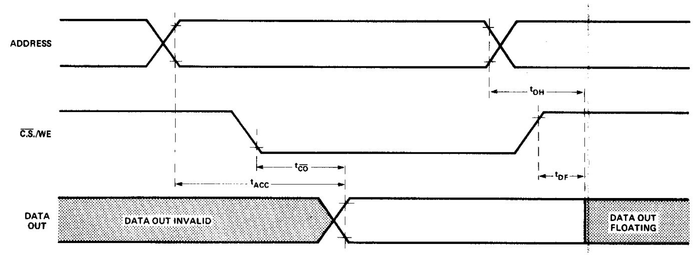
Symbol	Parameter	Typ.	Max.	Unit	Conditions
C_{IN}	Input Capacitance	4	6	pF	V_{IN}=0V
C_{OUT}	Output Capacitance	8	12	pF	V_{OUT}=0V

Note 1. This parameter is periodically sampled and not 100% tested.

A.C. Test Conditions:

Output Load: 1 TTL gate and C_L = 100pF
Input Rise and Fall Times: ≤20ns
Timing Measurement Reference Levels: 0.8V and 2.8V for inputs; 0.8V and 2.4V for outputs
Input Pulse Levels: 0.65V to 3.0V

Waveforms



Absolute Maximum Ratings*

Ambient Temperature Under Bias . . . . . . 0°C to 70°C
Storage Temperature . . . . -65°C to +150°C
Voltage On Any Pin
With Respect to Ground . . . . -0.5V to +7V
Power Dissipation . . . . 1 Watt

**COMMENT:*

Stresses above those listed under "Absolute Maximum Rating" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or at any other condition above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

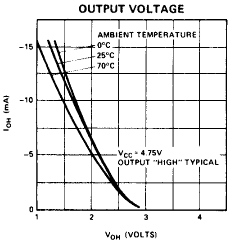
D.C. and Operating Characteristics

T_A = 0°C to 70°C, V_{CC} = 5V ±5% , unless otherwise specified.

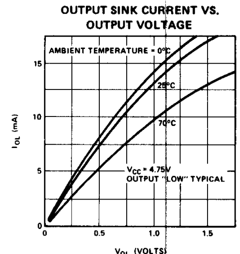
Symbol	Parameter	Min.	Typ.[1]	Max.	Unit	Test Conditions
I_{LI}	Input Load Current			10	μA	V_{IN} = 0 to 5.25V
I_{LOH}	I/O Leakage Current			15	μA	$\overline{CE}$ = 2.2V, $V_{I/O}$ = 4.0V
I_{LOL}	I/O Leakage Current			-50	μA	$\overline{CE}$ = 2.2V, $V_{I/O}$ = 0.45V
I_{CC1}	Power Supply Current		30	60	mA	V_{IN} = 5.25V $I_{I/O}$ = 0mA, T_A = 25°C
I_{CC2}	Power Supply Current			70	mA	V_{IN} = 5.25V $I_{I/O}$ = 0mA, T_A = 0°C
V_{IL}	Input Low Voltage	-0.5		+0.65	V	
V_{IH}	Input High Voltage	2.2		V_{CC}	V	
V_{OL}	Output Low Voltage			0.45	V	I_{OL} = 2.0mA
V_{OH}	Output High Voltage	2.2			V	I_{OH} = -150 μA

NOTES: 1. Typical values are for T_A = 25°C and nominal supply voltage.

OUTPUT SOURCE CURRENT VS.
OUTPUT VOLTAGE



OUTPUT SINK CURRENT VS.
OUTPUT VOLTAGE

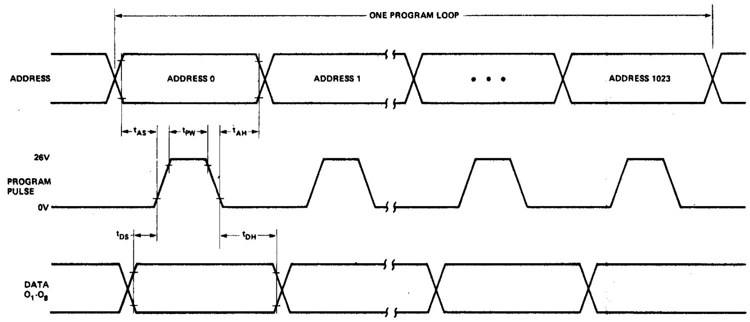


Waveforms

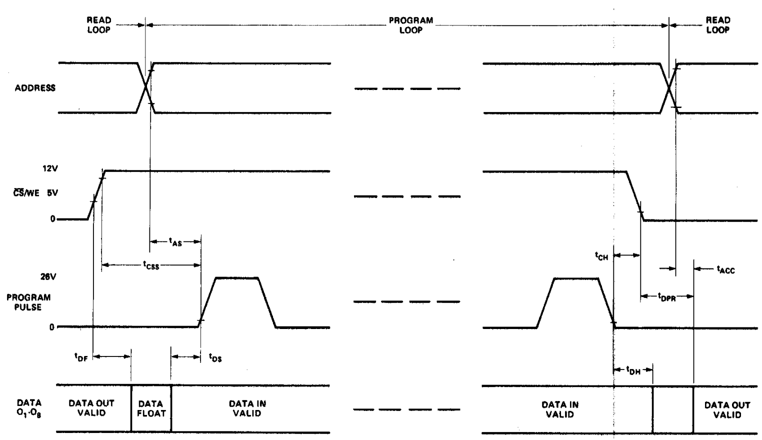
(Logic levels and timing reference levels same as in the Read Mode unless noted otherwise.)

A) Program Mode

$\overline{CS}$/WE = +12V



B) Read/Program/Read Transitions



intel®

Silicon Gate MOS 8302

2048 BIT MASK PROGRAMMABLE READ ONLY MEMORY

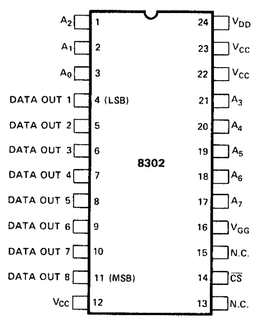
- **Access Time — 1 μsec Max.**
- **Fully Decoded, 256 x 8 Organization**
- **Inputs and Outputs TTL Compatible**
- **Three-State Output — OR-Tie Capability**
- **Static MOS — No Clocks Required**
- **Simple Memory Expansion — Chip Select Input Lead**
- **24-Pin Dual-In-Line Hermetically Sealed Ceramic Package**

The Intel® 8302 is a fully decoded 256 word by 8 bit metal mask ROM. It is ideal for large volume production runs of microcomputer systems initially using the 8702A erasable and electrically programmable ROM. The 8302 has the same pinning as the 8702A.

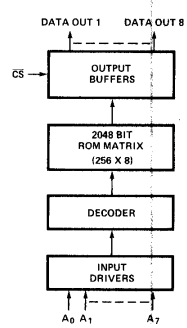
The 8302 is entirely static – no clocks are required. Inputs and outputs of the 8302 are TTL compatible. The output is three-state for OR-tie capability. A separate chip select input allows easy memory expansion. The 8302 is packaged in a 24 pin dual-in-line hermetically sealed ceramic package.

The 8302 is fabricated with p-channel silicon gate technology. This low threshold allows the design and production of higher performance MOS circuits and provides a higher functional density on a monolithic chip than conventional MOS technologies.

PIN CONFIGURATION



BLOCK DIAGRAM



PIN NAMES

A_0-A_7	ADDRESS INPUTS
$\overline{CS}$	CHIP SELECT INPUT
DO_1-DO_8	DATA OUTPUTS

Absolute Maximum Ratings*

Ambient Temperature Under Bias . . . . . . 0°C to 70°C
Storage Temperature . . . . -65°C to +150°C
Voltage On Any Pin
With Respect to Ground . . . . -0.5V to +7V
Power Dissipation . . . . 1 Watt

*COMMENT:

Stresses above those listed under "Absolute Maximum Rating" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or at any other condition above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

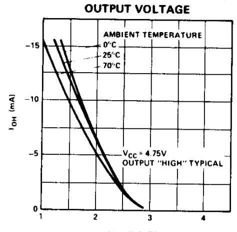
D.C. and Operating Characteristics

T_A = 0°C to 70°C, V_{CC} = 5V ±5% unless otherwise specified.

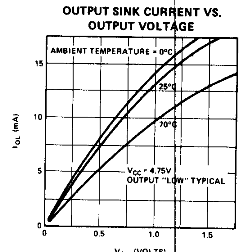
Symbol	Parameter	Min.	Typ.[1]	Max.	Unit	Test Conditions
I_{LI}	Input Current			10	μA	V_{IN} = 0 to 5.25V
I_{LOH}	I/O Leakage Current[2]			15	μA	$\overline{CE}$ = 2.2V, V_{OUT} = 4.0V
I_{LOL}	I/O Leakage Current[2]			-50	μA	$\overline{CE}$ = 2.2V, V_{OUT} = 0.45V
I_{CC1}	Power Supply Current		30	60	mA	V_{IN} = 5.25V, I_O = 0mA T_A = 25°C
I_{CC2}	Power Supply Current			70	mA	V_{IN} = 5.25V, I_O = 0mA T_A = 0°C
V_{IL}	Input "Low" Voltage	-0.5		+0.65	V	
V_{IH}	Input "High" Voltage	2.2		V_{CC}	V	
V_{OL}	Output "Low" Voltage			+0.45	V	I_{OL} = 2.0mA
V_{OH}	Output "High" Voltage	2.2			V	I_{OH} = -150 μA

NOTE: 1. Typical values are for T_A = 25°C and nominal supply voltage.
2. Input and Output tied together.

OUTPUT SOURCE CURRENT VS. OUTPUT VOLTAGE



OUTPUT SINK CURRENT VS. OUTPUT VOLTAGE



A.C. Characteristics

$T_A = 0°C$ to $+70°C$, $V_{CC} = +5V \pm 5\%$, $V_{DD} = -9V \pm 5\%$, $V_{GG} = -9V \pm 5\%$ unless otherwise noted

SYMBOL	TEST	MINIMUM	TYPICAL	MAXIMUM	UNIT
Freq.	Repetition Rate			1	MHz
t_{OH}	Previous read data valid			100	ns
t_{ACC}	Address to output delay		.700	1	μs
t_{DVGG}	Clocked V_{GG} set up	1			μs
t_{CS}	Chip select delay			200	ns
t_{CO}	Output delay from $\overline{CS}$			500	ns
t_{OD}	Output deselect			300	ns
t_{OHC}	Data out hold in clocked V_{GG} mode (Note 1)			5	μs

Note 1. The output will remain valid for t_{OHC} as long as clocked V_{GG} is at V_{CC}. An address change may occur as soon as the output is sensed (clocked V_{GG} may still be at V_{CC}). Data becomes invalid for the old address when clocked V_{GG} is returned to V_{GG}.

Capacitance* $T_A = 25°C$

SYMBOL	TEST	MINIMUM	TYPICAL	MAXIMUM	UNIT	CONDITIONS
C_{IN}	Input Capacitance		5	10	pF	$V_{IN} = V_{CC}$
C_{OUT}	Output Capacitance		5	10	pF	$\overline{CS} = V_{CC}$; $V_{OUT} = V_{CC}$
$C_{V_{GG}}$	V_{GG} Capacitance (Clocked V_{GG} Mode)			30	pF	$V_{GG} = V_{CC}$

Conditions: All unused pins are at A.C. ground.

*This parameter is periodically sampled and is not 100% tested.

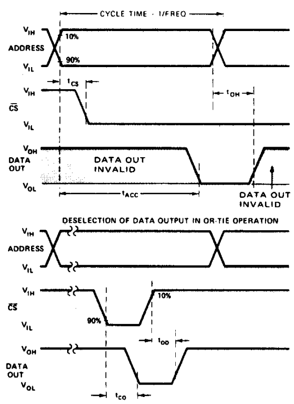
Switching Characteristics

Conditions of Test:

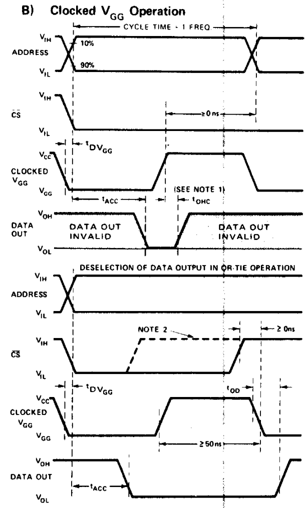
Input pulse amplitudes: 0 to 4V; t_R, $t_F \leq 50$ ns

Output load is 1 TTL gate; measurements made at output of TTL gate ($t_{PD} \leq 15$ ns)

A) Constant V_{GG} Operation



B) Clocked V_{GG} Operation

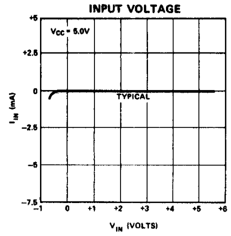


NOTE 1: The output will remain valid for t_{OHC} as long as clocked V_{GG} is at V_{CC}. An address change may occur as soon as the output is sensed (clocked V_{GG} may still be at V_{CC}). Data becomes invalid for the old address when clocked V_{GG} is returned to V_{GG}.

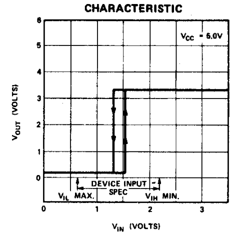
NOTE 2: If $\overline{CS}$ makes a transition from V_{IL} to V_{IH} while clocked V_{GG} is at V_{GG}, then deselection of output occurs at t_{OD} as shown in static operation with constant V_{GG}.

TYPICAL D.C. CHARACTERISTICS

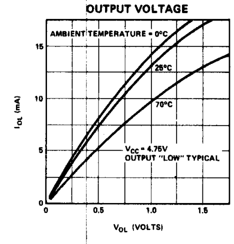
INPUT CURRENT VS. INPUT VOLTAGE



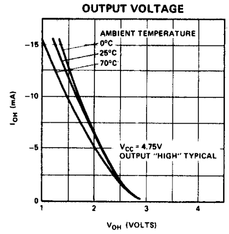
EFFECTIVE INPUT CHARACTERISTIC



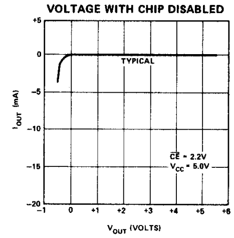
OUTPUT SINK CURRENT VS. OUTPUT VOLTAGE



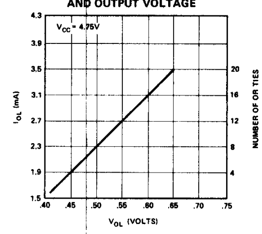
OUTPUT SOURCE CURRENT VS. OUTPUT VOLTAGE



OUTPUT CURRENT VS. OUTPUT VOLTAGE WITH CHIP DISABLED

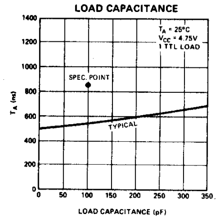


RELATIONSHIP BETWEEN OUTPUT SINK CURRENT, NUMBER OF OR-TIES, AND OUTPUT VOLTAGE

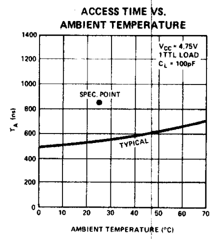


TYPICAL A.C. CHARACTERISTICS

ACCESS TIME VS. LOAD CAPACITANCE



ACCESS TIME VS. AMBIENT TEMPERATURE



intel® Silicon Gate MOS **8308**

8192 BIT STATIC MOS READ ONLY MEMORY
Organization -- 1024 Words x 8 Bits

- Fast Access – 450 ns
- Directly Compatible with 8080 CPU at Maximum Processor Speed
- Two Chip Select Inputs for Easy Memory Expansion
- Directly TTL Compatible – All Inputs and Outputs
- Three State Output – OR-Tie Capability
- Fully Decoded
- Standard Power Supplies +12V DC, ±5V DC

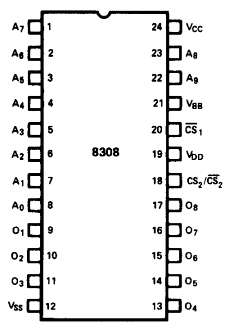
The Intel® 8308 is an 8,192 bit static MOS mask programmable Read Only Memory organized as 1024 words by 8-bits. This ROM is designed for 8080 microcomputer system applications where high performance, large bit storage, and simple interfacing are important design objectives. The inputs and outputs are fully TTL compatible.

A pin for pin compatible electrically programmed erasable ROM, the Intel® 8708, is available for system development and small quantity production use.

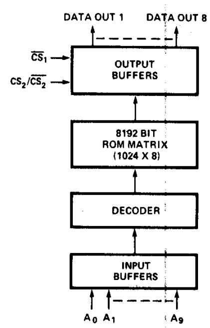
Two Chip Selects are provided – $\overline{CS}_1$ which is negative true, and $CS_2/\overline{CS}_2$ which may be programmed either negative or positive true at the mask level.

The 8308 read only memory is fabricated with N-channel silicon gate technology. This technology provides the designer with high performance, easy-to-use MOS circuits.

PIN CONFIGURATION



BLOCK DIAGRAM

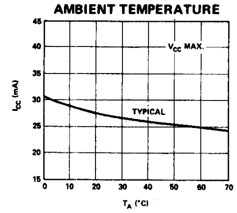


PIN NAMES

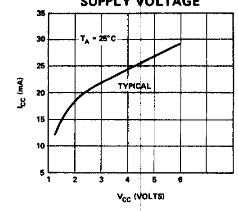
A_0-A_9	ADDRESS INPUTS
O_1-O_8	DATA OUTPUTS
$\overline{CS}_1$, CS_2	CHIP SELECT INPUTS

Typical D. C. and A. C. Characteristics

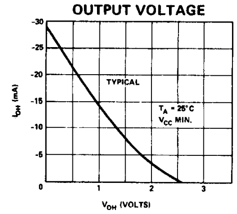
POWER SUPPLY CURRENT VS. AMBIENT TEMPERATURE



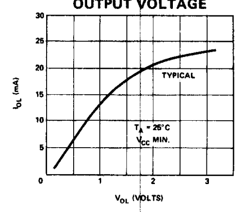
POWER SUPPLY CURRENT VS. SUPPLY VOLTAGE



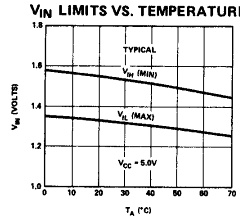
OUTPUT SOURCE CURRENT VS. OUTPUT VOLTAGE



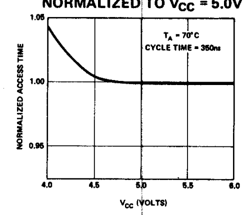
OUTPUT SINK CURRENT VS. OUTPUT VOLTAGE



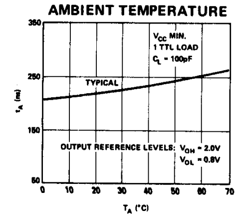
V_{IN} LIMITS VS. TEMPERATURE



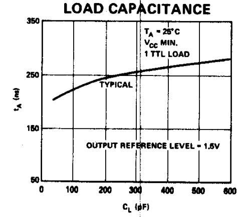
ACCESS TIME VS. V_{CC} NORMALIZED TO V_{CC} = 5.0V



ACCESS TIME VS. AMBIENT TEMPERATURE



ACCESS TIME VS. LOAD CAPACITANCE



A.C. Characteristics

$T_A = 0°C$ to $+70°C$, $V_{CC} = +5V \pm 5\%$; $V_{DD} = +12V \pm 5\%$, $V_{BB} = -5V \pm 5\%$, $V_{SS} = 0V$, Unless Otherwise Specified.

Symbol	Parameter	Limits[2]			Unit
		Min.	Typ.	Max.	
t_{ACC}	Address to Output Delay Time		200	450	ns
t_{CO1}	Chip Select 1 to Output Delay Time		85	160	ns
t_{CO2}	Chip Select 2 to Output Delay Time		125	220	ns
t_{DF}	Chip Deselect to Output Data Float Time		125	220	ns

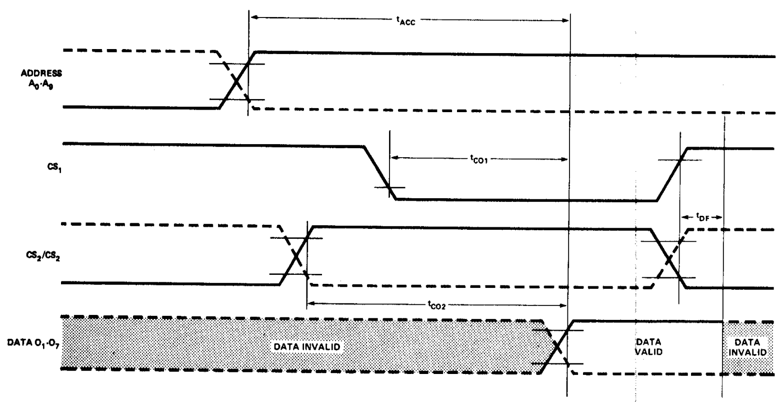
NOTE 2: Refer to conditions of Test for A.C. Characteristics. Add 50 nanoseconds (worst case) to specified values at $V_{OH} = 3.7V$ @ $I_{OH} = -1mA$, $C_L = 100pF$.

CONDITIONS OF TEST FOR A.C. CHARACTERISTICS

Output Load . . . . 1 TTL Gate, and $C_{LOAD} = 100pF$
Input Pulse Levels . . . . .65V to 3.3V
Input Pulse Rise and Fall Times . . . . 20 nsec
Timing Measurement Reference Level
. . . . 2.4V V_{IH}, V_{OH}; 0.8V V_{IL}, V_{OL}

CAPACITANCE $T_A = 25°C$, f = 1 MHz, $V_{BB} = -5V$, V_{DD}, V_{CC} and all other pins tied to V_{SS}.

Symbol	Test	Limits	
		Typ.	Max.
C_{IN}	Input Capacitance		6pF
C_{OUT}	Output Capacitance		12pF



Absolute Maximum Ratings*

Temperature Under Bias . . . . 0°C to 70°C
Storage Temperature . . . . −65°C to +150°C
All Input or Output Voltages with Respect to the most Negative Supply Voltage, V_{BB} . . . . +25V to −0.3V
Supply Voltages V_{DD}, V_{CC}, and V_{SS} with Respect to V_{BB} . . . . +20V to −0.3V
Power Dissipation 1.25W

***COMMENT:**
Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

D.C. and Operating Characteristics

T_A = 0°C to 70°C, V_{DD} = +12V ± 5%, V_{CC} = +5V ± 5%, V_{BB} [1] = -5V ± 5%, V_{SS} = 0V, unless otherwise noted.

Symbol	Parameter	Limits Min.	Typ.[2]	Max.	Unit	Conditions
I_{LI}	Input Load Current (all inputs except CE)		.01	10	µA	$V_{IN} = V_{IL\,MIN}$ to $V_{IH\,MAX}$
I_{LC}	Input Load Current		.01	10	µA	$V_{IN} = V_{IL\,MIN}$ to $V_{IH\,MAX}$
$\|I_{LO}\|$	Output Leakage Current for high impedance state		.01	10	µA	CE = V_{ILC} or $\overline{CS}$ = V_{IH}; V_O = 0V to 5.25V
I_{DD1}	V_{DD} Supply Current during CE off[3]		110	200	µA	CE = -1V to +.6V
I_{DD2}	V_{DD} Supply Current during CE on		80	100	mA	CE = V_{IHC}, T_A = 25°C
$I_{DD\,AV1}$	Average V_{DD} Current		55	80	mA	Cycle time=470ns, t_{CE} = 300ns; T_A = 25°C
$I_{DD\,AV2}$	Average V_{DD} Current		27	40	mA	Cycle time=1000ns, t_{CE} = 300ns; T_A = 25°C
I_{CC1} [4]	V_{CC} Supply Current during CE off		.01	10	µA	CE = V_{ILC} or $\overline{CS}$ = V_{IH}
I_{BB}	V_{BB} Supply Current		5	100	µA	
V_{IL}	Input Low Voltage	-1.0		0.6	V	t_T = 20ns — See Figure 4
V_{IH}	Input High Voltage	2.4		V_{CC}+1	V	
V_{ILC}	CE Input Low Voltage	-1.0		+1.0	V	
V_{IHC}	CE Input High Voltage	V_{DD}-1		V_{DD}+1	V	
V_{OL}	Output Low Voltage	0.0		0.45	V	I_{OL} = 2.0mA
V_{OH}	Output High Voltage	2.4		V_{CC}	V	I_{OH} = -2.0mA

NOTES:
1. The only requirement for the sequence of applying voltage to the device is that V_{DD}, V_{CC}, and V_{SS} should never be .3V more negative than V_{BB}.
2. Typical values are for T_A = 25°C and nominal power supply voltages.
3. The I_{DD} and I_{CC} currents flow to V_{SS}. The I_{BB} current is the sum of all leakage currents.
4. During CE on V_{CC} supply current is dependent on output loading, V_{CC} is connected to output buffer only.

intel®

MCS™ CUSTOM ROM ORDER FORM

8308 ROM

CUSTOMER ____________________

P.O. NUMBER ____________________

DATE ____________________

For Intel use only

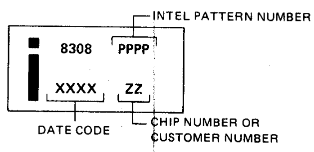
S# ____________	PPPP ____________
STD ____________	ZZ ____________
____________	DD ____________
APP ____________	DATE ____________

All custom 8308 ROM orders must be submitted on this form. Programming information should be sent in the form of computer punched cards or punched paper tape per the formats designated on this order form. Additional forms are available from Intel.

MARKING

The marking as shown at the right must contain the Intel® logo, the product type (P8308), the 4-digit Intel pattern number (PPPP), a date code (XXXX), and the 2-digit chip number (DD). An optional customer identification number may be substituted for the chip number (ZZ). Optional Customer Number (maximum 9 characters or spaces).

CUSTOMER NUMBER ____________________



MASK OPTION SPECIFICATIONS

A. CHIP NUMBER (CHIP SELECT OPTION)

Must be specified 0 or 1.

The chip number will be coded in terms of positive logic where a logic "1" is high level input.

Chip Select Truth Table

Chip Number	$\overline{CS1}$	CS2	Selected
0	0	0	Yes
1	0	1	Yes
0	1	0	No
1	1	1	No

Chip Number ____________

B. ROM Truth Table Format

Programming information should be sent in the form of computer punched cards or punched paper tape. In either case, a printout of the truth table should be accompanied with the order.

The following general format is applicable to the programming information sent to Intel:

- Data fields should be ordered beginning with the least significant address (0000) and ending with the most significant address (1023).
- A data field should start with the most significant bit and end with the least significant bit.
- The data field should consist of P's and N's. A P is to indicate a high level output (most positive) and an N a low level output (most negative). In terms of positive logic, a P is defined as a logic "1" and an N is defined as a logic "0". If the programming information is sent on a punched paper tape, then a start character, B, and an end character, F, must be used in the data field. See paragraph 2.

1. Punched Card Format

An 80-column Hollerith card (preferably interpreted) punched by an IBM 026 or 029 keypunch should be submitted. The first card will be a title card; the format is as follows:

A.C. Characteristics $T_A = 0°C$ to $70°C$, V_{DD} = 12V ± 5%, V_{CC} = 5V ± 10%, V_{BB} = -5V ± 5%,

READ, WRITE, AND READ MODIFY/WRITE CYCLE V_{SS} = 0V, unless otherwise noted.

Symbol	Parameter	Min.	Max.	Unit	Conditions
t_{REF}	Time Between Refresh		2	ms	
t_{AC}	Address to CE Set Up Time	0		ns	t_{AC} is measured from end of address transition
t_{AH}	Address Hold Time	100		ns	
t_{CC}	CE Off Time	130		ns	
t_T	CE Transition Time	10	40	ns	
t_{CF}	CE Off to Output High Impedance State	0		ns	

READ CYCLE

Symbol	Parameter	Min.	Max.	Unit	Conditions
t_{CY}	Cycle Time	470		ns	t_T = 20ns
t_{CE}	CE On Time	300	4000	ns	
t_{CO}	CE Output Delay		250	ns	C_{load} = 50pF, Load = One TTL Gate,
t_{ACC}	Address to Output Access		270	ns	Ref = 2.0V.
t_{WL}	CE to $\overline{WE}$	0		ns	$t_{ACC} = t_{AC} + t_{CO} + 1t_T$
t_{WC}	$\overline{WE}$ to CE on	0		ns	

WRITE CYCLE

Symbol	Parameter	Min.	Max.	Unit	Conditions
t_{CY}	Cycle Time	470		ns	t_T = 20ns
t_{CE}	CE On Time	300	4000	ns	
t_W	$\overline{WE}$ to CE Off	150		ns	
t_{CW}	CE to $\overline{WE}$	150		ns	
t_{DW} [2]	D_{IN} to $\overline{WE}$ Set Up	0		ns	
t_{DH}	D_{IN} Hold Time	0		ns	
t_{WP}	$\overline{WE}$ Pulse Width	50		ns	

Read Modify Write Cycle

Symbol	Parameter	Min.	Max.	Unit	Conditions
t_{RWC}	Read Modify Write(RMW) Cycle Time	590		ns	t_T = 20ns
t_{CRW}	CE Width During RMW	420	4000	ns	
t_{WC}	$\overline{WE}$ to CE on	0		ns	
t_W	$\overline{WE}$ to CE off	150		ns	C_{load} = 50pF, Load = One TTL Gate,
t_{WP}	$\overline{WE}$ Pulse Width	50		ns	Ref = 2.0V
t_{DW}	D_{IN} to $\overline{WE}$ Set Up	0		ns	
t_{DH}	D_{IN} Hold Time	0		ns	
t_{CO}	CE to Output Delay		250	ns	
t_{ACC}	Access Time		270	ns	$t_{ACC} = t_{AC} + t_{CO} + 1t_T$

Silicon Gate MOS ROM 8316A

16,384 BIT STATIC MOS READ ONLY MEMORY
Organization—2048 Words x 8 Bits
Access Time-850 ns max

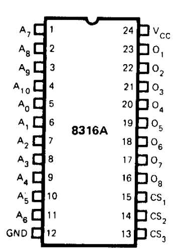
- **Single +5 Volts Power Supply Voltage**
- **Directly TTL Compatible — All Inputs and Outputs**
- **Low Power Dissipation of 31.4 μW/Bit Maximum**
- **Three Programmable Chip Select Inputs for Easy Memory Expansion**
- **Three-State Output — OR-Tie Capability**
- **Fully Decoded — On Chip Address Decode**
- **Inputs Protected — All Inputs Have Protection Against Static Charge**

The Intel® 8316A is a 16,384-bit static MOS read only memory organized as 2048 words by 8 bits. This ROM is designed for microcomputer memory applications where high performance, large bit storage, and simple interfacing are important design objectives.

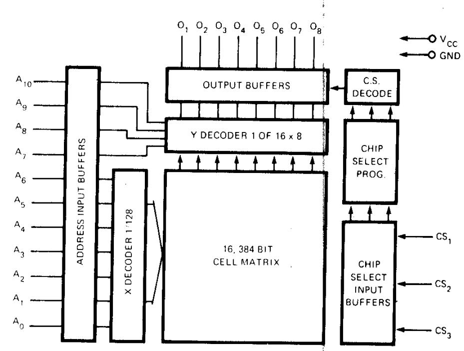
The inputs and outputs are fully TTL compatible. This device operates with a single +5V power supply. The three chip select inputs are programmable. Any combination of active high or low level chip select inputs can be defined and the desired chip select code is fixed during the masking process. These three programmable chip select inputs, as well as OR-tie compatibility on the outputs, facilitate easy memory expansion.

The 8316A read only memory is fabricated with N-channel silicon gate technology. This technology provides the designer with high performance, easy-to-use MOS circuits. Only a single +5V power supply is needed and all devices are directly TTL compatible.

PIN CONFIGURATION



BLOCK DIAGRAM

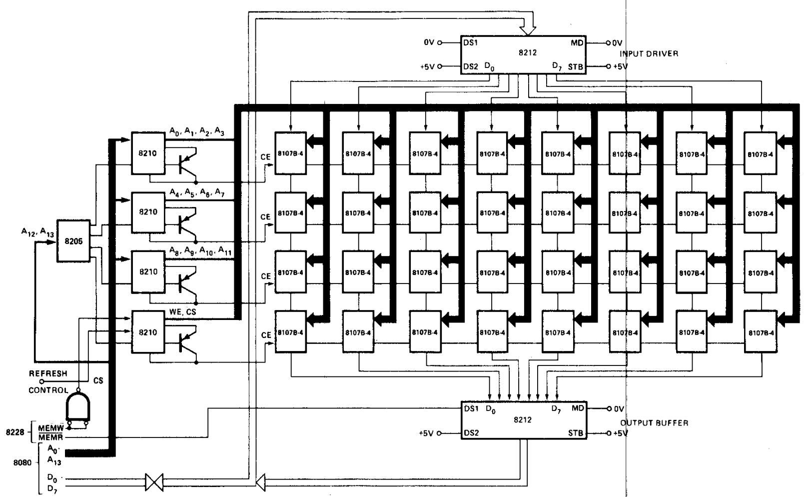


PIN NAMES

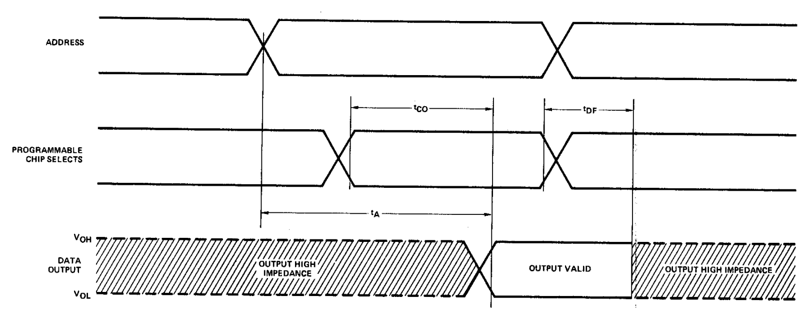
A_0-A_{10}	ADDRESS INPUTS
O_1-O_8	DATA OUTPUTS
CS_1-CS_3	PROGRAMMABLE CHIP SELECT INPUTS

Typical System

Below is an example of a 16K x 8 bit memory circuit. Device decoding is done with the CE input. All devices are unselected during refresh with CS input. The 8210, 8205 and 8212 are standard Intel products.



WAVEFORMS



16K ROM PROTOTYPING

ROM systems may be developed and programs may be verified using Intel's 1702A or 2708 PROMs.

A.C. Characteristics $T_A = 0°C$ to $70°C$, $V_{CC} = 5.0V \pm 5\%$, $V_{DD} = 12V \pm 5\%$

Symbol	Parameter	Min.	Typ.	Max.	Unit
t_{Ld+}	Delay Plus Rise Time for Low Voltage Drivers	5	13	20	ns
t_{Ld-}	Delay Plus Fall Time for Low Voltage Drivers	5	13	20	ns
t_{Hd+}	Delay Plus Rise Time for High Voltage Driver	10	30	40	ns
t_{Hd-}	Delay Plus Fall Time for High Voltage Driver	10	30	40	ns

Capacitance* $T_A = 25°C$

Symbol	Test	Typ.	Max.
C_{IN}	Input Capacitance	6pF	12pF

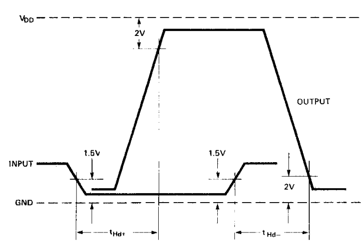
*This parameter is periodically sampled and is not 100% tested. Condition of measurement is f = 1 MHz, $V_{bias} = 2V$, $V_{CC} = 0V$, and $T_A = 25°C$.

A.C. CONDITIONS OF TEST

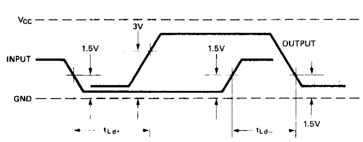
Test Load: $C_L = 200pF$ for Low Voltage Drivers,
$C_L = 350pF$ for High Voltage Drivers
Input Pulse Amplitudes: 3.0V
Input Pulse Rise and Fall Times: 5 ns between 1 volt and 2 volts
Measurement Points: See Waveforms

Waveforms

HIGH VOLTAGE DRIVER

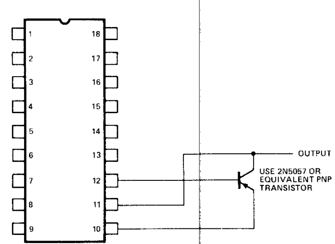


LOW VOLTAGE DRIVER



Application

HIGH VOLTAGE OUTPUT CONNECTIONS



intel®

MCS™ CUSTOM ROM ORDER FORM

8316A ROM

CUSTOMER____________________________________

P.O. NUMBER____________________________________

DATE____________________________________

For Intel use only

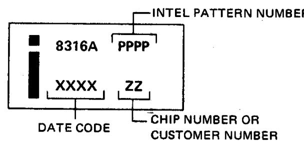
S#__________	PPPP__________
STD__________	ZZ__________
__________	DD__________
APP__________	DATE__________

All custom 8316A ROM orders must be submitted on this form. Programming information should be sent in the form of computer punched cards or punched paper tape per the formats designated on this order form. Additional forms are available from Intel.

MARKING

The marking as shown at the right must contain the Intel® logo, the product type (P8316A), the 4-digit Intel pattern number (PPPP), a date code (XXXX), and the 2-digit chip number (DD). An optional customer identification number may be substituted for the chip number (ZZ). Optional Customer Number (maximum 9 characters or spaces).

CUSTOMER NUMBER ____________________________



MASK OPTION SPECIFICATIONS

A. CHIP NUMBER ________ (Must be specified—any number from 0 through 7—DD).

The chip number will be coded in terms of positive logic where a logic "1" is a high level input.

Chip Number	CS3	CS2	CS1
0	0	0	0
1	0	0	1
2	0	1	0
3	0	1	1
4	1	0	0
5	1	0	1
6	1	1	0
7	1	1	1

B. ROM Truth Table Format

Programming information should be sent in the form of computer punched cards or punched paper tape. In either case, a printout of the truth table should be accompanied with the order.

The following general format is applicable to the programming information sent to Intel:

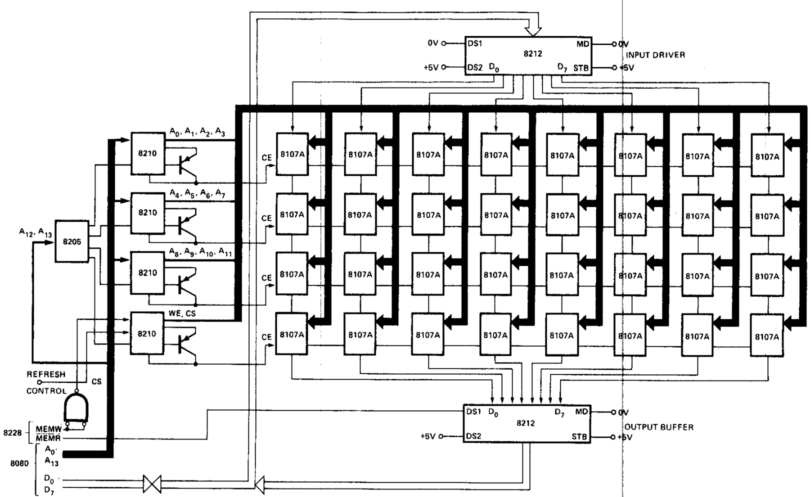
- Data fields should be ordered beginning with the least significant address (0000) and ending with the most significant address (2047).
- A data field should start with the most significant bit and end with the least significant bit.
- The data field should consist of P's and N's. A P is to indicate a high level output (most positive) and an N a low level output (most negative). In terms of positive logic, a P is defined as a logic "1" and an N is defined as a logic "0". If the programming information is sent on a punched paper tape, then a start character, B, and an end character, F, must be used in the data field.

1. Punched Card Format

An 80-column Hollerith card (preferably interpreted) punched by an IBM 026 or 029 keypunch should be submitted. The first card will be a title card; the format is as follows:

Typical System

Below is an example of a 16K x 8 bit memory circuit. Device decoding is done with the CE input. All devices are unselected during refresh with CS input. The 8210, 8205 and 8212 are standard Intel products.



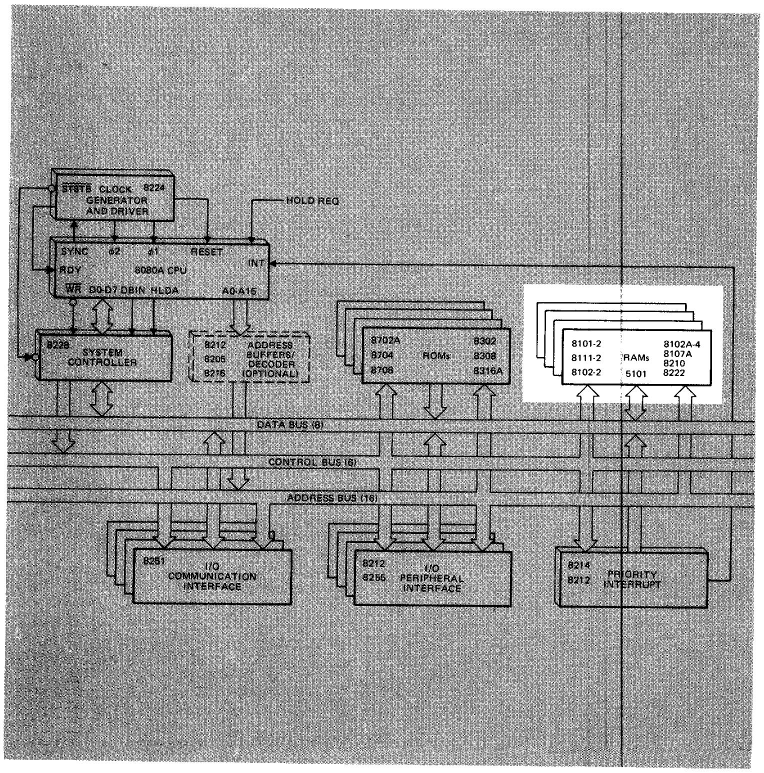
intel® Microcomputer Systems

RAMs

8101-2
8111-2

8102-2
8102A-4
8107B-4

5101
8210
8222



Silicon Gate MOS 8101-2

1024 BIT (256 x 4) STATIC MOS RAM WITH SEPARATE I/O

- **256 x 4 Organization to Meet Needs for Small System Memories**
- **Access Time — 850 nsec Max.**
- **Single +5V Supply Voltage**
- **Directly TTL Compatible — All Inputs and Output**
- **Static MOS — No Clocks or Refreshing Required**
- **Simple Memory Expansion — Chip Enable Input**
- **Inputs Protected — All Inputs Have Protection Against Static Charge**
- **Low Cost Packaging — 22 Pin Plastic Dual-In-Line Configuration**
- **Low Power — Typically 150 mW**
- **Three-State Output — OR-Tie Capability**
- **Output Disable Provided for Ease of Use in Common Data Bus Systems**

The Intel® 8101-2 is a 256 word by 4 bit static random access memory element using normally off N-channel MOS devices integrated on a monolithic array. It uses fully DC stable (static) circuitry and therefore requires no clocks or refreshing to operate. The data is read out nondestructively and has the same polarity as the input data.

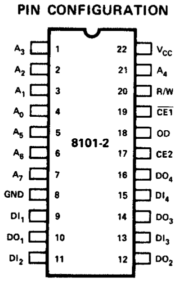
The 8101-2 is designed for memory applications where high performance, low cost, large bit storage, and simple interfacing are important design objectives.

It is directly TTL compatible in all respects: inputs, outputs, and a single +5V supply. Two chip-enables allow easy selection of an individual package when outputs are OR-tied. An output disable is provided so that data inputs and outputs can be tied for common I/O systems. Output disable is then used to eliminate any bidirectional logic.

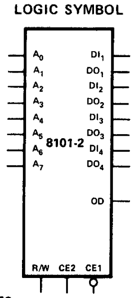
The Intel® 8101-2 is fabricated with N-channel silicon gate technology. This technology allows the design and production of high performance, easy-to-use MOS circuits and provides a higher functional density on a monolithic chip than either conventional MOS technology or P-channel silicon gate technology.

Intel's silicon gate technology also provides excellent protection against contamination. This permits the use of low cost silicone packaging.

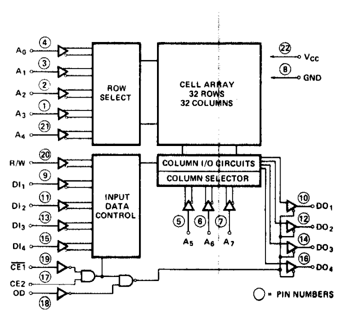
PIN CONFIGURATION



LOGIC SYMBOL



BLOCK DIAGRAM



PIN NAMES

D_{IN}	DATA INPUT	OD	OUTPUT DISABLE
$A_0 - A_7$	ADDRESS INPUTS	D_{OUT}	DATA OUTPUT
R/W	READ/WRITE INPUT	V_{CC}	POWER (+5V)
$\overline{CE1}$, CE2	CHIP ENABLE		

Functional Description

Data Latch

The 8 flip-flops that make up the data latch are of a "D" type design. The output (Q) of the flip-flop will follow the data input (D) while the clock input (C) is high. Latching will occur when the clock (C) returns low.

The data latch is cleared by an asynchronous reset input ($\overline{CLR}$). (Note: Clock (C) Overides Reset ($\overline{CLR}$).)

Output Buffer

The outputs of the data latch (Q) are connected to 3-state, non-inverting output buffers. These buffers have a common control line (EN); this control line either enables the buffer to transmit the data from the outputs of the data latch (Q) or disables the buffer, forcing the output into a high impedance state. (3-state)

This high-impedance state allows the designer to connect the 8212 directly onto the microprocessor bi-directional data bus.

Control Logic

The 8212 has control inputs $\overline{DS1}$, DS2, MD and STB. These inputs are used to control device selection, data latching, output buffer state and service request flip-flop.

$\overline{DS1}$, DS2 (Device Select)

These 2 inputs are used for device selection. When $\overline{DS1}$ is low and DS2 is high ($\overline{DS1} \cdot DS2$) the device is selected. In the selected state the output buffer is enabled and the service request flip-flop (SR) is asynchronously set.

MD (Mode)

This input is used to control the state of the output buffer and to determine the source of the clock input (C) to the data latch.

When MD is high (output mode) the output buffers are enabled and the source of clock (C) to the data latch is from the device selection logic ($\overline{DS1} \cdot DS2$).

When MD is low (input mode) the output buffer state is determined by the device selection logic ($\overline{DS1} \cdot DS2$) and the source of clock (C) to the data latch is the STB (Strobe) input.

STB (Strobe)

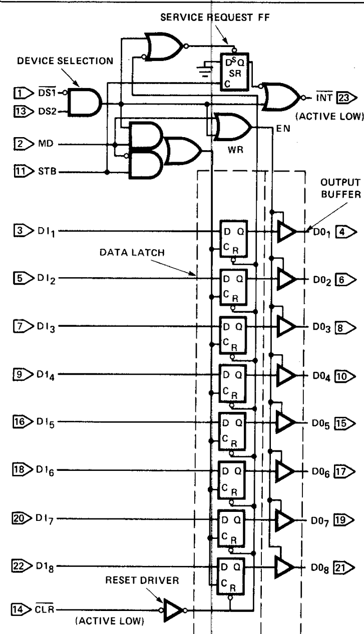
This input is used as the clock (C) to the data latch for the input mode MD = 0) and to synchronously reset the service request flip-flop (SR).

Note that the SR flip-flop is negative edge triggered.

Service Request Flip-Flop

The (SR) flip-flop is used to generate and control interrupts in microcomputer systems. It is asynchronously set by the $\overline{CLR}$ input (active low). When the (SR) flip-flop is set it is in the non-interrupting state.

The output of the (SR) flip-flop (Q) is connected to an inverting input of a "NOR" gate. The other input to the "NOR" gate is non-inverting and is connected to the device selection logic ($\overline{DS1} \cdot DS2$). The output of the "NOR" gate ($\overline{INT}$) is active low (interrupting state) for connection to active low input priority generating circuits.



STB	MD	$(\overline{DS_1} \cdot DS_2)$	DATA OUT EQUALS
0	0	0	3-STATE
1	0	0	3-STATE
0	1	0	DATA LATCH
1	1	0	DATA LATCH
0	0	1	DATA LATCH
1	0	1	DATA IN
0	1	1	DATA IN
1	1	1	DATA IN

$\overline{CLR}$ – RESETS DATA LATCH
SETS SR FLIP-FLOP
(NO EFFECT ON OUTPUT BUFFER)

CLR	$(\overline{DS_1} \cdot DS_2)$	STB	*SR	INT
0	0	0	1	1
0	1	0	1	0
1	1	⌐_ (falling edge)	0	0
1	1	0	1	0
1	0	0	1	1
1	1	⌐_ (falling edge)	1	0

*INTERNAL SR FLIP-FLOP

A.C. Characteristics

READ CYCLE T_A = 0°C to 70°C, V_{CC} = 5V ±5%, unless otherwise specified.

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
t_{RCY}	Read Cycle	850			ns	(See below)
t_A	Access Time			850	ns	
t_{CO}	Chip Enable To Output			650	ns	
t_{OD}	Output Disable To Output			550	ns	
t_{DF} [1]	Data Output to High Z State	0		200	ns	
t_{OH}	Previous Data Read Valid after change of Address	0			ns	

WRITE CYCLE

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
t_{WCY}	Write Cycle	850			ns	(See below)
t_{AW}	Write Delay	150			ns	
t_{CW}	Chip Enable To Write	750			ns	
t_{DW}	Data Setup	500			ns	
t_{DH}	Data Hold	100			ns	
t_{WP}	Write Pulse	630			ns	
t_{WR}	Write Recovery	50			ns	

A. C. CONDITIONS OF TEST

Input Pulse Levels: +0.65 Volt to 2.2 Volt

Input Pulse Rise and Fall Times: 20nsec

Timing Measurement Reference Level: 1.5 Volt

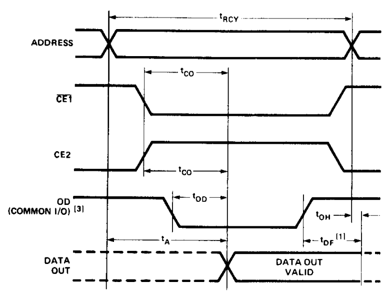
Output Load: 1 TTL Gate and C_L = 100pF

Capacitance T_A = 25°C, f = 1MHz

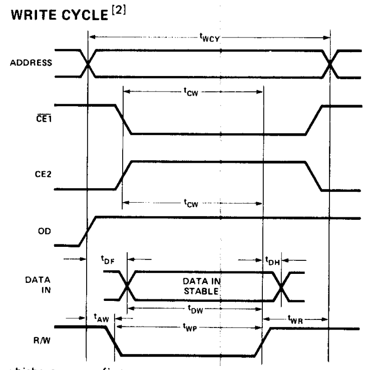
Symbol	Test	Limits (pF) Typ.	Limits (pF) Max.
C_{IN}	Input Capacitance (All Input Pins) V_{IN} = 0V	4	8
C_{OUT}	Output Capacitance V_{OUT} = 0V	8	12

Waveforms

READ CYCLE



WRITE CYCLE [2]

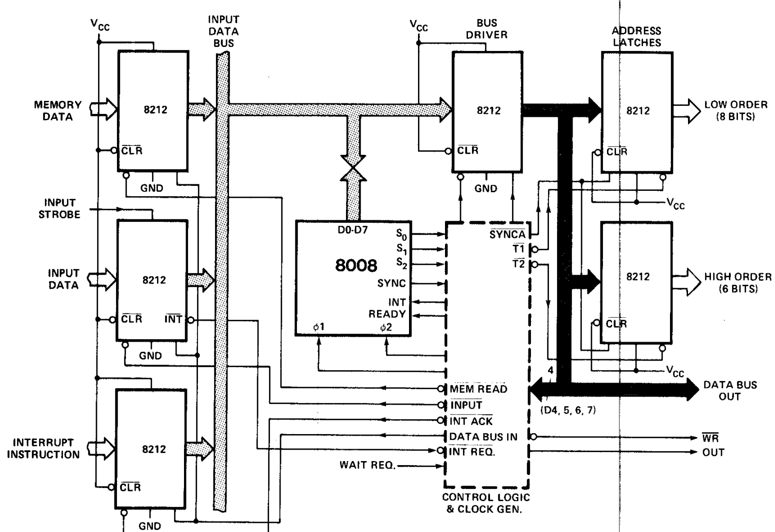


NOTES: 1. t_{DF} is with respect to the trailing edge of $\overline{CE1}$, CE2, or OD, whichever occurs first.
2. During the write cycle, OD is a logical 1 for common I/O and "don't care" for separate I/O operation.
3. OD should be tied low for separate I/O operation.

VIII. 8008 System

This shows the 8212 used in an 8008 microcomputer system. They are used to multiplex the data from three different sources onto the 8008 input data bus. The three sources of data are: memory data, input data, and the interrupt instruction. The 8212 is also used as the uni-directional bus driver to provide a proper drive to the address latches (both low order and high order are also 8212's) and to provide adequate drive to the output data bus. The control of these six 8212's in the 8008 system is provided by the control logic and clock generator circuits. These circuits consist of flip-flops, decoders, and gates to generate the control functions necessary for 8008 microcomputer systems. Also note that the input data port has a strobe input. This allows the processor to be interrupted from the input port directly. The control of the input bus consists of the data bus input signal, control logic, and the appropriate status signal for bus discipline whether memory read, input, or interrupt acknowledge. The combination of these four signals determines which one of these three devices will have access to the input data bus. The bus driver, which is implemented in an 8212, is also controlled by the control logic and clock generator so it can be 3-stated when necessary and also as a control transmission device to the address latches. Note: The address latches can be 3-stated for DMA purposes and they provide 15 milli amps drive, sufficient for large bus systems.

8008 SYSTEM



intel®

Silicon Gate MOS 8111-2

1024 BIT (256 x 4) STATIC MOS RAM WITH COMMON I/O AND OUTPUT DISABLE

- **Organization 256 Words by 4 Bits**
- **Access Time — 850 nsec Max.**
- **Common Data Input and Output**
- **Single +5V Supply Voltage**
- **Directly TTL Compatible — All Inputs and Output**
- **Static MOS — No Clocks or Refreshing Required**
- **Simple Memory Expansion — Chip Enable Input**
- **Fully Decoded — On Chip Address Decode**
- **Inputs Protected — All Inputs Have Protection Against Static Charge**
- **Low Cost Packaging — 18 Pin Plastic Dual-In-Line Configuration**
- **Low Power — Typically 150 mW**
- **Three-State Output — OR-Tie Capability**

The Intel® 8111-2 is a 256 word by 4 bit static random access memory element using normally off N-channel MOS devices integrated on a monolithic array. It uses fully DC stable (static) circuitry and therefore requires no clocks or refreshing to operate. The data is read out nondestructively and has the same polarity as the input data. Common input/output pins are provided.

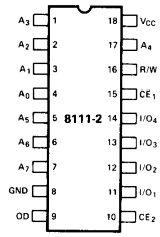
The 8111-2 is designed for memory applications in small systems where high performance, low cost, large bit storage, and simple interfacing are important design objectives.

It is directly TTL compatible in all respects: inputs, outputs, and a single +5V supply. Separate chip enable ($\overline{CE}$) leads allow easy selection of an individual package when outputs are OR-tied.

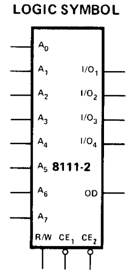
The Intel® 8111-2 is fabricated with N-channel silicon gate technology. This technology allows the design and production of high performance, easy-to-use MOS circuits and provides a higher functional density on a monolithic chip than either conventional MOS technology or P-channel silicon gate technology.

Intel's silicon gate technology also provides excellent protection against contamination. This permits the use of low cost silicone packaging.

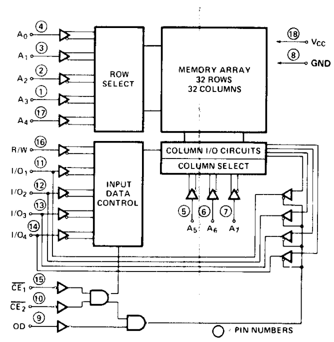
PIN CONFIGURATION



LOGIC SYMBOL



BLOCK DIAGRAM

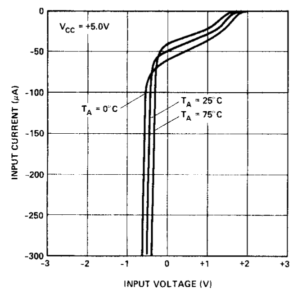


PIN NAMES

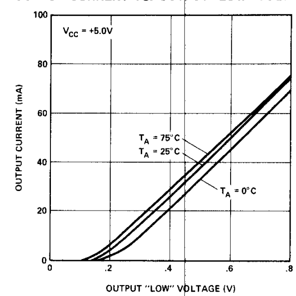
A_0-A_7	ADDRESS INPUTS
OD	OUTPUT DISABLE
R/W	READ/WRITE INPUT
$\overline{CE}_1$	CHIP ENABLE 1
$\overline{CE}_2$	CHIP ENABLE 2
I/O_1-I/O_4	DATA INPUT/OUTPUT

Typical Characteristics

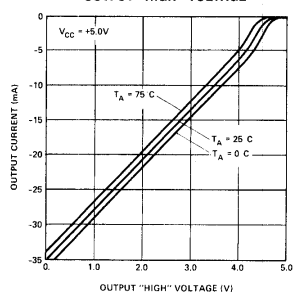
INPUT CURRENT VS. INPUT VOLTAGE



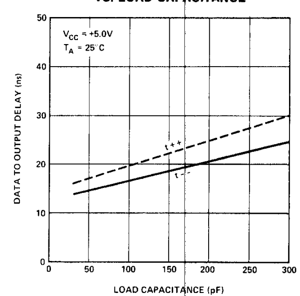
OUTPUT CURRENT VS. OUTPUT "LOW" VOLTAGE



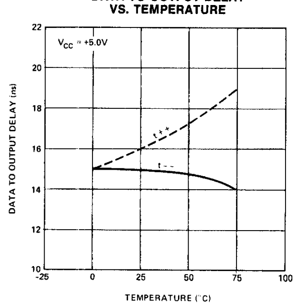
OUTPUT CURRENT VS. OUTPUT "HIGH" VOLTAGE



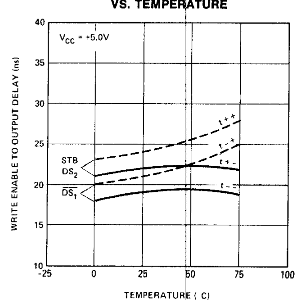
DATA TO OUTPUT DELAY VS. LOAD CAPACITANCE



DATA TO OUTPUT DELAY VS. TEMPERATURE



WRITE ENABLE TO OUTPUT DELAY VS. TEMPERATURE



A.C. Characteristics

READ CYCLE T_A = 0°C to 70°C, V_{CC} = 5V ±5%, unless otherwise specified.

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
t_{RCY}	Read Cycle	850			ns	(See below)
t_A	Access Time			850	ns	
t_{CO}	Chip Enable To Output			650	ns	
t_{OD}	Output Disable To Output			550	ns	
t_{DF} [1]	Data Output to High Z State	0		200	ns	
t_{OH}	Previous Data Read Valid after change of Address	0			ns	

WRITE CYCLE

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
t_{WCY}	Write Cycle	850			ns	(See below)
t_{AW}	Write Delay	150			ns	
t_{CW}	Chip Enable To Write	750			ns	
t_{DW}	Data Setup	500			ns	
t_{DH}	Data Hold	100			ns	
t_{WP}	Write Pulse	630			ns	
t_{WR}	Write Recovery	50			ns	

A. C. CONDITIONS OF TEST

Input Pulse Levels: +0.65 Volt to 2.2 Volt

Input Pulse Rise and Fall Times: 20nsec

Timing Measurement Reference Level: 1.5 Volt

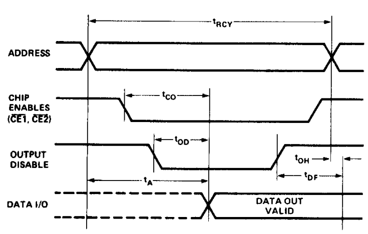
Output Load: 1 TTL Gate and C_L = 100pF

Capacitance T_A = 25°C, f = 1MHz

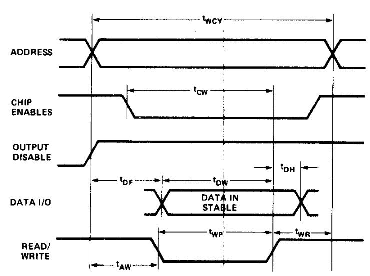
Symbol	Test	Limits (pF) Typ.	Limits (pF) Max.
C_{IN}	Input Capacitance (All Input Pins) V_{IN} = 0V	4	8
C_{OUT}	Output Capacitance V_{OUT} = 0V	10	15

Waveforms

READ CYCLE



WRITE CYCLE



NOTE: 1. t_{DF} is with respect to the trailing edge of $\overline{CE1}$, $\overline{CE2}$, or OD, whichever occurs first.

A.C. Characteristics

T_A = 0°C to +75°C V_{CC} = +5V ± 5%

Symbol	Parameter	Limits Min.	Typ.	Max.	Unit	Test Conditions
t_{pw}	Pulse Width	30			ns	
t_{pd}	Data To Output Delay			30	ns	
t_{we}	Write Enable To Output Delay			40	ns	
t_{set}	Data Setup Time	15			ns	
t_h	Data Hold Time	20			ns	
t_r	Reset To Output Delay			40	ns	
t_s	Set To Output Delay			30	ns	
t_e	Output Enable/Disable Time			45	ns	
t_c	Clear To Output Delay			55	ns	

CAPACITANCE* F = 1 MHz V_{BIAS} = 2.5V V_{CC} = +5V T_A = 25°C

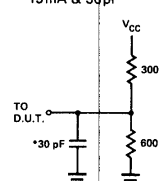
Symbol	Test	LIMITS Typ.	Max.
C_{IN}	DS_1 MD Input Capacitance	9 pF	12 pF
C_{IN}	DS_2, CK, ACK, DI_1-DI_8 Input Capacitance	5 pF	9 pF
C_{OUT}	DO_1-DO_8 Output Capacitance	8 pF	12 pF

*This parameter is sampled and not 100% tested.

Switching Characteristics

CONDITIONS OF TEST
Input Pulse Amplitude = 2.5 V
Input Rise and Fall Times 5 ns
Between 1V and 2V Measurements made at 1.5V
with 15 mA & 30 pF Test Load

TEST LOAD
15mA & 30pF



* INCLUDING JIG & PROBE CAPACITANCE

intel® Silicon Gate MOS **8101-2**

1024 BIT (256 x 4) STATIC MOS RAM WITH SEPARATE I/O

- **256 x 4 Organization to Meet Needs for Small System Memories**
- **Access Time — 850 nsec Max.**
- **Single +5V Supply Voltage**
- **Directly TTL Compatible — All Inputs and Output**
- **Static MOS — No Clocks or Refreshing Required**
- **Simple Memory Expansion — Chip Enable Input**
- **Inputs Protected — All Inputs Have Protection Against Static Charge**
- **Low Cost Packaging — 22 Pin Plastic Dual-In-Line Configuration**
- **Low Power — Typically 150 mW**
- **Three-State Output — OR-Tie Capability**
- **Output Disable Provided for Ease of Use in Common Data Bus Systems**

The Intel 8101-2® is a 256 word by 4 bit static random access memory element using normally off N-channel MOS devices integrated on a monolithic array. It uses fully DC stable (static) circuitry and therefore requires no clocks or refreshing to operate. The data is read out nondestructively and has the same polarity as the input data.

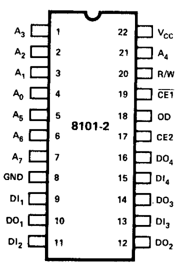
The 8101-2 is designed for memory applications where high performance, low cost, large bit storage, and simple interfacing are important design objectives.

It is directly TTL compatible in all respects: inputs, outputs, and a single +5V supply. Two chip-enables allow easy selection of an individual package when outputs are OR-tied. An output disable is provided so that data inputs and outputs can be tied for common I/O systems. Output disable is then used to eliminate any bidirectional logic.

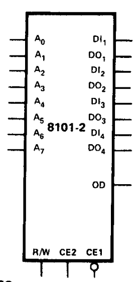
The Intel 8101-2 is fabricated with N-channel silicon gate technology. This technology allows the design and production of high performance, easy-to-use MOS circuits and provides a higher functional density on a monolithic chip than either conventional MOS technology or P-channel silicon gate technology.

Intel's silicon gate technology also provides excellent protection against contamination. This permits the use of low cost silicone packaging.

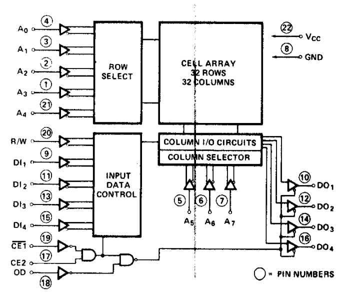
PIN CONFIGURATION



LOGIC SYMBOL



BLOCK DIAGRAM



PIN NAMES

D_{IN}	DATA INPUT	OD	OUTPUT DISABLE
$A_0 - A_7$	ADDRESS INPUTS	D_{OUT}	DATA OUTPUT
R/W	READ/WRITE INPUT	V_{CC}	POWER (+5V)
$\overline{CE1}$, CE2	CHIP ENABLE		

8255 BASIC FUNCTIONAL DESCRIPTION

General

The 8255 is a Programmable Peripheral Interface (PPI) device designed for use in 8080 Microcomputer Systems. Its function is that of a general purpose I/O component to interface peripheral equipment to the 8080 system bus. The functional configuration of the 8255 is programmed by the system software so that normally no external logic is necessary to interface peripheral devices or structures.

Data Bus Buffer

This 3-state, bi-directional, eight bit buffer is used to interface the 8255 to the 8080 system data bus. Data is transmitted or received by the buffer upon execution of INput or OUTput instructions by the 8080 CPU. Control Words and Status information are also transferred through the Data Bus buffer.

Read/Write and Control Logic

The function of this block is to manage all of the internal and external transfers of both Data and Control or Status words. It accepts inputs from the 8080 CPU Address and Control busses and in turn, issues commands to both of the Control Groups.

($\overline{CS}$)

Chip Select: A "low" on this input pin enables the communication between the 8255 and the 8080 CPU.

($\overline{RD}$)

Read: A "low" on this input pin enables the 8255 to send the Data or Status information to the 8080 CPU on the Data Bus. In essence, it allows the 8080 CPU to "read from" the 8255.

($\overline{WR}$)

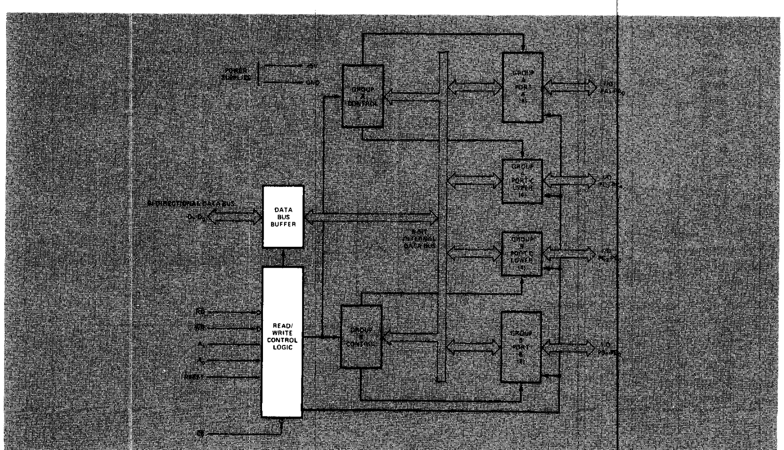
Write: A "low" on this input pin enables the 8080 CPU to write Data or Control words into the 8255.

(A_0 and A_1)

Port Select 0 and Port Select 1: These input signals, in conjunction with the $\overline{RD}$ and $\overline{WR}$ inputs, control the selection of one of the three ports or the Control Word Register. They are normally connected to the least significant bits of the Address Bus (A_0 and A_1).

8255 BASIC OPERATION

A_1	A_0	$\overline{RD}$	$\overline{WR}$	$\overline{CS}$	INPUT OPERATION (READ)
0	0	0	1	0	PORT A ⇒ DATA BUS
0	1	0	1	0	PORT B ⇒ DATA BUS
1	0	0	1	0	PORT C ⇒ DATA BUS
					OUTPUT OPERATION (WRITE)
0	0	1	0	0	DATA BUS ⇒ PORT A
0	1	1	0	0	DATA BUS ⇒ PORT B
1	0	1	0	0	DATA BUS ⇒ PORT C
1	1	1	0	0	DATA BUS ⇒ CONTROL
					DISABLE FUNCTION
X	X	X	X	1	DATA BUS ⇒ 3-STATE
1	1	0	1	0	ILLEGAL CONDITION



8255 Block Diagram

A.C. CHARACTERISTICS T_A = 0°C to 70°C, V_{CC} = 5V ±5% unless otherwise specified

SYMBOL	PARAMETER	LIMITS MIN.	TYP.(1)	MAX.	UNIT
READ CYCLE					
t_{RC}	READ CYCLE	850			ns
t_A	ACCESS TIME		500	850	ns
t_{CO}	CHIP ENABLE TO OUTPUT TIME			500	ns
t_{OH1}	PREVIOUS READ DATA VALID WITH RESPECT TO ADDRESS	50			ns
t_{OH2}	PREVIOUS READ DATA VALID WITH RESPECT TO CHIP ENABLE	0			ns
WRITE CYCLE					
t_{WC}	WRITE CYCLE	850			ns
t_{AW}	ADDRESS TO WRITE SETUP TIME	200			ns
t_{WP}	WRITE PULSE WIDTH	600			ns
t_{WR}	WRITE RECOVERY TIME	50			ns
t_{DW}	DATA SETUP TIME	650			ns
t_{DH}	DATA HOLD TIME	100			ns
t_{CW}	CHIP ENABLE TO WRITE SETUP TIME	750			ns

(1) Typical values are for T_A=25°C and nominal supply voltage.

A.C. CONDITIONS OF TEST

Input Pulse Levels: +0.65 Volt to 2.2 Volt

Input Pulse Rise and Fall Times: 20nsec

Timing Measurement Reference Level: 1.5 Volt

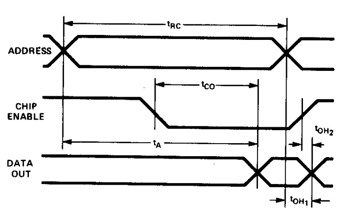
Output Load: 1 TTL Gate and C_L = 100 pF

CAPACITANCE T_A = 25°C, f = 1MHz

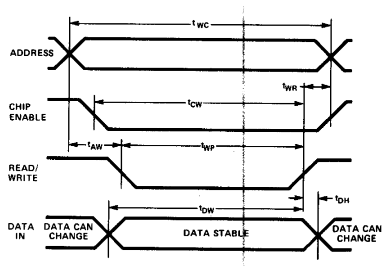
SYMBOL	TEST	LIMITS (pF) TYP.	MAX.
C_{IN}	INPUT CAPACITANCE (ALL INPUT PINS) V_{IN} = 0V	3	5
C_{OUT}	OUTPUT CAPACITANCE V_{OUT} = 0V	7	10

WAVEFORMS

READ CYCLE



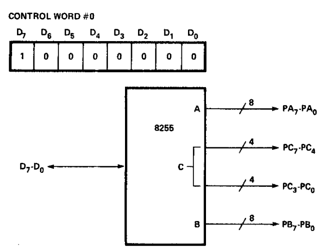
WRITE CYCLE

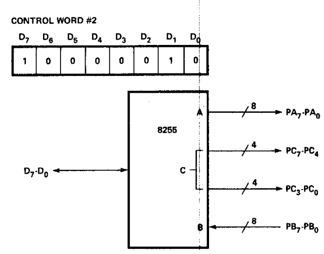


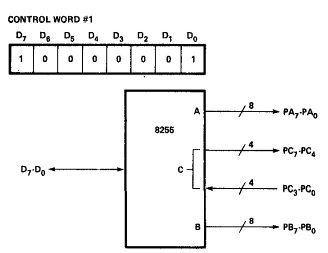
MODE 0 PORT DEFINITION CHART

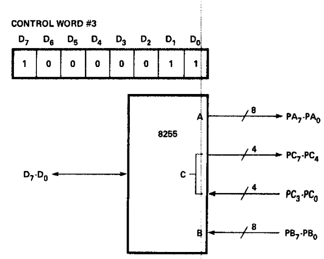
A		B		GROUP A			GROUP B	
D_4	D_3	D_1	D_0	PORT A	PORT C (UPPER)	#	PORT B	PORT C (LOWER)
0	0	0	0	OUTPUT	OUTPUT	0	OUTPUT	OUTPUT
0	0	0	1	OUTPUT	OUTPUT	1	OUTPUT	INPUT
0	0	1	0	OUTPUT	OUTPUT	2	INPUT	OUTPUT
0	0	1	1	OUTPUT	OUTPUT	3	INPUT	INPUT
0	1	0	0	OUTPUT	INPUT	4	OUTPUT	OUTPUT
0	1	0	1	OUTPUT	INPUT	5	OUTPUT	INPUT
0	1	1	0	OUTPUT	INPUT	6	INPUT	OUTPUT
0	1	1	1	OUTPUT	INPUT	7	INPUT	INPUT
1	0	0	0	INPUT	OUTPUT	8	OUTPUT	OUTPUT
1	0	0	1	INPUT	OUTPUT	9	OUTPUT	INPUT
1	0	1	0	INPUT	OUTPUT	10	INPUT	OUTPUT
1	0	1	1	INPUT	OUTPUT	11	INPUT	INPUT
1	1	0	0	INPUT	INPUT	12	OUTPUT	OUTPUT
1	1	0	1	INPUT	INPUT	13	OUTPUT	INPUT
1	1	1	0	INPUT	INPUT	14	INPUT	OUTPUT
1	1	1	1	INPUT	INPUT	15	INPUT	INPUT

MODE 0 CONFIGURATIONS









1024 BIT FULLY DECODED STATIC MOS RANDOM ACCESS MEMORY

- **Access Time — 450 ns Max.**
- **Single +5 Volts Supply Voltage**
- **Directly TTL Compatible — All Inputs and Output**
- **Static MOS — No Clocks or Refreshing Required**
- **Low Power — Typically 150 mW**
- **Three-State Output — OR-Tie Capability**
- **Simple Memory Expansion — Chip Enable Input**
- **Fully Decoded — On Chip Address Decode**
- **Inputs Protected — All Inputs Have Protection Against Static Charge**
- **Low Cost Packaging — 16 Pin Plastic Dual-In-Line Configuration**

The Intel® 8102A-4 is a 1024 word by one bit static random access memory element using normally off N-channel MOS devices integrated on a monolithic array. It uses fully DC stable (static) circuitry and therefore requires no clocks or refreshing to operate. The data is read out nondestructively and has the same polarity as the input data.

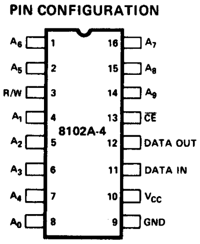
The 8102A-4 is designed for microcomputer memory applications where high performance, low cost, large bit storage, and simple interfacing are important design objectives.

It is directly TTL compatible in all respects: inputs, output, and a single +5 volt supply. A separate chip enable ($\overline{CE}$) lead allows easy selection of an individual package when outputs are OR-tied.

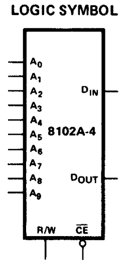
The Intel® 8102A-4 is fabricated with N-channel silicon gate technology. This technology allows the design and production of high performance, easy-to-use MOS circuits and provides a higher functional density on a monolithic chip than either conventional MOS technology or P-channel silicon gate technology.

Intel's silicon gate technology also provides excellent protection against contamination. This permits the use of low cost silicone packaging.

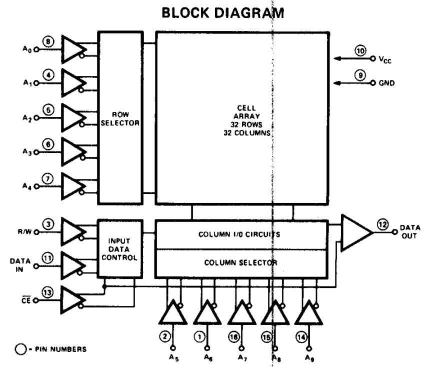
PIN CONFIGURATION



LOGIC SYMBOL



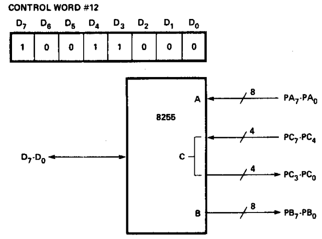
BLOCK DIAGRAM



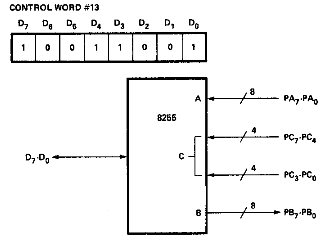
PIN NAMES

D_{IN}	DATA INPUT	$\overline{CE}$	CHIP ENABLE
A_0-A_9	ADDRESS INPUTS	D_{OUT}	DATA OUTPUT
R/W	READ/WRITE INPUT	V_{CC}	POWER (+5V)

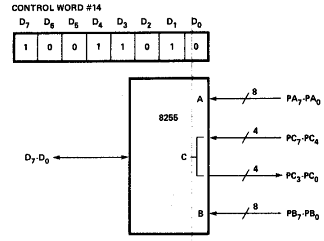
CONTROL WORD #12



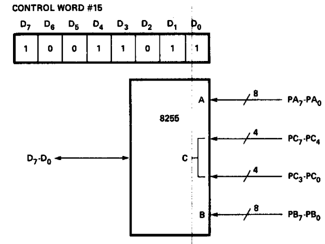
CONTROL WORD #13



CONTROL WORD #14



CONTROL WORD #15



Operating Modes

Mode 1 (Strobed Input/Output)

This functional configuration provides a means for transferring I/O data to or from a specified port in conjunction with strobes or "handshaking" signals. In Mode 1, Port A and Port B use the lines on Port C to generate or accept these "handshaking" signals.

Mode 1 Basic Functional Definitions:

- Two Groups (Group A and Group B)
- Each group contains one 8-bit data port and one 4-bit control/data port.
- The 8-bit data port can be either input or output. Both inputs and outputs are latched.
- The 4-bit port is used for control and status of the 8-bit data port.

A. C. Characteristics T_A = 0°C to 70°C, V_{CC} = 5V ±5% unless otherwise specified

Symbol	Parameter	Limits Min.	Typ.[1]	Max.	Unit
READ CYCLE					
t_{RC}	Read Cycle	450			ns
t_A	Access Time			450	ns
t_{CO}	Chip Enable to Output Time			230	ns
t_{OH1}	Previous Read Data Valid with Respect to Address	40			ns
t_{OH2}	Previous Read Data Valid with Respect to Chip Enable	0			ns
WRITE CYCLE					
t_{WC}	Write Cycle	450			ns
t_{AW}	Address to Write Setup Time	20			ns
t_{WP}	Write Pulse Width	300			ns
t_{WR}	Write Recovery Time	0			ns
t_{DW}	Data Setup Time	300			ns
t_{DH}	Data Hold Time	0			ns
t_{CW}	Chip Enable to Write Setup Time	300			ns

NOTE: 1. Typical values are for T_A = 25°C and nominal supply voltage.

A.C. CONDITIONS OF TEST

Input Pulse Levels:		0.8 Volt to 2.0 Volt
Input Rise and Fall Times:		10nsec
Timing Measurement Reference Levels	Inputs:	1.5 Volts
	Output:	0.8 and 2.0 Volts
Output Load:		1 TTL Gate and C_L = 100 pF

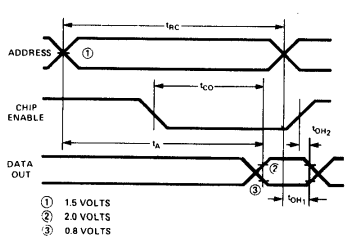
Capacitance[2] T_A = 25°C, f = 1MHz

SYMBOL	TEST	LIMITS (pF) TYP.[1]	MAX.
C_{IN}	INPUT CAPACITANCE (ALL INPUT PINS) V_{IN} = 0V	3	5
C_{OUT}	OUTPUT CAPACITANCE V_{OUT} = 0V	7	10

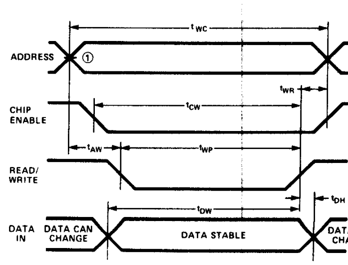
NOTE: 2. This parameter is periodically sampled and is not 100% tested.

Waveforms

READ CYCLE



WRITE CYCLE



Output Control Signal Definition

$\overline{OBF}$ (Output Buffer Full F/F)

The $\overline{OBF}$ output will go "low" to indicate that the CPU has written data out to the specified port. The OBF F/F will be set by the rising edge of the WR input and reset by the falling edge of the $\overline{ACK}$ input signal.

$\overline{ACK}$ (Acknowledge Input)

A "low" on this input informs the 8255 that the data from Port A or Port B has been accepted. In essence, a response from the peripheral device indicating that it has received the data output by the CPU.

INTR (Interrupt Request)

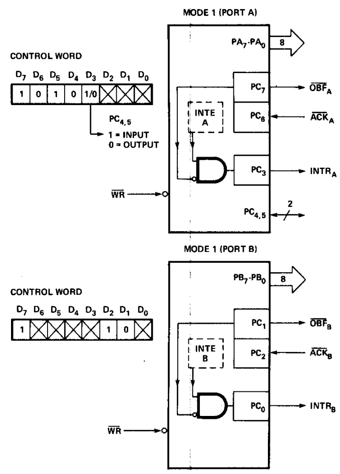
A "high" on this output can be used to interrupt the CPU when an output device has accepted data transmitted by the CPU. INTR is set by the rising edge of $\overline{ACK}$ if $\overline{OBF}$ is a "one" and INTE is a "one". It is reset by the falling edge of $\overline{WR}$.

INTE A

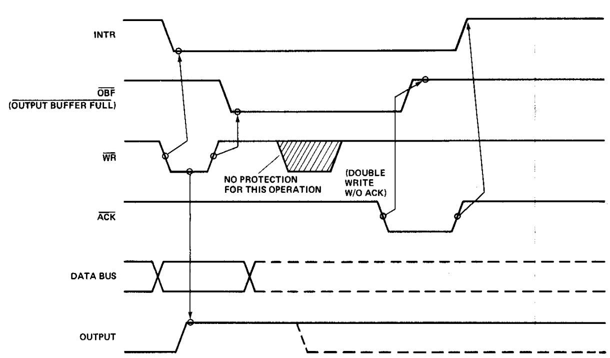
Controlled by bit set/reset of PC_6.

INTE B

Controlled by bit set/reset of PC_2.



Mode 1 Output



Basic Timing Output

intel® Silicon Gate MOS **8107B-4**

FULLY DECODED RANDOM ACCESS 4096 BIT DYNAMIC MEMORY

* Access Time -- 270 ns max.
* Read, Write Cycle Times -- 470 ns max.
* Refresh Period -- 2 ms

- **Low Cost Per Bit**
- **Low Standby Power**
- **Easy System Interface**
- **Only One High Voltage Input Signal — Chip Enable**
- **TTL Compatible -- All Address, Data, Write Enable, Chip Select Inputs**
- **Read-Modify-Write Cycle Time -- 590 ns**
- **Address Registers Incorporated on the Chip**
- **Simple Memory Expansion — Chip Select Input Lead**
- **Fully Decoded — On Chip Address Decode**
- **Output is Three State and TTL Compatible**
- **Industry Standard 22-Pin Configuration**

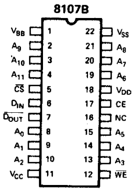
The Intel 8107B is a 4096 word by 1 bit dynamic n-channel MOS RAM. It was designed for memory applications where very low cost and large bit storage are important design objectives. The 8107B uses dynamic circuitry which reduces the standby power dissipation.

Reading information from the memory is non-destructive. Refreshing is most easily accomplished by performing one read cycle on each of the 64 row addresses. Each row address must be refreshed every two milliseconds. The memory is refreshed whether Chip Select is a logic one or a logic zero.

The 8107B is fabricated with n-channel silicon gate technology. This technology allows the design and production of high performance, easy to use MOS circuits and provides a higher functional density on a monolithic chip than other MOS technologies. The 8107B uses a single transistor cell to achieve high speed and low cost. It is a replacement for the 8107B.

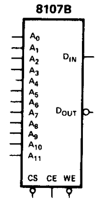
PIN CONFIGURATION

8107B



LOGIC SYMBOL

8107B

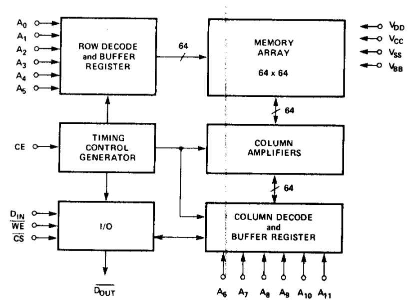


PIN NAMES

A_0-A_{11}	ADDRESS INPUTS*	V_{BB}	POWER (-5V)
CE	CHIP ENABLE	V_{CC}	POWER (+5V)
$\overline{CS}$	CHIP SELECT	V_{DD}	POWER (+12V)
D_{IN}	DATA INPUT	V_{SS}	GROUND
$\overline{D_{OUT}}$	DATA OUTPUT	$\overline{WE}$	WRITE ENABLE
NC	NOT CONNECTED		

*Refresh Address A_0-A_5.

BLOCK DIAGRAM



MODE DEFINITION SUMMARY TABLE

	MODE 0		MODE 1		MODE 2
	IN	OUT	IN	OUT	GROUP A ONLY
PA_0	IN	OUT	IN	OUT	←→
PA_1	IN	OUT	IN	OUT	←→
PA_2	IN	OUT	IN	OUT	←→
PA_3	IN	OUT	IN	OUT	←→
PA_4	IN	OUT	IN	OUT	←→
PA_5	IN	OUT	IN	OUT	←→
PA_6	IN	OUT	IN	OUT	←→
PA_7	IN	OUT	IN	OUT	←→
PB_0	IN	OUT	IN	OUT	—
PB_1	IN	OUT	IN	OUT	—
PB_2	IN	OUT	IN	OUT	—
PB_3	IN	OUT	IN	OUT	—
PB_4	IN	OUT	IN	OUT	—
PB_5	IN	OUT	IN	OUT	—
PB_6	IN	OUT	IN	OUT	—
PB_7	IN	OUT	IN	OUT	—
PC_0	IN	OUT	$INTR_B$	$INTR_B$	I/O
PC_1	IN	OUT	IBF_B	$\overline{OBF}_B$	I/O
PC_2	IN	OUT	$\overline{STB}_B$	$\overline{ACK}_B$	I/O
PC_3	IN	OUT	$INTR_A$	$INTR_A$	$INTR_A$
PC_4	IN	OUT	$\overline{STB}_A$	I/O	$\overline{STB}_A$
PC_5	IN	OUT	IBF_A	I/O	IBF_A
PC_6	IN	OUT	I/O	$\overline{ACK}_A$	$\overline{ACK}_A$
PC_7	IN	OUT	I/O	$\overline{OBF}_A$	$\overline{OBF}_A$

(Mode 2, PB_0–PB_7: MODE 0 OR MODE 1 ONLY)

Special Mode Combination Considerations

There are several combinations of modes when not all of the bits in Port C are used for control or status. The remaining bits can be used as follows:

If Programmed as Inputs –
All input lines can be accessed during a normal Port C read.

If Programmed as Outputs –
Bits in C upper (PC_7-PC_4) must be individually accessed using the bit set/reset function.

Bits in C lower (PC_3-PC_0) can be accessed using the bit set/reset function or accessed as a threesome by writing into Port C.

Source Current Capability on Port B and Port C

Any set of eight output buffers, selected randomly from Ports B and C can source 1mA at 1.5 volts. This feature allows the 8255 to directly drive Darlington type drivers and high-voltage displays that require such source current.

Reading Port C Status

In Mode 0, Port C transfers data to or from the peripheral device. When the 8255 is programmed to function in Modes 1 or 2, Port C generates or accepts "hand-shaking" signals with the peripheral device. Reading the contents of Port C allows the programmer to test or verify the "status" of each peripheral device and change the program flow accordingly.

There is no special instruction to read the status information from Port C. A normal read operation of Port C is executed to perform this function.

INPUT CONFIGURATION

D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0
I/O	I/O	IBF_A	$INTE_A$	$INTR_A$	$INTE_B$	IBF_B	$INTR_B$
GROUP A					GROUP B		

OUTPUT CONFIGURATION

D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0
$\overline{OBF}_A$	$INTE_A$	I/O	I/O	$INTR_A$	$INTE_B$	$\overline{OBF}_B$	$INTR_B$
GROUP A					GROUP B		

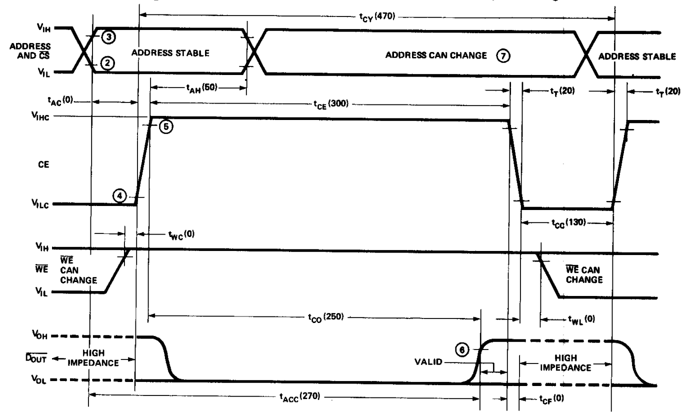
Mode 1 Status Word Format

D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0
$\overline{OBF}_A$	$INTE_1$	IBF_A	$INTE_2$	$INTR_A$	X	X	X
GROUP A					GROUP B		

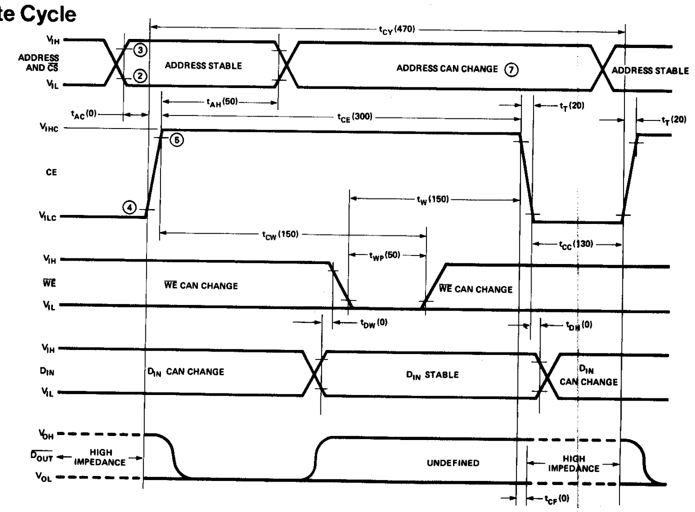
(DEFINED BY MODE 0 OR MODE 1 SELECTION)

Mode 2 Status Word Format

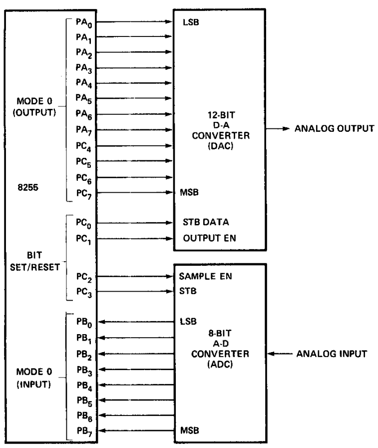
Read and Refresh Cycle [1] (Numbers in parentheses are for minimum cycle timing in ns)



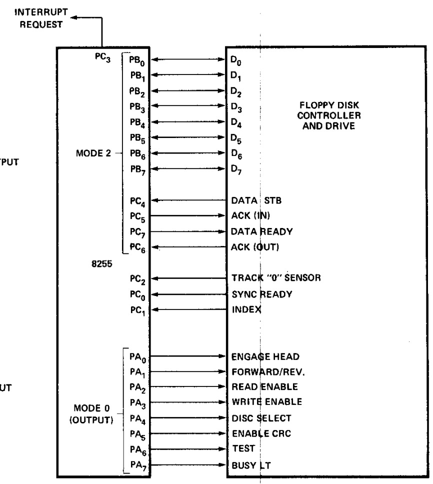
Write Cycle



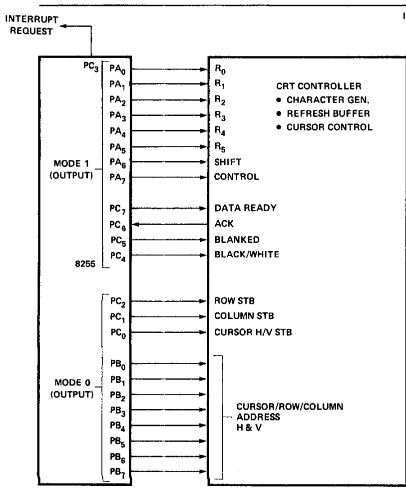
NOTES:
1. For Refresh cycle row and column addresses must be stable before t_{AC} and remain stable for entire t_{AH} period.
2. V_{IL} MAX is the reference level for measuring timing of the addresses, $\overline{CS}$, $\overline{WE}$, and D_{IN}.
3. V_{IH} MIN is the reference level for measuring timing of the addresses, $\overline{CS}$, $\overline{WE}$, and D_{IN}.
4. V_{SS} +2.0V is the reference level for measuring timing of CE.
5. V_{DD} −2V is the reference level for measuring timing of CE.
6. V_{SS} +2.0V is the reference level for measuring the timing of $\overline{D_{OUT}}$.
7. During CE high typically 0.5mA will be drawn from any address pin which is switched from low to high.



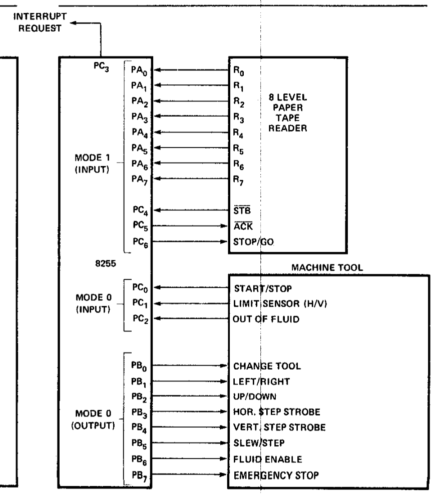
Digital to Analog, Analog to Digital



Basic Floppy Disc Interface



Basic CRT Controller Interface



Machine Tool Controller Interface

Typical Characteristics

Fig. 1. I_{DD} AV VS. TEMPERATURE

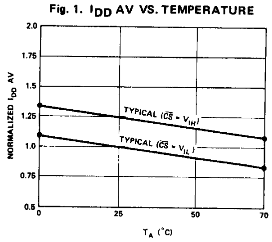


Fig. 2. TYPICAL I_{DD} AVERAGE VS. CYCLE TIME

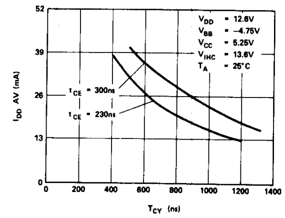


Fig. 3. I_{DD2} VS. TEMPERATURE

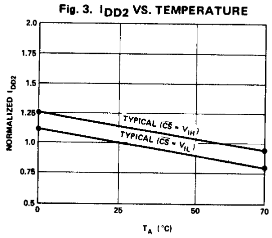


Fig. 4. TYPICAL V_{IL} MAX VS. CE RISE TIME

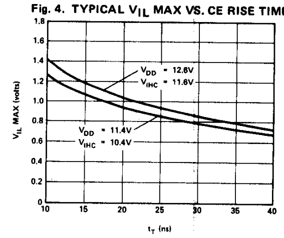


Fig. 5. TYPICAL I_{OH} VS. V_{OH}

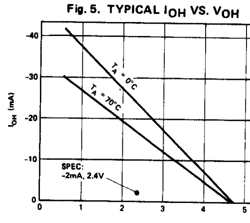


Fig. 6. TYPICAL I_{OL} VS. V_{OL}

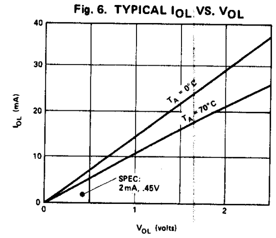


Fig. 7. TYPICAL REFRESH VS. TEMPERATURE

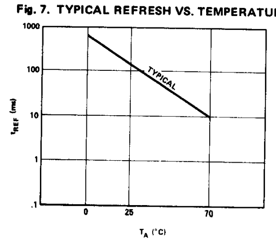
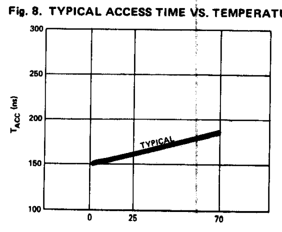


Fig. 8. TYPICAL ACCESS TIME VS. TEMPERATURE



D.C. CHARACTERISTICS $T_A = 0°C$ to $70°C$; $V_{CC} = +5V \pm 5\%$; $V_{SS} = 0V$

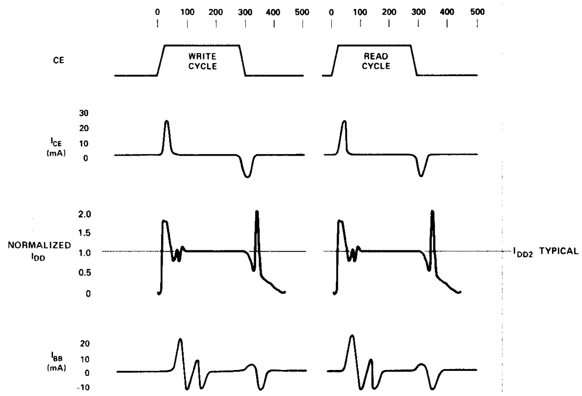
Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
V_{IL}	Input Low Voltage			.8	V	
V_{IH}	Input High Voltage	2.0			V	
V_{OL}	Output Low Voltage			.4	V	$I_{OL} = 1.6mA$
V_{OH}	Output High Voltage	2.4			V	$I_{OH} = -50\mu A$ ($-100\mu A$ for D.B. Port)
I_{OH}[1]	Darlington Drive Current		2.0		mA	$V_{OH} = 1.5V$, $R_{EXT} = 390\Omega$
I_{CC}	Power Supply Current		40		mA	

NOTE:
1. Available on 8 pins only.

A.C. CHARACTERISTICS $T_A = 0°C$ to $70°C$; $V_{CC} = +5V \pm 5\%$; $V_{SS} = 0V$

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Condition
t_{WP}	Pulse Width of $\overline{WR}$			430	ns	
t_{DW}	Time D.B. Stable Before $\overline{WR}$	10			ns	
t_{WD}	Time D.B. Stable After $\overline{WR}$	65			ns	
t_{AW}	Time Address Stable Before $\overline{WR}$	20			ns	
t_{WA}	Time Address Stable After $\overline{WR}$	35			ns	
t_{CW}	Time CS Stable Before $\overline{WR}$	20			ns	
t_{WC}	Time CS Stable After $\overline{WR}$	35			ns	
t_{WB}	Delay From $\overline{WR}$ To Output			500	ns	
t_{RP}	Pulse Width of $\overline{RD}$	430			ns	
t_{IR}	$\overline{RD}$ Set-Up Time	50			ns	
t_{HR}	Input Hold Time	50			ns	
t_{RD}	Delay From $\overline{RD}$ = 0 To System Bus	350			ns	
t_{OD}	Delay From $\overline{RD}$ = 1 To System Bus	150			ns	
t_{AR}	Time Address Stable Before $\overline{RD}$	50			ns	
t_{CR}	Time $\overline{CS}$ Stable Before $\overline{RD}$	50			ns	
t_{AK}	Width Of $\overline{ACK}$ Pulse	500			ns	
t_{ST}	Width Of $\overline{STB}$ Pulse	350			ns	
t_{PS}	Set-Up Time For Peripheral	150			ns	
t_{PH}	Hold Time For Peripheral	150			ns	
t_{RA}	Hold Time for A_1, A_0 After $\overline{RD}$ = 1	379			ns	
t_{RC}	Hold Time For CS After $\overline{RD}$ = 1	5			ns	
t_{AD}	Time From $\overline{ACK}$ = 0 To Output (Mode 2)			500	ns	
t_{KD}	Time From $\overline{ACK}$ = 1 To Output Floating			300	ns	
t_{WO}	Time From $\overline{WR}$ = 1 To $\overline{OBF}$ = 0			300	ns	
t_{AO}	Time From $\overline{ACK}$ = 0 To $\overline{OBF}$ = 1			500	ns	
t_{SI}	Time From $\overline{STB}$ = 0 To IBF			600	ns	
t_{RI}	Time From $\overline{RD}$ = 1 To IBF = 0			300	ns	

Typical Current Transients vs. Time



Applications

Refresh

The 8107B-4 is refreshed by either a read cycle, write cycle, or read-modify write cycle. Only the selected row of memory array is refreshed. The row address is selected by the input signals A_0 thru A_5. Each individual row address must receive at least one refresh cycle within any two milliseconds time period.

If a read cycle is used for refreshing, then the chip select input, $\overline{CS}$, can be a logic high or a logic low. If a write cycle or read-modify write cycle is used to refresh the device, then $\overline{CS}$ must be a logic high. This will prevent writing into the memory during refresh.

Power Dissipation

The operating power dissipation of a selected device is the sum of $V_{DD} \times I_{DDAV}$ and $V_{BB} \times I_{BB}$. For a cycle of 400ns and t_{CE} of 230ns typical power dissipation is 456mW.

Standby Power

The 8107B-4 is a dynamic RAM therefore when $V_{CE} = V_{ILC}$ very little power is dissipated. In a typical system most devices are in standby with V_{CE} at V_{ILC}. During this time only leakage currents flow (i.e., I_{DD1}, I_{CC1}, I_{BB}, I_{LO}, I_{L1}). The power dissipated during this inactive period is typically 1.4mW. The typical power dissipation required to perform refresh during standby is the refresh duty cycle, 1.3%, multiplied by the operating power dissipation, or 5.9mW. The total power dissipation during standby is then 7.3mW typical.

System Interfaces and Filtering

On the following page is an example of a 16K x 8 bit memory system. Device decoding is done with the CE input. All devices are unselected during refresh with CS. It is recommended that 1μF high frequency, low inductance capacitors be used on double sided boards. V_{CC} to V_{SS} decoupling is required only on the devices located around the periphery of the array. For each 36 devices a 100μF tantalum or equivalent capacitor should be placed from V_{DD} to V_{SS} close to the array.

intel Silicon Gate CMOS 5101, 5101-3, 5101L, 5101L-3

1024 BIT (256 x 4) STATIC CMOS RAM

*Ultra Low Standby Current: 15 nA/Bit for the 5101

- **Fast Access Time — 650 ns**
- **Single +5 V Power Supply**
- **CE_2 Controls Unconditional Standby Mode**
- **Directly TTL Compatible — All Inputs and Outputs**
- **Three-State Output**

The Intel® 5101 and 5101-3 are ultra-low power 1024 bit (256 words x 4-bits) static RAMs fabricated with an advanced ion-implanted silicon gate CMOS technology. The devices have two chip enable inputs. When CE_2 is at a low level, the minimum standby current is drawn by these devices, regardless of any other input transitions on the addresses and other control inputs. Also, when $\overline{CE_1}$ is at a high level and address and other control transitions are inhibited, the minimum standby current is drawn by these devices. When in standby the 5101 and 5101-3 draw from the single 5 volt supply only 15 microamps and 200 microamps, respectively. These devices are ideally suited for low power applications where battery operation or battery backup for non-volatility are required.

The 5101 and 5101-3 use fully DC stable (static) circuitry; it is not necessary to pulse chip select for each address transition. The data is read out non-destructively and has the same polarity as the input data. All inputs and outputs are directly TTL compatible. The 5101 and 5101-3 have separate data input and data output terminals. An output disable function is provided so that the data inputs and outputs may be wire OR-ed for use in common data I/O systems.

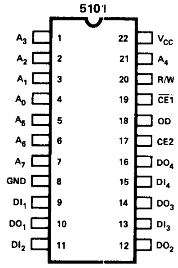
The 5101L and 5101L-3 are identical to the 5101 and 5101-3, respectively, with the additional feature of guaranteed data retention at a power supply voltage as low as 2.0 volts.

A pin compatible N-channel static RAM, the Intel 2101, is also available for low cost applications where a 256 x 4 organization is needed.

The Intel ion-implanted, silicon gate, complementary MOS (CMOS) allows the design and production of ultra-low power, high performance memories.

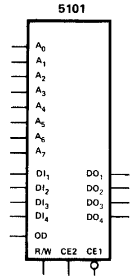
PIN CONFIGURATION

5101



LOGIC SYMBOL

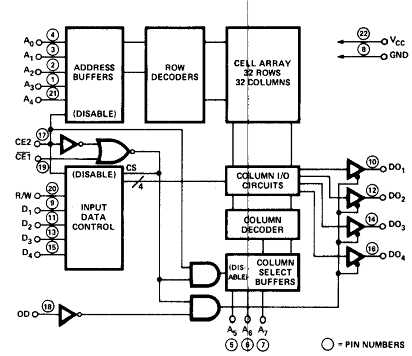
5101



PIN NAMES

DI_1 - DI_4	DATA INPUT	OD	OUTPUT DISABLE
$A_0 - A_7$	ADDRESS INPUTS	$DO_1 - DO_4$	DATA OUTPUT
R/W	READ/WRITE INPUT	V_{CC}	POWER (+5V)
$\overline{CE1}$, CE2	CHIP ENABLE		

BLOCK DIAGRAM



8251 BASIC FUNCTIONAL DESCRIPTION

General

The 8251 is a Universal Synchronous/Asynchronous Receiver/Transmitter designed specifically for the 8080 Microcomputer System. Like other I/O devices in the 8080 Microcomputer System its functional configuration is programmed by the systems software for maximum flexibility. The 8251 can support virtually any serial data technique currently in use (including IBM "bi-sync").

In a communication environment an interface device must convert parallel format system data into serial format for transmission and convert incoming serial format data into parallel system data for reception. The interface device must also delete or insert bits or characters that are functionally unique to the communication technique. In essence, the interface should appear "transparent" to the CPU, a simple input or output of byte-oriented system data.

Data Bus Buffer

This 3-state, bi-directional, 8-bit buffer is used to interface the 8251 to the 8080 system Data Bus. Data is transmitted or received by the buffer upon execution of INput or OUTput instructions of the 8080 CPU. Control words, Command words and Status information are also transferred through the Data Bus Buffer.

Read/Write Control Logic

This functional block accepts inputs from the 8080 Control bus and generates control signals for overall device operation. It contains the Control Word Register and Command Word Register that store the various control formats for device functional definition.

RESET (Reset)

A "high" on this input forces the 8251 into an "Idle" mode. The device will remain at "Idle" until a new set of control words is written into the 8251 to program its functional definition.

CLK (Clock)

The CLK input is used to generate internal device timing and is normally connected to the Phase 2 (TTL) output of the 8224 Clock Generator. No external inputs or outputs are referenced to CLK but the frequency of CLK must be greater than 30 times the Receiver or Transmitter clock inputs for synchronous mode (4.5 times for asynchronous mode).

$\overline{WR}$ (Write)

A "low" on this input informs the 8251 that the CPU is outputting data or control words, in essence, the CPU is writing out to the 8251.

$\overline{RD}$ (Read)

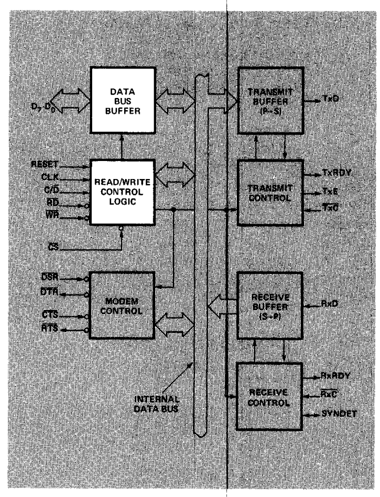
A "low" on this input informs the 8251 that the CPU is inputting data or status information, in essence, the CPU is reading from the 8251.

C/$\overline{D}$ (Control/Data)

This input, in conjunction with the $\overline{WR}$ and $\overline{RD}$ inputs informs the 8251 that the word on the Data Bus is either a data character, control word or status information.
1 = CONTROL 0 = DATA

$\overline{CS}$ (Chip Select)

A "low" on this input enables the 8251. No reading or writing will occur unless the device is selected.



C/$\overline{D}$	$\overline{RD}$	$\overline{WR}$	$\overline{CS}$	
0	0	1	0	8251 ⇒ DATA BUS
0	1	0	0	DATA BUS ⇒ 8251
1	0	1	0	STATUS ⇒ DATA BUS
1	1	0	0	DATA BUS ⇒ CONTROL
X	X	X	1	DATA BUS ⇒ 3-STATE

A.C. Characteristics for 5101, 5101-3, 5101L, 5101L-3

READ CYCLE $T_A = 0°C$ to $70°C$, $V_{CC} = 5V \pm 5\%$, unless otherwise specified.

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
t_{RC}	Read Cycle	650			ns	(See below)
t_A	Access Time			650	ns	
t_{CO1}	Chip Enable ($\overline{CE1}$) to Output			600	ns	
t_{CO2}	Chip Enable (CE2) to Output			700	ns	
t_{OD}	Output Disable To Output			350	ns	
t_{DF}	Data Output to High Z State	0		150	ns	
t_{OH1}	Previous Read Data Valid with Respect to Address Change	0			ns	
t_{OH2}	Previous Read Data Valid with Respect to Chip Enable	0			ns	

WRITE CYCLE

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
t_{WC}	Write Cycle	650			ns	(See below)
t_{AW}	Write Delay	150			ns	
t_{CW1}	Chip Enable ($\overline{CE1}$) To Write	550			ns	
t_{CW2}	Chip Enable (CE2) To Write	550			ns	
t_{DW}	Data Setup	400			ns	
t_{DH}	Data Hold	100			ns	
t_{WP}	Write Pulse	400			ns	
t_{WR}	Write Recovery	50			ns	
t_{DS}	Output Disable Setup	150			ns	

A. C. CONDITIONS OF TEST

Input Pulse Levels: +0.65 Volt to 2.2 Volt

Input Pulse Rise and Fall Times: 20nsec

Timing Measurement Reference Level: 1.5 Volt

Output Load: 1 TTL Gate and C_L = 100pF

Capacitance[2] $T_A = 25°C$, f = 1 MHz

Symbol	Test	Limits (pF) Typ.	Limits (pF) Max.
C_{IN}	Input Capacitance (All Input Pins) $V_{IN} = 0V$	4	8
C_{OUT}	Output Capacitance $V_{OUT} = 0V$	8	12

Receiver Buffer

The Receiver accepts serial data, converts this serial input to parallel format, checks for bits or characters that are unique to the communication technique and sends an "assembled" character to the CPU. Serial data is input to the RxD pin.

Receiver Control

This functional block manages all receiver-related activities.

RxRDY (Receiver Ready)

This output indicates that the 8251 contains a character that is ready to be input to the CPU. RxRDY can be connected to the interrupt structure of the CPU or for Polled operation the CPU can check the condition of RxRDY using a status read operation. RxRDY is automatically reset when the character is read by the CPU.

$\overline{\text{RxC}}$ (Receiver Clock)

The Receiver Clock controls the rate at which the character is to be received. In Synchronous Mode, the frequency of $\overline{\text{RxC}}$ is equal to the actual Baud Rate (1x). In Asynchronous Mode, the frequency of $\overline{\text{RxC}}$ is a multiple of the actual Baud Rate. A portion of the mode instruction selects the value of the multiplier; it can be 1x, 16x or 64x the Baud Rate.

For Example: If Baud Rate equals 300 Baud,
$\overline{\text{RxC}}$ equals 300 Hz (1x)
$\overline{\text{RxC}}$ equals 4800 Hz (16x)
$\overline{\text{RxC}}$ equals 19.2 kHz (64x).
If Baud Rate equals 2400 Baud,
$\overline{\text{RxC}}$ equals 2400 Hz (1x)
$\overline{\text{RxC}}$ equals 38.4 kHz (16x)
$\overline{\text{RxC}}$ equals 153.6 kHz (64x).

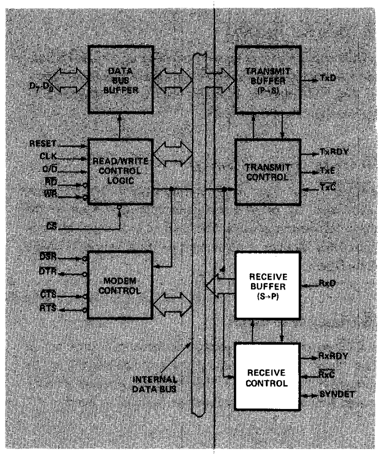
Data is sampled into the 8251 on the rising edge of $\overline{\text{RxC}}$.

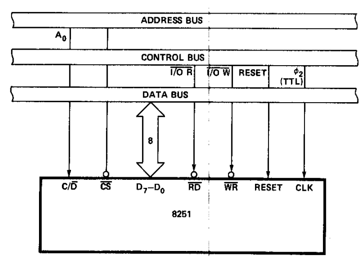
NOTE: In most communications systems, the 8251 will be handling both the transmission and reception operations of a single link. Consequently, the Receive and Transmit Baud Rates will be the same. Both $\overline{\text{TxC}}$ and $\overline{\text{RxC}}$ will require identical frequencies for this operation and can be tied together and connected to a single frequency source (Baud Rate Generator) to simplify the interface.

SYNDET (SYNC Detect)

This pin is used in SYNChronous Mode only. It is used as either input or output, programmable through the Control Word. It is reset to "low" upon RESET. When used as an output (internal Sync mode), the SYNDET pin will go "high" to indicate that the 8251 has located the SYNC character in the Receive mode. If the 8251 is programmed to use double Sync characters (bi-sync), then SYNDET will go "high" in the middle of the last bit of the second Sync character. SYNDET is automatically reset upon a Status Read operation.

When used as an input, (external SYNC detect mode), a positive going signal will cause the 8251 to start assembling data characters on the falling edge of the next $\overline{\text{RxC}}$. Once in SYNC, the "high" input signal can be removed. The duration of the high signal should be at least equal to the period of $\overline{\text{RxC}}$.





8251 Interface to 8080 Standard System Bus

Schottky Bipolar 8210

TTL-TO-MOS LEVEL SHIFTER AND HIGH VOLTAGE CLOCK DRIVER

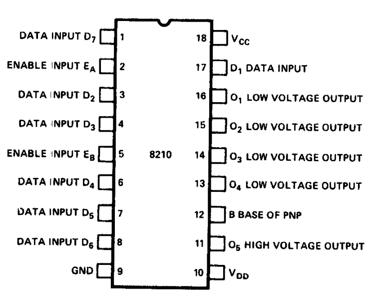
- **Four Low Voltage Drivers**
- **One High Voltage Driver**
- **TTL and DTL Compatible Inputs**
- **Outputs Compatible with 8107A MOS Memories**
- **Operates from Standard Bipolar and MOS Power Supplies**
- **Maximum MOS Device Protection — Output Clamp Diodes**

The Intel® 8210 is a Bipolar-to-MOS level shifter and high voltage driver which accepts TTL and DTL inputs. It contains four (4) low voltage drivers and one high voltage driver, each with current driving capabilities suitable for driving N-channel MOS memory devices. The 8210 is particularly suitable for driving the 8107A N-channel MOS memory chips. The 8210 operates from the 5 volt and 12 volt power supplies used to bias the memory devices.

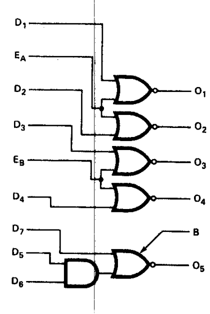
The four low voltage drivers feature two common enable inputs per pair of drivers which permits address or data decoding. The high voltage driver swings the 12 volts required to drive the chip enable (clock) input for the 8107A.

The 8210 high voltage driver requires an externally connected PNP transistor. The PNP base is connected to pin 12, the collector to pin 11, and the emitter to pin 10 or V_{DD}. The use of a fast switching, high voltage, high current gain PNP, like the 2N5057 is recommended.

PIN CONFIGURATION



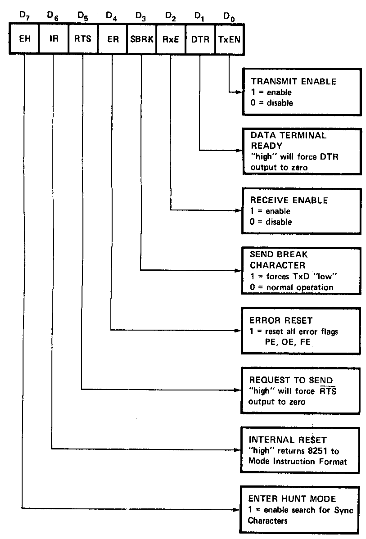
LOGIC SYMBOL



COMMAND INSTRUCTION DEFINITION

Once the functional definition of the 8251 has been programmed by the Mode Instruction and the Sync Characters are loaded (if in Sync Mode) then the device is ready to be used for data communication. The Command Instruction controls the actual operation of the selected format. Functions such as: Enable Transmit/Receive, Error Reset and Modem Controls are provided by the Command Instruction.

Once the Mode Instruction has been written into the 8251 and Sync characters inserted, if necessary, then all further "control writes" ($C/\overline{D}$ = 1) will load the Command Instruction. A Reset operation (internal or external) will return the 8251 to the Mode Instruction Format.



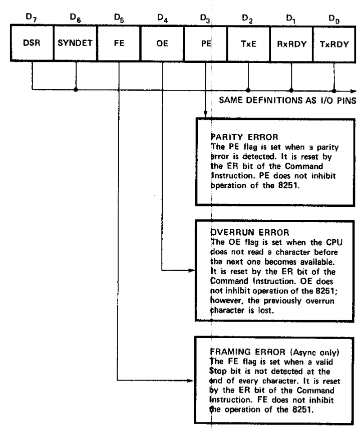
Command Instruction Format

STATUS READ DEFINITION

In data communication systems it is often necessary to examine the "status" of the active device to ascertain if errors have occurred or other conditions that require the processor's attention. The 8251 has facilities that allow the programmer to "read" the status of the device at any time during the functional operation.

A normal "read" command is issued by the CPU with the C/D input at one to accomplish this function.

Some of the bits in the Status Read Format have identical meanings to external output pins so that the 8251 can be used in a completely Polled environment or in an interrupt driven environment.



Status Read Format

Absolute Maximum Ratings*

Temperature Under Bias . . . . 0°C to 70°C
Storage Temperature . . . . –65°C to +150°C
Supply Voltage, V_{CC} . . . . –0.5 to +7V
Supply Voltage, V_{DD} . . . . –0.5 to +13V
All Input Voltages . . . . –1.0 to +5.5V
Outputs for Low Voltage Drivers . . . . –0.5 to +7V
Outputs for Clock Driver . . . . –1.0 to +13V
Power Dissipation at 25°C 2W

*COMMENT: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

D.C. Characteristics T_A = 0°C to 70°C, V_{CC} = 5.0V ± 5%, V_{DD} = 12V ± 5%

Symbol	Parameter	Min.	Max.	Unit	Test Conditions
I_{FD}	Data Input Load Current		–0.25	mA	V_F = 0.45V
I_{FE}	Enable Input Load Current		–0.50	mA	V_F = 0.45V
I_{RD}	Data Input Leakage Current		10	μA	V_R = 12.6V
I_{RE}	Enable Input Leakage Current		20	μA	V_R = 12.6V
V_{OL}	Output Low Voltage for all Drivers		0.45	V	I_{OL} = 3mA, V_{IH} = 2V
		–1.0		V	I_{OL} = –5mA
V_{OH1}	Output High Voltage for Low Voltage Drivers	V_{CC} –1.0		V	I_{OH} = –1mA, V_{IL} = 0.8V
			V_{CC} +1.0	V	I_{OH} = 5mA
V_{OH2}	Output High Voltage for High Voltage Driver	V_{DD} –0.75		V	I_{OH} = –1mA, V_{IL} = 0.8V
			V_{DD} + 0.5	V	I_{OH} = 5mA
I_{O1}	Pulsed Output Sink Current for Low Voltage Drivers	75		mA	V_O = 2V, V_{IH} = 2V
I_{O2}	Pulsed Output Sink Current for High Voltage Driver	100		mA	V_O = 3V, V_{IH} = 2V
I_{O3}	Pulsed Output Source Current for Low Voltage Drivers	–75		mA	V_O = V_{CC} –1.5V, V_{IL} = 0.8V
I_{O4}	Pulsed Output Source Current for High Voltage Driver	–100		mA	V_O = V_{DD} –3V, V_{IL} = 0.8V
V_{IL}	Input Low Voltage, All Inputs		0.8	V	
V_{IH}	Input High Voltage, All Inputs	2		V	

POWER SUPPLY CURRENT DRAIN AND POWER DISSIPATION

All driver outputs are in the state indicated

Symbol	Parameter	Typ.[1]	Max.	Unit	Test Conditions -- Input states to ensure the following output states: All Low Voltage Outputs	High Voltage Output	Additional Test Conditions
I_{CC1}	Current from V_{CC}	26	35	mA	Low	Low	V_{CC} = 5.25V, V_{DD} = 12.6V
I_{DD1}	Current from V_{DD}	12	16	mA	Low	Low	
P_{D1}	Power Dissipation	290	390	mW	Low	Low	
I_{CC2}	Current from V_{CC}	21	28	mA	Low	High	
I_{DD2}	Current from V_{DD}	26	35	mA	Low	High	
P_{D2}	Power Dissipation	450	600	mW	Low	High	
I_{CC3}	Current from V_{CC}	19	25	mA	High	Low	
I_{DD3}	Current from V_{DD}	12	16	mA	High	Low	
P_{D3}	Power Dissipation	260	340	mW	High	Low	
I_{CC4}	Current from V_{CC}	14	18	mA	High	High	
I_{DD4}	Current from V_{DD}	26	35	mA	High	High	
P_{D4}	Power Dissipation	410	550	mW	High	High	

[1] This parameter is periodically sampled and is not 100% tested. Condition of measurement is T_A = 25°C, V_{CC} = 5V, V_{DD} = 12V.

D.C. Characteristics:

T_A = 0°C to 70°C; V_{CC} = 5.0V ± 5%; V_{SS} = 0V

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
V_{IL}	Input Low Voltage	V_{SS}-.5		0.8	V	
V_{IH}	Input High Voltage	2.0		V_{CC}	V	
V_{OL}	Output Low Voltage			0.45	V	I_{OL} = 1.6mA
V_{OH}	Output High Voltage	2.2			V	I_{OH} = -100μA (DB_{0-7}) I_{OH} = -100μA (Others)
I_{DL}	Data Bus Leakage			50	μA	V_{OUT} = 4.5V
I_{LI}	Input Load Current			10	μA	@ 5.5V
I_{CC}	Power Supply Current		45	80		

Capacitance

T_A = 25°C; V_{CC} = V_{SS} = 0V

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
C_{IN}	Input Capacitance			10	pF	fc = 1MHz
$C_{I/O}$	I/O Capacitance			20	pF	Unmeasured pins returned to V_{SS}.

intel®

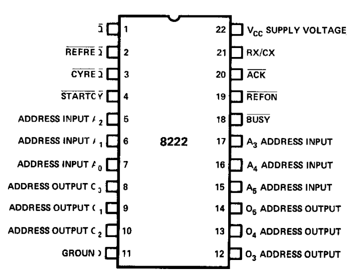
Schottky Bipolar 8222

DYNAMIC MEMORY REFRESH CONTROLLER

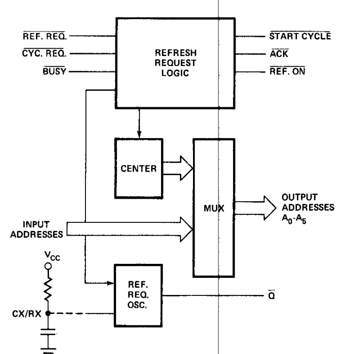
- **Adjustable Refresh Request Oscillator**
- **Ideal for 8107A, 8107B 4K RAM Refresh**
- **Internal Address Multiplexer**
- **Up to 6 Row Input Addresses (64 x 64 Organization)**

The 8222 is a refresh controller for dynamic RAMs requiring row refresh of up to 6 row input addresses (or 4K bits for 64 x 64 organization). The device contains an accurate refresh timer (whose frequency can be set by an external resistor and capacitor) plus all necessary control and I/O circuitry to provide for the refresh requirements of dynamic RAMs. The chip's high performance makes it especially suitable for use with high speed N-channel RAMs like the 8107B. The 8222 is designed for large, asynchronously driven, dynamic memory systems.

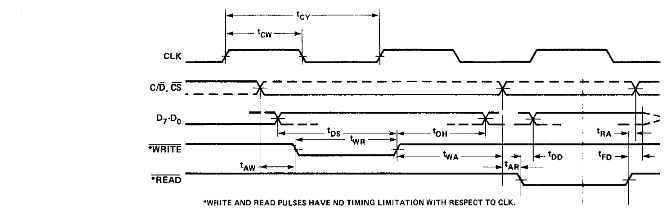
PIN CONFIGURATION



BLOCK DIAGRAM

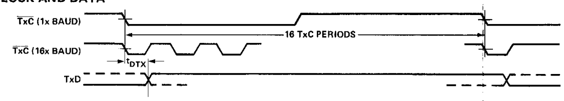


READ AND WRITE TIMING

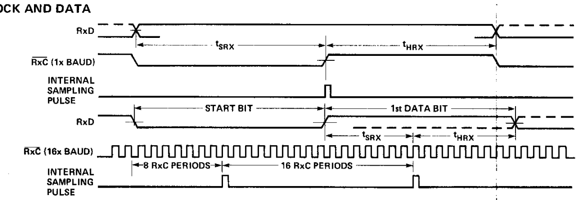


*WRITE AND READ PULSES HAVE NO TIMING LIMITATION WITH RESPECT TO CLK.

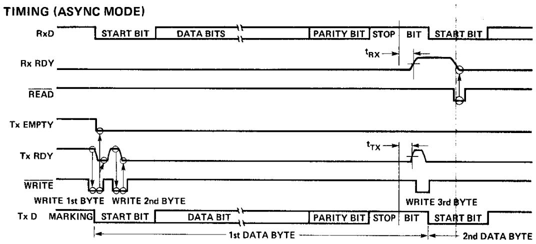
TRANSMITTER CLOCK AND DATA



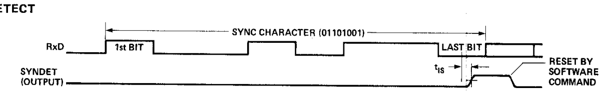
RECEIVER CLOCK AND DATA



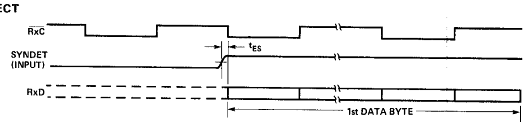
Tx RDY AND Rx RDY TIMING (ASYNC MODE)



INTERNAL SYNC DETECT



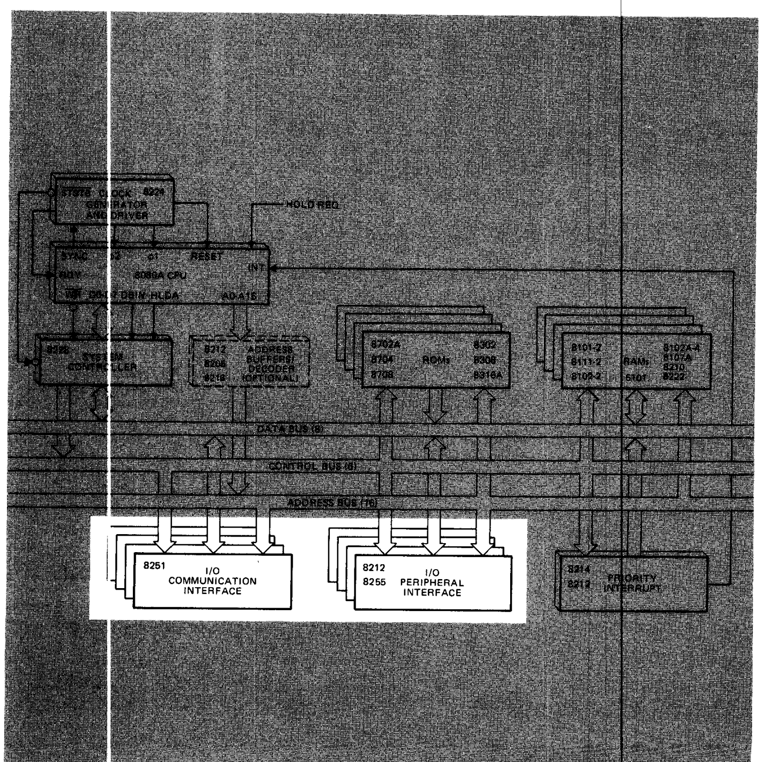
EXTERNAL SYNC DETECT



intel® Microcomputer Systems

I/O

8212
8255
8251



Logic Element Example

Probably the most overlooked application of the 8205 is that of a general purpose logic element. Using the "on-chip" enabling gate, the 8205 can be configured to gate its decoded outputs with system timing signals and generate strobes that can be directly connected to latches, flip-flops and one-shots that are used throughout the system.

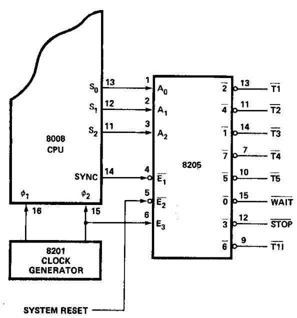
An excellent example of such an application is the "state decoder" in an 8008 CPU based system. The 8008 CPU issues three bits of information (S0, S1, S2) that indicate the nature of the data on the Data Bus during each machine state. Decoding of these signals is vital to generate strobes that can load the address latches, control bus discipline and general machine functions.

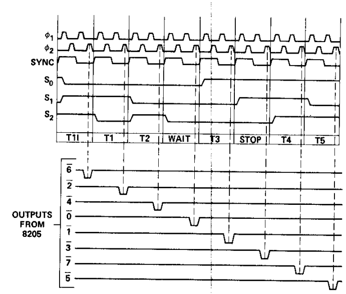
In the figure below a circuit is shown using the 8205 as the "state decoder" for an 8008 CPU that not only decodes the S0, S1, S2 outputs but gates these signals with the clock (phase 2) and the SYNC output of the 8008 CPU. The $\overline{T1}$ and $\overline{T2}$ decoded strobes can connect directly to devices like 8212s for latching the address information. The other decoded strobes can be used to generate signals to control the system data bus, memory timing functions and interrupt structure. RESET is connected to the enable gate so that strobes are not generated during system reset, eliminating accidental loading.

The power of such a circuit becomes evident when a single decoded strobe is logically broken down. Consider $\overline{T1}$ output, the boolean equation for it would be:

$$\overline{T1} = (\overline{S0} \cdot S1 \cdot \overline{S2}) \cdot (\overline{SYNC} \cdot \text{Phase } 2 \cdot \overline{\text{Reset}})$$

A six input NAND gate plus a few inverters would be needed to implement this function. The seven remaining outputs would need a similar circuit to duplicate their function, obviously a substantial savings in components can be achieved when using such a technique.





State Control Coding

S_0	S_1	S_2	STATE
0	1	0	T1
0	1	1	T1I
0	0	1	T2
0	0	0	WAIT
1	0	0	T3
1	1	0	STOP
1	1	1	T4
1	0	1	T5

Schottky Bipolar 8212

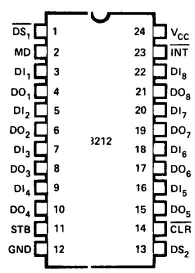
EIGHT-BIT INPUT/OUTPUT PORT

- **Fully Parallel 8-Bit Data Register and Buffer**
- **Service Request Flip-Flop for Interrupt Generation**
- **Low Input Load Current — .25 mA Max.**
- **Three State Outputs**
- **Outputs Sink 15 mA**
- **3.65V Output High Voltage for Direct Interface to 8080 CPU or 8008 CPU**
- **Asynchronous Register Clear**
- **Replaces Buffers, Latches and Multiplexers in Micro-computer Systems**
- **Reduces System Package Count**

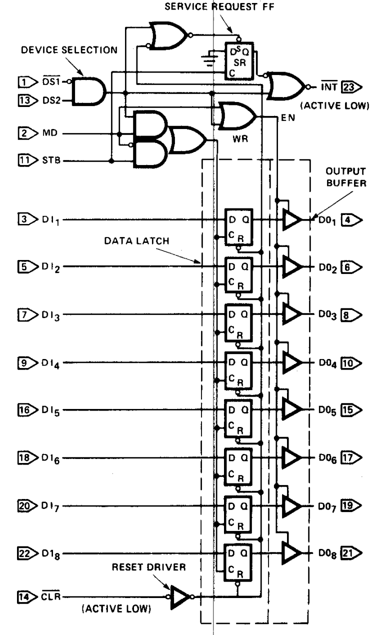
The 8212 input/output port consists of an 8-bit latch with 3-state output buffers along with control and device selection logic. Also included is a service request flip-flop for the generation and control of interrupts to the microprocessor.

The device is multimode in nature. It can be used to implement latches, gated buffers or multiplexers. Thus, all of the principal peripheral and input/output functions of a microcomputer system can be implemented with this device.

PIN CONFIGURATION



LOGIC DIAGRAM



PIN NAMES

DI_1-DI_8	DATA IN
DO_1-DO_8	DATA OUT
$\overline{DS_1}$-DS_2	DEVICE SELECT
MD	MODE
STB	STROBE
$\overline{INT}$	INTERRUPT (ACTIVE LOW)
$\overline{CLR}$	CLEAR (ACTIVE LOW)

8205 SWITCHING CHARACTERISTICS

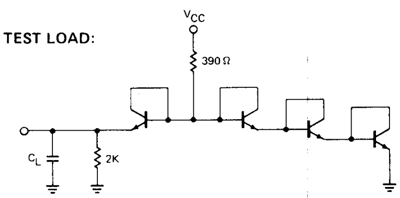
CONDITIONS OF TEST:

Input pulse amplitudes: 2.5V

Input rise and fall times: 5 nsec between 1V and 2V

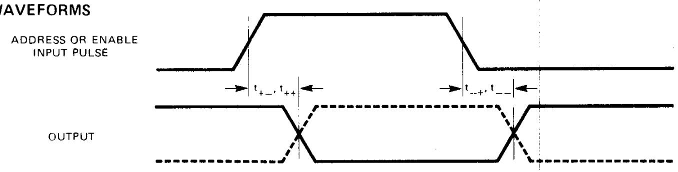
Measurements are made at 1.5V

TEST LOAD:



All Transistors 2N2369 or Equivalent. C_L = 30 pF

TEST WAVEFORMS



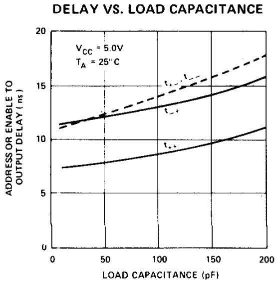
A.C. CHARACTERISTICS T_A = 0°C to +75°C, V_{CC} = 5.0V ±5% unless otherwise specified.

SYMBOL	PARAMETER		MAX. LIMIT	UNIT	TEST CONDITIONS
t_{++}	ADDRESS OR ENABLE TO OUTPUT DELAY		18	ns	
t_{-+}			18	ns	
t_{+-}			18	ns	
t_{--}			18	ns	
C_{IN} [1]	INPUT CAPACITANCE	P8205	4(typ.)	pF	f = 1 MHz, V_{CC} = 0V
		C8205	5(typ.)	pF	V_{BIAS} = 2.0V, T_A = 25°C

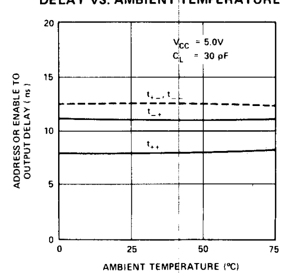
1. This parameter is periodically sampled and is not 100% tested.

TYPICAL CHARACTERISTICS

ADDRESS OR ENABLE TO OUTPUT DELAY VS. LOAD CAPACITANCE



ADDRESS OR ENABLE TO OUTPUT DELAY VS. AMBIENT TEMPERATURE



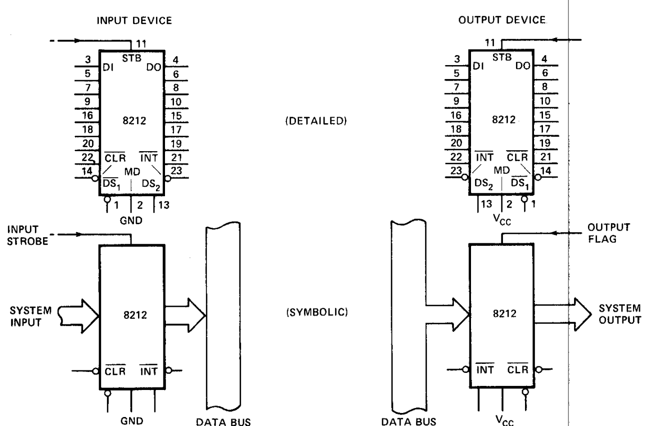
Applications Of The 8212 -- For Microcomputer Systems

I	Basic Schematic Symbol	VII	8080 Status Latch
II	Gated Buffer	VIII	8008 System
III	Bi-Directional Bus Driver	IX	8080 System:
IV	Interrupting Input Port		8 Input Ports
V	Interrupt Instruction Port		8 Output Ports
VI	Output Port		8 Level Priority Interrupt

I. Basic Schematic Symbols

Two examples of ways to draw the 8212 on system schematics—(1) the top being the detailed view showing pin numbers, and (2) the bottom being the symbolic view showing the system input or output as a system bus (bus containing 8 parallel lines). The output to the data bus is symbolic in referencing 8 parallel lines.

BASIC SCHEMATIC SYMBOLS



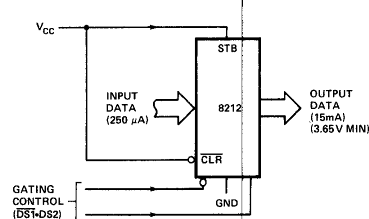
II. Gated Buffer (3 - STATE)

The simplest use of the 8212 is that of a gated buffer. By tying the mode signal low and the strobe input high, the data latch is acting as a straight through gate. The output buffers are then enabled from the device selection logic $\overline{DS1}$ and DS2.

When the device selection logic is false, the outputs are 3-state.

When the device selection logic is true, the input data from the system is directly transferred to the output. The input data load is 250 micro amps. The output data can sink 15 milli amps. The minimum high output is 3.65 volts.

GATED BUFFER
3-STATE



INTERRUPTS IN MICROCOMPUTER SYSTEMS

Microcomputer system design requires that I/O devices such as keyboards, displays, sensors and other components receive servicing in an efficient method so that large amounts of the total systems tasks can be assumed by the microcomputer with little or no effect on throughput.

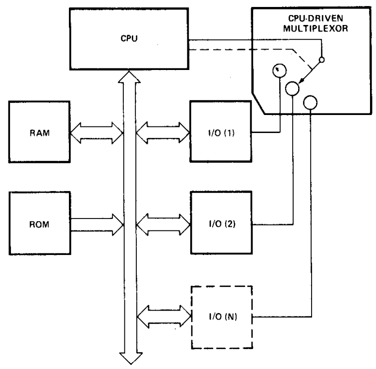
The most common method of servicing such devices is the **Polled** approach. This is where the processor must test each device in sequence and in effect "ask" each one if it needs servicing. It is easy to see that a large portion of the main program is looping through this continuence polling cycle and that such a method would have a serious, detrimental effect on system throughput thus limiting the tasks that could be assumed by the microcomputer and reducing the cost effectiveness of using such devices.

A more desireable method would be one that would allow the microprocessor to be executing its main program and only stop to service peripheral devices when it is told to do so by the device itself. In effect, the method would provide an external asynchronous input that would inform the processor that it should complete whatever instruction that is currently being executed and fetch a new routine that will service the requesting device. Once this servicing is complete however the processor would resume exactly where it left off.

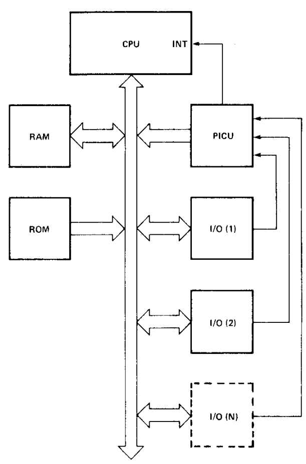
This method is called **Interrupt**. It is easy to see that system throughput would drastically increase, and thus more tasks could be assumed by the microcomputer to further enhance its cost effectiveness.

The Priority Interrupt Control Unit (PICU) functions as an overall manager in an Interrupt-Driven system environment. It accepts requests from the peripheral equipment, determines which of the incoming requests is of the highest importance (priority), ascertains whether the incoming request has a higher priority value than the level currently being serviced and issues an Interrupt to the CPU based on this determination.

Each peripheral device or structure usually has a special program or "routine" that is associated with its specific functional or operational requirements; this is referred to as a "service routine". The PICU, after issuing an Interrupt to the CPU, must somehow input information into the CPU that can "point" the Program Counter to the service routine associated with the requesting device. The PICU encodes the requesting level into such information for use as a "vector" to the correct Interrupt Service Routine.



Polled Method

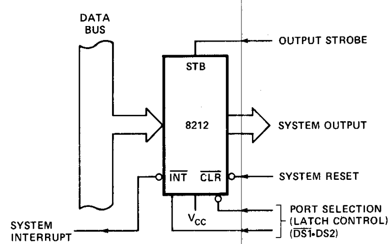


Interrupt Method

VI. Output Port (With Hand-Shaking)

The 8212 can be used to transmit data from the data bus to a system output. The output strobe could be a hand-shaking signal such as "reception of data" from the device that the system is outputting to. It in turn, can interrupt the system signifying the reception of data. The selection of the port comes from the device selection logic. ($\overline{DS1}$ • DS2)

OUTPUT PORT (WITH HAND-SHAKING)



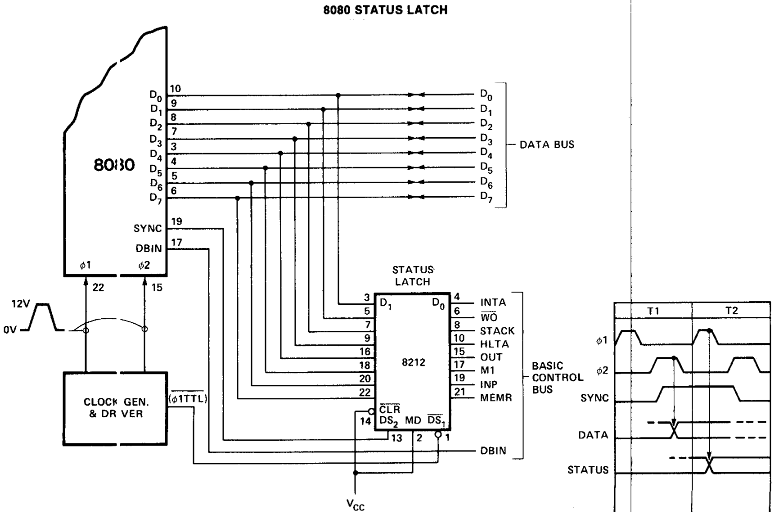
VII. 8080 Status Latch

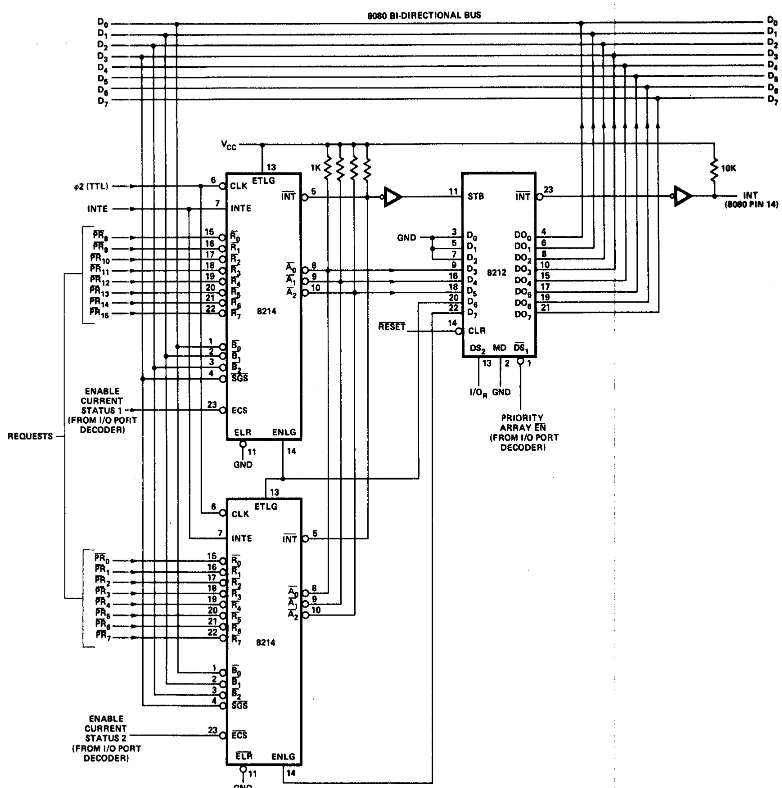
Here the 8212 is used as the status latch for an 8080 microcomputer system. The input to the 8212 latch is directly from the 8080 data bus. Timing shows that when the SYNC signal is true, which is connected to the DS2 input and the phase 1 signal is true, which is a TTL level coming from the clock generator; then, the status data will be latched into the 8212.

Note: The mode signal is tied high so that the output on the latch is active and enabled all the time.

It is shown that the two areas of concern are the bidirectional data bus of the microprocessor and the control bus.

8080 STATUS LATCH





16 Level Controller

IX. 8080 System

This drawing shows the 8212 used in the I/O section of an 8080 microcomputer system. The system consists of 8 input ports, 8 output ports, 8 level priority systems, and a bidirectional bus driver. (The data bus within the system is darkened for emphasis). Basically, the operation would be as follows: The 8 ports, for example, could be connected to 8 keyboards, each keyboard having its own priority level. The keyboard could provide a strobe input of its own which would clear the service request flip-flop. The $\overline{INT}$ signals are connected to an 8 level priority encoding circuit. This circuit provides a positive true level to the central processor (INT) along with a three-bit code to the interrupt instruction port for the generation of RESTART instructions. Once the processor has been interrupted and it acknowledges the reception of the interrupt, the Interrupt Acknowledge signal is generated. This signal transfers data in the form of a RESTART instruction onto the buffered data bus When the DBIN signal is true this RESTART instruction is gated into the microcomputer, in this case, the 8080 CPU. The 8080 then performs a software controlled interrupt service routine, saving the status of its current operation in the push-down stack and performing an INPUT instruction. The INPUT instruction thus sets the INP status bit, which is common to all input ports.

Also present is the address of the device on the 8080 address bus which in this system is connected to an 8205, one out of eight decoder with active low outputs. These active low outputs will enable one of the input ports, the one that interrupted the processor, to put its data onto the buffered data bus to be transmitted to the CPU when the data bus input signal is true. The processor can also output data from the 8080 data bus to the buffered data bus when the data bus input signal is false. Using the same address selection technique from the 8205 decoder and the output status bit, we can select with this system one of eight output ports to transmit the data to the system's output device structure.

Note: This basic I/O configuration for the 8080 can be expanded to 256 input devices and 256 output devices all using 8212 and, of course, the appropriate decoding.

Note that the 8080 is a 3.3-volt minimum high input requirement and that the 8212 has a 3.65-volt minimum high output providing the designer with a 350 milli volt noise margin worst case for 8080 systems when using the 8212.

FUNCTIONAL DESCRIPTION

Microprocessors like the 8080 are MOS devices and are generally capable of driving a single TTL load. The same is true for MOS memory devices. While this type of drive is sufficient in small systems with few components, quite often it is necessary to buffer the microprocessor and memories when adding components or expanding to a multi-board system.

The 8216/8226 is a four bit bi-directional bus driver specifically designed to buffer microcomputer system components.

Bi-Directional Driver

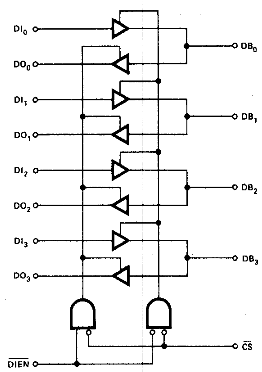
Each buffered line of the four bit driver consists of two separate buffers that are tri-state in nature to achieve direct bus interface and bi-directional capability. On one side of the driver the output of one buffer and the input of another are tied together (DB), this side is used to interface to the system side components such as memories, I/O, etc., because its interface is direct TTL compatible and it has high drive (50mA). On the other side of the driver the inputs and outputs are separated to provide maximum flexibility. Of course, they can be tied together so that the driver can be used to buffer a true bi-directional bus such as the 8080 Data Bus. The DO outputs on this side of the driver have a special high voltage output drive capability (3.65V) so that direct interface to the 8080 and 8008 CPUs is achieved with an adequate amount of noise immunity (350mV worst case).

Control Gating $\overline{\text{DIEN}}$, $\overline{\text{CS}}$

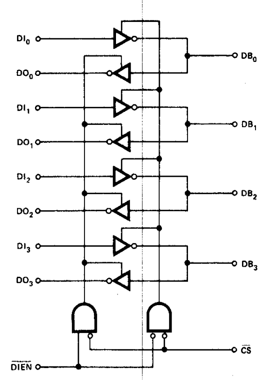
The $\overline{\text{CS}}$ input is actually a device select. When it is "high" the output drivers are all forced to their high-impedance state. When it is at "zero" the device is selected (enabled) and the direction of the data flow is determined by the $\overline{\text{DIEN}}$ input.

The $\overline{\text{DIEN}}$ input controls the direction of data flow (see Figure 1) for complete truth table. This direction control is accomplished by forcing one of the pair of buffers into its high impedance state and allowing the other to transmit its data. A simple two gate circuit is used for this function.

The 8216/8226 is a device that will reduce component count in microcomputer systems and at the same time enhance noise immunity to assure reliable, high performance operation.



(a) 8216



(b) 8226

$\overline{\text{DIEN}}$	$\overline{\text{CS}}$	
0	0	DI → DB
1	0	DB → DO
0	1	HIGH IMPEDANCE
1	1	HIGH IMPEDANCE

Figure 1. 8216/8226 Logic Diagrams

Absolute Maximum Ratings*

Temperature Under Bias Plastic . . −65°C to +75°C
Storage Temperature . . . . −65°C to +160°C
All Output or Supply Voltages . . . . −0.5 to +7 Volts
All Input Voltages . . . . −1.0 to 5.5 Volts
Output Currents . . . . 125 mA

*COMMENT: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or at any other condition above those indicated in the operational sections of this specification is not implied.

D.C. Characteristics

T_A = 0°C to +75°C V_{CC} = +5V ±5%

Symbol	Parameter	Limits Min.	Limits Typ.	Limits Max.	Unit	Test Conditions
I_F	Input Load Current ACK, DS_2, CR, DI_1-DI_8 Inputs			−.25	mA	V_F = .45V
I_F	Input Load Current MD Input			−.75	mA	V_F = .45V
I_F	Input Load Current DS_1 Input			−1.0	mA	V_F = .45V
I_R	Input Leakage Current ACK, DS, CR, DI_1-DI_8 Inputs			10	μA	V_R = 5.25V
I_R	Input Leakage Current MO Input			30	μA	V_R = 5.25V
I_R	Input Leakage Current DS_1 Input			40	μA	V_R = 5.25V
V_C	Input Forward Voltage Clamp			−1	V	I_C = −5 mA
V_{IL}	Input "Low" Voltage			.85	V	
V_{IH}	Input "High" Voltage	2.0			V	
V_{OL}	Output "Low" Voltage			.45	V	I_{OL} = 15 mA
V_{OH}	Output "High" Voltage	3.65	4.0		V	I_{OH} = −1 mA
I_{SC}	Short Circuit Output Current	-15		-75	mA	V_O = 0 V
$\lvert I_O \rvert$	Output Leakage Current High Impedance State			20	μA	V_O = .45V/5.25V
I_{CC}	Power Supply Current		90	130	mA	

D.C. AND OPERATING CHARACTERISTICS

ABSOLUTE MAXIMUM RATINGS*

Temperature Under Bias . . . . 0°C to 70°C
Storage Temperature . . . . -65°C to +150°C
All Output and Supply Voltages . . . . -0.5V to +7V
All Input Voltages . . . . -1.0V to +5.5V
Output Currents . . . . 125 mA

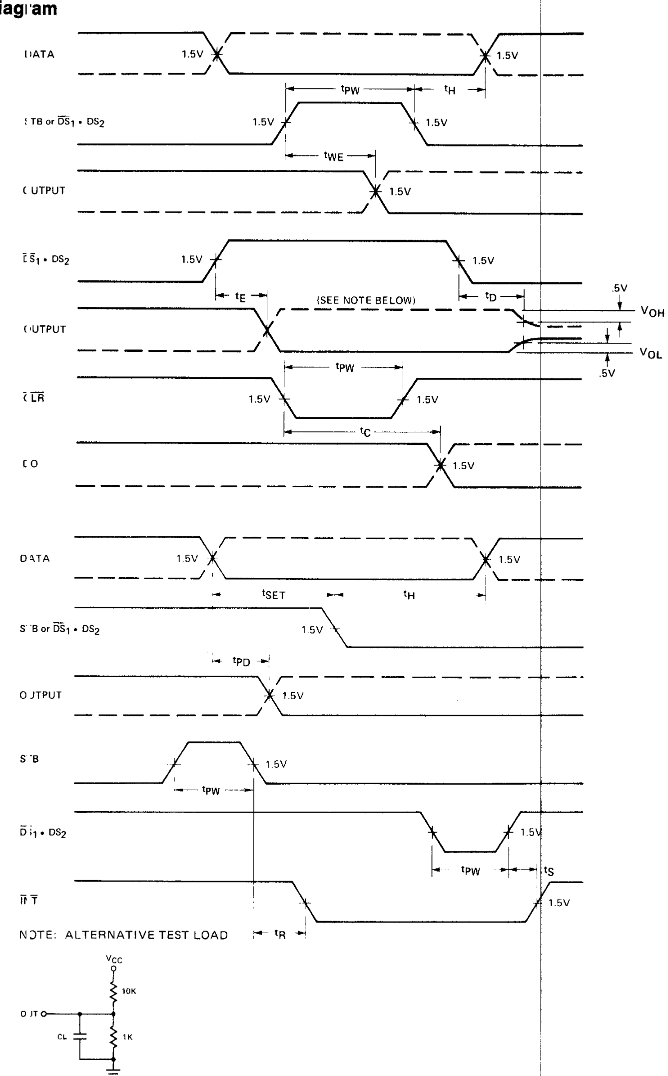
*COMMENT: Stresses above those listed under "Absolute Maximum Rating" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or at any other condition above those indicated in the operational sections of this specification is not implied.

T_A = 0°C to +70°C, V_{CC}=+5V ±5%

Symbol	Parameter	Limits Min.	Limits Typ.	Limits Max.	Unit	Conditions
I_{F1}	Input Load Current $\overline{DIEN}$, $\overline{CS}$		-0.15	-.5	mA	V_F = 0.45
I_{F2}	Input Load Current All Other Inputs		-0.08	-.25	mA	V_F = 0.45
I_{R1}	Input Leakage Current $\overline{DIEN}$, $\overline{CS}$			20	μA	V_R = 5.25V
I_{R2}	Input Leakage Current DI Inputs			10	μA	V_R = 5.25V
V_C	Input Forward Voltage Clamp			-1	V	I_C = -5mA
V_{IL}	Input "Low" Voltage			.95	V	
V_{IH}	Input "High" Voltage	2.0			V	
$\|I_O\|$	Output Leakage Current (3-State) DO / DB			20 100	μA	V_O = 0.45V/5.25V
I_{CC}	Power Supply Current 8216		95	130	mA	
I_{CC}	Power Supply Current 8226		85	120	mA	
V_{OL1}	Output "Low" Voltage		0.3	.45	V	DO Outputs I_{OL}=15mA DB Outputs I_{OL}=25mA
V_{OL2}	Output "Low" Voltage 8216		0.5	.6	V	DB Outputs I_{OL}=55mA
V_{OL2}	Output "Low" Voltage 8226		0.5	.6	V	DB Outputs I_{OL}=50mA
V_{OH1}	Output "High" Voltage	3.65	4.0		V	DO Outputs I_{OH} = -1mA
V_{OH2}	Output "High" Voltage	2.4	3.0		V	DB Outputs I_{OH} = -10mA
I_{OS}	Output Short Circuit Current	-15 -30	-35 -75	-65 -120	mA mA	DO Outputs $V_O \cong$ 0V, DB Outputs V_{CC}=5.0V

NOTE: Typical values are for T_A = 25°C, V_{CC} = 5.0V.

Timing Diagram



intel

Silicon Gate MOS 8255

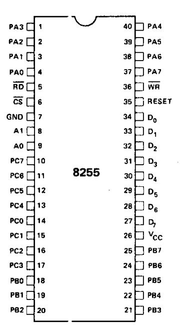
PROGRAMMABLE PERIPHERAL INTERFACE

- 24 Programmable I/O Pins
- Completely TTL Compatible
- Fully Compatible with MCS™-8 and MCS™-80 Microprocessor Families
- Direct Bit Set/Reset Capability Easing Control Application Interface
- 40 Pin Dual In-Line Package
- Reduces System Package Count

The 8255 is a general purpose programmable I/O device designed for use with both the 8008 and 8080 microprocessors. It has 24 I/O pins which may be individually programmed in two groups of twelve and used in three major modes of operation. In the first mode (Mode 0), each group of twelve I/O pins may be programmed in sets of 4 to be input or output. In Mode 1, the second mode, each group may be programmed to have 8 lines of input or output. Of the remaining four pins three are used for handshaking and interrupt control signals. The third mode of operation (Mode 2) is a Bidirectional Bus mode which uses 8 lines for a bidirectional bus and five lines, borrowing one from the other group, for handshaking.

Other features of the 8255 include bit set and reset capability and the ability to source 1mA of current at 1.5 volts. This allows darlington transistors to be directly driven for applications such as printers and high voltage displays.

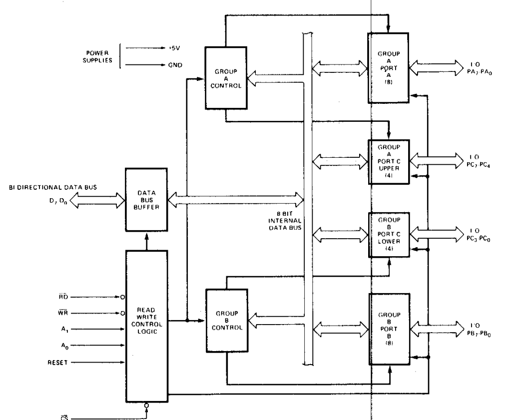
PIN CONFIGURATION



PIN NAMES

D_7–D_0	DATA BUS (BI-DIRECTIONAL)
RESET	RESET INPUT
$\overline{CS}$	CHIP SELECT
$\overline{RD}$	READ INPUT
$\overline{WR}$	WRITE INPUT
A0, A1	PORT ADDRESS
PA7-PA0	PORT A (BIT)
PB7-PB0	PORT B (BIT)
PC7-PC0	PORT C (BIT)
V_{CC}	+5 VOLTS
GND	∅ VOLTS

8255 BLOCK DIAGRAM



8253 PRELIMINARY FUNCTIONAL DESCRIPTION

In Microcomputer-based systems the most common interface is to a mechanical device such as a printer head or stepper motor. All such devices have inherent delays that must be accounted for if accurate and reliable performance is to be achieved. The systems software allows for such delays by programmed timing loops. This type of programming requires significant overhead and maintenance of multiple loops gets extremely complicated.

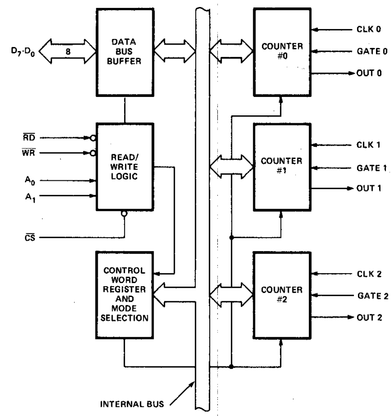
The 8253 Programmable Interval Timer is a single chip solution to system timing problems. In essence, it is a group of three 16-bit counters that are independent in nature but driven commonly as I/O peripheral ports. Instead of setting up timing loops in the system software, the programmer configures the 8253 to match his requirements. The programmer initializes one of the three counters of the 8253 with the quantity and mode desired then, upon command, the 8253 will count out the delay and interrupt the microcomputer when it has finished its task. It is easy to see that the software overhead is minimal and that multiple delays can be easily maintained by assigned interrupt levels to different counters. Other functions that are non-delay in nature and require counters can also be implemented with the 8253.

- Programmable Baud Rate Generator
- Event Counter
- Binary Rate Multiplier
- Real Time Clock

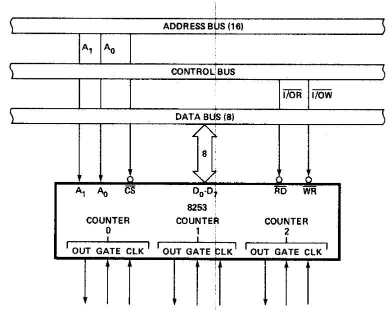
System Interface

The 8253 is a component of the MCS-80 system and interfaces in the same manner as all other peripherals of the family. It is treated by the systems software as an array of I/O ports; three are counters and the fourth is a control register for programming. The OUT lines of each counter would normally be tied to the interrupt request inputs of the 8259.

The 8253 represents a significant improvement for solving one of the most common problems in system design and reducing software overhead.



8253 Block Diagram.



8253 System Interface.

(RESET)

Reset: A "high" on this input clears all internal registers including the Control Register and all ports (A, B, C) are set to the input mode.

Group A and Group B Controls

The functional configuration of each port is programmed by the systems software. In essence, the 8080 CPU "outputs" a control word to the 8255. The control word contains information such as "mode", "bit set", "bit reset" etc. that initializes the functional configuration of the 8255.

Each of the Control blocks (Group A and Group B) accepts "commands" from the Read/Write Control Logic, receives "control words" from the internal data bus and issues the proper commands to its associated ports.

Control Group A – Port A and Port C upper (C7-C4)
Control Group B – Port B and Port C lower (C3-C0)

The Control Word Register can **Only** be written into. No Read operation of the Control Word Register is allowed.

Ports A, B, and C

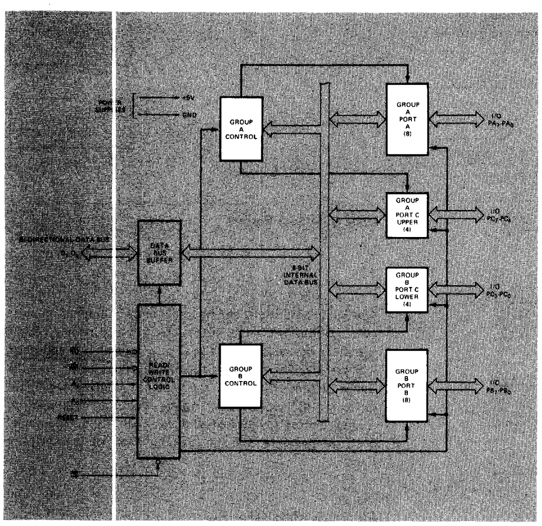
The 8255 contains three 8-bit ports (A, B, and C). All can be configured in a wide variety of functional characteristics by the system software but each has its own special features or "personality" to further enhance the power and flexibility of the 8255.

Port A: One 8-bit data output latch/buffer and one 8-bit data input latch.

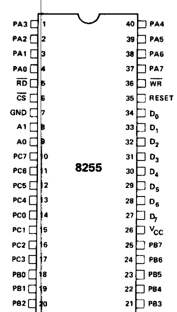
Port B: One 8-bit data input/output latch/buffer and one 8-bit data input buffer.

Port C: One 8-bit data output latch/buffer and one 8-bit data input buffer (no latch for input). This port can be divided into two 4-bit ports under the mode control. Each 4-bit port contains a 4-bit latch and it can be used for the control signal outputs and status signal inputs in conjunction with Ports A and B.

8255 BLOCK DIAGRAM



PIN CONFIGURATION



PIN NAMES

D_7–D_0	DATA BUS (BI-DIRECTIONAL)
RESET	RESET INPUT
$\overline{CS}$	CHIP SELECT
$\overline{RD}$	READ INPUT
$\overline{WR}$	WRITE INPUT
A0, A1	PORT ADDRESS
PA7-PA0	PORT A (BIT)
PB7-PB0	PORT B (BIT)
PC7-PC0	PORT C (BIT)
V_{CC}	+5 VOLTS
GND	ø VOLTS

8257 PRELIMINARY FUNCTIONAL DESCRIPTION

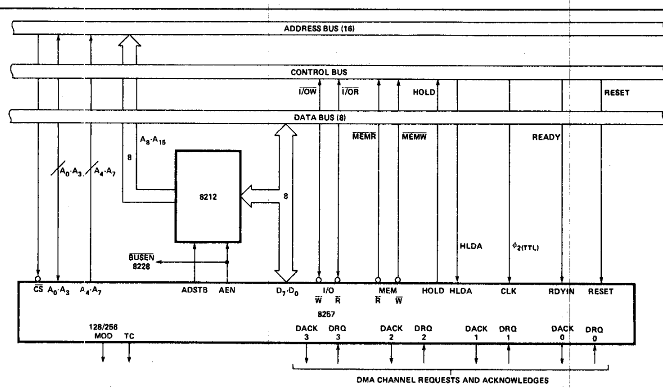
The transfer of data between a mass storage device such as a floppy disk or mag cassette and system RAM memory is often limited by the speed of the microprocessor. Removing the processor during such a transfer and letting an auxillary device manage the transfer in a more efficient manner would greatly improve the speed and make mass storage devices more attractive, even to the small system designer.

The transfer technique is called DMA (Direct Memory Access); in essence the CPU is idled so that it no longer has control of the system bus and a DMA controller takes over to manage the transfer.

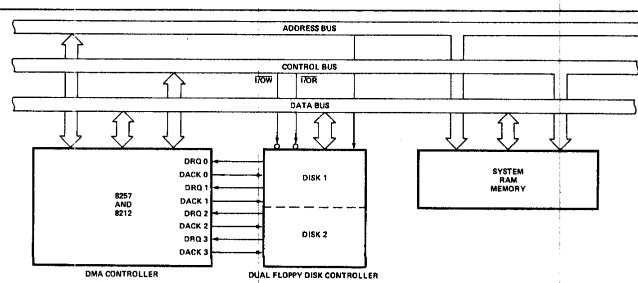
The 8257 Programmable DMA Controller is a single chip, four channel device that can efficiently manage DMA activities. Each channel is assigned a priority level so that if multi-DMA activities are required each mass storage device can be serviced, based on its importance in the system. In operation, a request is made from a peripheral device for access to the system bus. After its priority is accepted a HOLD command is ussued to the CPU, the CPU issues a HLDA and that DMA channel has complete control of the system bus. Transfers can be made in blocks, suspending the processors operation during the entire transfer or, the transfer can be made a few bytes at a time, hidden in the execution states of each instruction cycle, (cycle-stealing).

The modes and priority resolving are maintained by the system software as well as initializing each channel as to the starting address and length of transfer.

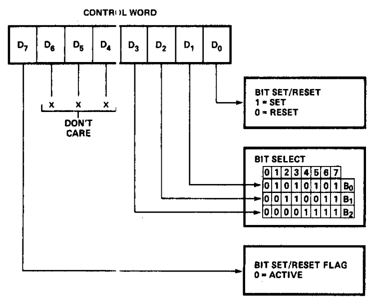
The system interface is similar to the other peripherals of the MCS-80 but an additional 8212 is necessary to control the entire address bus. A special control signal BUSEN is connected directly to the 8228 so that the data bus and control bus will be released at the proper time.



System Interface 8257.



System Application of 8257.



Bit Set/Reset Format

When Port C is being used as status/control for Port A or B, these bits can be set or reset by using the Bit Set/Reset operation just as if they were data output ports.

Interrupt Control Functions

When the 8255 is programmed to operate in Mode 1 or Mode 2, control signals are provided that can be used as interrupt request inputs to the CPU. The interrupt request signals, generated from Port C, can be inhibited or enabled by setting or resetting the associated INTE flip-flop, using the Bit set/reset function of Port C.

This function allows the Programmer to disallow or allow a specific I/O device to interrupt the CPU without effecting any other device in the interrupt structure.

INTE flip-flop definition:

(BIT-SET) – INTE is SET – Interrupt enable
(BIT-RESET) – INTE is RESET – Interrupt disable

Note: All Mask flip-flops are automatically reset during mode selection and device Reset.

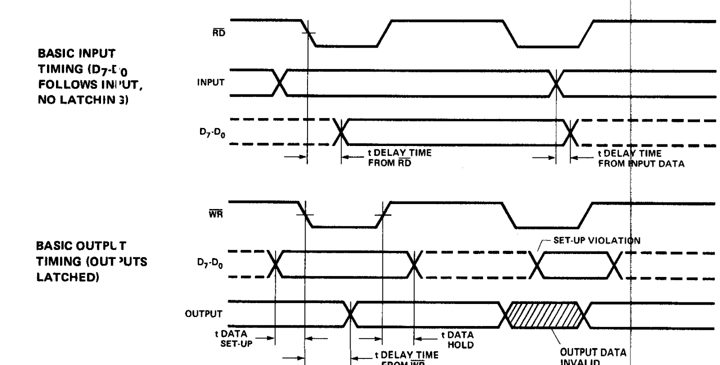
Operating Modes

Mode 0 (Basic Input/Output)

This functional configuration provides simple Input and Output operations for each of the three ports. No "handshaking" is required, data is simply written to or read from a specified port.

Mode 0 Basic Functional Definitions:

- Two 8-bit ports and two 4-bit ports.
- Any port can be input or output.
- Outputs are latched.
- Inputs are not latched.
- 16 different Input/Output configurations are possible in this Mode.



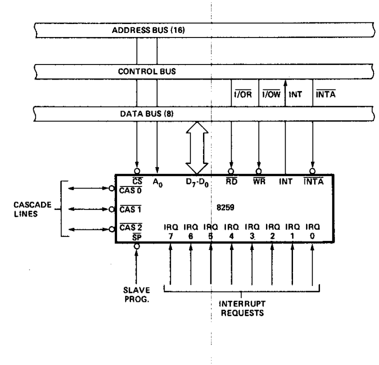
Mode 0 Timing

8259 PRELIMINARY FUNCTIONAL DESCRIPTION

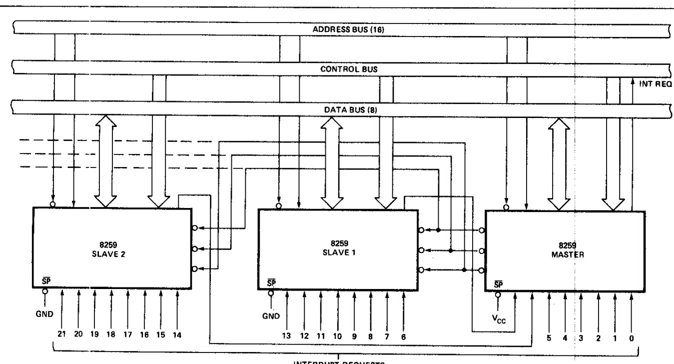
In microcomputer systems, the rate at which a peripheral device or devices can be serviced determines the total amount of system tasks that can be assigned to the control of the microprocessor. The higher the throughput the more jobs the microcomputer can do and the more cost effective it becomes. Interrupts have long been accepted as a key to improving system throughput by servicing a peripheral device only when the device has requested it to do so. Efficient managing of the interrupt requests to the CPU will have a significant effect on the overall cost effectiveness of the microcomputer system.

The 8259 Programmable Interrupt Controller is a single-chip device that can manage eight levels of requests and has built-in features for expandability to other 8259s (up to 64 levels). It is programmed by the systems software as an I/O peripheral. A selection of priority algorithms is available to the programmer so that the manner in which the requests are processed by the 8259 can be configured to match his system requirements. The priority assignments and algorithms can be changed or reconfigured dynamically at any time during the main program. This means that the complete interrupt structure can be defined as required, based on the total system environment.

The system interface is the same as other peripheral devices in the MCS-80. A special input is provided ($\overline{SP}$) to program the 8259 as a slave or master device when expanding to more than eight levels. Basically the master accepts INT inputs from the slaves and issues a composite request to the 8080A; when it receives the $\overline{INTA}$ from the 8228 it puts the first byte on the CALL on the bus. On subsequent $\overline{INTA}$s the interrupting slave puts out the address of the vector.



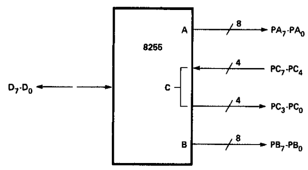
8259 System Interface.



Cascading the 8259 22 Level Controller (Expandable to 64 levels).

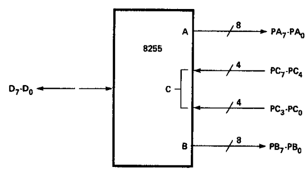
CONTROL WORD #4

D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0
1	0	0	0	1	0	0	0



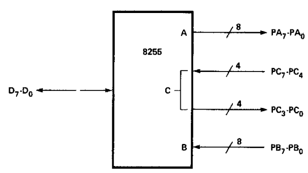
CONTROL WORD #5

D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0
1	0	0	0	1	0	0	1



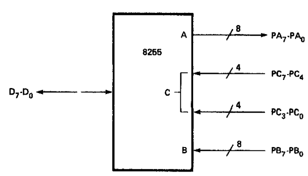
CONTROL WORD #6

D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0
1	0	0	0	1	0	1	0



CONTROL WORD #7

D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0
1	0	0	0	1	0	1	1



CONTROL WORD #8

D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0
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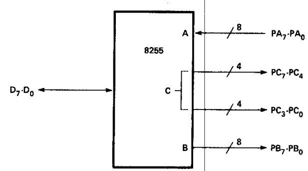

CONTROL WORD #9

D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0
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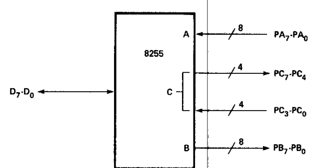

CONTROL WORD #10

D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0
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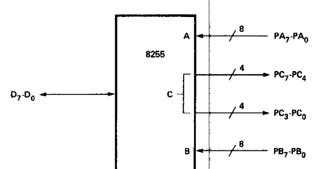

CONTROL WORD #11

D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0
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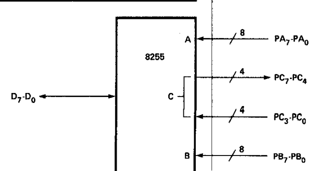

PACKAGING INFORMATION

Dimensions in inches and (millimeters).

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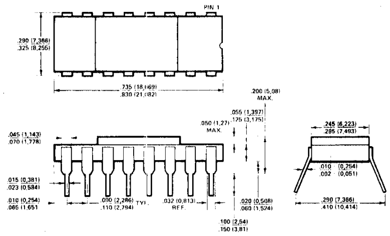
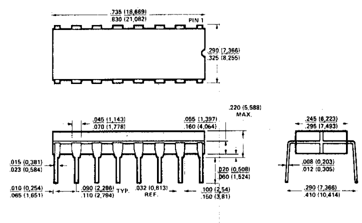
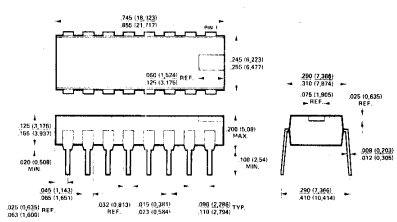


16-LEAD CerDIP DUAL IN-LINE PACKAGE (D)



16-LEAD PLASTIC DUAL IN-LINE PACKAGE (P)



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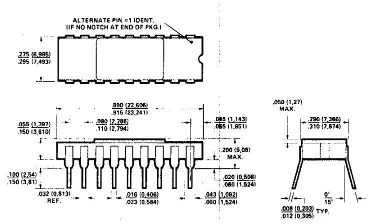

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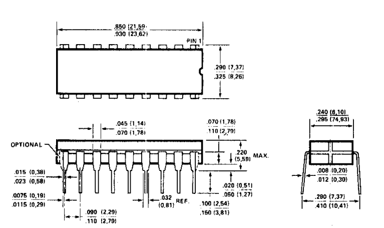

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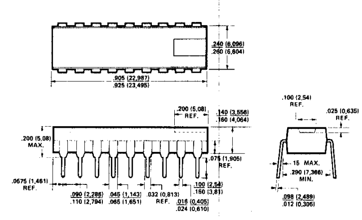
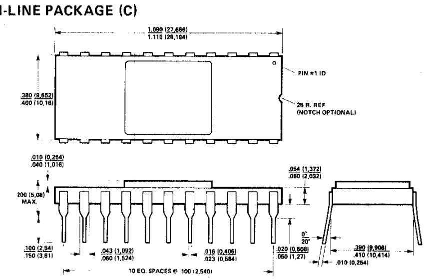


22-LEAD CERAMIC DUAL IN-LINE PACKAGE (C)



Input Control Signal Definition

STB (Strobe Input

A "low" on this input loads data into the input latch.

IBF (Input Buffer Full F/F)

A "high" on this output indicates that the data has been loaded into the input latch; in essence, an acknowledgement. IBF is set by the falling edge of the STB input and is reset by the rising edge of the RD input.

INTR (Interrupt Request)

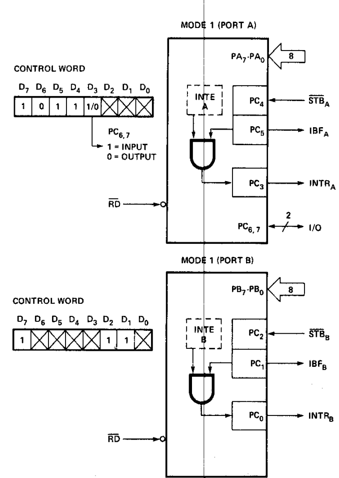
A "high" on this output can be used to interrupt the CPU when an input device is requesting service. INTR is set by the rising edge of $\overline{STB}$ if IBF is a "one" and INTE is a "one". It is reset by the falling edge of $\overline{RD}$. This procedure allows an input device to request service from the CPU by simply strobing its data into the port.

INTE A

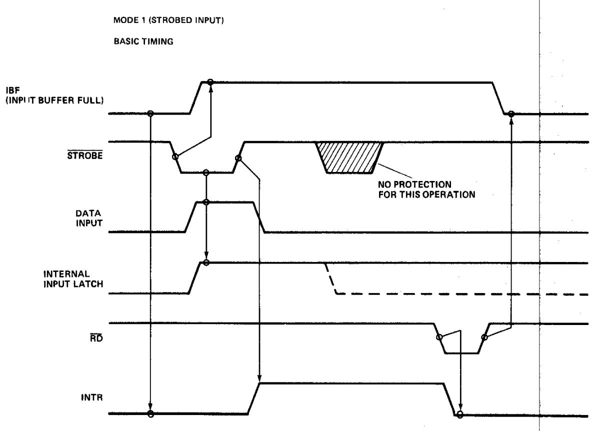
Controlled by bit set/reset of PC_4.

INTE B

Controlled by bit set/reset of PC_2.



Mode 1 Input



Basic Timing Input

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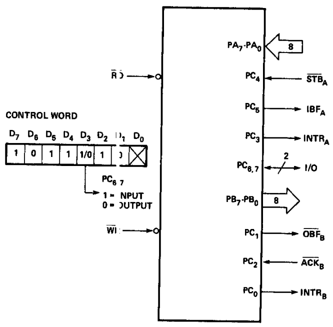
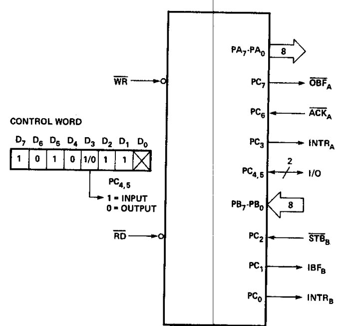
***Field Application Location**

Combinations of Mode 1

Port A and Port B can be individually defined as input or output in Mode 1 to support a wide variety of strobed I/O applications.



PORT A – (STROBED INPUT)
PORT B – (STROBED OUTPUT)



PORT A – (STROBED OUTPUT)
PORT B – (STROBED INPUT)

Operating Modes

Mode 2 (Strobed Bi-Directional Bus I/O)

This functional configuration provides a means for communicating with a peripheral device or structure on a single 8-bit bus for both transmitting and receiving data (bi-directional bus I/O). "Handshaking" signals are provided to maintain proper bus flow discipline in a similar manner to Mode 1. Interrupt generation and enable/disable functions are also available.

Mode 2 Basic Functional Definitions:

- Used in Group A only.
- One 8-bit, bi-directional bus Port (Port A) and a 5-bit control Port (Port C).
- Both inputs and outputs are latched.
- The 5-bit control port (Port C) is used for control and status for the 8-bit, bi-directional bus port (Port A).

Bi-Directional Bus I/O Control Signal Definition

INTR (Interrupt Request)

A high on this output can be used to interrupt the CPU for both input or output operations.

Output Operations

$\overline{OBF}$ (Output Buffer Full)

The $\overline{OBF}$ output will go "low" to indicate that the CPU has written data out to Port A.

$\overline{ACK}$ (Acknowledge)

A "low" on this input enables the tri-state output buffer of Port A to send out the data. Otherwise, the output buffer will be in the high-impedance state.

INTE 1 (The INTE Flip-Flop associated with $\overline{OBF}$)

Controlled by bit set/reset of PC_6.

Input Operations

$\overline{STB}$ (Strobe Input)

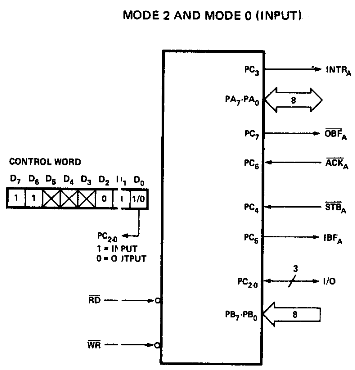
A "low" on this input loads data into the input latch.

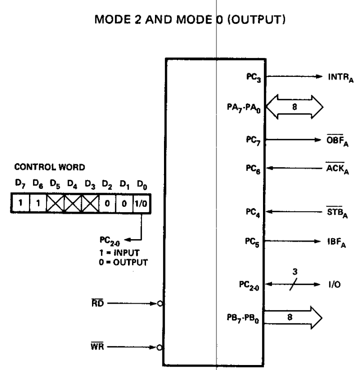
IBF (Input Buffer Full F/F)

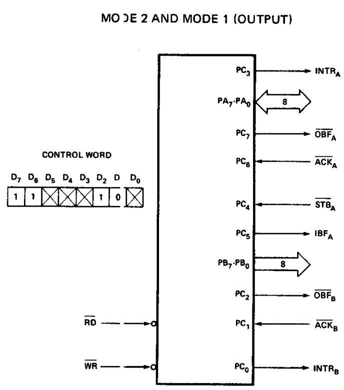
A "high" on this output indicates that data has been loaded into the input latch.

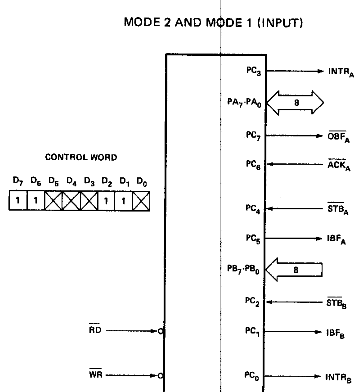
INTE 2 (The INTE Flip-Flop associated with IBF)

Controlled by bit set/reset of PC_4.









Mode 2 Combinations

INSTRUCTION SET

Summary of Processor Instructions

Mnemonic	Description	D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0	Clock[2] Cycles
		Instruction Code[1]								
$MOV_{r1,r2}$	Move register to register	0	1	D	D	D	S	S	S	5
MOV M, r	Move register to memory	0	1	1	1	0	S	S	S	7
MOV r, M	Move memory to register	0	1	D	D	D	1	1	0	7
HLT	Halt	0	1	1	1	0	1	1	0	7
MVI r	Move immediate register	0	0	D	D	D	1	1	0	7
MVI M	Move immediate memory	0	0	1	1	0	1	1	0	10
INR r	Increment register	0	0	D	D	D	1	0	0	5
DCR r	Decrement register	0	0	D	D	D	1	0	1	5
INR M	Increment memory	0	0	1	1	0	1	0	0	10
DCR M	Decrement memory	0	0	1	1	0	1	0	1	10
ADD r	Add register to A	1	0	0	0	0	S	S	S	4
ADC r	Add register to A with carry	1	0	0	0	1	S	S	S	4
SUB r	Subtract register from A	1	0	0	1	0	S	S	S	4
SBB r	Subtract register from A with borrow	1	0	0	1	1	S	S	S	4
ANA r	And register with A	1	0	1	0	0	S	S	S	4
XRA r	Exclusive Or register with A	1	0	1	0	1	S	S	S	4
ORA r	Or register with A	1	0	1	1	0	S	S	S	4
CMP r	Compare register with A	1	0	1	1	1	S	S	S	4
ADD M	Add memory to A	1	0	0	0	0	1	1	0	7
ADC M	Add memory to A with carry	1	0	0	0	1	1	1	0	7
SUB M	Subtract memory from A	1	0	0	1	0	1	1	0	7
SBB M	Subtract memory from A with borrow	1	0	0	1	1	1	1	0	7
ANA M	And memory with A	1	0	1	0	0	1	1	0	7
XRA M	Exclusive Or memory with A	1	0	1	0	1	1	1	0	7
ORA M	Or memory with A	1	0	1	1	0	1	1	0	7
CMP M	Compare memory with A	1	0	1	1	1	1	1	0	7
ADI	Add immediate to A	1	1	0	0	0	1	1	0	7
ACI	Add immediate to A with carry	1	1	0	0	1	1	1	0	7
SUI	Subtract immediate from A	1	1	0	1	0	1	1	0	7
SBI	Subtract immediate from A with borrow	1	1	0	1	1	1	1	0	7
ANI	And immediate with A	1	1	1	0	0	1	1	0	7
XRI	Exclusive Or immediate with A	1	1	1	0	1	1	1	0	7
ORI	Or immediate with A	1	1	1	1	0	1	1	0	7
CPI	Compare immediate with A	1	1	1	1	1	1	1	0	7
RLC	Rotate A left	0	0	0	0	0	1	1	1	4
RRC	Rotate A right	0	0	0	0	1	1	1	1	4
RAL	Rotate A left through carry	0	0	0	1	0	1	1	1	4
RAR	Rotate A right through carry	0	0	0	1	1	1	1	1	4
JMP	Jump unconditional	1	1	0	0	0	0	1	1	10
JC	Jump on carry	1	1	0	1	1	0	1	0	10
JNC	Jump on no carry	1	1	0	1	0	0	1	0	10
JZ	Jump on zero	1	1	0	0	1	0	1	0	10
JNZ	Jump on no zero	1	1	0	0	0	0	1	0	10
JP	Jump on positive	1	1	1	1	0	0	1	0	10
JM	Jump on minus	1	1	1	1	1	0	1	0	10
JPE	Jump on parity even	1	1	1	0	1	0	1	0	10
JPO	Jump on parity odd	1	1	1	0	0	0	1	0	10
CALL	Call unconditional	1	1	0	0	1	1	0	1	17
CC	Call on carry	1	1	0	1	1	1	0	0	11/17
CNC	Call on no carry	1	1	0	1	0	1	0	0	11/17
CZ	Call on zero	1	1	0	0	1	1	0	0	11/17
CNZ	Call on no zero	1	1	0	0	0	1	0	0	11/17
CP	Call on positive	1	1	1	1	0	1	0	0	11/17
CM	Call on minus	1	1	1	1	1	1	0	0	11/17
CPE	Call on parity even	1	1	1	0	1	1	0	0	11/17
CPO	Call on parity odd	1	1	1	0	0	1	0	0	11/17
RET	Return	1	1	0	0	1	0	0	1	10
RC	Return on carry	1	1	0	1	1	0	0	0	5/11
RNC	Return on no carry	1	1	0	1	0	0	0	0	5/11

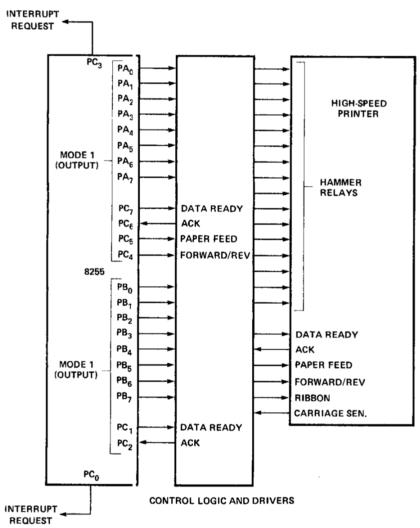
Mnemonic	Description	D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0	Clock[2] Cycles
		Instruction Code[1]								
RZ	Return on zero	1	1	0	0	1	0	0	0	5/11
RNZ	Return on no zero	1	1	0	0	0	0	0	0	5/11
RP	Return on positive	1	1	1	1	0	0	0	0	5/11
RM	Return on minus	1	1	1	1	1	0	0	0	5/11
RPE	Return on parity even	1	1	1	0	1	0	0	0	5/11
RPO	Return on parity odd	1	1	1	0	0	0	0	0	5/11
RST	Restart	1	1	A	A	A	1	1	1	11
IN	Input	1	1	0	1	1	0	1	1	10
OUT	Output	1	1	0	1	0	0	1	1	10
LXI B	Load immediate register Pair B & C	0	0	0	0	0	0	0	1	10
LXI D	Load immediate register Pair D & E	0	0	0	1	0	0	0	1	10
LXI H	Load immediate register Pair H & L	0	0	1	0	0	0	0	1	10
LXI SP	Load immediate stack pointer	0	0	1	1	0	0	0	1	10
PUSH B	Push register Pair B & C on stack	1	1	0	0	0	1	0	1	11
PUSH D	Push register Pair D & E on stack	1	1	0	1	0	1	0	1	11
PUSH H	Push register Pair H & L on stack	1	1	1	0	0	1	0	1	11
PUSH PSW	Push A and Flags on stack	1	1	1	1	0	1	0	1	11
POP B	Pop register pair B & C off stack	1	1	0	0	0	0	0	1	10
POP D	Pop register pair D & E off stack	1	1	0	1	0	0	0	1	10
POP H	Pop register pair H & L off stack	1	1	1	0	0	0	0	1	10
POP PSW	Pop A and Flags off stack	1	1	1	1	0	0	0	1	10
STA	Store A direct	0	0	1	1	0	0	1	0	13
LDA	Load A direct	0	0	1	1	1	0	1	0	13
XCHG	Exchange D & E, H & L Registers	1	1	1	0	1	0	1	1	4
XTHL	Exchange top of stack, H & L	1	1	1	0	0	0	1	1	18
SPHL	H & L to stack pointer	1	1	1	1	1	0	0	1	5
PCHL	H & L to program counter	1	1	1	0	1	0	0	1	5
DAD B	Add B & C to H & L	0	0	0	0	1	0	0	1	10
DAD D	Add D & E to H & L	0	0	0	1	1	0	0	1	10
DAD H	Add H & L to H & L	0	0	1	0	1	0	0	1	10
DAD SP	Add stack pointer to H & L	0	0	1	1	1	0	0	1	10
STAX B	Store A indirect	0	0	0	0	0	0	1	0	7
STAX D	Store A indirect	0	0	0	1	0	0	1	0	7
LDAX B	Load A indirect	0	0	0	0	1	0	1	0	7
LDAX D	Load A indirect	0	0	0	1	1	0	1	0	7
INX B	Increment B & C registers	0	0	0	0	0	0	1	1	5
INX D	Increment D & E registers	0	0	0	1	0	0	1	1	5
INX H	Increment H & L registers	0	0	1	0	0	0	1	1	5
INX SP	Increment stack pointer	0	0	1	1	0	0	1	1	5
DCX B	Decrement B & C	0	0	0	0	1	0	1	1	5
DCX D	Decrement D & E	0	0	0	1	1	0	1	1	5
DCX H	Decrement H & L	0	0	1	0	1	0	1	1	5
DCX SP	Decrement stack pointer	0	0	1	1	1	0	1	1	5
CMA	Complement A	0	0	1	0	1	1	1	1	4
STC	Set carry	0	0	1	1	0	1	1	1	4
CMC	Complement carry	0	0	1	1	1	1	1	1	4
DAA	Decimal adjust A	0	0	1	0	0	1	1	1	4
SHLD	Store H & L direct	0	0	1	0	0	0	1	0	16
LHLD	Load H & L direct	0	0	1	0	1	0	1	0	16
EI	Enable Interrupts	1	1	1	1	1	0	1	1	4
DI	Disable interrupt	1	1	1	1	0	0	1	1	4
NOP	No-operation	0	0	0	0	0	0	0	0	4

NOTES: 1. DDD or SSS – 000 B – 001 C – 010 D – 011 E – 100 H – 101 L – 110 Memory – 111 A.
2. Two possible cycle times, (5/11) indicate instruction cycles dependent on condition flags.

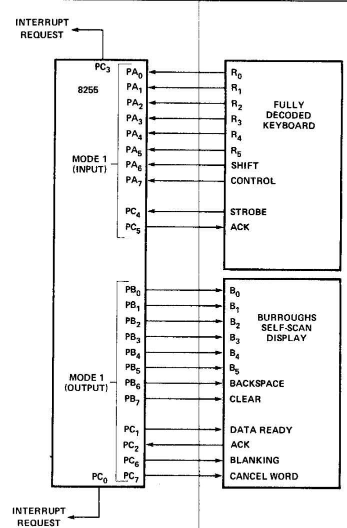
APPLICATIONS OF THE 8255

The 8255 is a very powerful tool for interfacing peripheral equipment to the 8080 microcomputer system. It represents the optimum use of available pins and is flexible enough to interface almost any I/O device without the need for additional external logic.

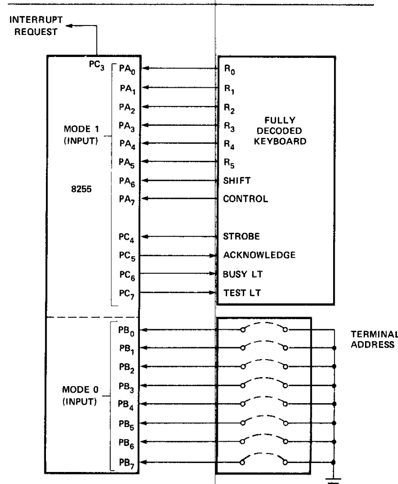
Each peripheral device in a Microcomputer system usually has a "service routine" associated with it. The routine manages the software interface between the device and the CPU. The functional definition of the 8255 is programmed by the I/O service routine and becomes an extension of the systems software. By examining the I/O devices interface characteristics for both data transfer and timing, and matching this information to the examples and tables in the Detailed Operational Description, a control word can easily be developed to initialize the 8255 to exactly "fit" the application. Here are a few examples of typical applications of the 8255.



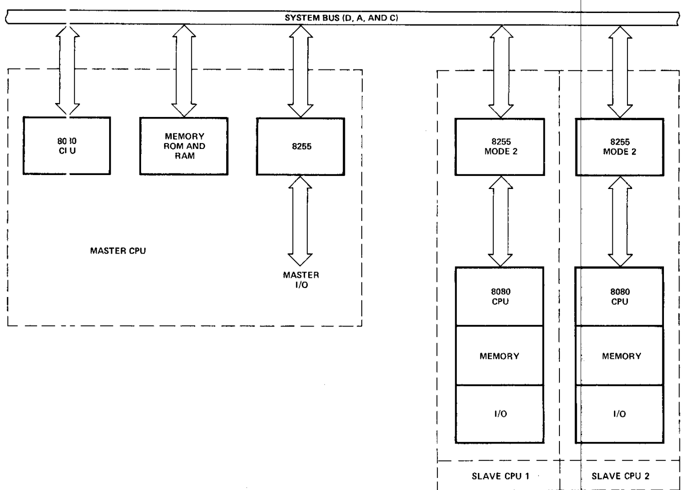
Printer Interface



Keyboard and Display Interface



Keyboard and Terminal Address Interface



Distributed Intelligence Multi-Processor Interface